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Semiconductor Group



CMOS
Logic Circuits
for
Design Engineers

Third Edition

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Logic Circuits

for

Design Engineers

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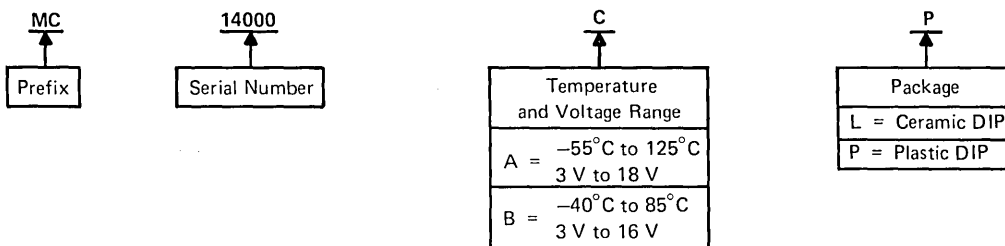
* To be announced

CMOS INTERCHANGEABILITY GUIDE

Direct replacements were based on similarity of electrical and mechanical characteristics as shown in currently published data. Interchangeability in particular applications is not guaranteed. Before using a device as a substitute, the user should compare the specifications of the substitute device with the specifications of the original.

Texas Instruments makes no warranty as to the information furnished and buyer assumes all risk in the use thereof. No liability is assumed for damages resulting from the use of the information contained in this list.

MOTOROLA INTERCHANGEABILITY



TEMPERATURE RANGE
AND
PACKAGE COMBINATION EQUIVALENTS

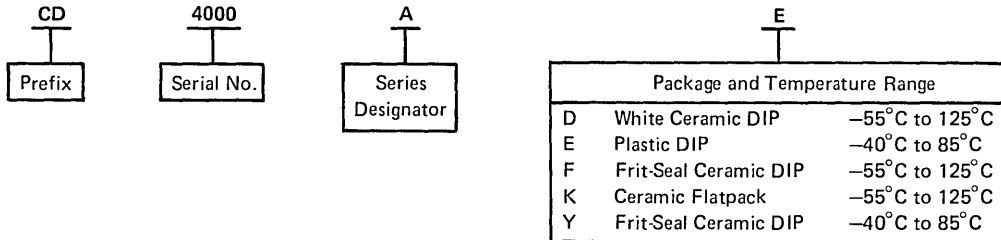
MOTOROLA
MC14___CP
MC14___CL
MC14___AL

TI
TP4___AN
TP4___AJ
TF4___AJ

MOTOROLA TYPE	TI DIRECT REPLACEMENT	MOTOROLA TYPE	TI DIRECT REPLACEMENT
MC14000___	T_4000A__	MC14029___	T_4029A__
MC14001___	T_4001A__	MC14030___	T_4030A__
MC14002___	T_4002A__	MC14040___	T_4040A__
MC14007___	T_4007A__	MC14042___	T_4042A__
MC14008___	T_4008A__	MC14043___	T_4043A__
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MC14010___	T_4010A__	MC14049___	T_4049A__
MC14011___	T_4011A__	MC14050___	T_4050A__
MC14012___	T_4012A__	MC14051___	T_4051A__
MC14013___	T_4013A__	MC14052___	T_4052A__
MC14014___	T_4014A__	MC14053___	T_4053A__
MC14015___	T_4015A__	MC14507___	T_4507A__
MC14016___	T_4016A__	MC14512___	T_4512A__
MC14017___	T_4017A__	MC14518___	T_4518A__
MC14018___	T_4018A__	MC14519___	T_4519A__
MC14019___	T_4019A__	MC14520___	T_4520A__
MC14020___	T_4020A__	MC14522___	T_4522A__
MC14021___	T_4021A__	MC14526___	T_4526A__
MC14022___	T_4022A__	MC14531___	T_4531A__
MC14023___	T_4023A__	MC14581___	T_4581A__
MC14024___	T_4024A__	MC14582___	T_4582A__
MC14025___	T_4025A__		
MC14027___	T_4027A__		
MC14028___	T_4028A__		

CMOS INTERCHANGEABILITY GUIDE

RCA INTERCHANGEABILITY



TEMPERATURE RANGE AND PACKAGE COMBINATION EQUIVALENTS

RCA	TI
CD4 ___AE	TP4 ___AN
CD4 ___AF	TF4 ___AJ
CD4 ___AY	TP4 ___AJ

RCA TYPE	TI DIRECT REPLACEMENT	RCA TYPE	TI DIRECT REPLACEMENT
CD4000A_	T_4000A_	CD4022A_	T_4022A_
CD4001A_	T_4001A_	CD4023A_	T_4023A_
CD4002A_	T_4002A_	CD4024A_	T_4024A_
CD4007A_	T_4007A_	CD4025A_	T_4025A_
CD4008A_	T_4008A_	CD4027A_	T_4027A_
CD4009A_	T_4009A_	CD4028A_	T_4028A_
CD4010A_	T_4010A_	CD4029A_	T_4029A_
CD4011A_	T_4011A_	CD4030A_	T_4030A_
CD4012A_	T_4012A_	CD4040A_	T_4040A_
CD4013A_	T_4013A_	CD4042A_	T_4042A_
CD4014A_	T_4014A_	CD4043A_	T_4043A_
CD4015A_	T_4015A_	CD4044A_	T_4044A_
CD4016A_	T_4016A_	CD4049A_	T_4049A_
CD4017A_	T_4017A_	CD4050A_	T_4050A_
CD4018A_	T_4018A_	CD4051A_	T_4051A_
CD4019A_	T_4019A_	CD4052A_	T_4052A_
CD4020A_	T_4020A_	CD4053A_	T_4053A_
CD4021A_	T_4021A_	CD4518A_	T_4518A_
		CD4520A_	T_4520A_

GLOSSARY

LETTER SYMBOLS, TERMS, AND DEFINITIONS

LETTER SYMBOLS, TERMS, AND DEFINITIONS

These symbols, terms, and definitions are in accordance with those currently agreed upon by the JEDEC Council of the Electronic Industries Association (EIA) for use in the USA and by the International Electrotechnical Commission (IEC) for international use. The definitions are grouped into sections applying to voltages, currents, switching characteristics, and classification of circuit complexity.

VOLTAGES

V_{IH} High-level input voltage

An input voltage level within the more positive (less negative) of the two ranges of values used to represent the binary variables. A minimum value is specified that is the least-positive (most-negative) value of high-level input voltage for which operation of the logic element within specification limits is guaranteed.

V_{IL} Low-level input voltage

An input voltage level within the less positive (more negative) of the two ranges of values used to represent the binary variables. A maximum value is specified that is the most-positive (least-negative) value of low-level input voltage for which operation of the logic element within specification limits is guaranteed.

V_{OH} High-level output voltage

The voltage at an output terminal with input conditions applied that according to the product specification will establish a high level at the output.

V_{OL} Low-level output voltage

The voltage at an output terminal with input conditions applied that according to the product specification will establish a low level at the output.

V_{T+} Positive-going threshold voltage

The voltage level at a transition-operated input that causes operation of the logic element according to specification as the input voltage rises from a level below the negative-going threshold voltage, V_{T-}.

V_{T-} Negative-going threshold voltage

The voltage level at a transition-operated input that causes operation of the logic element according to specification as the input voltage falls from a level above the positive-going threshold voltage, V_{T+}.

CURRENTS

I_{CC}, I_{DD}, I_{EE}, I_{SS} supply current

The current into*, respectively, the V_{CC}, V_{DD}, V_{EE}, or V_{SS} supply terminal of an integrated circuit.

I_{IH} High-level input current

The current into* an input when a high-level voltage is applied to that input.

I_{IL} Low-level input current

The current into* an input when a low-level voltage is applied to that input.

I_{OH} High-level output current

The current into* an output with input conditions applied that according to the product specification will establish a high level at the output.

*Current out of a terminal is given as a negative value.

GLOSSARY

LETTER SYMBOLS, TERMS, AND DEFINITIONS

I_{OL} Low-level output current

The current into* an output with input conditions applied that according to the product specification will establish a low level at the output.

I_{OZ} Off-state (high-impedance-state) output current (of a three-state output)

The current into* an output having three-state capability with input conditions applied that according to the product specification will establish the high-impedance state at the output.

SWITCHING CHARACTERISTICS

f_{max} Maximum clock frequency

The highest rate at which the clock input of a bistable circuit can be driven through its required sequence while maintaining stable transitions of logic level at the output with input conditions established that should cause changes of output logic level in accordance with the specification.

t_a Access time (of a memory)

The time between the application of a specific input pulse and the availability of valid data signals at an output.

t_h Hold time

The interval during which a signal is retained at a specified input terminal after an active transition occurs at another specified input terminal.

NOTES: 1. The hold time is the actual time between two events and may be insufficient to accomplish the intended result. A minimum value is specified that is the shortest interval for which correct operation of the logic element is guaranteed.
2. The hold time may have a negative value in which case the minimum limit defines the longest interval (between the release of data and the active transition) for which correct operation of the logic element is guaranteed.

t_{h(min)} Minimum hold time

The shortest hold time for which correct operation is obtained.

t_{PHL} Propagation delay time, high-to-low-level output

The time between the specified reference points on the input and output voltage waveforms with the output changing from the defined high level to the defined low level.

t_{PHZ} Output disable time (of a three-state output) from high level

The time between the specified reference points on the input and output voltage waveforms with the three-state output changing from the defined high level to a high-impedance (off) state.

t_{PLH} Propagation delay time, low-to-high-level output

The time between the specified reference points on the input and output voltage waveforms with the output changing from the defined low level to the defined high level.

t_{PLZ} Output disable time (of a three-state output) from low level

The time between the specified reference points on the input and output voltage waveforms with the three-state output changing from the defined low level to a high-impedance (off) state.

t_{PHZ} Output enable time (of a three-state output) to high level

The time between the specified reference points on the input and output voltage waveforms with the three-state output changing from a high-impedance (off) state to the defined high level.

*Current out of a terminal is given as a negative value.

GLOSSARY

LETTER SYMBOLS, TERMS, AND DEFINITIONS

tpZL Output enable time (of a three-state output) to low level

The time between the specified reference points on the input and output voltage waveforms with the three-state output changing from a high-impedance (off) state to the defined low-level.

t_{su} Setup time

The time interval between the application of a signal that is maintained at a specified input terminal and a consecutive active transition at another specified input terminal.

NOTES: 1. The setup time is the actual time between two events and may be insufficient to accomplish the setup. A minimum value is specified that is the shortest interval for which correct operation of the logic element is guaranteed.

2. The setup time may have a negative value in which case the minimum limit defines the longest interval (between the active transition and the application of the other signal) for which correct operation of the logic element is guaranteed.

t_{su(min)} Minimum setup time

The shortest setup time for which correct operation is obtained.

tTLH Transition time, low-to-high-level output

The time between a specified low-level voltage and a specified high-level voltage on a waveform that is changing from the defined low level to the defined high level.

tTHL Transition time, high-to-low-level output

The time between a specified high-level voltage and a specified low-level voltage on a waveform that is changing from the defined high level to the defined low level.

t_w Average pulse width

The time between 50-percent-amplitude points (or other specified reference points) on the leading and trailing edges of a pulse.

t_{w(min)} Minimum pulse width

The shortest pulse width for which correct operation is obtained.

CLASSIFICATION OF CIRCUIT COMPLEXITY

Gate equivalent circuit

A basic unit-of-measure of relative digital-circuit complexity. The number of gate equivalent circuits is that number of individual logic gates that would have to be interconnected to perform the same function.

LSI Large-scale integration

A concept whereby a complete major subsystem or system function is fabricated as a single microcircuit. In this context a major subsystem or system, whether logical or linear, is considered to be one that contains 100 or more equivalent gates or circuitry of similar complexity.

MSI Medium-scale integration

A concept whereby a complete subsystem function is fabricated as a single microcircuit. The subsystem or system is smaller than for LSI, but whether digital or linear, is considered to be one that contains 12 or more equivalent gates or circuitry of similar complexity.

SSI Small-scale integration

Integrated circuits of less complexity than medium-scale integration (MSI).

LOGIC GRAPHIC SYMBOLS

The logic graphic symbols used in this book are in accordance with American National Standard Graphic Symbols for Logic Diagrams (Two-State Devices) ANSI Y32.14-1973 (IEEE Std. 91-1973) which supersedes ASA Y32.14-1962, MIL-STD-806B, and MIL-STD-806C. The following is only a brief explanation of the more common symbols used in this book.

basic logic concepts

The binary numbers 1 and 0 are used in pure logic where 1 represents true, yes, or active and 0 represents false, no, or inactive. These terms should not be confused with the physical quantity (e.g., voltage) that may be used to implement the logic, nor should the term "active" be confused with a level that turns a device on or off. A truth table for a relationship in logic shows (implicitly or explicitly) all the combinations of true and false input conditions and the result (output). There are only two basic logic relationships, AND and OR. The following illustrations assume two inputs (A and B), but these can be generalized to apply to more than two inputs.

AND Y is true if and only if A is true and B is true (or more generally, if all inputs are true).

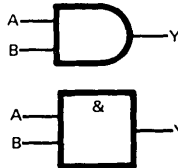
Y = 1 if and only if A = 1 and B = 1.

$$Y = A \cdot B$$

TRUTH TABLE

A	B	Y
1	1	1
1	0	0
0	1	0
0	0	0

SYMBOLS



Y32.14-1973 continues the use of both distinctive-shape and rectangular symbols for the simpler logic functions. Both forms are shown here for AND and OR; however, throughout the rest of this section, and in the data sheets in this book, usually only the distinctive shapes will be used for these functions. The rectangular symbols are most useful when making up complex combinations of logic functions.

OR Y is true if and only if A is true or B is true (or more generally, if one or more input(s) is (are) true.

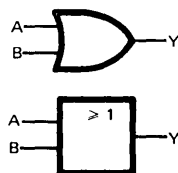
Y = 1 if and only if A = 1 or B = 1.

$$Y = A + B$$

TRUTH TABLE

A	B	Y
1	1	1
1	0	1
0	1	1
0	0	0

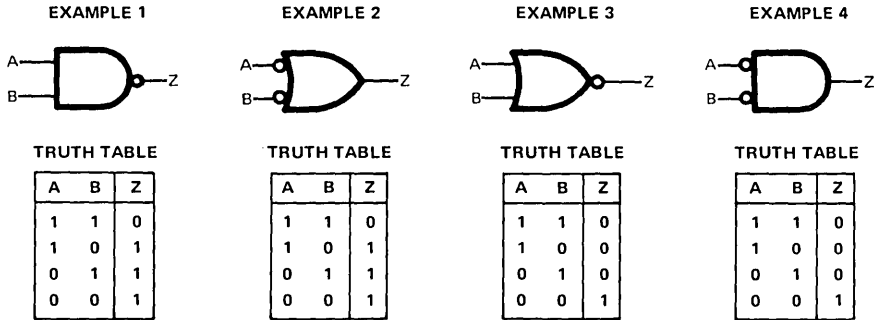
SYMBOLS



CMOS LOGIC GRAPHIC SYMBOLS

negation

In logic symbology, the presence of the negation indication symbol \circ provides for the representation of logic function inputs and outputs in terms independent of their physical values, the 0-state of the input or output being the 1-state of the symbol referred to by the symbol description.



Example 1 says that Z is not true if A is true and B is true or that Z is true if A and B are not both true. $\bar{Z} = AB$ or $Z = \overline{AB}$. This is frequently referred to as NAND (for NOT AND).

Example 2 says that Z is true if A is not true or if B is not true. $Z = \bar{A} + \bar{B}$. Note that this truth table is identical to that of Example 1. The logic equation is merely a De Morgan's transformation of the equations in Example 1. The symbols are equivalent.

Example 3, $\bar{Z} = A + B$ or $Z = \overline{A + B}$, and **Example 4**, $Z = \bar{A} \cdot \bar{B}$, also share a common truth table and are equivalent transformations of each other. The NOT OR form (Example 3) is frequently referred to as NOR.

logic implementation and polarity indication

Devices that can perform the basic logic functions, AND and OR, are called gates. Any device that can perform one of these functions can also be used to perform the other if the relationship of the input and output voltage levels to the logic variables 1 and 0 is redefined suitably.

In describing the operation of electronic logic devices, the symbol H is used to represent a "high level," which is a voltage within the more-positive (less-negative) of the two ranges of voltages used to represent the binary variables. L is used to represent a "low level," which is a voltage within the less-positive (more-negative) range.

A function table for a device shows (implicitly or explicitly) all the combinations of input conditions and the resulting output conditions.

In graphic symbols, inputs or outputs that are active when at the high level are shown without polarity indication. The polarity indicator symbol \triangleleft denotes that the active state of an input or output *with respect to the symbol to which it is attached* is the low level.

CMOS LOGIC GRAPHIC SYMBOLS

EXAMPLE 5

Assume two devices having the following function tables.

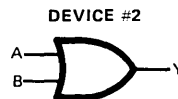
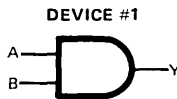
**DEVICE #1
FUNCTION TABLE**

A	B	Y
H	H	H
H	L	L
L	H	L
L	L	L

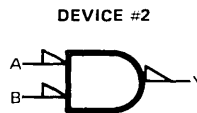
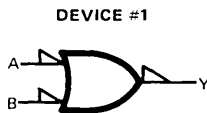
**DEVICE #2
FUNCTION TABLE**

A	B	Y
H	H	H
H	L	H
L	H	H
L	L	L

By assigning the relationships $H = 1, L = 0$ at both input and output, Device #1 can perform the AND function and Device #2 can perform the OR function. Such a consistent assignment is referred to as positive logic. The corresponding logic symbols would be:



Alternatively, by assigning the relationships $H = 0, L = 1$ at both input and output, Device #1 can perform the OR function and Device #2 can perform the AND function. Such a consistent assignment is referred to as negative logic. The corresponding logic symbols would be:



The use of the polarity indicator symbol (\blacktriangle) automatically invokes a mixed-logic convention. That is, positive logic is used at the inputs and outputs that do not have polarity indicators, negative logic is used at the inputs and outputs that have polarity indicators.

**EXAMPLE 6
FUNCTION TABLE**

A	B	Z
H	H	L
H	L	H
L	H	H
L	L	H

**EXAMPLE 7
FUNCTION TABLE**

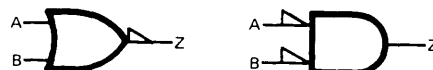
A	B	Z
H	H	L
H	L	L
L	H	L
L	L	H

This may be shown either of two ways:



Note the equivalence of these symbols to examples 1 and 2 and the fact that the function table is a positive-logic translation ($H = 1, L = 0$) of the NAND truth table, and also note that the function table is the negative-logic translation ($H = 0, L = 1$) of the NOR truth table, given in Example 3.

This may be shown either of two ways:



Note the equivalence of these symbols to examples 3 and 4 and the fact that the function table is a positive-logic translation ($H = 1, L = 0$) of the NOR truth table, and also note that the function table is the negative-logic translation ($H = 0, L = 1$) of the NAND truth table, given in Example 1.

It should be noted that one can easily convert from the symbology of positive logic merely by substituting a polarity indicator (\blacktriangle) for each negation indicator (\circ) while leaving the distinctive shapes alone. To convert from the symbology of negative logic, a polarity indicator (\blacktriangle) is substituted for each negation indicator (\circ) and the OR shape is substituted for the AND shape or vice versa.

CMOS LOGIC GRAPHIC SYMBOLS

choice of AND/OR symbols

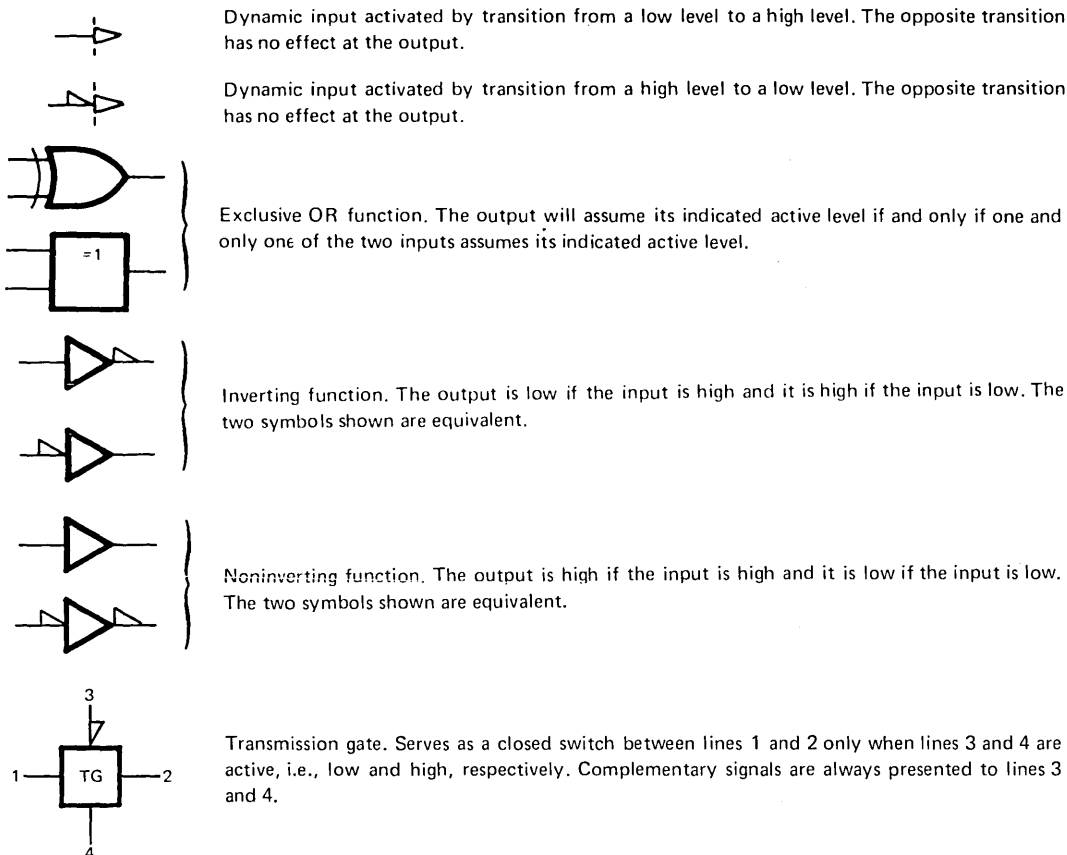
The preceding material stated and demonstrated that any device that can perform OR logic can also perform AND logic and vice versa. De Morgan's transformation is illustrated in Examples 1 through 7. The rules of the transformation are:

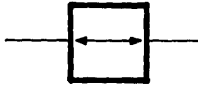
1. At each input or output having a negation (\circ) or polarity (\triangle) indicator, delete the indicator.
2. At each input or output not having an indicator, add a negation (\circ) or polarity (\triangle) indicator.
3. Substitute the AND symbol (\square) for the OR symbol (\cup) or vice versa.

These steps do not alter the assumed convention; positive logic stays positive, negative logic stays negative, and mixed logic stays mixed.

The choice of symbol may be influenced by these considerations: (1) The operation being performed may best be understood as AND or OR. (2) In a function more complex than a basic gate, the inputs will usually be considered as inherently active high or active low (e.g., the J and \bar{K} inputs of a J- \bar{K} flip-flop are active high and active low, respectively). (3) In a chain of logic, understanding and the writing of logic equations are often facilitated if active-low or negated outputs feed into active-low or negated inputs.

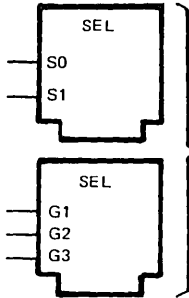
other symbols



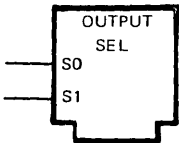


Bilateral switch. When the switch is on, signals can be transmitted in either direction.

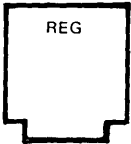
control blocks



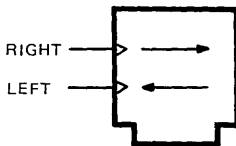
Selector control block. These symbols are used with an array of OR symbols to provide a point of placement for selection (S) or gating (G) lines. The selection lines enable the input designated 0, 1, . . . n of each OR function by means of a binary code where S0 is the least-significant digit. If the 1 level of these lines is low, polarity indicators (\triangleleft) will be used. The gating lines have an AND relation with the respective input of each OR function: G1 with the inputs numbered 1, G2 with the inputs numbered 2, and so forth. If the enabling levels of these lines is low, polarity indicators (\triangleright) will be used. For example applications, see '4051A and '4321A for the first symbol; '4019A and '4519A for the second symbol.



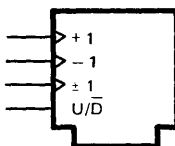
Output selector control block. This symbol is used with a block symbol having multiple outputs to form a decoder. The selection lines enable the output designated 0, 1, . . . n of each block by means of a binary code where S0 is the least significant digit. If the 1 level of these lines is low, polarity indicators (\triangleleft) will be used. For example application of this symbol, see '4028A.



Register control block. This symbol is used with an associated array of flip-flop symbols to provide a point of placement for common function lines, such as a common clear.



Shift register control block. These symbols are used with an array of flip-flop symbols to form a shift register. An active transition at the inputs causes left or right shifting as indicated. For example applications of this symbol, see '4014A, '4015A, and '4021A.





Counter control block. This symbol is used with an array of flip-flops or other circuits serving as a binary or decade counter. An active transition at the +1 or -1 input causes the counter to increment one count upward or downward, respectively. An active transition at the ±1 input causes the counter to increment one count upward or downward depending on the input at an up/down control. For example applications of these symbols, see '4017A, '4029A, '4360A, and '4522A.

CMOS

EXPLANATION OF FUNCTION TABLES



EXPLANATION OF FUNCTION TABLES

The following symbols are now being used in function tables on TI data sheets:

- H = high level (steady state)
- L = low level (steady state)
- ↑ = transition from low to high level
- ↓ = transition from high to low level
- X = irrelevant (any input, including transitions)
- a..h = the level of steady-state inputs at inputs A through H respectively
- Q_0 = level of Q before the indicated steady-state input conditions were established
- \bar{Q}_0 = complement of Q_0 or level of \bar{Q} before the indicated steady-state input conditions were established
- Q_n = level of Q before the most recent active transition indicated by ↓ or ↑
-  = one high-level pulse
-  = one low-level pulse

TOGGLE = each output changes to the complement of its previous level on each active transition indicated by ↓ or ↑.

If, in the input columns, a row contains only the symbols H, L, and/or X, this means the indicated output is valid whenever the input configuration is achieved and regardless of the sequence in which it is achieved. The output persists so long as the input configuration is maintained.

If, in the input columns, a row contains H, L, and/or X together with ↑ and/or ↓, this means the output is valid whenever the input configuration is achieved but the transition(s) must occur following the achievement of the steady-state levels. If the output is shown as a level (H, L, Q_0 , or \bar{Q}_0), it persists so long as the steady-state input levels and the levels that terminate indicated transitions are maintained. Unless otherwise indicated, input transitions in the opposite direction to those shown have no effect at the output. (If the output is shown as a pulse,  or , the pulse follows the indicated input transition and persists for an interval dependent on the circuit.)

CMOS EXPLANATION OF FUNCTION TABLES

The most complex function tables in this book are those of the shift registers. These embody all of the symbols used in any of the other function tables, plus more. Below is the function table of an 8-bit static shift register, e.g. type TF4021.

FUNCTION TABLE

INPUTS				INTERNAL OUTPUTS		OUTPUTS		
CONTROL P/ \bar{S}	CLOCK	PARALLEL A-H	SERIAL	(2 OF 5)		Q _F	Q _G	Q _H
				Q _A	Q _B			
H	X	a-h	X	a	b	f	h	h
L	↑	X	H	H	Q _{An}	Q _{En}	Q _{Fn}	Q _{Gn}
L	↑	X	L	L	Q _{An}	Q _{En}	Q _{Fn}	Q _{Gn}
L	L	X	X	Q _{A0}	Q _{B0}	Q _{F0}	Q _{G0}	Q _{H0}

The first line of the table represents asynchronous parallel loading of the register and says that if P/\bar{S} is high then, without regard to the serial input or the clock, the data entered at A will be at internal output Q_A, data entered at B will be at Q_B, and so forth.

The second and third lines represent the loading of high-and low-level data, respectively, from the serial input and the shifting of previously entered data one bit; data previously at Q_A is now at Q_B, the previous levels of Q_E, Q_F, and Q_G and now at Q_F, Q_E, and Q_H, respectively, and the data previously at Q_H is no longer in the register. This entry of serial data and shift takes place on the low-to-high transition of the clock when P/\bar{S} is low and the levels at inputs A through H have no effect.

The fourth line simply states that so long as the clock remains low while P/\bar{S} is low, no other input has any effect and the outputs maintain the levels they assumed on the last rising transition of the clock.

Since only the rising transition of the clock has been shown to be active, the fourth line implicitly shows that no further change in the outputs will occur while the clock remains high or on the high-to-low transition of the clock.

CMOS LOGIC CIRCUITS

INTRODUCTION

This booklet contains descriptive information on CMOS integrated circuits manufactured by Texas Instruments. Included are data sheets providing electrical and switching characteristics. The circuits designated with 40XXA numbers are plug-in replacements for the RCA family of CMOS devices. The 43XXA devices are unique Texas Instruments functions. The 45XXA devices are plug-in replacements for the Motorola family of CMOS devices.

Circuits designated with an "A" suffix are those devices having an operating voltage range of 3 to 15 volts with specifications at 5 to 10 volts.

The circuits designated with a "B" suffix are those devices whose voltage range is 3 to 18 volts with specifications at 5, 10, and 15 volts. Additionally the data sheets on the "B" parts more clearly define the product in a system-oriented manner. The specific areas where the "B" data sheets are more descriptive than the "A" data sheets are:

- Input and Output Characteristics
- Noise Immunity
- Drive Capability
- Specifications at 15 volts

The "B" series (including all "B" series data sheets) is presented first, then the "A" series; for most type numbers there is both an "A" series device and a "B" series device. Within each series the data sheets are arranged in type-number sequence.

Texas Instruments CMOS offers the design engineer:

- Choice of two packages . . .
 - Plastic dual-in-line
 - Ceramic hermetically sealed dual-in-line
- Choice of temperature ranges . . .
 - Series TF . . . -55°C to 125°C (full military range)
 - Series TP . . . -40°C to 85°C
- Protective network on each input
- Low power dissipation (quiescent)
- High noise immunity
- Threshold voltage, input and supply current stability
- Easy interface capability to
 - TTL (including low-power and low-power Schottky)
 - Linear
 - N-Channel MOS
 - P-Channel MOS

SERIES '4000B GENERAL INFORMATION

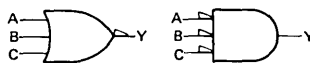
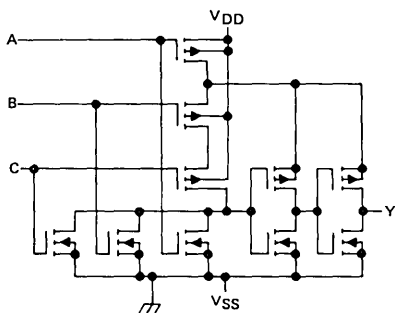
"B" SERIES INFORMATION

BUFFERED CIRCUITS

Most 4XXXXB digital circuits will have double- or triple-buffered output stages to attain:

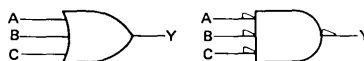
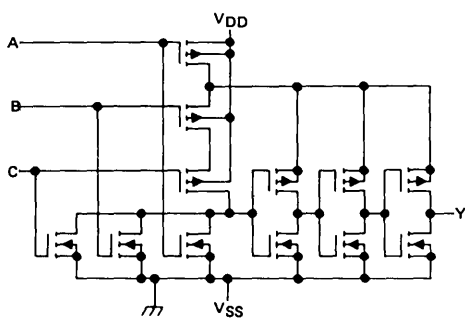
- Uniform dynamic performance
- Improved capacitance drive
- Uniform input characteristics
- Lower input capacitance
- Uniform output characteristics
- Lower over-all system CV^2f power
- Improved noise immunity

Figure 1 shows typical three-input NOR, OR, and NAND gate circuits. The input transistor sizes are minimized to reduce input capacitance and are buffered from the large output transistors, which are designed to give symmetrical output characteristics.



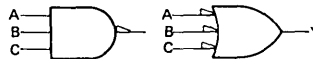
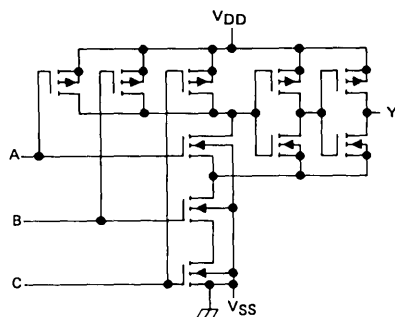
positive logic:

$$Y = \overline{A + B + C} \text{ or } Y = \overline{ABC}$$



positive logic:

$$Y = A + B + C \text{ or } Y = \overline{\overline{ABC}}$$



positive logic:

$$Y = \overline{ABC} \text{ or } Y = \overline{A + B + C}$$

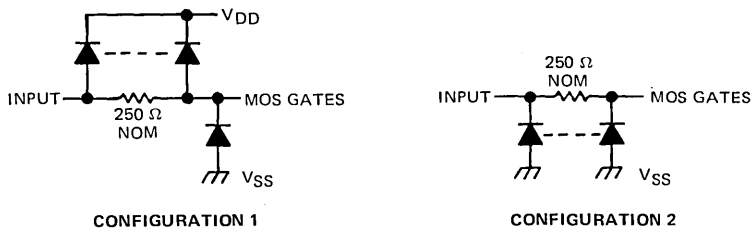
FIGURE 1—DOUBLE- AND TRIPLE-BUFFERED CMOS CIRCUITS

SERIES '4000B

GENERAL INFORMATION

INPUT PROTECTION

Input protection networks have been standardized to the two configurations below:



Configuration 1 is used on the whole family except for the '4049B and '4050B, which use configuration 2. In each case the diodes to V_{SS} have a reverse breakdown of approximately 22 to 28 volts. These networks are incorporated as protection against occasional electrostatic overstress. It is not recommended that units be subjected to continuously repeated overstress. CMOS is much less sensitive to electrostatic overstress than other MOS technologies; however, care should be taken in handling these networks much the same as is required for other high-impedance integrated circuits:

- 1) Equipment should be properly grounded.
- 2) Work surfaces should be electrically conductive and connected to earth ground.
- 3) Handling should be minimized.

INPUT CHARACTERISTICS

For input voltages between V_{SS} and V_{DD} the protective networks are in reverse-biased, low-current states. Typically the input current at 25°C will be on the order of a few picoamps. Because such small currents are difficult to measure, inputs are specified at only $V_{DD} = 15$ volts. The maximum limit is the sum of all inputs simultaneously measured in parallel.

The 4XXXB devices have input capacitances of typically 3 to 5 pF.

OUTPUT CHARACTERISTICS

Digital CMOS inputs represent such small loads to CMOS driving units that the outputs will typically equal either V_{SS} or V_{DD} in a quiescent logic state. However for most system applications, one must specify the logic output levels under a load to indicate interface capabilities of the output to other circuits, the output transient drive capability, and the susceptibility to noise. It is intended to guarantee a standard "B" series output to drive one Low-Power Schottky TTL input and to have nearly symmetrical output impedances. For these reasons the output source and sink currents are specified at output voltages that are symmetrically related; that is at $V_{DD} = 5$ V, $V_O = V_{DD} - 0.4$ V and $1/2 V_{DD}$ for I_{OH} and $V_O = 0.4$ V and $1/2 V_{DD}$ for I_{OL} .

SERIES '4000B GENERAL INFORMATION

NOISE IMMUNITY

Noise immunity is the inherent ability of a device to receive electrical noise at its inputs without propagating signals that would cause erroneous logic levels subsequently in the system. Noise immunity does not imply that no output transient will occur. It does mean that the amplitude of such a transient will be reduced as it is propagated through the system. The "A" series noise immunity is typically 30% of $V_{DD}-V_{SS}$. Because the "B" series has internal buffers, this noise immunity is increased to typically 45% of the supply voltage. Noise margin is a specific measure of noise immunity under specific conditions of load, supply voltage, and temperature. High-level noise margin is defined as $V_{OH\ min} - V_{IH\ min}$ and low-level noise margin is defined as $V_{IL\ max} - V_{OL\ max}$, where the following definitions apply:

- $V_{IH\ min}$ The minimum value of high-level input voltage for which operation of the logic element within specification limits is guaranteed.
- $V_{IL\ max}$ The maximum value of low-level input voltage for which operation of the logic element within specification limits is guaranteed.
- $V_{OH\ min}$ The minimum high-level output voltage that will occur under specific conditions of input voltage, supply voltage, load, and temperature.
- $V_{OL\ max}$ The maximum low-level output voltage that will occur under specific conditions of input voltage, supply voltage, load, and temperature.

Historically the CMOS industry has applied these definitions of noise margins under the conditions of no output load with the units stressed one input at a time while the other inputs are at V_{DD} or V_{SS} . A more realistic system application would require all inputs to be stressed simultaneously in a worst case combination and the outputs to be loaded. Under guaranteed data sheet conditions of $V_{OH\ min}$, $V_{IH\ min}$, $V_{IL\ max}$, and $V_{OL\ max}$, Texas Instruments guarantees worst-case noise margins of:

<u>LOGIC LEVEL</u>	<u>$V_{DD} = 5\ V$</u>	<u>$V_{DD} = 10\ V$</u>	<u>$V_{DD} = 15\ V$</u>
High	0.6 V	1.5 V	1.5 V
Low	0.6 V	1.5 V	1.5 V

These noise margins are equivalent to the following under conditions of no load and one input stressed at a time.

<u>LOGIC LEVEL</u>	<u>$V_{DD} = 5\ V$</u>	<u>$V_{DD} = 10\ V$</u>	<u>$V_{DD} = 15\ V$</u>
High	1.5 V	3.0 V	4.0 V
Low	1.5 V	3.0 V	4.0 V

SERIES '4000B

GENERAL INFORMATION

POWER DISSIPATION

CMOS power dissipation is defined primarily by two contributing factors; a steady-state "leakage" current contribution and dynamic power dissipation. The dynamic power is normally the major factor and consists of two components: the capacitive term (CV^2f) and the "through" current, which results when both the N-channel and the P-channel transistors are simultaneously on. The curves of Figure 2 show CMOS power of a two-input NOR circuit as compared to equivalent circuits in the three most popular TTL families. From this comparison one can clearly see that CMOS offers the optimum power versus frequency for system frequencies less than 100 kHz. From 1 MHz up, the trade-off favors Low-Power Schottky TTL.

CMOS quiescent supply current specified in subsequent detailed specifications is primarily reverse current of diodes and off-state current of MOS transistors. Since CMOS logic functions consist of series and parallel combinations of MOS transistors, one must measure the reverse current in sufficient logic states to ensure that all junctions and transistors are stressed. For example a two-input NOR gate would require an I_{DD} measurement with both inputs low to stress both n-channel transistors. Then, one must apply a high, low combination to stress one p-channel transistor followed by a low, high combination to stress the other. This method of measurement is being used on all Texas Instruments CMOS products.

SPECIFICATION GROUPING

The products in this book are classified into two groups each having common characteristics. The first group (SSI, small-scale integration) comprises the basic gate functions, buffers, and small analog functions, the second group (CSSI, complex small-scale integration, and MSI, medium-scale integration) comprises the dual flip-flops and the more complex functions. The type numbers in each group of the "B" series are shown below.

GROUP 1 (SSI)	GROUP 2 (CSSI and MSI)
4000B♦	4013B
4001B	4014B♦
4002B♦	4015B♦
4009B	4018B
4010B	4021B♦
4011B	4029B♦
4012B♦	4035B♦
4016B	4042B
4023B♦	4043B
4025B♦	4044B
4030B	4051B
4049B	4052B
4050B	4053B
4069B	4376B
4070B	4377B
4071B	
4072B♦	
4073B♦	
4075B♦	
4081B	
4082B♦	
4085B♦	

♦Future products to be announced

SERIES '4000B GENERAL INFORMATION

POWER DISSIPATION PER GATE
vs
FREQUENCY FOR TTL AND CMOS

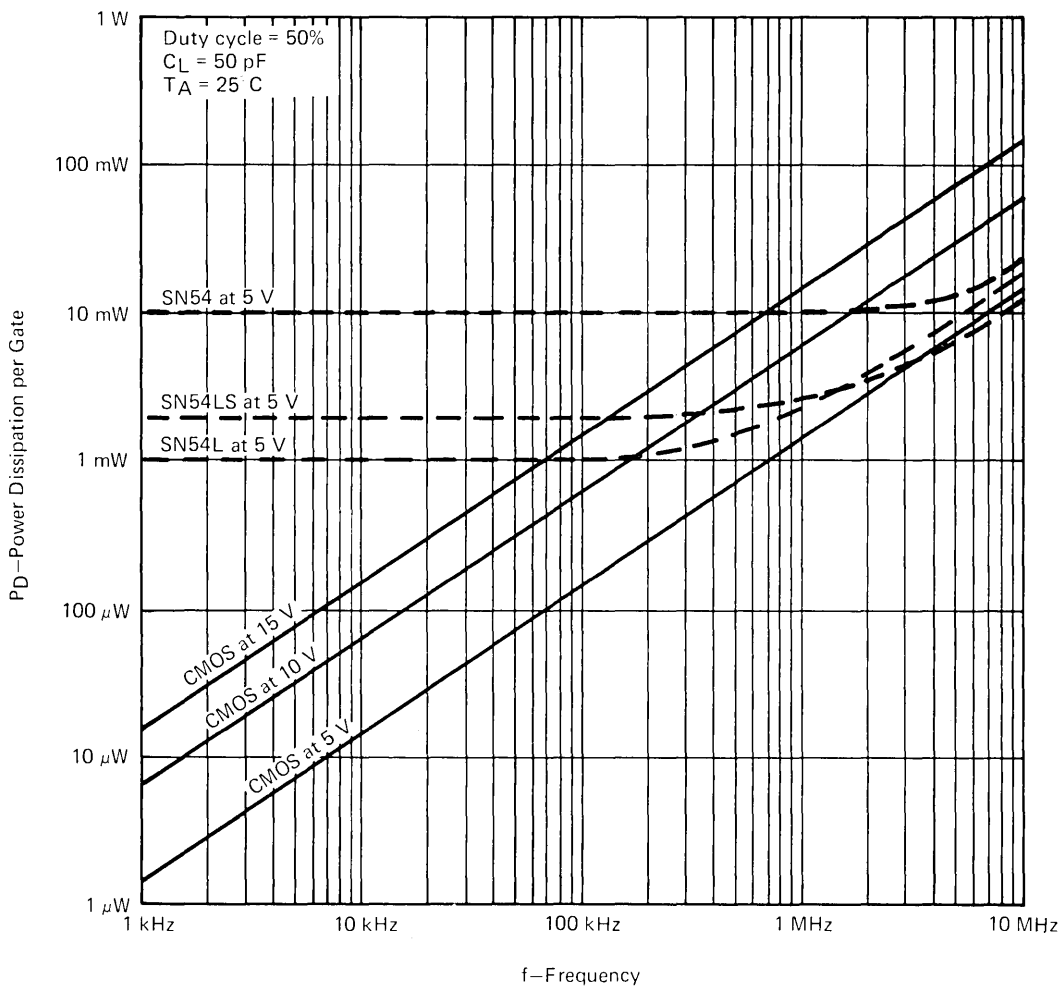


FIGURE 2

SERIES '4000B

COMMON ELECTRICAL SPECIFICATIONS

SEPTEMBER 1975

The following electrical specifications apply for most series '4000B CMOS products. Each individual product specification references the appropriate sections of this common specification and lists exceptions if there are any.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{DD} (see Note 1)	18 V
Input current	± 10 mA
Continuous total dissipation (see Note 2)	200 mW
Operating free-air temperature range: TF4000B Series	-55°C to 125°C
TP4000B Series	-40°C to 85°C
Storage temperature range	-65°C to 150°C

NOTES: 1. Throughout this page, the following page, and the individual product specifications, voltage values are with respect to the V_{SS} terminal unless otherwise noted.
2. Power dissipation averaged over a 1-second interval must fall within the continuous dissipation rating.

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V_{DD} (see Note 3)		3	18	V
Input voltage, V_I		0	V_{DD}	V
Operating free-air temperature, T_A	TF4000B Series	-55	125	$^{\circ}\text{C}$
	TP4000B Series	-40	85	$^{\circ}\text{C}$
Rise time, any input, t_r			15	μs
Fall time, any input, t_f			15	μs

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

TF4000B Series

PARAMETER	TEST CONDITIONS	$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		$V_{DD} = 15\text{ V}$		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
V_{IH} High-level input voltage		4		8		12		V
V_{IL} Low-level input voltage			1		2		3	V
V_{OH} High-level output voltage	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, I_O = I_{OH\text{ min}}$	4.6		9.5		13.5		V
V_{OL} Low-level output voltage	See Note 3 $I_O = I_{OL\text{ min}}$		0.4		0.5		1.5	V
I_{OH} High-level output current	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, V_O = V_{OH\text{ min}}$	$T_A = -55^{\circ}\text{C}$	-0.5	-1.1	-3.8	mA		
		$T_A = 25^{\circ}\text{C}$	-0.4	-0.9	-3			
		$T_A = 125^{\circ}\text{C}$	-0.4	-0.65	-2.3			
	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, V_O = \frac{1}{2} V_{DD}$	$T_A = -55^{\circ}\text{C}$	-2	-7.5	-11			
		$T_A = 25^{\circ}\text{C}$	-1.6	-6	-9			
		$T_A = 125^{\circ}\text{C}$	-1.2	-4	-6			
I_{OL} Low-level output current	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, V_O = V_{OL\text{ max}}$	$T_A = -55^{\circ}\text{C}$	0.5	1.1	3.8	mA		
		$T_A = 25^{\circ}\text{C}$	0.4	0.9	3			
		$T_A = 125^{\circ}\text{C}$	0.4	0.65	2.3			
	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, V_O = \frac{1}{2} V_{DD}$	$T_A = -55^{\circ}\text{C}$	2	7.5	11			
		$T_A = 25^{\circ}\text{C}$	1.6	6	9			
		$T_A = 125^{\circ}\text{C}$	1.2	4	6			
I_I Input current	$V_I = V_{DD}$ or 0 V					± 1	μA	
I_{DD} Quiescent or supply current $-I_{SS}$ current	Group 1† products All logic states, Group 2† products No load	$T_A = -55^{\circ}\text{C}$ or 25°C	0.5	1	2	μA		
		$T_A = 125^{\circ}\text{C}$	30	60	120			
		$T_A = -55^{\circ}\text{C}$ or 25°C	5	10	20			
		$T_A = 125^{\circ}\text{C}$	300	600	1200			

NOTE 3: The output voltage limits are guaranteed for any appropriate combination of high and low inputs.
† See group designation on individual product specifications and page 22 for a list of all products by group.

SERIES '4000B COMMON ELECTRICAL SPECIFICATIONS

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

TP4000B Series

PARAMETER		TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT			
			MIN	MAX	MIN	MAX	MIN	MAX				
V _{IH}	High-level input voltage		4		8		12		V			
V _{IL}	Low-level input voltage		1		2		3		V			
V _{OH}	High-level output voltage	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, I _O = I _{OH} min	4.6		9.5		13.5		V			
V _{OL}	Low-level output voltage	See Note 3, I _O = I _{OL} min	0.4		0.5		1.5		V			
I _{OH}	High-level output current	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = V _{OH} min	T _A = -40°C		-0.45		-1		-3.4			
			T _A = 25°C		-0.4		-0.9		-3			
			T _A = 85°C		-0.4		-0.75		-2.7			
		V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = ½ V _{DD}	T _A = -40°C		-1.8		-6.7		-10			
			T _A = 25°C		-1.6		-6		-9			
			T _A = 85°C		-1.3		-5		-7.2			
I _{OL}	Low-level output current	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = V _{OL} max	T _A = -40°C		0.45		1		3.4			
			T _A = 25°C		0.4		0.9		3			
			T _A = 85°C		0.4		0.75		2.7			
		V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = ½ V _{DD}	T _A = -40°C		1.8		6.7		10			
			T _A = 25°C		1.6		6		9			
			T _A = 85°C		1.3		5		7.2			
I _I	Input current	V _I = V _{DD} or 0 V					±1		μA			
I _{DD} or -I _{SS}	Quiescent or supply current	Group 1 [†] products	V _I = V _{DD} or 0 V, All logic states,		T _A = -40°C or 25°C		5		10		20	
			No load		T _A = 85°C		70		140		280	
		Group 2 [†] products	V _I = V _{DD} or 0 V, All logic states,		T _A = -40°C or 25°C		50		100		200	
			No load		T _A = 85°C		700		1400		2800	

NOTE 3: The output voltage limits are guaranteed for any appropriate combination of high and low inputs.

[†]See group designation on individual product specifications and page 22 for a list of all products by group.

CMOS LOGIC CIRCUITS

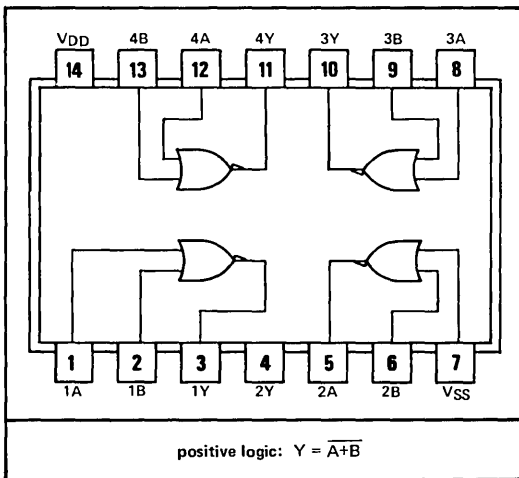
TYPES TF4000B, TF4001B, TF4002B, TP4000B, TP4001B, TP4002B NOR GATES

SEPTEMBER 1975

- '4000B ... Dual 3-Input NOR Gates Plus Inverter \diamond
- '4001B ... Quad 2-Input NOR Gates
- '4002B ... Dual 4-Input NOR Gates \diamond

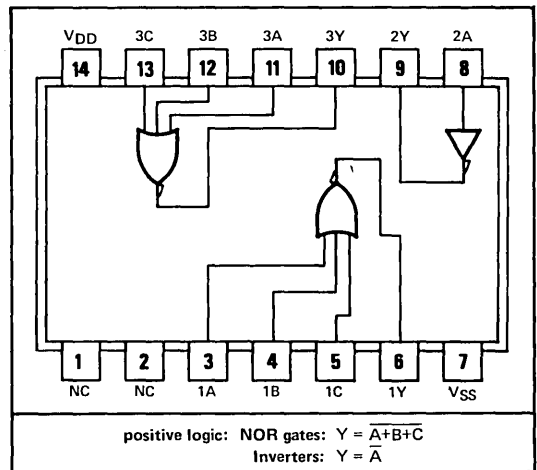
TF4001B, TP4001B

J OR N DUAL-IN-LINE PACKAGE (TOP VIEW)



TF4000B, TP4000B \diamond

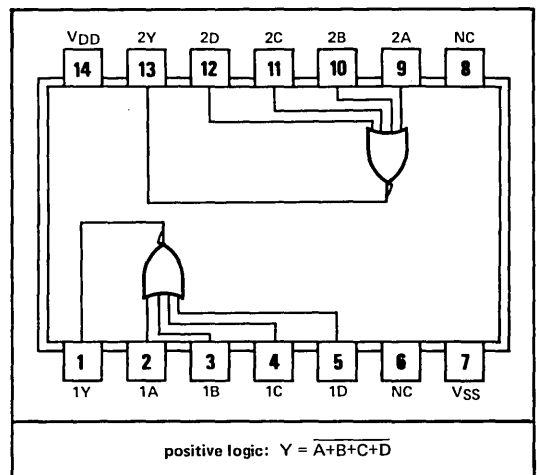
J OR N DUAL-IN-LINE PACKAGE (TOP VIEW)



NC—No internal connection

TF4002B, TP4002B \diamond

J OR N DUAL-IN-LINE PACKAGE (TOP VIEW)



NC—No internal connection

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 1

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	$V_{DD} = 5V$	$V_{DD} = 10V$	$V_{DD} = 15V$	UNIT
		TYP	MAX	TYP	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 k Ω , See Note 1	175	50	40	ns
t _{PHL} Propagation delay time, high-to-low-level output		175	50	40	
t _{TLH} Transition time, low-to-high-level output		95	35	30	
t _{THL} Transition time, high-to-low-level output		95	35	30	

NOTE 1: See load circuit and voltage waveforms on page 170.

\diamond Future products to be announced.

CMOS LOGIC CIRCUITS

TYPES TF4009B, TF4010B, TP4009B, TP4010B HEX INVERTING AND NONINVERTING BUFFERS/CONVERTERS

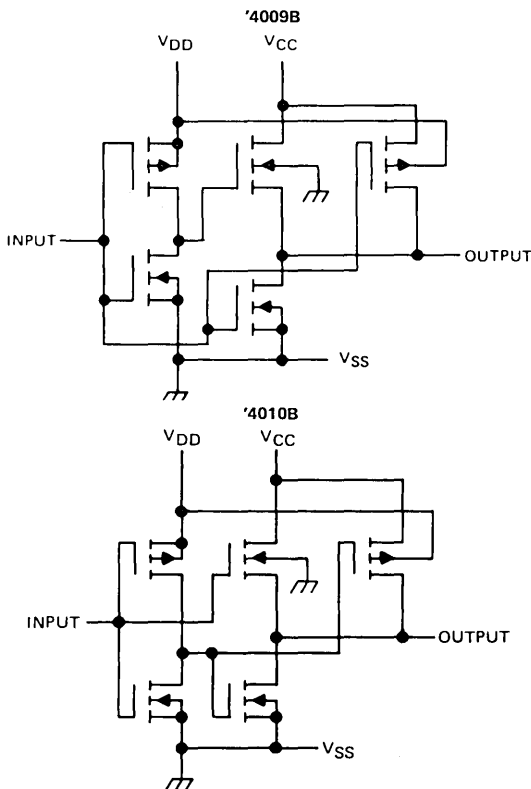
SEPTEMBER 1975

- High Current Sinking Capability

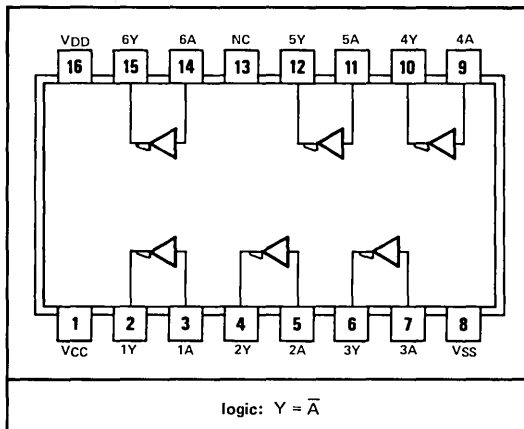
description

The '4009B and '4010B hex CMOS inverting and noninverting buffers may be used as current sinks for source drivers, hex CMOS drivers, or CMOS to DTL or TTL logic-level converters. Conversion ranges are from CMOS logic operating at supply levels to 18 volts to DTL or TTL operating at supply levels of 3 volts to 18 volts. Conversion to logic output levels greater than 6 volts is permitted provided that the VCC supply voltage is not higher than the VDD supply voltage (see Note 1).

schematic (each buffer)

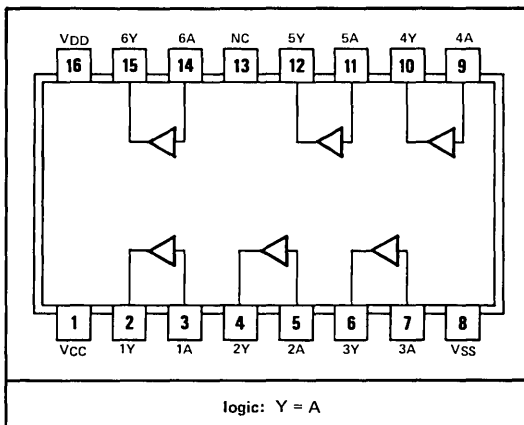


J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)
TF4009B, TP4009B



NC—No internal connection

TF4010B, TP4010B



NC—No internal connection

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24 and below	Page 24	Pages 24 and 25, group 1, except as on following page

absolute maximum ratings over operating free-air temperature range

Supply voltage, VCC (see Note 1)	VDD
Minimum rise time of supply voltages	10 μs
Output load capacitance if VCC exceeds 10.5 V	5000 pF

NOTE 1: If VCC is allowed to exceed VDD, the device may latch up and draw sufficient current to cause permanent damage.

TYPES TF4009B, TF4010B, TP4009B, TP4010B

HEX INVERTING AND NONINVERTING BUFFERS/CONVERTERS

electrical characteristics over recommended operating free-air temperature range, $V_{CC} = V_{DD}$

TF4009B and TF1010B

PARAMETER	TEST CONDITIONS	$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		$V_{DD} = 15\text{ V}$		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
V_{IH} High-level output voltage		4		8		12		V
V_{IL} Low-level output voltage		TF4009B		1	2	2		V
		TF4010B		1	2	3		
V_{OH} High-level output voltage	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, I_O = 0$	4.6		9.5		13.5		V
	$V_{IH} = V_{DD}, V_{IL} = 0, I_O = I_{OH\text{ min}}$	4.6		9.5		13.5		
V_{OL} Low-level output voltage	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, I_O = 0$	0.4		0.5		1.5		V
	$V_{IH} = V_{DD}, V_{IL} = 0, I_O = I_{OL\text{ min}}$	0.4		0.5		1.5		
I_{OL} Low-level output current	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, V_O = V_{OL\text{ max}}$	$T_A = -55^\circ\text{C}$	3.75	10	30	mA		
		$T_A = 25^\circ\text{C}$	3.2	8	24			
		$T_A = 125^\circ\text{C}$	2.1	5.6	17			
	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, V_O = \frac{1}{2} V_{DD}$	$T_A = -55^\circ\text{C}$	11	36	53			
		$T_A = 25^\circ\text{C}$	9.2	29	42			
		$T_A = 125^\circ\text{C}$	6	20	30			

TP4009B and TP4010B

PARAMETER	TEST CONDITIONS	$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		$V_{DD} = 15\text{ V}$		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
V_{IH} High-level input voltage		4		8		12		V
V_{IL} Low-level input voltage		TP4009B		1	2	2		V
		TP4010B		1	2	3		
V_{OH} High-level output voltage	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, I_O = 0$	4.6		9.5		13.5		V
	$V_{IH} = V_{DD}, V_{IL} = V_{IL} = 0, I_O = I_{OH\text{ min}}$	4.6		9.5		13.5		
V_{OL} Low-level output voltage	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, I_O = 0$	0.4		0.5		1.5		V
	$V_{IH} = V_{DD}, V_{IL} = 0, I_O = I_{OL\text{ min}}$	0.4		0.5		1.5		
I_{OL} Low-level output current	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, V_O = V_{OL\text{ max}}$	$T_A = -40^\circ\text{C}$	3.6	9.6	28	mA		
		$T_A = 25^\circ\text{C}$	3.2	8	24			
		$T_A = 85^\circ\text{C}$	2.5	6.6	19			
	$V_{IH} = V_{IH\text{ min}}, V_{IL} = V_{IL\text{ max}}, V_O = \frac{1}{2} V_{DD}$	$T_A = -40^\circ\text{C}$	10	34	49			
		$T_A = 25^\circ\text{C}$	9.2	29	42			
		$T_A = 85^\circ\text{C}$	7.1	24	33			

switching characteristics at 25°C free-air temperature

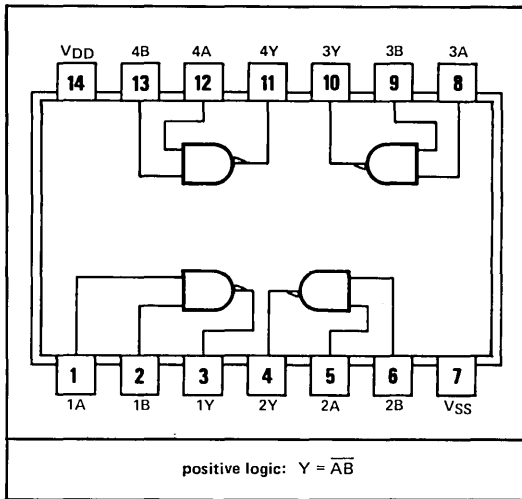
PARAMETER	TEST CONDITIONS	$V_{DD} = 5\text{ V}$	$V_{DD} = 10\text{ V}$	$V_{DD} = 15\text{ V}$	UNIT
		TYP	MAX	TYP	
t_{PLH} Propagation delay time, low-to-high-level output	$V_{CC} = V_{DD}, C_L = 50\text{ pF}, R_L = 200\text{ k}\Omega, \text{ See Note 2}$	55	40	35	ns
t_{PHL} Propagation delay time, high-to-low-level output		50	28	23	
t_{TLH} Transition time, low-to-high-level output		135	110	100	
t_{THL} Transition time, high-to-low-level output		30	28	25	
t_{PLH} Propagation delay time, low-to-high-level output	$V_{CC} = \frac{1}{2} V_{DD}, C_L = 50\text{ pF}, R_L = 200\text{ k}\Omega, \text{ See Note 2}$		25		ns
t_{PHL} Propagation delay time, high-to-low-level output			25		

NOTE 2: See load circuit and voltage waveforms on page 170.

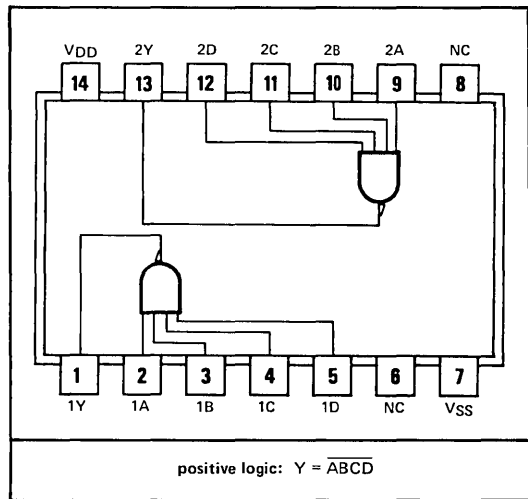
PRINTED IN U.S.A.

'4011B . . . Quad 2-Input NAND Gates
'4012B . . . Dual 4-Input NAND Gates◊

TF4011B, TP4011B
J OR N DUAL-IN-LINE PACKAGE (TOP VIEW)



TF4012B, TP4012B◊
J OR N DUAL-IN-LINE PACKAGE (TOP VIEW)



NC—No internal connection

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 1

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT
		TYP	MAX	TYP	MAX	TYP	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	175		50		40		ns
t _{PHL} Propagation delay time, high-to-low-level output		175		50		40		
t _{TLH} Transition time, low-to-high-level output		95		35		30		
t _{THL} Transition time, high-to-low-level output		95		35		30		

NOTE 1: See load circuit and voltage waveforms on page 170.

◊Future product to be announced.

CMOS LOGIC CIRCUITS

TYPES TF4013B, TP4013B DUAL D-TYPE EDGE-TRIGGERED FLIP-FLOPS

SEPTEMBER 1975

- Toggle Rate . . . 12 MHz Typical at $V_{DD} = 15\text{ V}$

description

These circuits are dual D-type transition-operated master-slave flip-flops with buffered outputs, independent direct overriding preset and clear inputs, and D and clock inputs. While the clock is low, the data at the D input is entered into the master section, which is isolated from the slave section. On the rising transition of the clock, the D input is disabled and data previously set up in the master section is transferred to the slave section and appears in true form at the Q output.

Presetting and clearing are independent of the clock and are accomplished by a high-level voltage at the respective input. The \bar{Q} output is complementary to the Q output except for the nonstable situation that exists when both preset and clear inputs are simultaneously high.

FUNCTION TABLE
(EACH FLIP-FLOP)

PRESET		INPUTS		OUTPUTS	
PRESET	CLEAR	CK	D	Q	\bar{Q}
H	L	X	X	H	L
L	H	X	X	L	H
H	H	X	X	H*	H*
L	L	\uparrow	L	L	H
L	L	\uparrow	H	H	L
L	L	L	X	Q_0	\bar{Q}_0

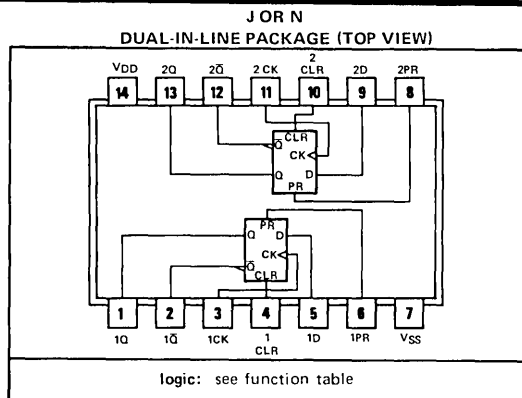
See explanation of function tables on pages 16 and 17.

*This configuration is nonstable; that is, it will not persist when preset and clear return to their inactive (low) level.

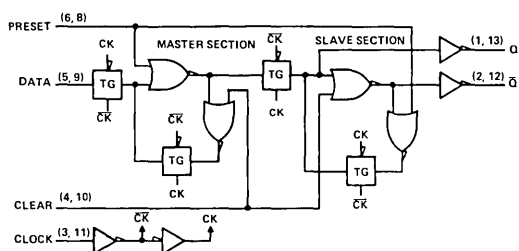
switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	$V_{DD} = 5\text{ V}$	$V_{DD} = 10\text{ V}$	$V_{DD} = 15\text{ V}$	UNIT
		TYP	MAX	TYP	
f_{max} Maximum clock frequency	$C_L = 50\text{ pF}$, $R_L = 200\text{ k}\Omega$, See Note 1	4	10	12	MHz
t_{PLH} Propagation delay time, low-to-high-level output from clock, preset, or clear		225	95	85	ns
t_{PHL} Propagation delay time, high-to-low-level output from clock, preset, or clear		225	95	85	ns
t_{TLH} Transition time, low-to-high-level output		95	35	30	ns
t_{THL} Transition time, high-to-low-level output		95	35	30	ns
$t_w(\min)$ Minimum pulse width, clock high, clock low, preset, or clear		125	50	40	ns
$t_{su}(\min)$ Minimum setup time		25	10	8	ns
$t_h(\min)$ Minimum hold time		0	0	0	ns

NOTE 1: See load circuit and voltage waveforms on page 170.



functional block diagram



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 2

**FUTURE CMOS PRODUCT
TO BE ANNOUNCED**

**TYPES TF4014B, TP4014B
8-BIT STATIC SHIFT REGISTERS**

SEPTEMBER 1975

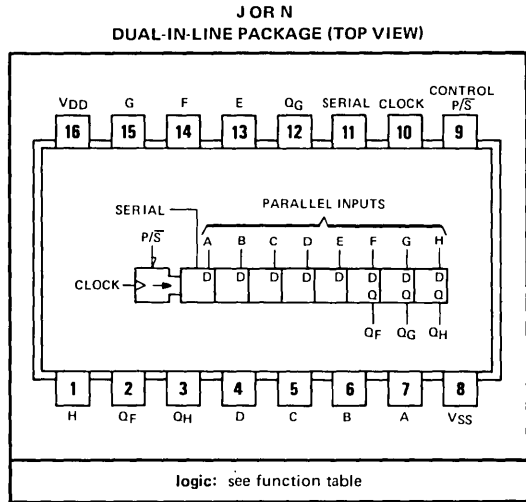
- Synchronous Parallel or Serial Input, Serial Output
- Parallel Outputs from Sixth, Seventh, and Eighth Bits
- Maximum Clock Frequency . . . 5 MHz Typical at 10 V

description

These 8-bit synchronous registers have a single serial input and parallel-in access to each stage. D-type master-slave flip-flops are used for each stage with parallel access to the outputs of bits F, G, and H.

Both serial and parallel entry are made synchronously on the low-to-high transition of the clock input and under the control of the parallel-load/serial-shift input, P/S. When the P/S input is high, data is broadside loaded into the register from the parallel inputs. When the P/S input is low, data is entered at the serial input and each bit shifts one bit position in the direction Q_A through Q_H.

The TF4021B and TP4021B are similar to these registers, except for having asynchronous parallel inputs.



logic: see function table

specifications

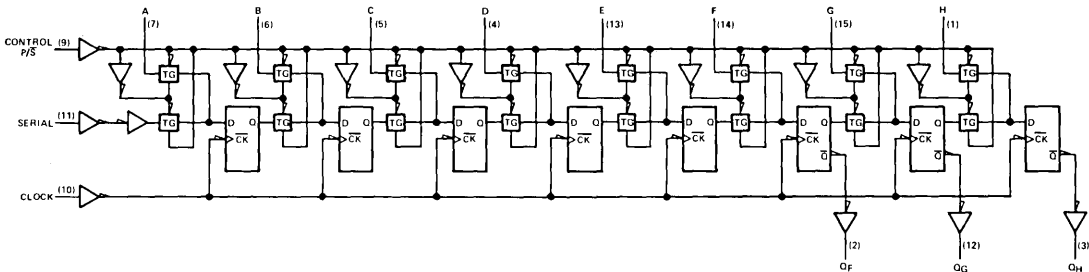
MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 2

FUNCTION TABLE

INPUTS				INTERNAL OUTPUTS (2 of 5)		OUTPUTS		
CONTROL P/S	CLOCK	PARALLEL A-H	SERIAL	Q _A	Q _B	Q _F	Q _G	Q _H
H	↑	a-h	X	a	b	f	g	h
L	↑	X	H	H	Q _{An}	Q _{En}	Q _{Fn}	Q _{Gn}
L	↑	X	L	L	Q _{An}	Q _{En}	Q _{Fn}	Q _{Gn}
X	L	X	X	Q _{A0}	Q _{B0}	Q _{F0}	Q _{G0}	Q _{H0}

See explanation of function tables on pages 16 and 17.

functional block diagram



TYPES TF4014B, TP4014B

8-BIT STATIC SHIFT REGISTERS

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT
		TYP	MAX	TYP	MAX	TYP	MAX	
f _{max} Maximum clock frequency	C _L = 50 pF, R _L = 200 kΩ, See Note 1	2.5		5		7		MHz
t _{PLH} Propagation delay time, low-to-high-level output		300		125		90		ns
t _{PHL} Propagation delay time, high-to-low-level output		300		125		90		ns
t _{TLH} Transition time, low-to-high-level output		95		35		30		ns
t _{THL} Transition time, high-to-low-level output		95		35		30		ns
t _{w(min)} Minimum pulse width, clock high or clock low		200		100		100		ns
t _{su(min)} Minimum setup time		100		50		50		ns
t _{h(min)} Minimum hold time		0		0		0		ns

NOTE 1: See load circuit and voltage waveforms on page 170.

FUTURE CMOS PRODUCT TO BE ANNOUNCED

TYPES TP4015B, TP4015B DUAL 4-BIT STATIC SHIFT REGISTERS

SEPTEMBER 1975

- Maximum Clock Frequency . . . 5 MHz
Typical at 10 V

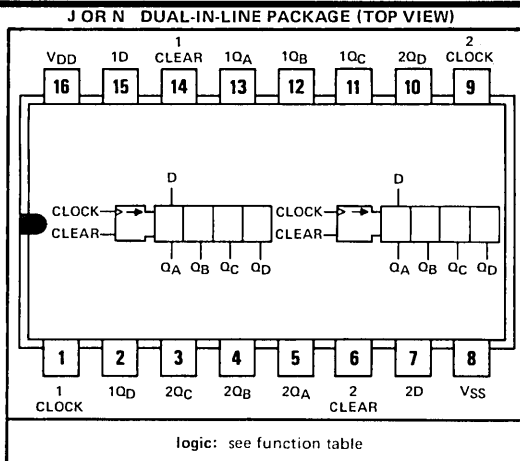
description

These dual 4-bit static shift registers consist of two identical, independent, 4-stage serial-input, parallel-output registers. Each register has independent clock and clear inputs as well as a single serial data input. The register stages are D-type master-slave flip-flops with Q outputs available from each of the four bits on both registers. Data is shifted from one bit to the next during the low-to-high-level transition of the clock. A high level applied to the clear line sets all outputs of the associated registers to the low level.

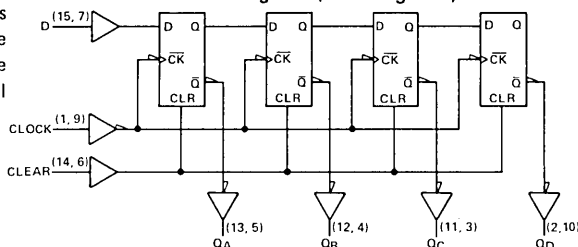
FUNCTION TABLE
(EACH REGISTER)

INPUTS			OUTPUTS			
CLEAR	CLOCK	D	Q _A	Q _B	Q _C	Q _D
H	X	X	L	L	L	L
L	↑	L	L	Q _{An}	Q _{Bn}	Q _{Cn}
L	↑	H	H	Q _{An}	Q _{Bn}	Q _{Cn}
L	L	X	Q _{A0}	Q _{B0}	Q _{C0}	Q _{D0}

See explanation of function tables on pages 16 and 17.



functional block diagram (each register)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 2

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V			V _{DD} = 10 V			V _{DD} = 15 V			UNIT	
		TYP	MAX		TYP	MAX		TYP	MAX			
f _{max} Maximum clock frequency	C _L = 50 pF, R _L = 200 kΩ, See Note 1	3			5			7			MHz	
t _{PLH} Propagation delay time, low-to-high-level output from clock		250			100			80			ns	
t _{PHL} Propagation delay time, high-to-low-level output		from clock	250			100			80			ns
		from clear	300			125			100			
t _{TLH} Transition time, low-to-high-level output			95			35			30			ns
t _{THL} Transition time, high-to-low-level output			95			35			30			ns
t _{w(min)} Minimum pulse width		clock high or low	165			100			75			ns
		clear	125			50			50			
t _{su(min)} Minimum setup time			100			50			50			ns
t _{h(min)} Minimum hold time			0			0			0			ns

NOTE 1: See load circuit and voltage waveforms on page 170.

- Difference in r_{on} between Switches in One Package Typically $10\ \Omega$ when $V_I = V_{SS}$ or V_{DD}
- High Degree of Linearity . . . $< 0.5\%$ Distortion Typical at 1 kHz
- Switches Can Transmit Signals in Either Direction at Frequencies of up to 50 MHz Typically
- Extremely Low Off-State Switch Current Resulting in Very High Effective Off-State Resistance . . . 10 pA Typical at $V_{DD} - V_{SS} = 10\ V$
- Maximum Control Input Frequency . . . 10 MHz Typical at $V_{DD} = 10\ V$, $C_L = 15\ pF$, $R_L = 1\ k\Omega$
- High On/Off Output Voltage Ratio . . . 65 dB Typical
- Extremely High Control-Input Impedance (Control Circuit Isolated from Switch Circuit) . . . $10^{12}\ \Omega$ Typical
- Low Crosstalk Between Switches . . . 50 dB Typical at 0.9 MHz, $R_L = 1\ k\Omega$
- Control Input Current . . . $< 10\ pA$ Typical

description

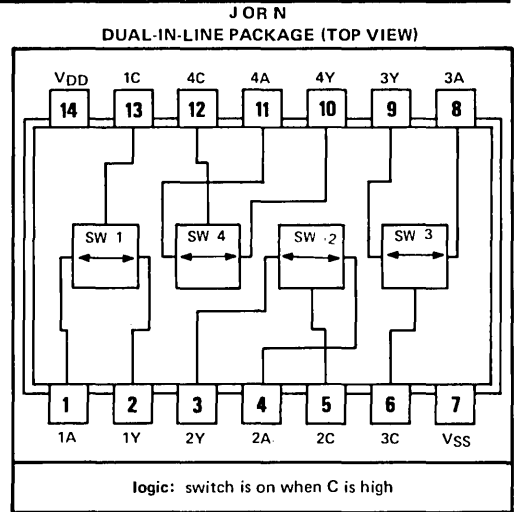
The '4016B is a quadruple bilateral switch constructed with P-channel and N-channel enhancement-type devices in a monolithic structure, and finds primary use where low power dissipation and/or high noise immunity is desired.

Applications include digital switching and multiplexing; analog-to-digital and digital-to-analog conversion; digital control of frequency, impedance, phase and analog-signal gain; signal gating; and use as a squelch control, chopper, modulator, demodulator, or commutating switch.

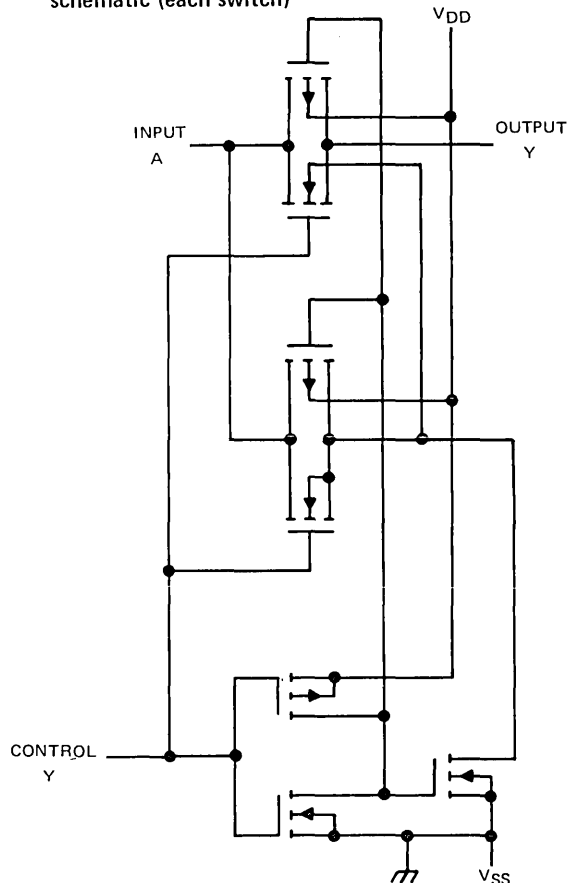
The P⁻ well of the analog transmission gate is connected to V_{SS} when the control input is low (gate off) and is switched to the analog input when the control input is high (gate on). This provides a more uniform on-state resistance with varying analog input voltages.

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	See the following page. Electrical characteristics on pages 24 and 25 do not apply.



schematic (each switch)



TYPES TF4016B, TP4016B QUAD BILATERAL SWITCHES

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

TF4016B

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
V _{IH}	High-level control input voltage	3		4		4		V
V _{IL}	Low-level control input voltage		0.9		0.9		0.9	V
V _{OH}	High-level output voltage A at 0 V, C at V _{IL} max, I _O = 10 μA	4.5		9		12		V
V _{OL}	Low-level output voltage A at 0 V, C at V _{IH} min, I _O = 10 μA		0.5		1		1	V
	Input-to-output off-state current A at 0 V to V _{DD} , C at 0 V, Y at 5 V				±125			nA
	Small-signal on-state resistance A at V _{DD} , ½ V _{DD} , or 0 V, C at V _{DD} , R _L = 10 kΩ to ½ V _{DD}				660		400	Ω
					960		600	
I _I	Input current V _I = V _{DD} or 0 V						±1	μA
Total Quiescent Current [†]	A at 0 V to V _{DD} , C at 0 V, Y at 0 V to V _{DD}				0.5		1	2
					30		60	120
	A = Y = 0 V to V _{DD} , C at V _{DD}				0.5		1	2
					30		60	120

TP4016B

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
V _{IH}	High-level control input voltage	3		4		4		V
V _{IL}	Low-level control input voltage		0.9		0.9		0.9	V
V _{OH}	High-level output voltage A at 0 V, C at V _{IL} max, I _O = 10 μA	3.5		7		10		V
V _{OL}	Low-level output voltage A at 0 V, C at V _{IH} min, I _O = 10 μA		1.5		3		5	V
	Input-to-output off-state current A at 0 V to V _{DD} , C at 0 V, Y at 5 V				±125			nA
	Small-signal on-state resistance A at V _{DD} , ½ V _{DD} , or 0 V, C at V _{DD} , R _L = 10 kΩ to ½ V _{DD}				660		400	Ω
					960		600	
I _I	Input current V _I = V _{DD} or 0 V						±1	μA
Total Quiescent Current [†]	A at 0 V to V _{DD} , C at 0 V, Y at 0 V to V _{DD}				5		10	20
					70		140	280
	A = Y = 0 V to V _{DD} , C at V _{DD}				5		10	20
					70		140	280

[†]This is the total of supply current, control input current, and input-to-output off-state current.

TYPES TF4016B, TP4016B QUAD BILATERAL SWITCHES

switching characteristics at 25°C free-air temperature

PARAMETER [†]	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 15 V	UNIT
				TYP	MAX	TYP	
t _{PLH}	A	Y	R _L = 10 kΩ, C _L = 50 pF, C at V _{DD} . See Figure 1	30	15	12	ns
t _{PHL}	A	Y		30	15	12	
t _{PLH}	C	Y	C _L = 50 pF, See Figure 2	80	30	25	ns
t _{PHL}	C	Y		R _L = 10 kΩ to 0 V	80	30	
			R _L = 10 kΩ to V _{DD}	80	30	25	

[†] t_{PLH} ≡ Propagation delay time, low-to-high-level output
t_{PHL} ≡ Propagation delay time, high-to-low-level output

PARAMETER MEASUREMENT INFORMATION

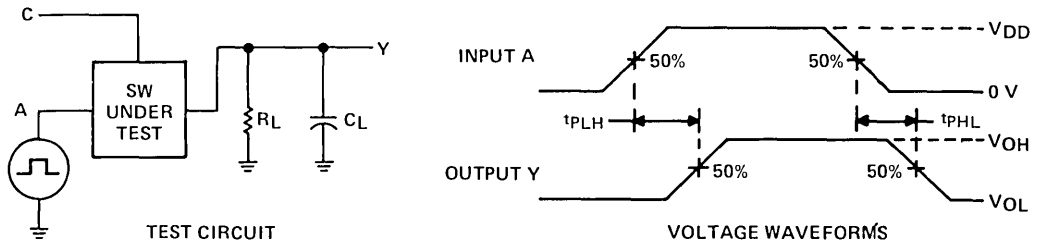


FIGURE 1—PROPAGATION DELAY TIME, SWITCH INPUT A TO OUTPUT Y

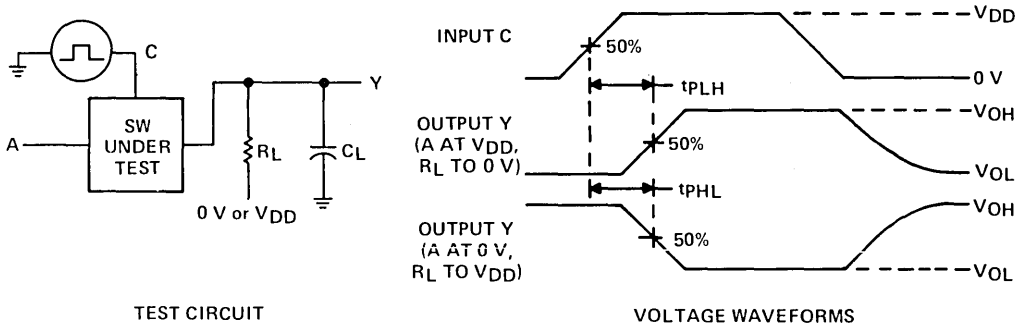


FIGURE 2—PROPAGATION DELAY TIMES, CONTROL INPUT C TO OUTPUT Y

NOTES: A. Input pulses are supplied by generators having the following characteristics: Z_{out} = 50 Ω, PRR = 10 kHz, t_r ≤ 20 ns, t_f ≤ 20 ns.
B. C_L includes probe and jig capacitance.
C. The waveforms are monitored on an oscilloscope with the following characteristics: t_r ≤ 10 ns, R_{in} ≥ 1 MΩ.

CMOS LOGIC CIRCUITS

TYPES TF4018B, TP4018B PRESETTABLE DIVIDE-BY-N COUNTERS

SEPTEMBER 1975

- Maximum Clock Frequency . . . 5 MHz
Typical at $V_{DD} = 10\text{ V}$

description

The '4018B consist of five Johnson counters, buffered \bar{Q} outputs from each stage, and preset control gating. Clear, preset enable, clock, feedback, and five parallel load inputs are provided.

A high clear signal asynchronously clears the counter so that all \bar{Q} outputs are high. A high preset enable signal asynchronously loads the counter and the \bar{Q} outputs will take on the complements of the parallel inputs. The counter is advanced one count on the low-to-high transition of the clock input.

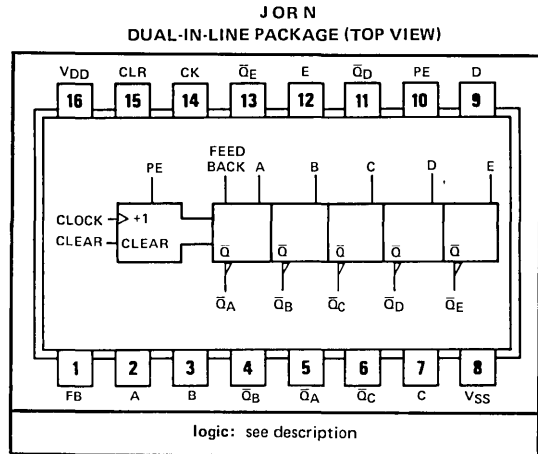
Various counter configurations may be implemented as follows:

Divide by	Connect These Outputs to Feedback Input	Via	Results from Each \bar{Q} Output (See Timing Diagram)
10	\bar{Q}_E	direct	5 counts high, 5 counts low
9	\bar{Q}_D, \bar{Q}_E	AND gate	5 counts high, 4 counts low
8	\bar{Q}_D	direct	4 counts high, 4 counts low
7	\bar{Q}_C, \bar{Q}_D	AND gate	4 counts high, 3 counts low
6	\bar{Q}_C	direct	3 counts high, 3 counts low
5	\bar{Q}_B, \bar{Q}_C	AND gate	3 counts high, 2 counts low
4	\bar{Q}_B	direct	2 counts high, 2 counts low
3	\bar{Q}_A, \bar{Q}_B	AND gate	2 counts high, 1 count low
2	\bar{Q}_A	direct	1 count high, 1 count low

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		$V_{DD} = 15\text{ V}$		UNIT
		TYP	MAX	TYP	MAX	TYP	MAX	
f_{max} Maximum clock frequency		2.5		5		7		MHz
t_{PLH} Propagation delay time, low-to-high-level output from clock, clear, or preset enable	to $\bar{Q}_A, \bar{Q}_B, \bar{Q}_C, \bar{Q}_D$	500		200		150		ns
	to \bar{Q}_E	350		125		100		
t_{PHL} Propagation delay time, high-to-low-level output from clock, clear, or preset enable	to $\bar{Q}_A, \bar{Q}_B, \bar{Q}_C, \bar{Q}_D$	500		200		150		ns
	to \bar{Q}_E	350		125		100		
t_{TLH} Transition time, low-to-high-level output		95		35		30		ns
t_{THL} Transition time, high-to-low-level output		95		35		30		ns
$t_{w(min)}$ Minimum pulse width	clock high or low	200		100		75		ns
	clear or preset enable	200		100		75		
$t_{su(min)}$ Minimum setup time	feedback input	75		75		65		ns
	clear or preset enable inactive state	300		100		100		
$t_h(min)$ Minimum hold time at feedback input		0		0		0		ns

NOTE 1: See load circuit and voltage waveforms on page 170.



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 2

FUTURE CMOS PRODUCT TO BE ANNOUNCED

TYPES TF4021B, TP4021B 8-BIT STATIC SHIFT REGISTERS

SEPTEMBER 1975

- Asynchronous Parallel or Synchronous Serial Input, Serial Output
- Parallel Outputs from Sixth, Seventh, and Eighth Bits
- Maximum Clock Frequency . . . 5 MHz Typical at 10 V

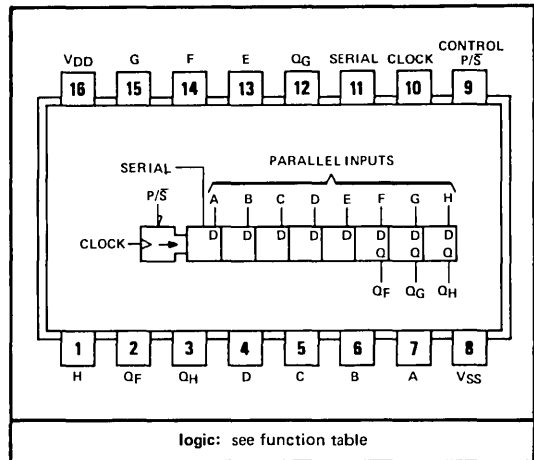
description

These 8-bit registers have a single serial input and parallel-in access to each stage. D-type master-slave flip-flops are used for each stage with parallel access to the outputs of bits F, G, and H.

When the parallel-load/serial-shift input, $\overline{P/S}$ is high, data is broadside loaded into the register from the parallel inputs independently of the clock. When the $\overline{P/S}$ input is low, data is synchronously entered at the serial input and each bit shifts one bit position in the direction Q_A toward Q_H . Serial operations occur on the low-to-high transition of the clock input.

The TF4014B and TP4014B are similar to these registers, except for having synchronous parallel inputs.

J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



logic: see function table

specifications

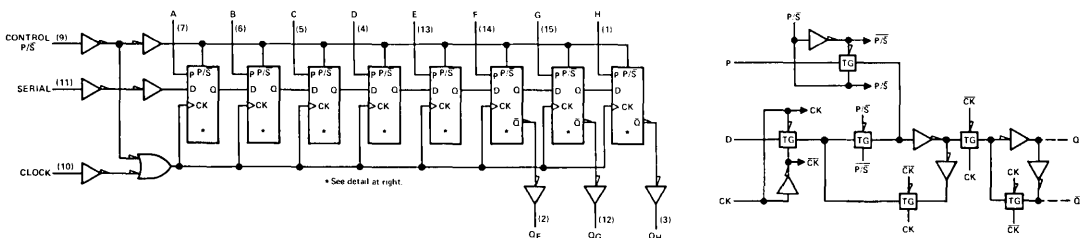
MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 2

FUNCTION TABLE

INPUTS				INTERNAL OUTPUTS (2 OF 5)		OUTPUTS		
CONTROL $\overline{P/S}$	CLOCK	PARALLEL A-H	SERIAL	Q_A	Q_B	Q_F	Q_G	Q_H
H	X	a-h	X	a	b	f	g	h
L	\uparrow	X	H	H	Q_{An}	Q_{En}	Q_{Fn}	Q_{Gn}
L	\uparrow	X	L	L	Q_{An}	Q_{En}	Q_{Fn}	Q_{Gn}
L	L	X	X	Q_{A0}	Q_{B0}	Q_{F0}	Q_{G0}	Q_{H0}

See explanation of function tables, pages 16 and 17.

functional block diagram



DETAIL OF EACH STAGE

TYPES TF4021B, TP4021B

8-BIT STATIC SHIFT REGISTERS

switching characteristics at 25° C free-air temperature

PARAMETER		TEST CONDITIONS	V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 15 V	UNIT	
			TYP	MAX	TYP		MAX
f _{max}	Maximum clock frequency	C _L = 50 pF, R _L = 200 kΩ, See Note 1	2.5	5	7	MHz	
t _{PLH}	Propagation delay time, low-to-high-level output		300	125	75	ns	
t _{PHL}	Propagation delay time, high-to-low-level output		300	125	75	ns	
t _{TLH}	Transition time, low-to-high-level output		95	35	30	ns	
t _{THL}	Transition time, high-to-low-level output		95	35	30	ns	
t _{w(min)}	Minimum pulse width		clock high or low	200	100	100	ns
			P/S high	200	100	100	
t _{su(min)}	Minimum setup time			100	50	50	ns
t _{h(min)}	Minimum hold time			0	0	0	ns

NOTE 1: See load circuit and voltage waveforms on page 170.

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CMOS LOGIC CIRCUITS

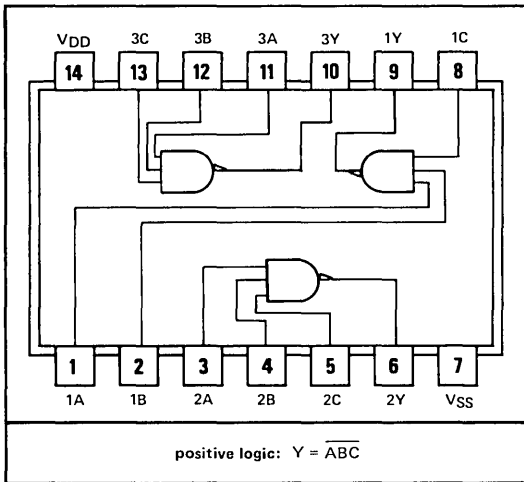
TYPES TF4023B, TF4025B, TP4023B, TP4025B NAND AND NOR GATES

SEPTEMBER 1975

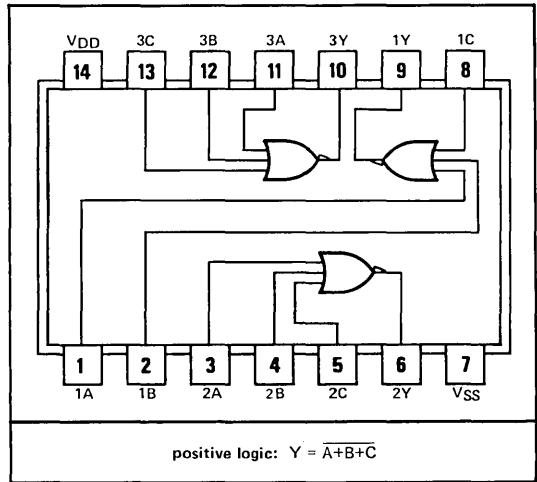
'4023B . . . Triple 3-Input NAND Gates \diamond

'4025B . . . Triple 3-Input NOR Gates \diamond

TF4023B, TP4023B \diamond
J OR N DUAL-IN-LINE PACKAGE (TOP VIEW)



TF4025B, TP4025B \diamond
J OR N DUAL-IN-LINE PACKAGE (TOP VIEW)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 1

switching characteristics at 25° C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 15 V	UNIT
		TYP	MAX	TYP	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	175	50	40	ns
t _{PHL} Propagation delay time, high-to-low-level output		175	50	40	
t _{TLH} Transition time, low-to-high-level output		95	35	30	
t _{THL} Transition time, high-to-low-level output		95	35	30	

NOTE 1: See load circuit and voltage waveforms on page 170.

\diamond Future products to be announced.

FUTURE CMOS PRODUCT TO BE ANNOUNCED

TYPES TF4029B, TP4029B PRESETTABLE UP/DOWN BINARY/DECADE COUNTERS

SEPTEMBER 1975

- Medium Speed Operation . . . 5 MHz
Typical at $V_{DD} = 10\text{ V}$
- Binary or Decade Up/Down Counting
- BCD Outputs in Decade Mode

description

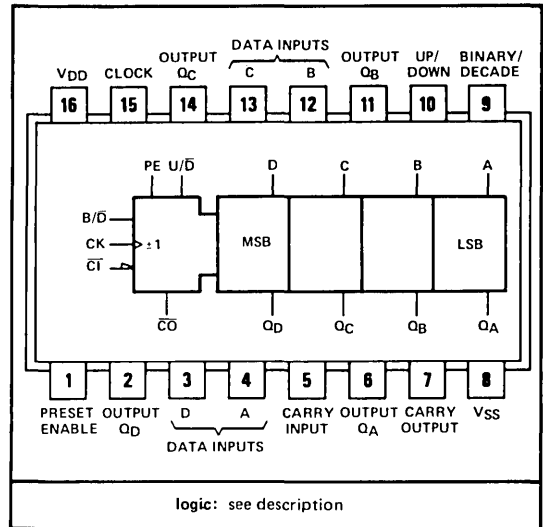
The '4029B counter consists of a four-stage binary or BCD-decade up/down counter with provision for look-ahead carry in both counting modes. The inputs consist of a single clock, carry input (clock enable), binary/decade, up/down, preset enable, and four individual parallel data inputs. Four separate buffered data outputs and a carry output are provided.

A high at the preset-enable input allows information at the parallel inputs to preset the counter to any count independently of the clock. A low at each parallel input, when the preset-enable input is high, resets the counter to its zero count. The counter is advanced one count at the low-to-high transition of the clock when the carry input and preset-enable input are low. Advancement is inhibited when the carry input or preset-enable input is high. The carry output is normally high and goes low when the counter reaches its maximum count in the up mode or its minimum count in the down mode, provided the carry input is low. The carry input terminal must be connected to V_{SS} when not in use.

Binary counting is accomplished when the binary/decade input is high; the counter counts in the decade mode when the binary/decade input is low. The counter counts up when the up/down input is high, and down when the up/down input is low.

Multiple packages can be connected in either a parallel-clocking or a ripple-clocking arrangement as shown in Figure 1 of the '4029A data. Parallel clocking provides synchronous control and hence faster response from all counting outputs. Ripple clocking permits longer clock input rise and fall times.

JOR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



logic: see description

SUMMARY OF CONTROL INPUT FUNCTIONS
(COMPLETE COUNTER)

CONTROL INPUT	LOGIC LEVEL	FUNCTION
Binary/Decade (B/D)	H L	Binary count Decade count
Up/Down (U/D)	H L	Count up Count down
Preset enable (PE)	H L	Parallel load Enable counting
Carry input (CI)	H L	Inhibit counting Enable counting

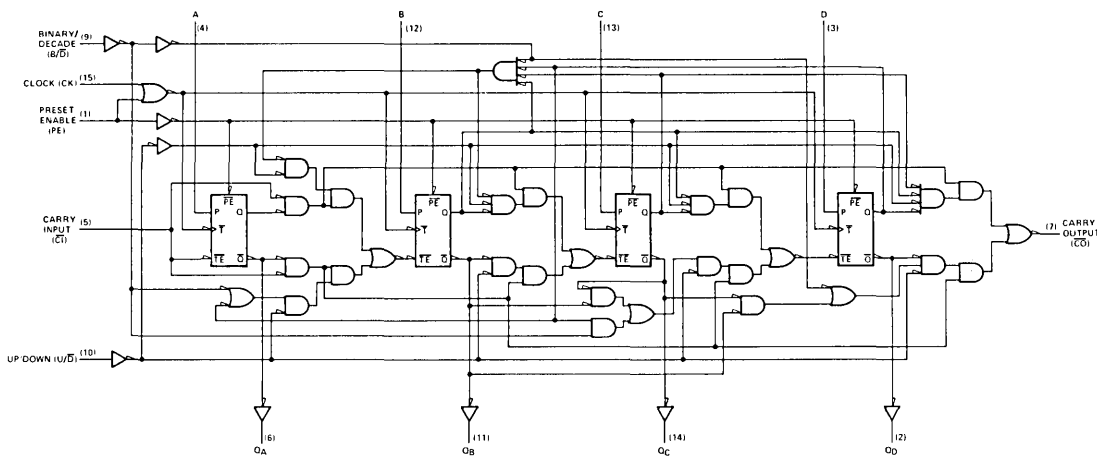
specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 2

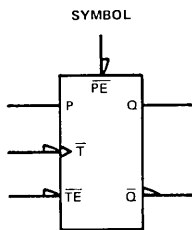
The waveforms and typical application data given for '4029A on pages 107 and 108 also apply for '4029B.

TYPES TF4029B, TP4029B PRESETTABLE UP/DOWN BINARY/DECADE COUNTERS

functional block diagram



EACH FLIP-FLOP



TE = toggle-enable input
P = parallel data input
T = toggle input

FUNCTION TABLE (NOT INCLUDING GATING EXTERNAL TO THE FLIP-FLOP)

INPUTS				OUTPUTS	
PE	TE	T	P	Q	Q̄
L	X	L	H	H	L
L	X	L	L	L	H
H	H	↓	X	Q _n	Q̄ _n
H	L	↓	X	Q̄ _n	Q _n
X	X	H	X	Q ₀	Q̄ ₀

H = high level (steady state)
L = low level (steady state)
X = irrelevant (any input, including transitions)
↓ = transition from high to low level
Q_n = the level of Q before the most-recent
↓ transition of T.
Q₀ = the level of Q before the indicated
steady-state conditions were established

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 15 V	UNIT
		TYP	MAX	TYP	
f _{max} Maximum clock frequency		2.5	5	7	MHz
t _{PLH} Propagation delay time, low-to-high-level	CK to any Q	325	115	100	ns
	CK to C ₀	425	150	125	
t _{PHL} or high-to-low-level output	PE to any Q	325	115	100	
	PE to C ₀	425	150	125	
	CI to C ₀	175	50	45	
t _{TLH} Transition time, low-to-high-level output		95	35	30	ns
t _{THL} Transition time, high-to-low-level output		95	35	30	ns
t _{w(min)} Minimum pulse width	CK high or low	200	100	75	ns
	PE	115	80	80	
t _{su(min)} Minimum setup time	B/D, U/D, or CI	325	115	100	ns
	PE inactive state	325	115	100	
t _{h(min)} Minimum hold time	B/D, U/D, or CI	0	0	0	ns

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4030B, TP4030B QUAD EXCLUSIVE-OR GATES

SEPTEMBER 1975

APPLICATIONS INCLUDE:

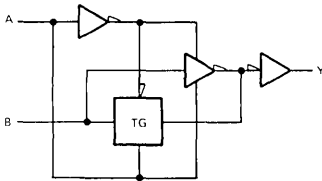
- Even- and Odd-Parity Generators and Checkers
- Logical Comparators
- Adders and Subtractors
- True/Complement Gating

FUNCTION TABLE

INPUTS		OUTPUT
A	B	Y
L	L	L
H	L	H
L	H	H
H	H	L

H = high level, L = low level

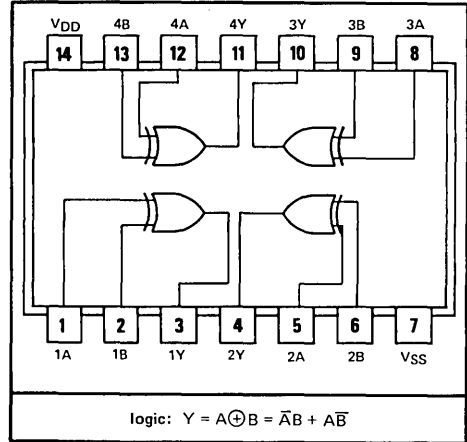
functional block diagram (each gate)



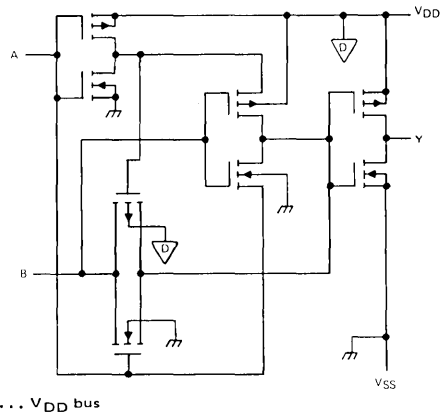
specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 1

J OR N DUAL-IN-LINE PACKAGE (TOP VIEW)



schematic (each gate)



switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 15 V	UNIT
		TYP	MAX	TYP	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	110	50	40	ns
t _{PHL} Propagation delay time, high-to-low-level output		110	50	40	ns
t _{TLH} Transition time, low-to-high-level output		95	35	30	ns
t _{THL} Transition time, high-to-low-level output		95	35	30	ns

NOTE 1: See load circuit and voltage waveforms on page 170.

**FUTURE CMOS PRODUCT
TO BE ANNOUNCED**

**TYPES TF4035B, TP4035B
4-BIT PARALLEL-IN/PARALLEL-OUT
SHIFT REGISTERS**

SEPTEMBER 1975

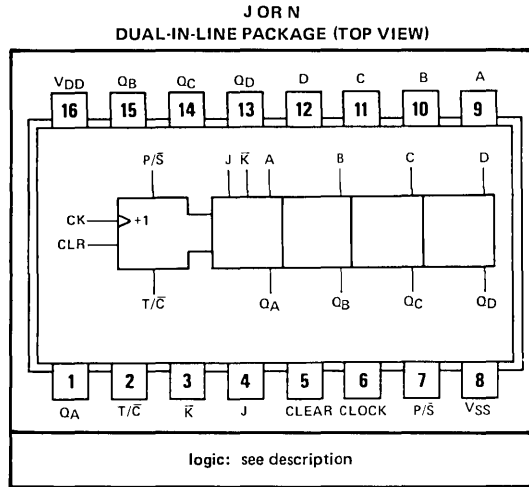
- J/ \bar{K} Serial Input to First Stage

description

These 4-bit synchronous registers have J- \bar{K} serial inputs and parallel access to each stage. D-type master-slave flip-flops are used for each stage with parallel access to the outputs of each stage.

Both serial and parallel entry are made synchronously on the low-to-high transition of the clock input and under the control of the parallel-load/serial-shift input, P/ \bar{S} . When the P/ \bar{S} input is high, data is broadside loaded into the register from the parallel inputs. When the P/ \bar{S} is low, data is entered serially from the J and \bar{K} inputs and each bit shifts one bit position in the direction Q_A towards Q_D. The J- \bar{K} inputs permit the first stage to perform as a J- \bar{K} , D-, or T-type flip-flop as shown in the function table.

When the true/complement input, T/ \bar{C} , is high, data out is not inverted relative to the inputs, but when T/ \bar{C} is low, the data out is inverted.



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 2

FUNCTION TABLE

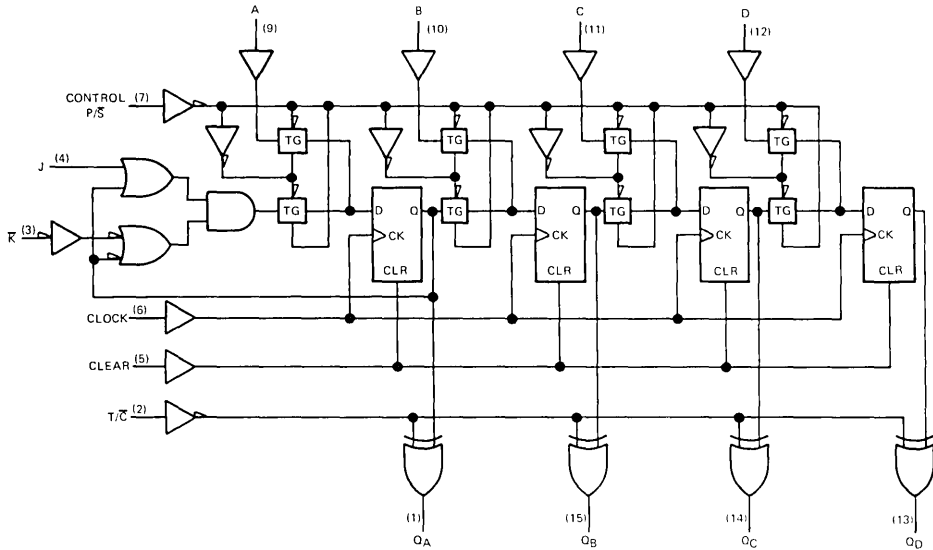
INPUTS					OUTPUTS [†]			
CLEAR	P/ \bar{S}	CLOCK	PARALLEL A B C D	SERIAL J \bar{K}	Q _A	Q _B	Q _C	Q _D
H	X	X	X X X X	X X	L	L	L	L
L	H	↑	a b c d	X X	a	b	c	d
L	L	↑	X X X X	L H	Q _{A0}	Q _{A0}	Q _{Bn}	Q _{Cn}
L	L	↑	X X X X	L L	L	Q _{An}	Q _{Bn}	Q _{Cn}
L	L	↑	X X X X	H H	H	Q _{An}	Q _{Bn}	Q _{Cn}
L	L	↑	X X X X	H L	\bar{Q}_{An}	Q _{An}	Q _{Bn}	Q _{Cn}
L	X	L	X X X X	X X	Q _{A0}	Q _{B0}	Q _{C0}	Q _{D0}

[†]All output levels shown assume T/ \bar{C} is high. If T/ \bar{C} goes low, the internal operation of the register is not affected; however, when T/ \bar{C} is low, all output levels will be the complement of the data originally entered and of what they would have been if T/ \bar{C} had remained high.
See explanation of function tables, pages 16 and 17.

TYPES TF4035B, TP4035B

4-BIT PARALLEL-IN/PARALLEL-OUT SHIFT REGISTERS

functional block diagram



switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 15 V	UNIT
		TYP	MAX	TYP	
f _{max} Maximum clock frequency		2.5	5	7	MHz
t _{PLH} Propagation delay time, low-to-high-level output from clock or clear		250	100	80	ns
t _{PHL} Propagation delay time, high-to-low-level output from clock or clear		250	100	80	ns
t _{T LH} Transition time, low-to-high-level output		95	35	30	ns
t _{T HL} Transition time, high-to-low-level output		95	35	30	ns
t _{w(min)} Minimum pulse width	clock high or low	200	100	75	ns
	clear	125	50	50	
	parallel inputs	100	50	45	
t _{su(min)} Minimum setup time	J or \bar{K} inputs	250	100	80	ns
	parallel inputs	0	0	0	
t _{h(min)} Minimum hold time	J or \bar{K} inputs	0	0	0	ns
	parallel inputs	0	0	0	

NOTE 1: See load circuit and voltage waveforms on page 170.

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CMOS LOGIC CIRCUITS

TYPES TF4042B, TP4042B QUAD D-TYPE LATCHES

SEPTEMBER 1975

- Control and Polarity Inputs
- Complementary Outputs

description

The '4042B is a quadruple D-type latch with common control and polarity inputs, C and P. Complementary buffered outputs are available from each latch.

When P is high, C determines the state of all the latches. If C is high, the latches pass data from their D inputs to their Q outputs and the data complement to their \bar{Q} outputs. If C is low, the data is latched.

When P is low, C still determines the state of all the latches, but now data is passed when C is low and is latched when C is high.

FUNCTION TABLE

P	C	FUNCTION
H	H	Pass data
H	L	Latch data
L	H	Latch data
L	L	Pass data

H = high level, L = low level

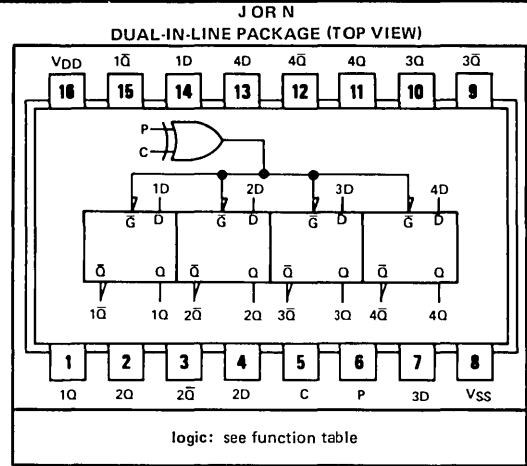
specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 2

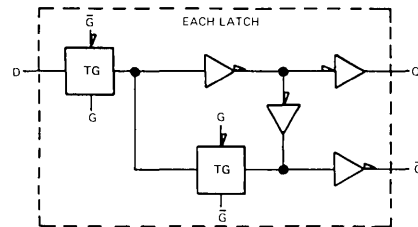
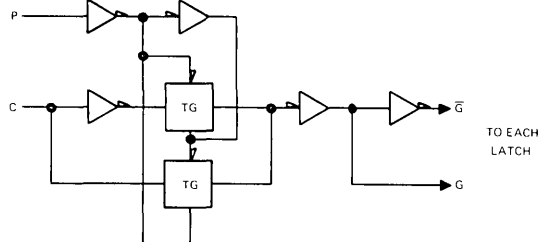
switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 15 V	UNIT
		TYP	MAX	TYP	
t _{PLH} Propagation delay time, low-to-high-level output	from C	150	75	65	ns
	from D	120	40	30	
t _{PHL} Propagation delay time, high-to-low-level output	from C	150	75	65	ns
	from D	120	40	30	
t _{TLH} Transition time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	95	35	30	ns
t _{THL} Transition time, high-to-low-level output		95	35	30	ns
t _{w(min)} Minimum pulse width, control input set to pass data		150	50	50	ns
t _{su(min)} Minimum data setup time before latching		50	25	25	ns
t _{h(min)} Minimum data hold time after latching		0	0	0	ns

NOTE 1: See load circuit and voltage waveforms on page 170.



functional block diagram



CMOS LOGIC CIRCUITS

TYPES TF4043B, TF4044B, TP4043B, TP4044B QUAD S-R AND \bar{S} - \bar{R} LATCHES WITH 3-STATE OUTPUTS

SEPTEMBER 1975

- 3-State Outputs with Common Enable

description

The '4043B and '4044B are quadruple S-R and \bar{S} - \bar{R} latches, respectively, with three-state outputs. Each latch has separate active-high ('4043B) or active-low ('4044B) set and reset inputs. The three-state outputs are controlled by a common output control. When high, this control permits each output to assume the state of the cross-coupled NOR-gate or NAND-gate latch. When the output control is low, all the outputs are in a high-impedance state.

FUNCTION TABLES
(EACH LATCH)
TF4043B, TP4043B

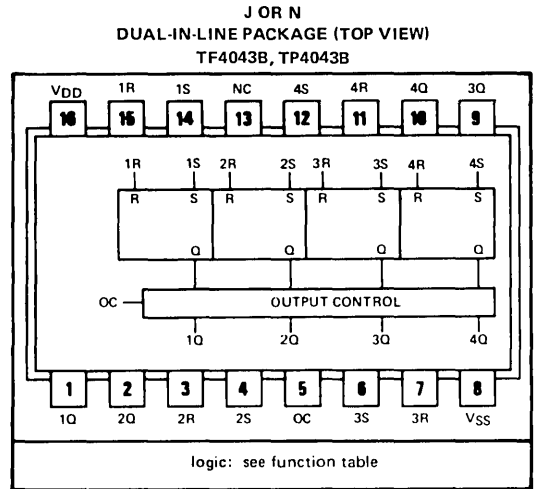
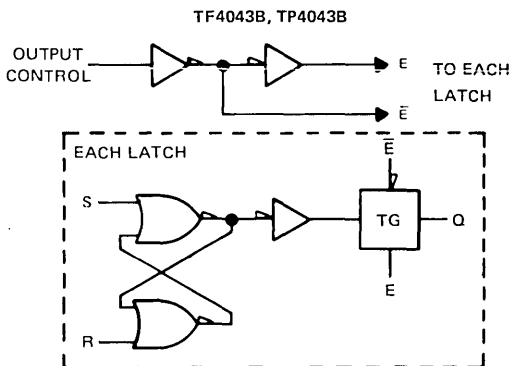
OUTPUT CONTROL	INPUTS		OUTPUT Q
	S	R	
L	X	X	Hi-Z
H	L	L	No change
H	H	L	H
H	L	H	L
H	H	H	H*

TF4044B, TP4044B

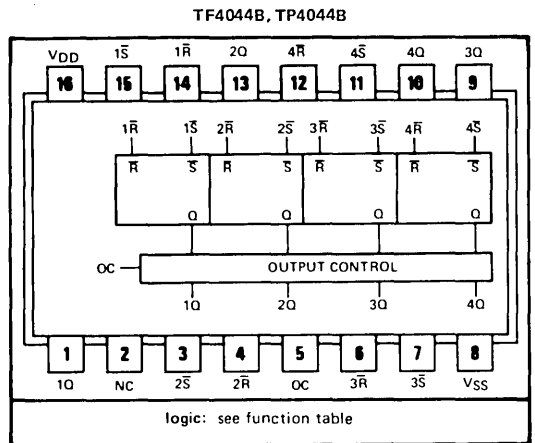
OUTPUT CONTROL	INPUTS		OUTPUT Q
	\bar{S}	\bar{R}	
L	X	X	Hi-Z
H	H	H	No change
H	L	H	H
H	H	L	L
H	L	L	L*

This output level is psuedo stable; that is, it may not persist when the S and R inputs return to their inactive (low) level or the \bar{S} and \bar{R} inputs return to their inactive (high) level. See explanation of function tables, pages 16 and 17.

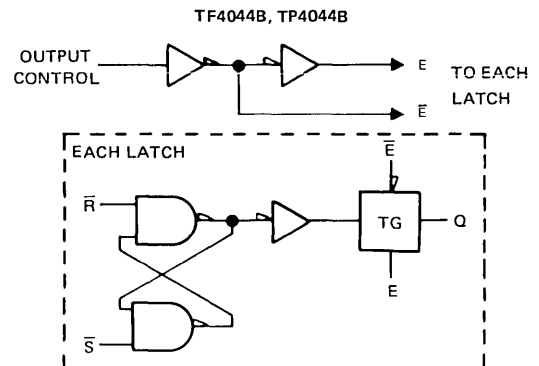
functional block diagrams



NC—No internal connection



NC—No internal connection



TYPES TF4043B, TF4044B, TP4043B, TP4044B

QUAD S-R AND $\bar{S}\bar{R}$ LATCHES WITH 3-STATE OUTPUTS

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 2, except as below

electrical characteristics over recommended operating free-air temperature range

TF4043B and TF4044B

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
I _{OH} High-level output current	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = V _{OH} min	T _A = -55°C	-0.25		-0.55		-1.9	mA
		T _A = 25°C	-0.2		-0.45		-1.5	
		T _A = 125°C	-0.2		-0.33		-1.2	
	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = ½ V _{DD}	T _A = -55°C	-1		-3.7		-5.5	
		T _A = 25°C	-0.8		-3		-4.5	
		T _A = 125°C	-0.6		-2		-3	
I _{OL} Low-level output current	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = V _{OL} max	T _A = -55°C	0.4		0.8		1.9	mA
		T _A = 25°C	0.3		0.6		1.5	
		T _A = 125°C	0.2		0.45		1.2	
	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = ½ V _{DD}	T _A = -55°C	1		3.7		5.5	
		T _A = 25°C	0.8		3		4.5	
		T _A = 125°C	0.6		2		3	
I _{OZH} Off-state output current, high-level voltage applied	OC at V _{SS} , V _O = V _{DD}	T _A = -55°C or 25°C	-0.5		-1		-2	μA
		T _A = 125°C	-7		-14		-28	
I _{OZL} Off-state output current, low-level voltage applied	OC at V _{SS} , V _O = 0 V	T _A = -55°C or 25°C	0.5		1		2	μA
		T _A = 125°C	7		14		28	

TP4043B and TP4044B

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
I _{OH} High-level output current	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = V _{OH} min	T _A = -40°C	-0.22		-0.5		-1.7	mA
		T _A = 25°C	-0.2		-0.45		-1.5	
		T _A = 85°C	-0.2		-0.37		-1.3	
	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = ½ V _{DD}	T _A = -40°C	-0.9		-3.3		-5	
		T _A = 25°C	-0.8		-3		-4.5	
		T _A = 85°C	-0.65		-2.5		-3.6	
I _{OL} Low-level output current	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = V _{OL} max	T _A = -40°C	0.35		0.75		1.7	mA
		T _A = 25°C	0.3		0.6		1.5	
		T _A = 85°C	0.25		0.5		1.3	
	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = ½ V _{DD}	T _A = -40°C	0.9		3.3		5	
		T _A = 25°C	0.8		3		4.5	
		T _A = 85°C	0.65		2.5		3.6	
I _{OZH} Off-state output current, high-level voltage applied	OC at V _{SS} , V _O = V _{DD}	T _A = -40°C or 25°C	-0.5		-1		-2	μA
		T _A = 85°C	-7		-14		-28	
I _{OZL} Off-state output current, low-level voltage applied	OC at V _{SS} , V _O = 0 V	T _A = -40°C or 25°C	0.5		1		2	μA
		T _A = 85°C	7		14		28	

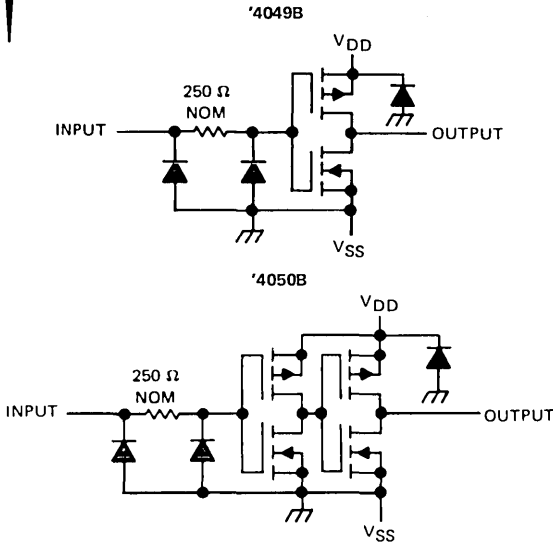
CMOS LOGIC CIRCUITS

TYPES TF4049B, TF4050B, TP4049B, TP4050B HEX INVERTING AND NONINVERTING BUFFERS

SEPTEMBER 1975

- High Current Sinking Capability

schematic (each buffer)



description

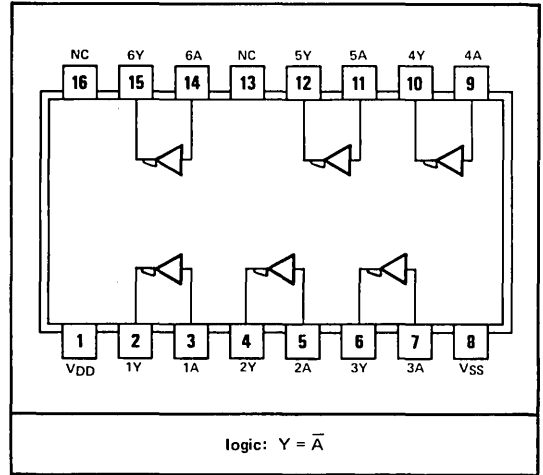
The '4049B and '4050B hex CMOS inverting and noninverting buffers may be used as current sinks or source drivers, hex CMOS drivers, or high-to-low-logic-level (e.g., CMOS to DTL or TTL) converters. Logic-level conversion is accomplished using only one supply voltage (V_{DD}). The high-level input signal (V_{IH}) can exceed the V_{DD} supply voltage when this device is used for logic-level conversions. Table 1 shows the range of voltage levels that can be utilized in these applications. Conversions to logic levels greater than six volts are permitted provided that V_{DD} is less than or equal to V_{IH} .

Since these devices require only one power supply, V_{DD} , they should be used in place of the '4009B and '4010B in all current driver or logic-level conversion applications. They are interchangeable with '4009B and '4010B, respectively, and can be substituted in existing as well as new designs. Pin 16 of the '4049B and '4050B is not internally connected; therefore, any external connection to this pin does not affect circuit operation.

TABLE 1

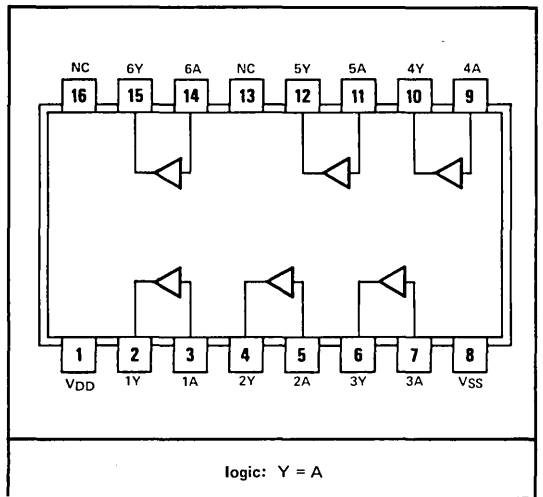
FUNCTION	INPUT HIGH-LEVEL VOLTAGE RANGE	OUTPUT HIGH-LEVEL VOLTAGE RANGE	POWER SUPPLY VOLTAGE RANGE (V_{DD})
Level Shifter	3 to 18 V	3 to 6 V	3 to 6 V
Buffer	3 to 18 V	3 to 18 V	3 to 18 V

J O R N
DUAL-IN-LINE PACKAGE (TOP VIEW)
TF4049B, TP4049B



NC—No internal connection

TF4050A, TP4050B



NC—No internal connection

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 1, except as on following page

TYPES TF4049B, TF4050B, TP4049B, TP4050B HEX INVERTING AND NONINVERTING BUFFERS

electrical characteristics over recommended operating free-air temperature range

TF4049B and TF4050B

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT	
		MIN	MAX	MIN	MAX	MIN	MAX		
V _{IH} High-level output voltage		4		8		12		V	
V _{IL} Low-level output voltage		TF4049B		1		2		V	
		TF4050B		1		2			
V _{OH} High-level output voltage	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, I _O = 0	4.6		9.5		13.5		V	
	V _{IH} = V _{DD} , V _{IL} = 0, I _O = I _{OH} min	4.6		9.5		13.5			
V _{OL} Low-level output voltage	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, I _O = 0			0.4		0.5		V	
	V _{IH} = V _{DD} , V _{IL} = 0, I _O = I _{OL} min			0.4		0.5			
I _{OL} Low-level output current	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = V _{OL} max	T _A = -55°C	3.75		10		30		mA
		T _A = 25°C	3.2		8		24		
		T _A = 125°C	2.1		5.6		17		
	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = ½ V _{DD}	T _A = -55°C	11		36		53		
		T _A = 25°C	9.2		29		42		
		T _A = 125°C	6		20		30		

TP4049B and TP4050B

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT	
		MIN	MAX	MIN	MAX	MIN	MAX		
V _{IH} High-level input voltage		4		8		12		V	
V _{IL} Low-level input voltage		TP4049B		1		2		V	
		TP4050B		1		2			
V _{OH} High-level output voltage	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, I _O = 0	4.6		9.5		13.5		V	
	V _{IH} = V _{DD} , V _{IL} = 0, I _O = I _{OH} min	4.6		9.5		13.5			
V _{OL} Low-level output voltage	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, I _O = 0			0.4		0.5		V	
	V _{IH} = V _{DD} , V _{IL} = 0, I _O = I _{OL} min			0.4		0.5			
I _{OL} Low-level output current	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = V _{OL} max	T _A = -40°C	3.6		9.6		28		mA
		T _A = 25°C	3.2		8		24		
		T _A = 85°C	2.5		6.6		19		
	V _{IH} = V _{IH} min, V _{IL} = V _{IL} max, V _O = ½ V _{DD}	T _A = -40°C	10		34		49		
		T _A = 25°C	9.2		29		42		
		T _A = 85°C	7.1		24		33		

'4049B switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT
		TYP	MAX	TYP	MAX	TYP	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	80		50		40		ns
t _{PHL} Propagation delay time, high-to-low-level output		30		20		15		ns
t _{TLH} Transition time, low-to-high-level output		80		40		30		ns
t _{THL} Transition time, high-to-low-level output		35		25		20		ns

'4050B switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT
		TYP	MAX	TYP	MAX	TYP	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	100		60		45		ns
t _{PHL} Propagation delay time, high-to-low-level output		70		40		30		ns
t _{TLH} Transition time, low-to-high-level output		80		40		30		ns
t _{THL} Transition time, high-to-low-level output		35		25		20		ns

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4051B, TF4052B, TF4053B, TP4051B, TP4052B, TP4053B ANALOG MULTIPLEXERS/DEMULTIPLEXERS

SEPTEMBER 1975

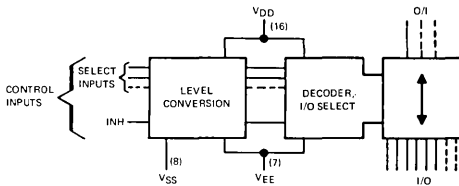
- Difference in r_{on} Between Switches in One Package Typically 5Ω at $V_{DD}-V_{EE} = 15 V$
- High Degree of Linearity . . . $< 0.1\%$ Distortion Typical at 1 kHz, $V_{DD}-V_{EE} = 15 V$
- Switches Can Transmit Signals in Either Direction at Frequencies of up to 40 MHz Typically at $V_{DD}-V_{EE} = 10 V$
- Extremely Low Off-State Switch Current Resulting in Very High Effective Off-State Resistance . . . 10 pA Typical at $V_{DD}-V_{SS} = 10 V$
- Low Crosstalk Between Switches . . . 40 dB Typical at 1 MHz, $R_L = 1 k\Omega$

description

These devices are analog multiplexers/demultiplexers incorporating built-in level shifting. Any combination of supply voltages is permissible provided that V_{SS} and V_{EE} are each within the range of -3 to -18 volts with respect to V_{DD} . The level shifting is between V_{SS} and V_{EE} . The control input range is V_{SS} to V_{DD} and the analog signal range is V_{EE} to V_{DD} . The common situation of positive digital signals controlling the multiplexing of both positive and negative analog signals can be accommodated. The table indicates some of the possible combinations of supply, input, and output voltages.

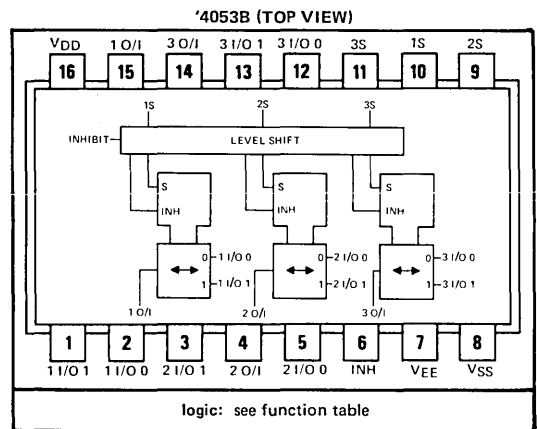
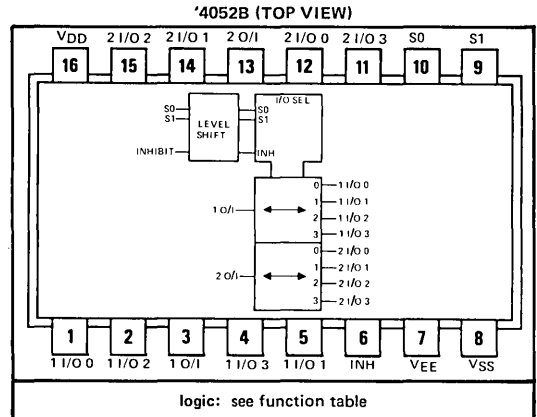
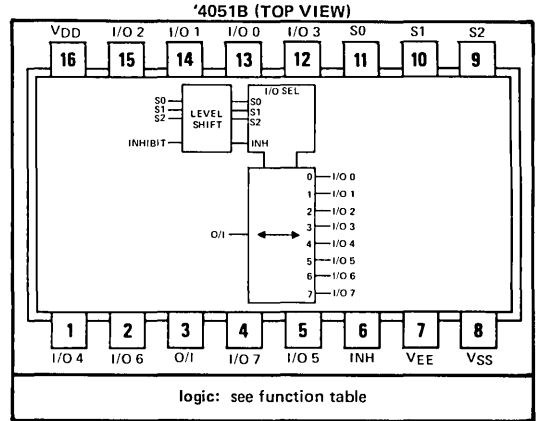
TYPICAL SUPPLY AND SIGNAL VOLTAGES

V_{DD}	15 V	10 V	7.5 V	7.5 V
V_{SS}	0 V	0 V	0 V	-7.5 V
V_{EE}	0 V	-5 V	-7.5 V	-7.5 V
Control Inputs	0 to 15 V	0 to 10 V	0 to 7.5 V	-7.5 to 7.5 V
Analog Signals	0 to 15 V	-5 to 10 V	-7.5 to 7.5 V	-7.5 to 7.5 V



INTERNAL POWER SUPPLY CONNECTIONS

JORN DUAL-IN-LINE PACKAGES



TYPES TF4051B, TF4052B, TF4053B, TP4051B, TP4052B, TP4053B ANALOG MULTIPLEXERS/DEMULTIPLEXERS

description (continued)

These digitally controlled bilateral analog switches have low on-state impedance and very low off-state current. When the inhibit input terminal is high, all channels are off.

The '4051B is a single eight-channel multiplexer having three binary control inputs (S0, S1, and S2) and an inhibit input. The three binary signals select one of eight channels to be turned on.

The '4052B is a dual four-channel multiplexer having two binary control inputs (S0 and S1) and an inhibit input. The two binary signals select one of four channels in each of the two sections and the selected channels are respectively paired between the independent sections.

The '4053B is a triple two-channel multiplexer having three separate control inputs (1S, 2S, and 3S) and a common inhibit input. Each input independently selects one of two channels in one of the three sections so that any of eight combinations may be selected.

**'4051B
FUNCTION TABLE**

INPUTS				CHANNEL TURNED ON
INH	S2	S1	S0	
H	X	X	X	None
L	L	L	L	0
L	L	L	H	1
L	L	H	L	2
L	L	H	H	3
L	H	L	L	4
L	H	L	H	5
L	H	H	L	6
L	H	H	H	7

**'4052B
FUNCTION TABLE
(EACH BILATERAL SWITCH)**

INPUTS			CHANNEL TURNED ON
INH	S1	S0	
H	X	X	None
L	L	L	0
L	L	H	1
L	H	L	2
L	H	H	3

**'4053B
FUNCTION TABLE
(EACH BILATERAL SWITCH)**

INPUTS		CHANNEL TURNED ON
INH	S	
H	X	None
L	L	0
L	H	1

H = high level, L = low level, X = irrelevant

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24 and below	Page 24	Pages 24 and 25, group 2, except as below. I_{OH} and I_{OL} do not apply

absolute maximum ratings over operating free-air temperature range

Supply voltage V_{EE} (with respect to V_{DD}) -18 V

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted), $V_{EE} = V_{SS} = 0 V$

PARAMETER	TEST CONDITIONS	$V_{DD} = 5 V$		$V_{DD} = 10 V$		$V_{DD} = 15 V$		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
V_{OH} High-level output voltage	Control inputs at V_{IH} min or V_{IL} max, I/O at 0 V, $I_O = 10 \mu A$, Channel off,	4.6		9.5		13.5		V
V_{OL} Low-level output voltage	Control inputs at V_{IH} min or V_{IL} max, I/O at 0 V, $I_O = 10 \mu A$, Channel on,		0.4		0.5		1.5	V
Input-to-output off-state current	Control inputs at 0 V or V_{DD} , I/O at 5 V, O/I at 0 V to V_{DD} , Channel off, $T_A = 25^\circ C$				± 125			nA

TYPES TF4051B, TF4052B, TF4053B, TP4051B, TP4052B, TP4053B

ANALOG MULTIPLEXERS/DEMULTIPLEXERS

on-state resistance at 25°C free-air temperature, $R_L = 10\text{ k}\Omega$ to 0 V

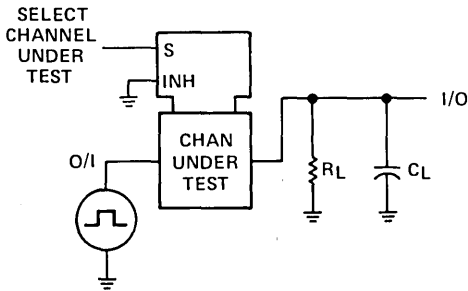
TEST CONDITIONS			TYP	MAX	UNIT
$V_{DD} = 7.5\text{ V}$	$V_{EE} = -7.5\text{ V}$,	$V_{SS} = 0\text{ V}$	80		Ω
$V_{DD} = 15\text{ V}$,	$V_{EE} = 0\text{ V}$,	$V_{SS} = 0\text{ V}$			
$V_{DD} = 5\text{ V}$,	$V_{EE} = -5\text{ V}$,	$V_{SS} = 0\text{ V}$	120		Ω
$V_{DD} = 10\text{ V}$,	$V_{EE} = 0\text{ V}$,	$V_{SS} = 0\text{ V}$			
$V_{DD} = 5\text{ V}$,	$V_{EE} = 0\text{ V}$,	$V_{SS} = 0\text{ V}$	270		Ω

switching characteristics at 25°C free-air temperature, $V_{EE} = V_{SS} = 0\text{ V}$

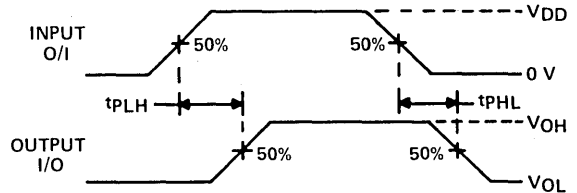
PARAMETER [†]	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	$V_{DD} = 5\text{ V}$	$V_{DD} = 10\text{ V}$	$V_{DD} = 15\text{ V}$	UNIT
				TYP	MAX	TYP	
t_{PLH}	O/I	I/O	$R_L = 10\text{ k}\Omega$, $C_L = 50\text{ pF}$, See Figure 1	25	10	8	ns
t_{PHL}	O/I	I/O		25	10	8	
t_{PLH}	S	I/O	$C_L = 50\text{ pF}$, See Figure 2	400	200	170	ns
t_{PHL}	S	I/O	$R_L = 10\text{ k}\Omega$ to V_{DD}	400	200	170	
t_{PLH}	INH	I/O	$C_L = 50\text{ pF}$, See Figure 2	600	300	250	ns
t_{PHL}	INH	I/O	$R_L = 10\text{ k}\Omega$ to V_{DD}	600	300	250	

[†] t_{PLH} ≡ Propagation delay time, low-to-high-level output
 t_{PHL} ≡ Propagation delay time, high-to-low-level output.

PARAMETER MEASUREMENT INFORMATION

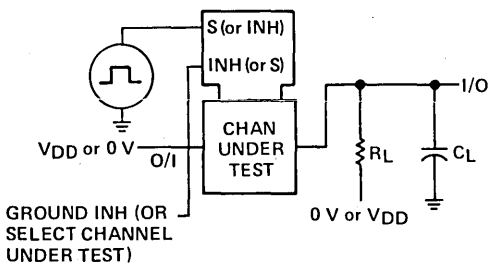


TEST CIRCUIT

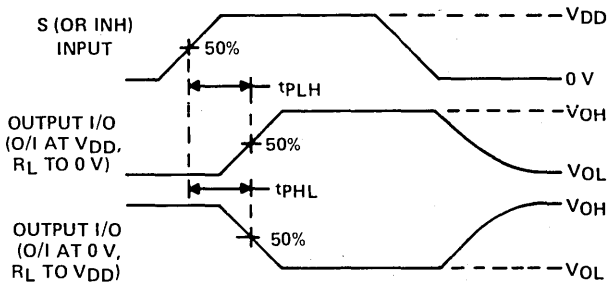


VOLTAGE WAVEFORMS

FIGURE 1



TEST CIRCUIT



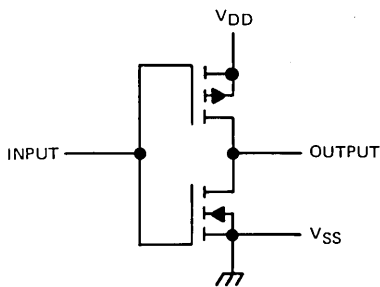
VOLTAGE WAVEFORMS

FIGURE 2

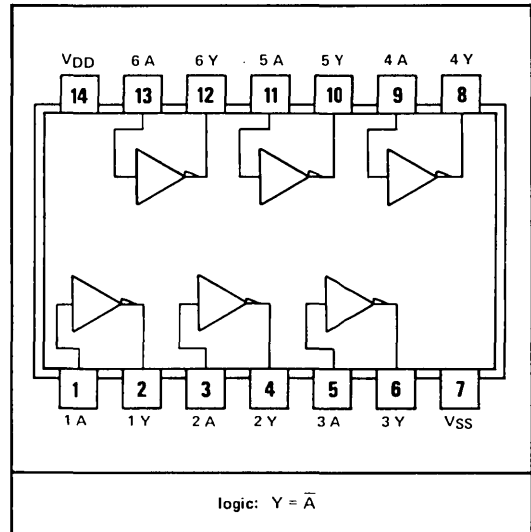
NOTES: A. Input pulses are supplied by generators having the following characteristics: $Z_{out} = 50\ \Omega$, $PRR = 10\text{ kHz}$, $t_r \leq 20\text{ ns}$, $t_f \leq 20\text{ ns}$.
 B. C_L includes probe and jig capacitance.
 C. The waveforms are monitored on an oscilloscope with the following characteristics: $t_r \leq 20\text{ ns}$, $R_{in} \geq 1\text{ M}\Omega$.

- Designed to be Interchangeable with RCA CD4069B
- Medium Speed Operation
t_{PHL} = t_{PLH} = 40 ns typ at 10 V

schematic (each buffer)



J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 1

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1		125		80		70	ns
t _{PHL} Propagation delay time, high-to-low-level output			125		80		70	
t _{TLH} Transition time, low-to-high-level output			200		100		80	ns
t _{THL} Transition time, high-to-low-level output			200		100		80	

NOTE 1: See load circuit and voltage waveforms on page 170.

APPLICATIONS INCLUDE:

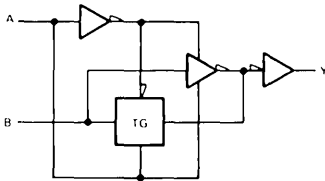
- Even- and Odd-Parity Generators and Checkers
- Logical Comparators
- Adders and Subtractors
- True/Complement Gating

FUNCTION TABLE

INPUTS		OUTPUT
A	B	Y
L	L	L
H	L	H
L	H	H
H	H	L

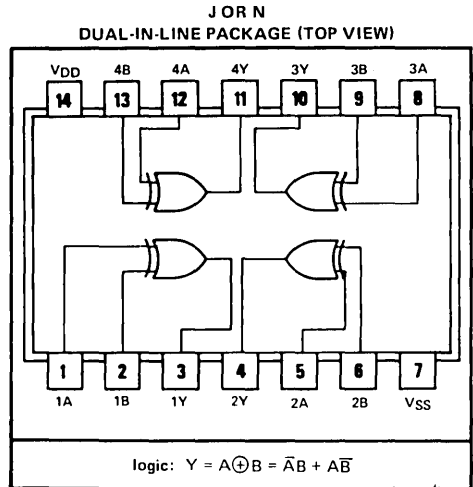
H = high level, L = low level

functional block diagram (each gate)

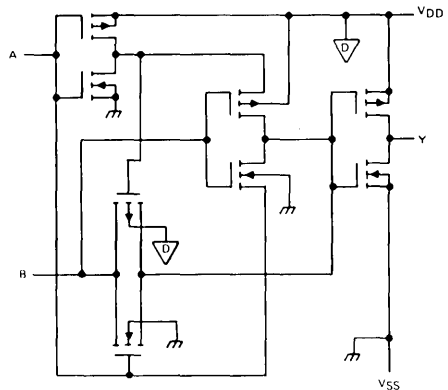


specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 1



schematic (each gate)



switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 15 V	UNIT
		TYP	MAX	TYP	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	175	70	50	ns
t _{PHL} Propagation delay time, high-to-low-level output		175	70	50	ns
t _{TLH} Transition time, low-to-high-level output		100	50	40	ns
t _{THL} Transition time, high-to-low-level output		100	50	40	ns

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

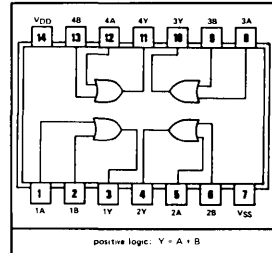
TYPES '4071B, '4072B, '4073B, '4075B, '4081B, '4082B, '4085B OR, AND, AND AND-OR-INVERT GATES

SEPTEMBER 1975

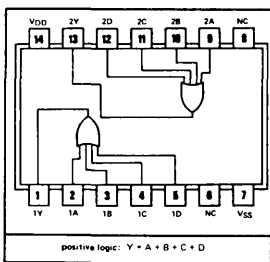
- All Products Available in J or N Dual-In-Line Packages

- '4071B ... Quad 2-Input OR Gates
- '4072B ... Dual 4-Input OR Gates
- '4073B ... Triple 3-Input AND Gates
- '4075B ... Triple 3-Input OR Gates
- '4081B ... Quad 2-Input AND Gates
- '4082B ... Dual 4-Input AND Gates
- '4085B ... Dual 3-Wide 2-2-1 Input AND-OR-Invert Gates

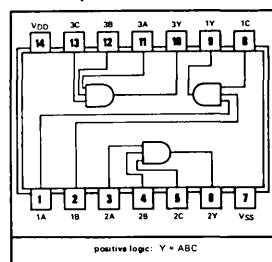
TF4071B, TP4071B (TOP VIEW)



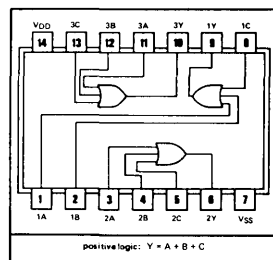
TF4072B, TP4072B (TOP VIEW)



TF4073B, TP4073B (TOP VIEW)

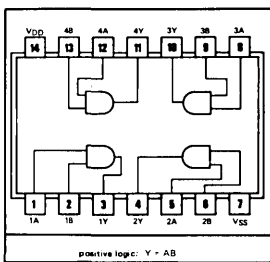


TF4075B, TP4075B (TOP VIEW)

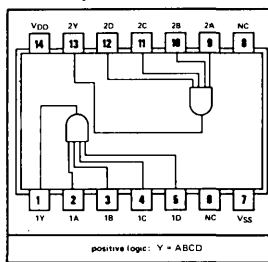


NC—No internal connection

TF4081B, TP4081B (TOP VIEW)

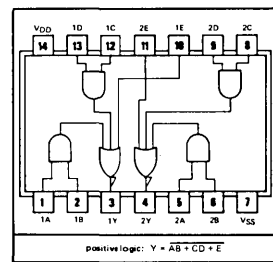


TF4082B, TP4082B (TOP VIEW)



NC—No internal connection

TF4085B, TP4085B (TOP VIEW)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 1

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 15 V	UNIT
		TYP	MAX	TYP	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	225	65	50	ns
t _{PHL} Propagation delay time, high-to-low-level output		225	65	50	
t _{TLH} Transition time, low-to-high-level output		95	35	30	
t _{THL} Transition time, high-to-low-level output		95	35	30	

NOTE 1: See load circuit and voltage waveforms on page 170.

◇ Future products to be announced.

CMOS LOGIC CIRCUITS

TYPES TF4376B, TP4376B QUAD S-R LATCHES

SEPTEMBER 1975

- Same as TF4043B and TP4043B except with Normal 2-State Totem-Pole Outputs

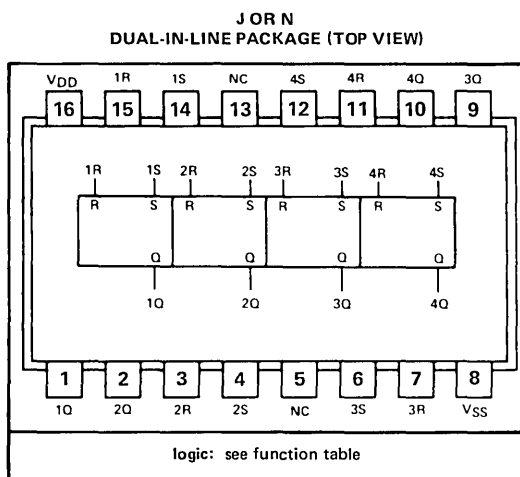
description

The '4376B is a quadruple S-R latch with normal two-state totem-pole outputs. Each latch has separate active-high set and reset inputs.

FUNCTION TABLE
(EACH LATCH)

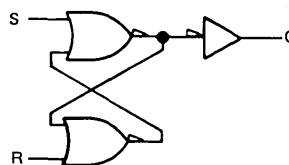
INPUTS		OUTPUT
S	R	Q
L	L	No change
H	L	H
L	H	L
H	H	H*

*This output level is psuedo stable; that is, it may not persist when the S and R inputs return to their inactive (low) level. See explanation of function tables, pages 16 and 17.



NC—No internal connection

functional block diagram (each latch)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 2

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 15 V		UNIT
		TYP	MAX	TYP	MAX	TYP	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	165		70		60		ns
t _{PHL} Propagation delay time, high-to-low-level output		165		70		60		ns
t _{TLH} Transition time, low-to-high-level output		85		30		25		ns
t _{THL} Transition time, high-to-low-level output		85		30		25		ns
t _{w(min)} Minimum R and S pulse width		80		40		35		ns

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4377B, TP4377B QUAD \bar{S} - \bar{R} LATCHES

SEPTEMBER 1975

- Same as TF4044B and TP4044B except with Normal 2-State Totem-Pole Outputs

description

The '4377B is a quadruple \bar{S} - \bar{R} latch with normal two-state totem-pole outputs. Each latch has separate active-low set and reset inputs.

FUNCTION TABLE
(EACH LATCH)

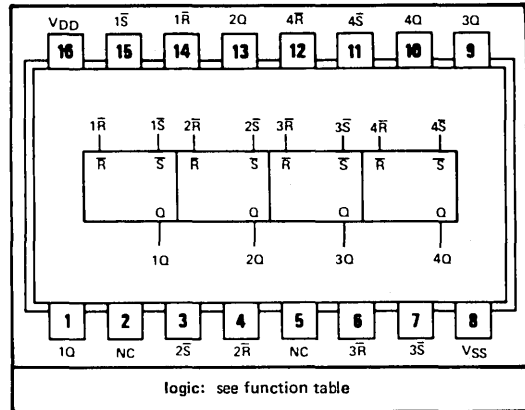
INPUTS		OUTPUT Q
\bar{S}	\bar{R}	
H	H	No change
L	H	H
H	L	L
L	L	H*

*This output level is psuedo stable; that is, it may not persist when the \bar{S} and \bar{R} inputs return to their inactive (high) level. See explanation of function tables, pages 16 and 17.

specifications

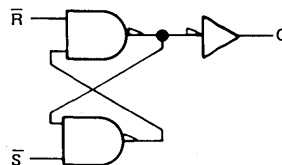
MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 24	Page 24	Pages 24 and 25, group 2

J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



NC—No internal connection

functional block diagram (each latch)



switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 15 V	UNIT
		TYP	MAX	TYP	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	165	70	60	ns
t _{PHL} Propagation delay time, high-to-low-level output		165	70	60	ns
t _{TLH} Transition time, low-to-high-level output		85	30	25	ns
t _{THL} Transition time, high-to-low-level output		85	30	25	ns
t _{w(min)} Minimum \bar{R} and \bar{S} pulse width		80	40	35	ns

NOTE 1: See load circuit and voltage waveforms on page 170.

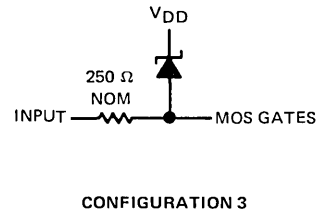
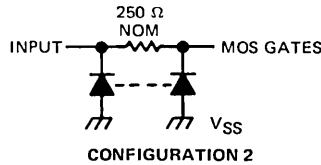
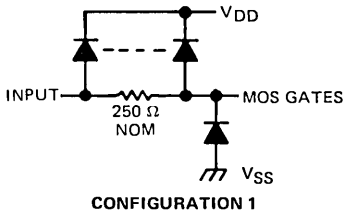
SERIES '4000A

GENERAL INFORMATION

"A" SERIES INFORMATION

INPUT PROTECTION

Input protection networks have been standardized to the three configurations below:



Configuration 1 is used on the whole family except for the '4049A and '4050A (which use configuration 2) and the '4518A and '4520A (which use configuration 3). In configurations 1 and 2 the diodes to V_{SS} have a reverse breakdown of approximately 22 to 28 volts. In configuration 3, the breakdown voltage of the zener diode is approximately 25 volts. These networks are incorporated as protection against occasional electrostatic overstress. It is not recommended that units be subjected to continuously repeated overstress. CMOS is much less sensitive to electrostatic overstress than other MOS technologies; however, care should be taken in handling these networks much the same as is required for other high-impedance integrated circuits:

- 1) Equipment should be properly grounded.
- 2) Work surfaces should be electrically conductive and connected to earth ground.
- 3) Handling should be minimized.

INPUT CHARACTERISTICS

For input voltages between V_{SS} and V_{DD} , the protective networks are in reverse-biased, low-current states. Typically, this reverse current is in the picoampere range at 25°C. When quiescent supply current is measured, all inputs are connected in such a manner that the current through all the inputs is included. The input capacity is typically 3 to 7 pF except for the '4049A for which 15 pF is typical. All unused inputs must be connected to V_{SS} or V_{DD} , whichever is appropriate.

OUTPUT CHARACTERISTICS

The data sheets should be consulted for drive capabilities. Typically, the dc fan-out to other CMOS is 50, but reduced switching speeds are caused by adding capacitive loading. TI data sheets specify switching speeds for $C_L = 50$ pF or a typical load of 10 CMOS inputs. With 15 pF loads these devices switch at speeds similar to their respective RCA and Motorola equivalents.

NOISE MARGINS

The '4000A series is specified in such a manner as to measure noise immunity by applying V_{IH} min or V_{IL} max to one input at a time while all other inputs are at V_{DD} or V_{SS} , as appropriate. The output is not loaded in this test and is allowed to deviate to the value of V_{OH} min or V_{OL} max in the data sheet.

SERIES '4000A GENERAL INFORMATION

SPECIFICATION GROUPING

The products in this book are classified into three groups each having common characteristics. The first group (SSI, small-scale integration) comprises the basic gate functions, the second group (CSSI, complex small-scale integration) comprises the dual flip-flops, buffers, and small analog functions, and the third group (MSI, medium-scale integration) comprises the more complex functions. The type numbers in each group of the "A" series are shown in the following table.

GROUP 1 (SSI)	GROUP 2 (CSSI)	GROUP 3 (MSI)
4000A	4009A	4008A
4001A	4010A	4014A
4002A	4013A	4015A
4007A	4016A	4017A
4011A	4019A	4018A
4012A	4027A	4020A
4023A	4030A	4021A
4025A	4049A	4022A
4301A	4050A	4024A
4302A	4304A	4028A
4303A	4316A	4029A
4311A	4507A	4040A
4315A	4519A	4042A
		4043A
		4044A
		4051A
		4052A
		4053A
		4320A
		4321A
		4360A
		4361A
		4362A
		4363A
		4370A
		4376A
		4377A
		4380A♦
		4512A
		4518A
		4520A
		4522A
		4526A
		4531A
		4581A
		4582A

♦ Future products to be announced

SERIES '4000A

COMMON ELECTRICAL SPECIFICATIONS

SEPTEMBER 1975

The following electrical specifications apply for most series '4000A CMOS products. Each individual product specification references the appropriate sections of this common specification and lists exceptions if there are any.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{DD} (see Note 1)	15 V
Input current	± 10 mA
Continuous total dissipation	200 mW
Operating free-air temperature range: TF4000A Series	-55°C to 125°C
TP4000A Series	-40°C to 85°C
Storage temperature range	-65°C to 150°C

NOTE 1: Throughout this page, the following page, and the individual product specifications, voltage values are with respect to the V_{SS} terminal unless otherwise noted.

recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, V_{DD}	3	15	V
Input voltage, V_I	0	V_{DD}	V
Operating free-air temperature, T_A	TF4000A Series		-55 125 $^{\circ}\text{C}$
	TP4000A Series		-40 85 $^{\circ}\text{C}$
Rise time, any input, t_r		15	μs
Fall time, any input, t_f		15	μs

electrical characteristics at $V_{DD} = 5\text{ V}$ and 10 V

PARAMETER		TEST CONDITIONS†		TF4000A SERIES		TP4000A SERIES		UNIT				
				$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$			$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$	
				MIN	MAX	MIN	MAX		MIN	MAX	MIN	MAX
V_{IH}	High-level input voltage		$T_A = \text{MIN}, 25^\circ\text{C}$ or MAX	3.5	8	3.5	8	V				
V_{IL}	Low-level input voltage		$T_A = \text{MIN}, 25^\circ\text{C}$, or MAX	1.5	2	1.5	2	V				
V_{OH}	High-level output voltage	$V_{IH} = V_{DD}, V_{IL} = 0, I_O = 0$	$T_A = \text{MIN}, 25^\circ\text{C}$, or MAX	4.95	9.95	4.95	9.95	V				
		One input at V_{IH} min or V_{IL} max, All other inputs at V_{DD} or 0 V , $I_O = 0$	$T_A = \text{MIN}, 25^\circ\text{C}$, or MAX	4.5	9	4.5	9					
		$V_{IH} = V_{DD}, V_{IL} = 0, I_O = I_{OH}$ min	$T_A = \text{MIN}, 25^\circ\text{C}$, or MAX	2.5	9.5	2.5	9.5					
V_{OL}	Low-level output voltage	$V_{IH} = V_{DD}, V_{IL} = 0, I_O = 0$	$T_A = \text{MIN}, 25^\circ\text{C}$, or MAX	0.05	0.05	0.05	0.05	V				
		One input at V_{IH} min or V_{IL} max, All other inputs at V_{DD} or 0 V , $I_O = 0$	$T_A = \text{MIN}, 25^\circ\text{C}$, or MAX	0.5	1	0.5	1					
		$V_{IH} = V_{DD}, V_{IL} = 0, I_O = I_{OL}$ min	$T_A = \text{MIN}, 25^\circ\text{C}$, or MAX	0.4	0.5	0.4	0.5					
I_{OH}	High-level output current	$V_{IH} = V_{DD}, V_{IL} = 0, V_O = V_{OH}$ min	$T_A = \text{MIN}$	-0.65	-0.65	-0.35	-0.3	mA				
			$T_A = 25^\circ\text{C}$	-0.5	-0.5	-0.3	-0.25					
			$T_A = \text{MAX}$	-0.35	-0.35	-0.25	-0.2					
I_{OL}	Low-level output current	$V_{IH} = V_{DD}, V_{IL} = 0, V_O = V_{OL}$ max	$T_A = \text{MIN}$	0.5	1.1	0.35	0.75	mA				
			$T_A = 25^\circ\text{C}$	0.4	0.9	0.3	0.6					
			$T_A = \text{MAX}$	0.3	0.65	0.25	0.5					
I_{DD} or $-I_{SS}$	Quiescent supply current	No load, $V_I = V_{DD}$ or 0 V	$T_A = \text{MIN}$ or 25°C	0.05	0.1	0.5	5	μA				
			$T_A = \text{MAX}$	3	6	15	30					
			$T_A = \text{MIN}$ or 25°C	1	2	10	20					
			$T_A = \text{MAX}$	60	120	140	280					
			$T_A = \text{MIN}$ or 25°C	5	10	50	100					
			$T_A = \text{MAX}$	300	600	700	1400					

electrical characteristics at $V_{DD} = 15\text{ V}$

PARAMETER		TEST CONDITIONS†		TF4000A SERIES		TP4000A SERIES		UNIT
				MIN	MAX	MIN	MAX	
I_I	Input current	$V_I = V_{DD}$ or 0 V	$T_A = \text{MIN}, 25^\circ\text{C}$, or MAX	± 1		± 1		μA
I_{DD} or $-I_{SS}$	Quiescent supply current	No load, $V_I = V_{DD}$ or 0 V	$T_A = \text{MIN}$ or 25°C	1		15		μA
			$T_A = \text{MAX}$	18		90		
			$T_A = \text{MIN}$ or 25°C	6		60		
			$T_A = \text{MAX}$	360		840		
			$T_A = \text{MIN}$ or 25°C	30		300		
			$T_A = \text{MAX}$	1800		4200		

† $T_A = \text{MIN}$ or MAX refers to the respective value specified under recommended operating conditions.

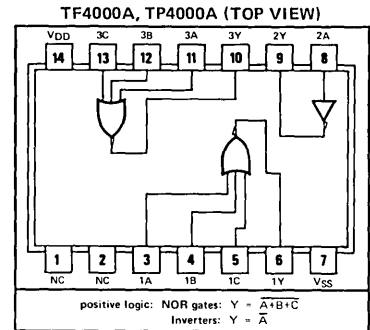
‡See group designation on individual product specifications and page 61 for a list of all products by group.

CMOS LOGIC CIRCUITS

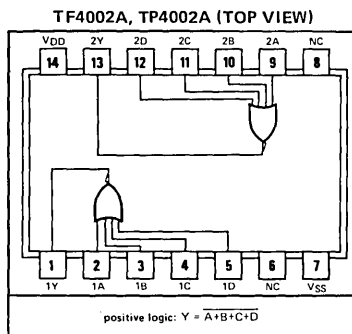
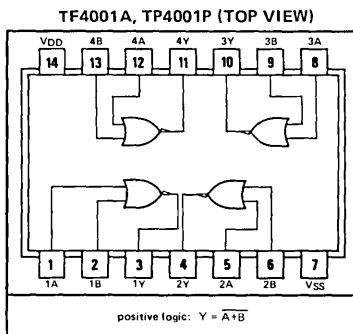
TYPES TF4000A, TF4001A, TF4002A, TP4000A, TP4001A, TP4002 AND OTHER NOR GATES

SEPTEMBER 1975

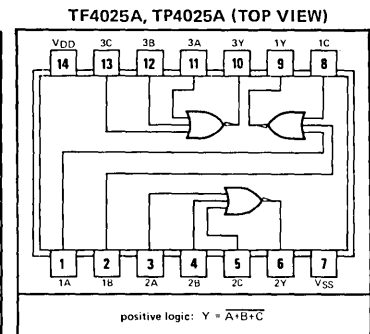
- Designed to be Interchangeable with RCA CD4000A, CD4001A, CD4002A, and CD4025A
- All Products Available in J or N Dual-in-Line Packages
 - '4000 . . . Dual 3-Input NOR Gates Plus Inverters
 - '4001 . . . Quadruple 2-Input NOR Gates
 - '4002 . . . Dual 4-Input NOR Gates
 - '4025 . . . Triple 3-Input NOR Gates



NC—No internal connection



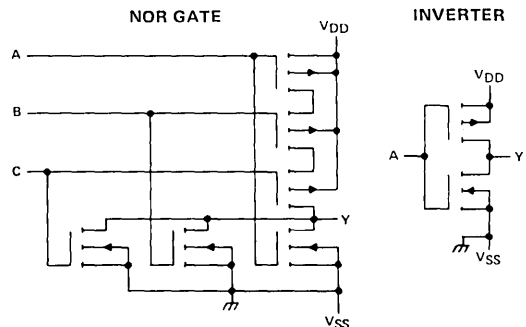
NC—No internal connection



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, Group 1

typical schematics



switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4000A, TF4001A TF4002A, TF4025A		TP4000A, TP4001A TP4002A, TP4025A		UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	
t_{PLH} Propagation delay time, low-to-high-level output	$C_L = 50\text{ pF}$ §, $R_L = 200\text{ k}\Omega$, See Note 1	150	100	200	130	ns
t_{PHL} Propagation delay time, high-to-low-level output		150	100	200	130	ns
t_{TLH} Transition time, low-to-high-level output		350	175	450	300	ns
t_{THL} Transition time, high-to-low-level output		350	175	450	300	ns

§ With a 15-pF load, these devices switch with times similar to those of the RCA CD4000A, CD4001A, CD4002A, and CD4025A, respectively.
NOTE 1: See load circuit and voltage waveforms on page 170.

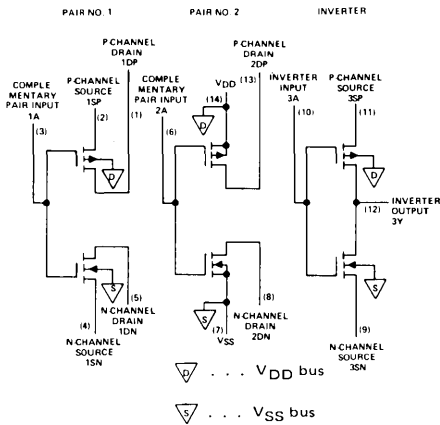
CMOS LOGIC CIRCUITS

TYPES TF4007A, TP4007A DUAL COMPLEMENTARY PAIRS PLUS INVERTERS

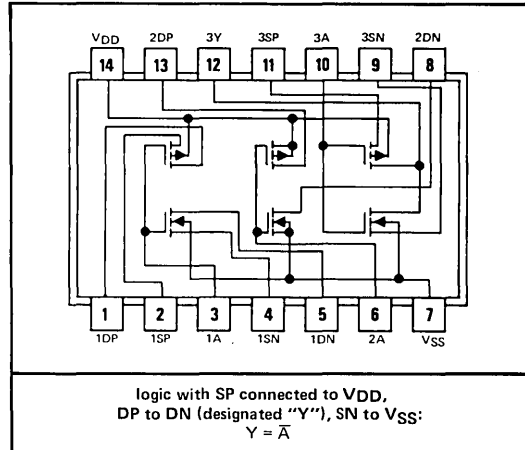
SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4007A

schematic



J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, Group 1, except as below

electrical characteristics (see note 1)

$V_{DD} = 5\text{ V}$ and 10 V

PARAMETER	TEST CONDITIONS†	TF4007A		TP4007A		UNIT	
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$			
		MIN	MAX	MIN	MAX		
I_{OH} High-level output current	$V_{IH} = V_{DD}$, $V_{IL} = 0$, $V_O = V_{OH\ min}$	$T_A = \text{MIN}$	-1.75	-1.35	-1.3	-0.65	mA
		$T_A = 25^\circ\text{C}$	-1.4	-1.1	-1.1	-0.55	
		$T_A = \text{MAX}$	-1	-0.75	-0.9	-0.45	
I_{OL} Low-level output current	$V_{IH} = V_{DD}$, $V_{IL} = 0$, $V_O = V_{OL\ max}$	$T_A = \text{MIN}$	0.75	1.6	0.35	1.2	mA
		$T_A = 25^\circ\text{C}$	0.6	1.3	0.3	1	
		$T_A = \text{MAX}$	0.4	0.95	0.25	0.8	
I_{DD} or $-I_{SS}$ Quiescent supply current	$V_I = V_{DD}$ or 0 , No load	$T_A = \text{MIN}$ or 25°C	0.05	0.1	0.5	1	μA
		$T_A = \text{MAX}$	3	6	15	30	

$V_{DD} = 15\text{ V}$

PARAMETER	TEST CONDITIONS†	TF4007A		TP4007A		UNIT	
		MIN	MAX	MIN	MAX		
I_{DD} or $-I_{SS}$ Quiescent supply current	$V_I = V_{DD}$ or 0 , No load	$T_A = \text{MIN}$ or 25°C	1		3		μA
		$T_A = \text{MAX}$	18		90		

† $T_A = \text{MIN}$ or MAX refers to the respective values of temperature specified under recommended operating conditions.

NOTE 1: All measurements are made with each pair of transistors connected to form an inverter.

TYPES TF4007A, TP4007A

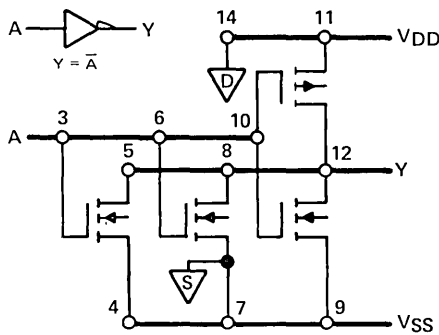
DUAL COMPLEMENTARY PAIRS PLUS INVERTERS

switching characteristics at 25°C free-air temperature (see note 1)

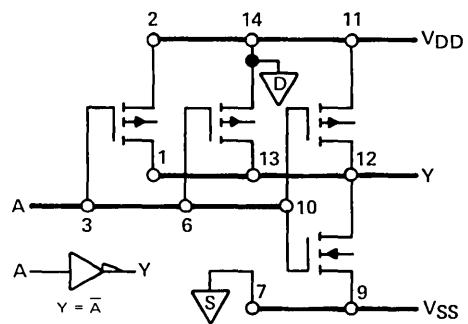
PARAMETER	TEST CONDITIONS	TF4007A		TP4007A		UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	
t _{pLH} Propagation delay time, low-to-high-level output	C _L = 50 pF §, R _L = 200 kΩ, See Note 2	110	90	135	125	ns
t _{pHL} Propagation delay time, high-to-low-level output		110	90	135	125	ns
t _{TLH} Transition time, low-to-high-level output		160	95	220	120	ns
t _{THL} Transition time, high-to-low-level output		160	95	220	120	ns

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4007A.
 NOTES: 1. All measurements are made with each pair of transistors connected to form an inverter.
 2. See load circuit and voltage waveforms on page 170.

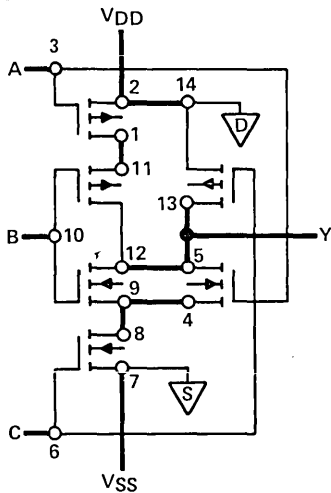
TYPICAL APPLICATION DATA



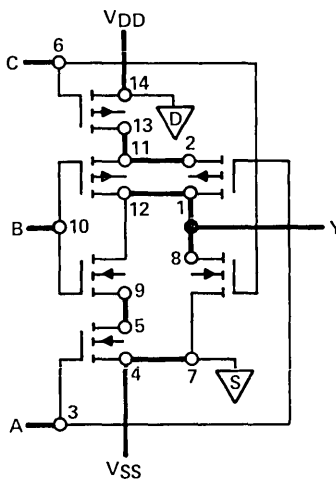
HIGH-SINK-CURRENT DRIVER



HIGH-SOURCE-CURRENT DRIVER

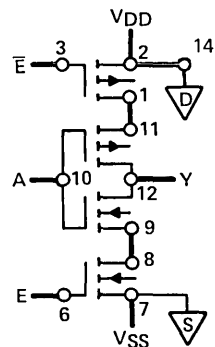


$$Y = \overline{AB} + \overline{C} = \overline{(A+B)C}$$



$$Y = (\overline{A+B})\overline{C} = \overline{AB + C}$$

AOI FUNCTIONS USING RELAY (TREE) LOGIC



FUNCTION TABLE

E	Ē	A	Y
H	L	H	L
H	L	L	H
L	H	X	Hi Z

Y = \overline{A} when E is high
 Y = hi Z when E is low

3-STATE BUFFER

CMOS LOGIC CIRCUITS

TYPES TF4008A, TP4008A FOUR-BIT FULL ADDERS

SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4008A
- High-Speed Operation
- Look-Ahead Carry Output

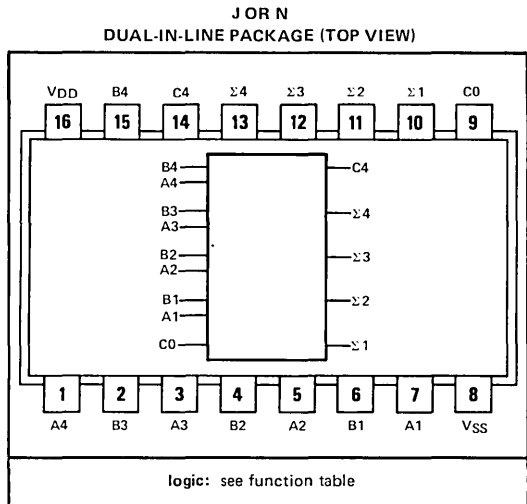
description

These full adders perform the addition of two 4-bit binary numbers. The sum (Σ) outputs are provided for each bit and the resultant carry (C4) is obtained from the fourth bit. The adders are designed so that logic levels of the input and output, including the carry, are in their true form. Thus the end-around carry is accomplished without the need for level inversion. These circuits feature full look ahead across four bits to achieve partial look-ahead performance with the economy of ripple carry.

**FUNCTION TABLE
(EACH BIT)**

INPUTS			OUTPUTS	
A _i	B _i	C _{i-1}	C _i	Σ_i
L	L	L	L	L
H	L	L	L	H
L	H	L	L	H
H	H	L	H	L
L	L	H	L	H
H	L	H	H	L
L	H	H	H	L
H	H	H	H	H

H = high level; L = low level;
i = bit number 1, 2, 3, or 4



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 3

switching characteristics at 25°C free-air temperature

PARAMETER‡	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4008A		TP4008A		UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	
t _{PLH}	A _i or B _i	Σ _i	C _L = 50 pF §, R _L = 200 kΩ, See Note 1	1000	350	1400	500	ns
t _{PHL}				1000	350	1400	500	
t _{PLH}	Any A or B	C4		750	300	1000	350	ns
t _{PHL}				750	300	1000	350	
t _{PLH}	C0	Any Σ		900	325	1200	400	ns
t _{PHL}				900	325	1200	400	
t _{PLH}	C0	C4		350	150	450	200	ns
t _{PHL}				350	150	450	200	
t _{TLH}		C4 or Any Σ		350	150	400	220	ns
t _{THL}				350	150	400	220	

‡t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

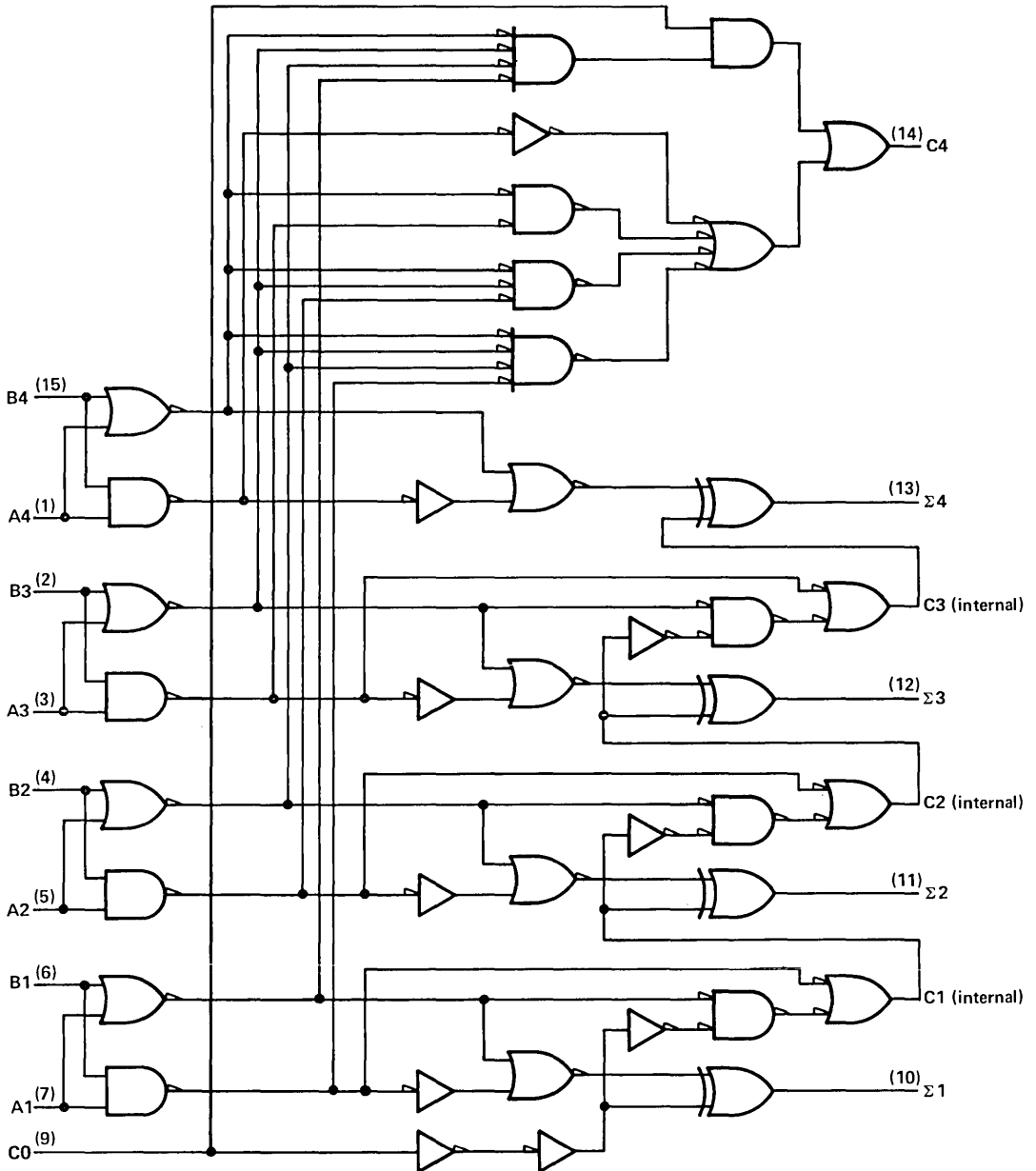
t_{THL} ≡ Transition time, high-to-low-level output

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4008A.

NOTE 1: See load circuit and voltage waveforms on page 170.

TYPES TF4008A, TP4008A FOUR-BIT FULL ADDERS

functional block diagram



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CMOS LOGIC CIRCUITS

TYPES TF4009A, TF4010A, TP4009A, TP4010A HEX INVERTING AND NONINVERTING BUFFERS/CONVERTERS

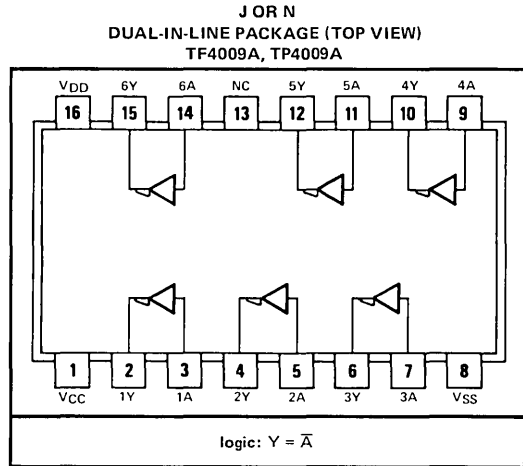
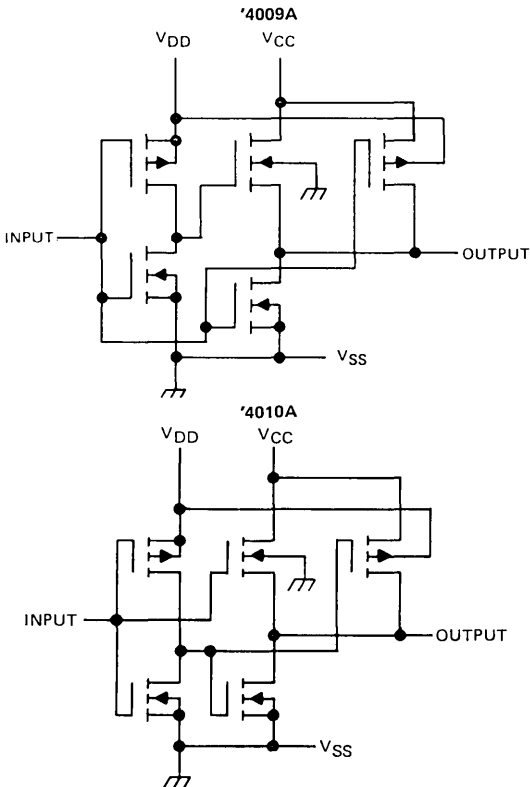
SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4009A and RCA CD4010A
- High Current Sinking Capability . . . 8 mA Minimum at $V_{OL} = 0.5 V$, $V_{DD} = 10 V$, $T_A = 25^\circ C$

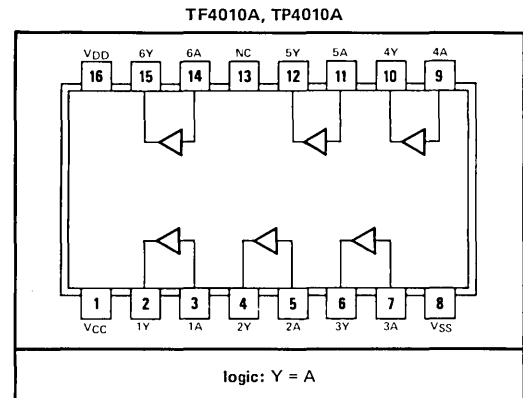
description

The '4009A and '4010A hex CMOS inverting and noninverting buffers may be used as current sinks for source drivers, hex CMOS drivers, or CMOS to DTL or TTL logic-level converters. Conversion ranges are from CMOS logic operating at supply levels of 3 volts to 15 volts to DTL or TTL operating at supply levels of 3 volts to 15 volts. Conversion to logic output levels greater than 6 volts is permitted provided that the V_{CC} supply voltage is not higher than the V_{DD} supply voltage (see Note 1).

schematic (each buffer)



NC—No internal connection



NC—No internal connection

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62 and below	Page 62	Page 63, Group 2, except as on following page

absolute maximum ratings over operating free-air temperature range

Supply voltage, V_{CC} (see Note 1)	V_{DD}
Minimum rise time of supply voltages	10 μs
Output load capacitance if V_{CC} exceeds 10.5 V	5000 pF

NOTE 1: If V_{CC} is allowed to exceed V_{DD} , the device may latch up and draw sufficient current to cause permanent damage.

TYPES TF4009A, TF4010A, TP4009A, TP4010A

HEX INVERTING AND NONINVERTING BUFFERS/CONVERTERS

electrical characteristics, $V_{CC} = V_{DD}$

*4009A only

PARAMETER	TEST CONDITIONS†	TF4009A		TP4009A		UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	
V_{IL} Low-level input voltage	$T_A = \text{MIN or } 25^\circ\text{C}$	1		2		V
	$T_A = \text{MAX}$	0.9		1.9		

*4009A and *4010A at $V_{DD} = 5\text{ V}$ and 10 V

PARAMETER	TEST CONDITIONS†	TF4009A, TF4010A		TP4009A, TP4010A		UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	
I_{OH} High-level output current	$V_{IH} = V_{DD}$, $V_{IL} = 0$, $V_O = V_{OH\text{ min}}$	$T_A = \text{MIN}$		-1.85		mA
	$T_A = 25^\circ\text{C}$		-0.9			
I_{OL} Low-level output current	$V_{IH} = V_{DD}$, $V_{IL} = 0$, $V_O = V_{OL\text{ max}}$	$T_A = \text{MAX}$		-1.25		mA
		$T_A = 25^\circ\text{C}$		-0.6		
		$T_A = \text{MIN}$		-1		
I_{DD} or Quiescent supply current $-I_{SS}$	$V_I = V_{DD}$ or 0 , No load	$T_A = \text{MIN or } 25^\circ\text{C}$		3		μA
		$T_A = 25^\circ\text{C}$		5		
		$T_A = \text{MAX}$		70		

*4009A and *4010A at $V_{DD} = 15\text{ V}$

PARAMETER	TEST CONDITIONS†	TF4009A, TF4010A		TP4009A, TP4010A		UNIT
		$V_{DD} = 15\text{ V}$		$V_{DD} = 15\text{ V}$		
		MIN	MAX	MIN	MAX	
I_{DD} or Quiescent supply current $-I_{SS}$	$V_I = V_{DD}$ or 0 , No load	$T_A = \text{MIN or } 25^\circ\text{C}$		15		μA
	$T_A = \text{MAX}$		210			

† $T_A = \text{MIN or MAX}$ refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4009A, TF4010A		TP4009A, TP4010A		UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	
t_{PLH} Propagation delay time, low-to-high-level output	$V_{CC} = V_{DD}$, $C_L = 50\text{ pF}$ §, $R_L = 200\text{ k}\Omega$, See Note 2	110		80		ns
t_{PHL} Propagation delay time, high-to-low-level output		100		55		
t_{TLH} Transition time, low-to-high-level output		270		220		ns
t_{THL} Transition time, high-to-low-level output		60		55		
t_{PLH} Propagation delay time, low-to-high-level output	$V_{CC} = \frac{1}{2} V_{DD}$, $C_L = 50\text{ pF}$ §, $R_L = 200\text{ k}\Omega$, See Note 2			45		ns
t_{PHL} Propagation delay time, high-to-low-level output				45		

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4009A and RCA CD 4010A respectively.

NOTE 2: See load circuit and voltage waveforms on page 170.

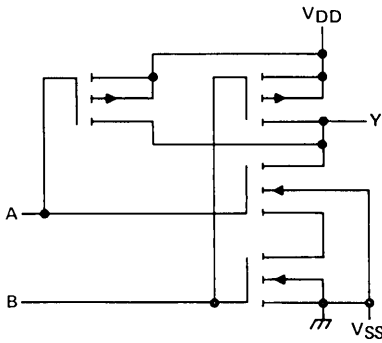
CMOS LOGIC CIRCUITS

TYPES TF4011A, TP4011A QUAD 2-INPUT NAND GATES

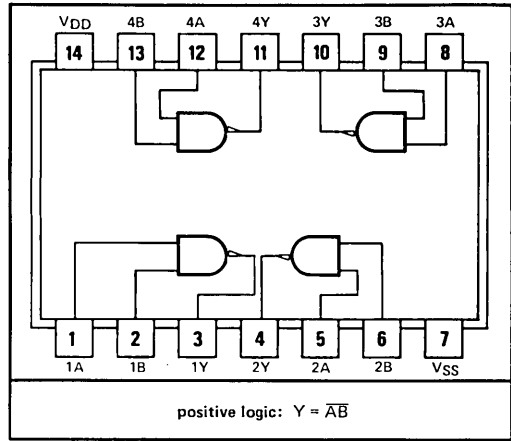
SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4011A

schematic (each gate)



J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, Group 1, except as below

electrical characteristics

PARAMETER	TEST CONDITIONS†	TF4011A		TP4011A		UNIT	
		V _{DD} = 10 V		V _{DD} = 10 V			
		MIN	MAX	MIN	MAX		
I _{OH} High-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OH} min	T _A = MIN	-0.65	-0.75	-0.35	-0.35	mA
	T _A = 25° C	-0.5	-0.6	-0.3	-0.3		
	T _A = MAX	-0.35	-0.4	-0.25	-0.25		
I _{OL} Low-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL} max	T _A = MIN	0.5	1.1	0.25	0.6	mA
	T _A = 25° C	0.4	0.9	0.2	0.5		
	T _A = MAX	0.3	0.65	0.16	0.4		

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4011A		TP4011A		UNIT
		V _{DD} = 10 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF §, R _L = 200 kΩ, See Note 1	150	100	200	130	ns
t _{PHL} Propagation delay time, high-to-low-level output		150	100	200	130	ns
t _{TLLH} Transition time, low-to-high-level output		350	175	450	300	ns
t _{TTHL} Transition time, high-to-low-level output		350	175	450	300	ns

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4011A.

NOTE 1: See load circuit and voltage waveforms on page 170.

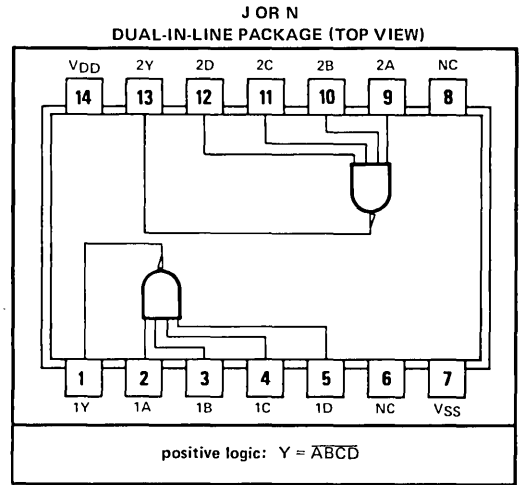
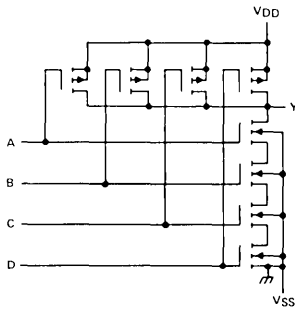
CMOS LOGIC CIRCUITS

TYPES TF4012A, TP4012A DUAL 4-INPUT NAND GATES

SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4012A

schematic (each gate)



NC—No internal connection

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, Group 1, except as below

electrical characteristics

PARAMETER	TEST CONDITIONS†	TF4012A		TP4012A		UNIT	
		V _{DD} = 5 V		V _{DD} = 10 V			
		MIN	MAX	MIN	MAX		MIN
I _{OL} Low-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL} max	T _A = MIN	0.5	1.1	0.25	0.6	mA
	T _A = 25°C	0.4	0.9	0.2	0.5		
	T _A = MAX	0.3	0.65	0.18	0.4		

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4012A		TP4012A		UNIT				
		V _{DD} = 5 V		V _{DD} = 10 V						
		MIN	MAX	MIN	MAX		MIN	MAX		
t _{pLH} Propagation delay time, low-to-high-level output	C _L = 50 pF §, R _L = 200 kΩ, See Note 1	150		80		200		110		ns
t _{pHL} Propagation delay time, high-to-low-level output		250		150		400		200		
t _{TLH} Transition time, low-to-high-level output		350		175		470		250		
t _{THL} Transition time, high-to-low-level output		500		300		670		400		

§ With a 15-pF load, these devices switch with times similar to those of the RCA CD4012A.

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4013A, TP4013A DUAL D-TYPE EDGE-TRIGGERED FLIP-FLOPS

SEPTEMBER 1975

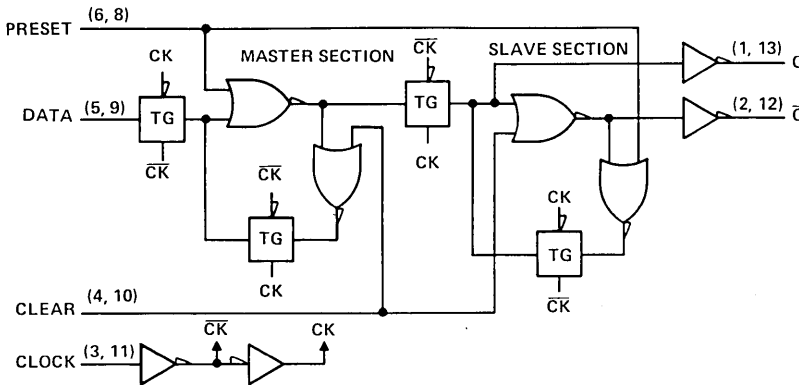
- Designed to be Interchangeable with RCA CD4013A
- Toggle Rate . . . 10 MHz Typical at $V_{DD} = 10\text{ V}$

description

These circuits are dual D-type transition-operated master-slave flip-flops with buffered outputs, independent direct overriding preset and clear inputs, and D and clock inputs. While the clock is low, the data at the D input is entered in the master section which is isolated from the slave section. On the rising transition of the clock, the D input is disabled and data previously set up in the master section is transferred to the slave section and appears in true form at the Q output.

Presetting and clearing are independent of the clock and are accomplished by a high-level voltage at the respective input. The \bar{Q} output is complementary to the Q output except for the nonstable situation that exists when both preset and clear inputs are simultaneously high.

functional block diagram (each flip-flop)



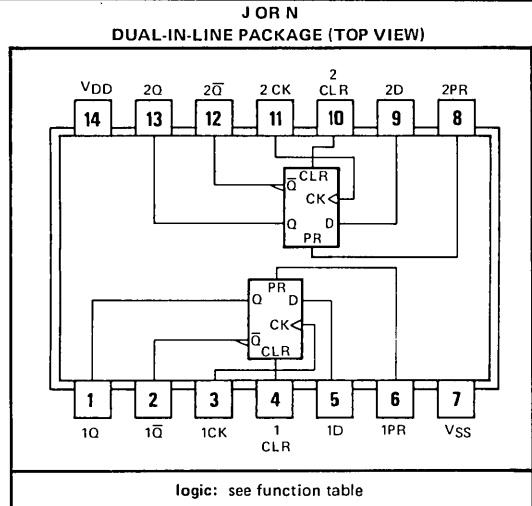
specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and on following page	Page 63, Group 2, except as on following page

FUNCTION TABLE
(EACH FLIP-FLOP)

INPUTS				OUTPUTS	
PRESET	CLEAR	CK	D	Q	\bar{Q}
H	L	X	X	H	L
L	H	X	X	L	H
H	H	X	X	H*	H*
L	L	↑	L	L	H
L	L	↑	H	H	L
L	L	L	X	Q_0	\bar{Q}_0

See explanation of function tables on pages 16 and 17.
*This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (low) level.



logic: see function table

TYPES TF4013A, TP4013A

DUAL D-TYPE EDGE-TRIGGERED FLIP-FLOPS

recommended operating conditions

		TF4013A				TP4013A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Pulse width, t _w (C _L = 50 pF)	Clock high or low	200		80		500		100		ns
	Preset or clear	250		100		500		125		
Setup time, t _{su}		40		20		50		25		ns

electrical characteristics

PARAMETER	TEST CONDITIONS†	TF4013A				TP4013A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
I _{OH} High-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OH} min	T _A = MIN	-0.65		-0.8		-0.35		-0.4	mA
		T _A = 25°C	-0.5		-0.65		-0.3		-0.35	
		T _A = MAX	-0.35		-0.45		-0.25		-0.3	
I _{OL} Low-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL} max	T _A = MIN	0.5		1.25		0.35		0.75	mA
		T _A = 25°C	0.4		1		0.3		0.6	
		T _A = MAX	0.3		0.75		0.25		0.5	

† T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER‡	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4013A				TP4013A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}			C _L = 50 pF§, R _L = 200 kΩ, See Note 1	2.5		7		1		5		MHz
t _{PLH} or t _{PHL}	Clock	Q or \bar{Q}		420		185		550		250		ns
t _{PLH} or t _{PHL}	Preset or Clear	Q or \bar{Q}		420		185		550		250		ns
t _{TLH} or t _{THL}		Any		235		130		300		175		ns

‡ f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

t_{THL} ≡ Transition time, high-to-low-level output

§ With a 15-pF load, these devices switch with times similar to those of the RCA CD4013A.

NOTE 1: See load circuit and voltage waveforms on page 170.

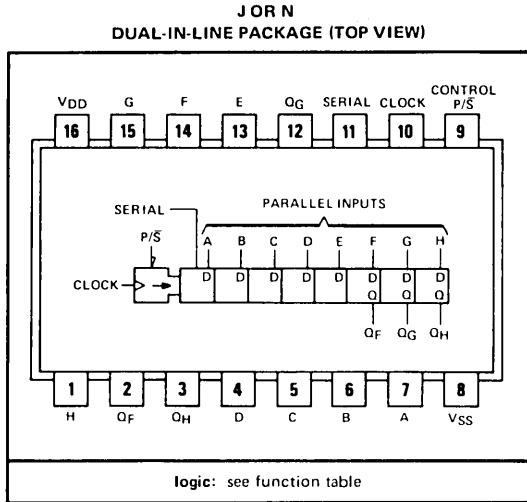
- Designed to be Interchangeable with RCA CD4014A
- Synchronous Parallel or Serial Input, Serial Output
- Parallel Outputs from Sixth, Seventh, and Eighth Bits
- Maximum Clock Frequency . . . 5 MHz
Typical at 10 V

description

These 8-bit synchronous registers have a single serial input and parallel-in access to each stage. D-type master-slave flip-flops are used for each stage with parallel access to the outputs of bits F, G, and H.

Both serial and parallel entry are made synchronously on the low-to-high transition of the clock input and under the control of the parallel-load/serial-shift input, P/S. When the P/S input is high, data is broadcast loaded into the register from the parallel inputs. When the P/S input is low, data is entered at the serial input and each bit shifts one bit position in the direction Q_A toward Q_H.

The TF4021A, and TP4021A are similar to these registers, except for having asynchronous parallel inputs.



specifications

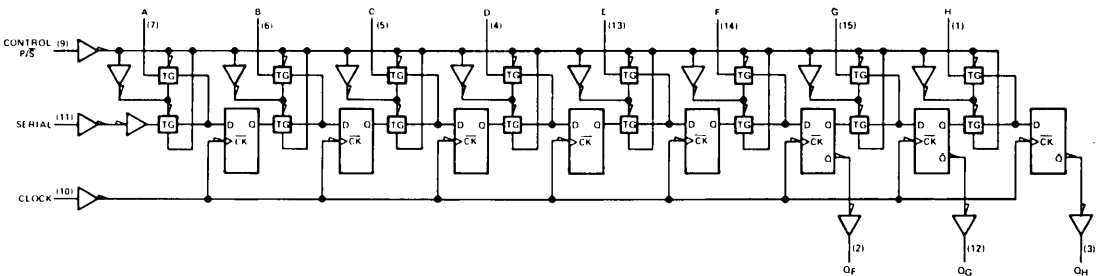
MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and on following page	Page 63, Group 3, except as on following page

FUNCTION TABLE

CONTROL P/S	INPUTS			INTERNAL OUTPUTS (2 of 5)		OUTPUTS		
	CLOCK	PARALLEL A-H	SERIAL	Q _A	Q _B	Q _F	Q _G	Q _H
H	↑	a-h	X	a	b	f	g	h
L	↑	X	H	H	Q _{An}	Q _{En}	Q _{Fn}	Q _{Gn}
L	↑	X	L	L	Q _{An}	Q _{En}	Q _{Fn}	Q _{Gn}
X	L	X	X	Q _{A0}	Q _{B0}	Q _{F0}	Q _{G0}	Q _{H0}

See explanation of function tables, pages 16 and 17.

functional block diagram



TYPES TF4014A, TP4014A

8-BIT STATIC SHIFT REGISTERS

recommended operating conditions

		TF4014A				TP4014A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Width of clock pulse, t _w (clock)	Clock high or low	500		175		830		200		ns
Setup time, t _{SU}		350		80		500		100		ns

electrical characteristics

PARAMETER		TEST CONDITIONS†		TF4014A				TP4014A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
I _{OH} High-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OH} min	T _A = MIN	-0.25		-0.25		-0.12		-0.12		mA	
		T _A = 25°C	-0.2		-0.2		-0.1		-0.1			
		T _A = MAX	-0.14		-0.14		-0.08		-0.08			
I _{OL} Low-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL} max	T _A = MIN	0.15		0.31		0.072		0.12		mA	
		T _A = 25°C	0.12		0.25		0.06		0.1			
		T _A = MAX	0.085		0.175		0.05		0.08			

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER		TEST CONDITIONS		TF4014A				TP4014A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max} Maximum clock frequency				1		3		0.6		2.5	MHz	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF §, R _L = 200 kΩ, See Note 1			975		300		1300		400	ns	
t _{PHL} Propagation delay time, high-to-low-level output				975		300		1300		400	ns	
t _{TLH} Transition time, low-to-high-level output				550		225		700		300	ns	
t _{THL} Transition time, high-to-low-level output				550		225		700		300	ns	

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4014A.

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4015A, TP4015A DUAL 4-BIT STATIC SHIFT REGISTERS

SEPTEMBER 1975

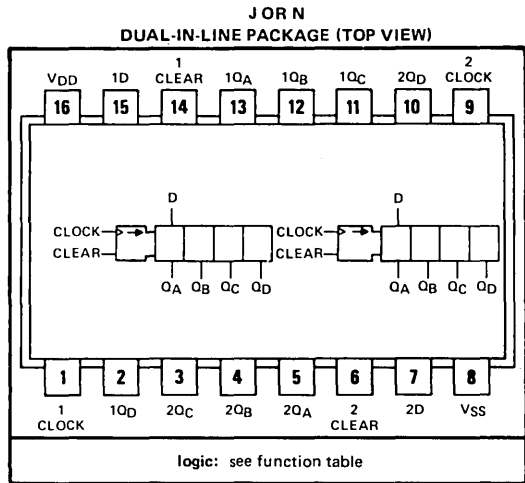
- Designed to be Interchangeable with RCA CD4015A
- Maximum Clock Frequency . . . 5 MHz
Typical at 10 V

description

These dual 4-bit static shift registers consist of two identical, independent, 4-stage serial-input, parallel-output registers. Each register has independent clock and clear inputs as well as a single serial data input. The register stages are D-type master-slave flip-flops with Q outputs available from each of the four bits on both registers. Data is shifted from one bit to the next during the low-to-high-level transition of the clock. A high level applied to the clear line sets all outputs of the associated register to the low level.

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and on following page	Page 63, group 3

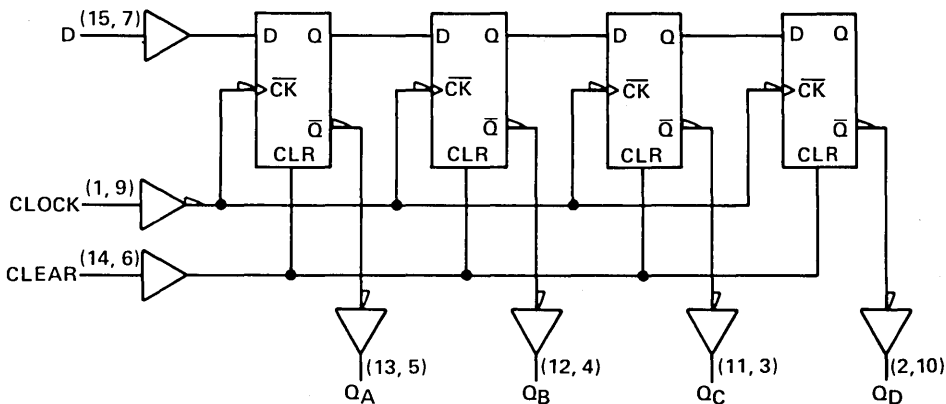


FUNCTION TABLE
(EACH REGISTER)

INPUTS			OUTPUTS			
CLEAR	CLOCK	D	Q _A	Q _B	Q _C	Q _D
H	X	X	L	L	L	L
L	↑	L	L	Q _{An}	Q _{Bn}	Q _{Cn}
L	↑	H	H	Q _{An}	Q _{Bn}	Q _{Cn}
L	L	X	Q _{A0}	Q _{B0}	Q _{C0}	Q _{D0}

See explanation of function tables on pages 16 and 17.

functional block diagram (each register)



TYPES TF4015A, TP4015A

DUAL 4-BIT STATIC SHIFT REGISTERS

recommended operating conditions

		TF4015A				TP4015A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Pulse width, t _w	Clock high or low	500		175		830		200		ns
	Clear	500		175		830		200		
Setup time, t _{su}		350		80		500		100		ns

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4015A				TP4015A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max} Maximum clock frequency	C _L = 50 pF [§] , R _L = 200 kΩ, See Note 1	1		3		0.6		2.5		MHz
t _{PLH} Propagation delay time, low-to-high-level output from clock		750		225		1000		300		ns
t _{PHL} Propagation delay time, high-to-low-level output from clock or clear		750		225		1000		300		
t _{TLH} Transition time, low-to-high-level output		350		150		400		220		ns
t _{THL} Transition time, high-to-low-level output		350		150		400		220		

[§]With a 15-pF load, these devices switch with times similar to those of the RCA CD4015A.
NOTE 1: See load circuit and voltage waveforms on page 170.

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CMOS LOGIC CIRCUITS

TYPES TF4016A, TP4016A QUAD BILATERAL SWITCHES

SEPTEMBER 1975

- Designed to be Interchangeable with Motorola MC14016A, Similar to RCA CD4016A (See TF4316A)
- Difference in r_{ON} between Switches in One Package Typically $10\ \Omega$ when $V_I = V_{SS}$ or V_{DD}
- High Degree of Linearity . . . $< 0.5\%$ Distortion Typical at 1 kHz
- Switches Can Transmit Signals in Either Direction at Frequencies of up to 50 MHz Typically
- Extremely Low Off-State Switch Current Resulting in Very High Effective Off-State Resistance . . . $10\ \text{pA}$ Typical at $V_{DD} - V_{SS} = 10\ \text{V}$
- Maximum Control Input Frequency . . . 10 MHz Typical at $V_{DD} = 10\ \text{V}$, $C_L = 15\ \text{pF}$, $R_L = 1\ \text{k}\Omega$
- High On/Off Output Voltage Ratio . . . 65 dB Typical
- Extremely High Control-Input Impedance (Control Circuit Isolated from Switch Circuit) . . . $10^{12}\ \Omega$ Typical
- Low Crosstalk Between Switches . . . 50 dB Typical at 0.9 MHz, $R_L = 1\ \text{k}\Omega$
- Control Input Current . . . $< 10\ \text{pA}$ Typical

description

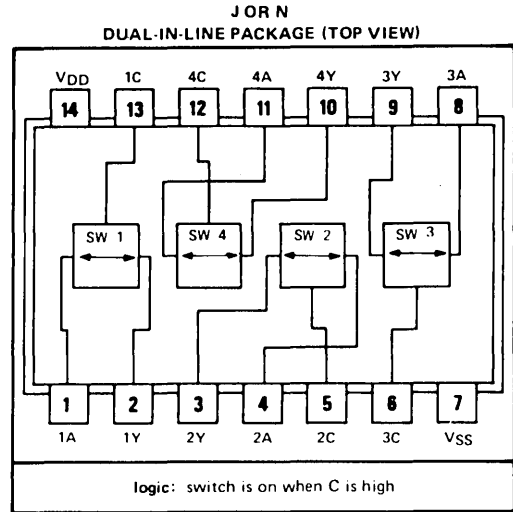
The '4016A is a quadruple bilateral switch constructed with P-channel and N-channel enhancement-type devices in a monolithic structure, and finds primary use where low power dissipation and/or high noise immunity is desired.

Applications include digital switching and multiplexing; analog-to-digital and digital-to-analog conversion; digital control of frequency, impedance, phase and analog-signal gain; signal gating; and use as a squelch control, chopper, modulator, demodulator, or commutating switch.

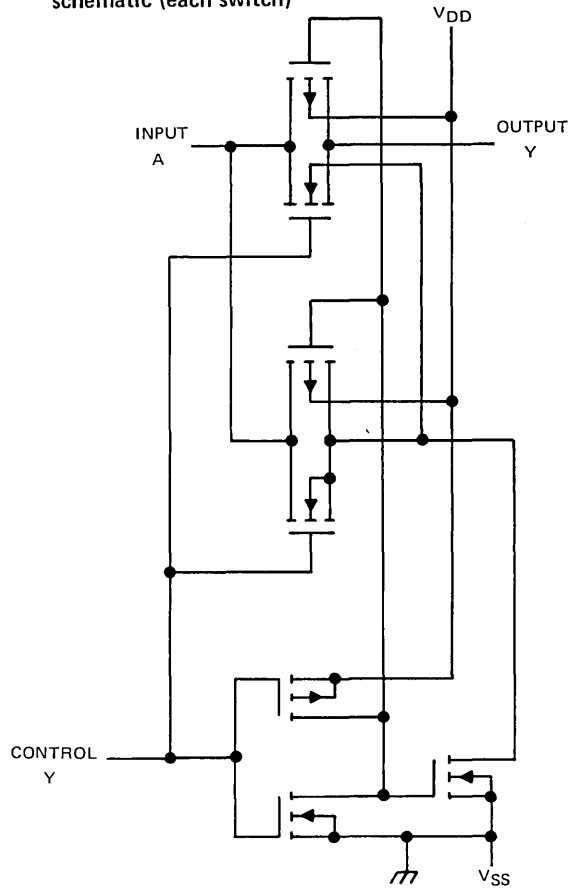
The P^- well of the analog transmission gate is connected to V_{SS} when the control input is low (gate off) and is switched to the analog input when the control input is high (gate on). This provides a more uniform on-state resistance with varying analog input voltages.

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	See the following page. Page 63 does not apply.



schematic (each switch)



TYPES TF4016A, TP4016A

QUAD BILATERAL SWITCHES

electrical characteristics over recommended operating free-air temperature range

$V_{DD} = 5\text{ V}$ and 10 V

PARAMETER	TEST CONDITIONS†	$V_{DD} = 5$		TF4016A		TP4016A		UNIT
		$V_{DD} = 10\text{ V}$		MIN	MAX	MIN	MAX	
		MIN	MAX					
V_{IH} High-level control input voltage		3		4		4		V
V_{IL} Low-level control input voltage			0.9		0.9		0.9	V
V_{OH} High-level output voltage	A at 0 V, C at V_{IL} max, $I_O = 10\ \mu\text{A}$	4.5		9		9		V
V_{OL} Low-level output voltage	A at 0 V, C at V_{IH} min, $I_O = 10\ \mu\text{A}$		0.5		1		1	V
Input-to-output off-state current	A at 0 V to V_{DD} , Y at 5 V, C at 0 V, $T_A = 25^\circ\text{C}$				± 125		± 125	nA
Total Quiescent Current ††	A at 0 V to V_{DD} , Y at 0 V to V_{DD} , C at 0 V, $T_A = \text{MIN or } 25^\circ\text{C}$				1		1	μA
	A = Y = 0 V to V_{DD} , C at V_{DD} , $T_A = \text{MAX}$				60		16	μA
	A = Y = 0 V to V_{DD} , C at V_{DD} , $T_A = \text{MIN or } 25^\circ\text{C}$				1		1	μA
	A = Y = 0 V to V_{DD} , C at V_{DD} , $T_A = \text{MAX}$				60		16	μA

$V_{DD} = 15\text{ V}$

PARAMETER	TEST CONDITIONS†	TF4016A		TP4016A		UNIT
		MIN	MAX	MIN	MAX	
I_I Input current	$V_I = 0$ or V_{DD}		± 1		± 1	μA
I_{DD} or Quiescent supply current $-I_{SS}$	$V_I = V_{DD}$ or 0, $T_A = \text{MIN or } 25^\circ\text{C}$		3		3	μA
	No load, $T_A = \text{MAX}$		180		48	μA

† $T_A = \text{MIN or MAX}$ refers to the respective values of free-air temperature specified under recommended operating conditions.

†† This is the total of supply current, control input current, and input-to-output off-state current.

on-state resistance at specified free-air temperature, C at V_{DD} , $R_L = 10\text{ k}\Omega$ to 0 V

TEST CONDITIONS			TF4016A		TP4016A		UNIT
			MIN	MAX	MIN	MAX	
$V_{DD} = 5\text{ V}$, A at 5, 0.25, -0.25 or -5 V	$V_{SS} = -5\text{ V}$,	$T_A = \text{MIN}$		600		610	Ω
		$T_A = 25^\circ\text{C}$		660		660	
		$T_A = \text{MAX}$		960		840	
$V_{DD} = 7.5\text{ V}$, A at 7.5, 0.25, -0.25, or -7.5 V	$V_{SS} = -7.5\text{ V}$,	$T_A = \text{MIN}$		360		370	Ω
		$T_A = 25^\circ\text{C}$		400		400	
		$T_A = \text{MAX}$		600		520	
$V_{DD} = 10\text{ V}$, A at 10, 5.6, or 0.25 V	$V_{SS} = 0\text{ V}$,	$T_A = \text{MIN}$		600		610	Ω
		$T_A = 25^\circ\text{C}$		660		660	
		$T_A = \text{MAX}$		960		840	
$V_{DD} = 15\text{ V}$, A at 15, 9.3, or 0.25 V	$V_{SS} = 0\text{ V}$,	$T_A = \text{MIN}$		360		370	Ω
		$T_A = 25^\circ\text{C}$		400		400	
		$T_A = \text{MAX}$		600		520	

TYPES TF4016A, TP4016A QUAD BILATERAL SWITCHES

switching characteristics at 25°C free-air temperature

PARAMETER‡	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4016A		TP4016A		UNIT
				V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 5 V	V _{DD} = 10 V	
				MIN	MAX	MIN	MAX	
t _{PLH}	A	Y	R _L = 10 kΩ, C _L = 50 pF§, C at V _{DD} , See Figure 1	85	45	125	70	ns
t _{PHL}	A	Y		85	45	125	70	
t _{PLH}	C	Y	C _L = 50 pF§, R _L = 10 kΩ to 0 V	150	75	225	115	ns
t _{PHL}	C	Y	See Figure 2, R _L = 10 kΩ to V _{DD}	150	75	225	115	

‡t_{PLH} = Propagation delay time, low-to-high-level output

t_{PHL} = Propagation delay time, high-to-low-level output

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4016A.

PARAMETER MEASUREMENT INFORMATION

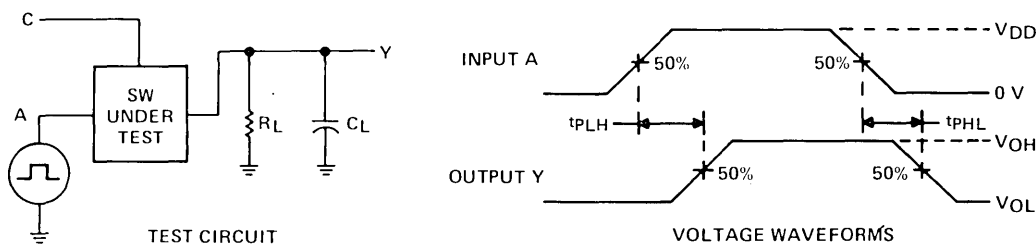


FIGURE 1—PROPAGATION DELAY TIME, SWITCH INPUT A TO OUTPUT Y

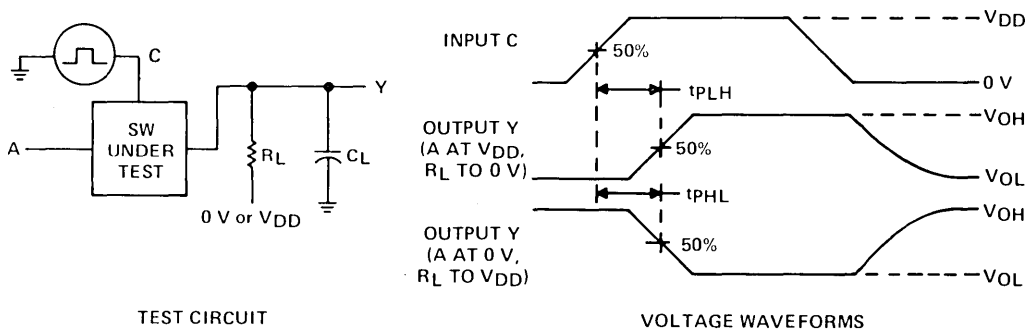


FIGURE 2—PROPAGATION DELAY TIMES, CONTROL INPUT C TO OUTPUT Y

- NOTES: A. Input pulses are supplied by generators having the following characteristics: Z_{out} = 50 Ω, PRR = 10 kHz, t_r ≤ 20 ns, t_f ≤ 20 ns.
 B. C_L includes probe and jig capacitance.
 C. The waveforms are monitored on an oscilloscope with the following characteristics: t_r ≤ 10 ns, R_{in} ≥ 1 MΩ.

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TEXAS INSTRUMENTS
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- Designed to be Interchangeable with RCA CD4017A
- Medium-Speed Operation . . . 5 MHz
Typical Maximum Clock Frequency at $V_{DD} = 10\text{ V}$
- Fully Static Operation
- Carry Output for Cascading

description

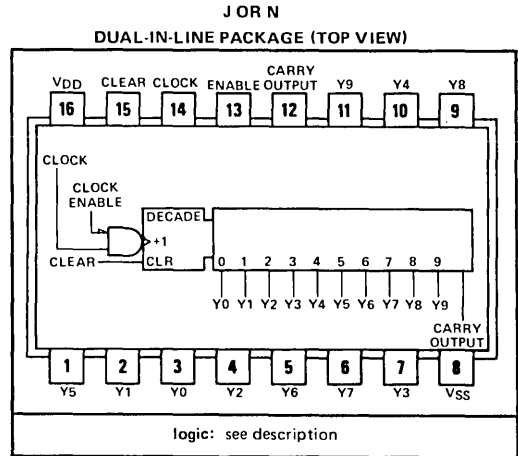
The '4017A is a five-stage Johnson decade counter and an output decoder that converts the Johnson binary code to a decimal number. High-speed operation and spike-free outputs are obtained by use of the Johnson decade counter configuration.

The ten decoded outputs are normally low and go high only at their respective decimal time period. A high clear signal asynchronously clears the decade counter and sets the carry output and Y_0 high. With enable low, the count is advanced on a low-to-high transition at the clock input. Alternatively if the clock input is high, the count is advanced on a high-to-low transition at enable. The carry output is high while $Y_0, Y_1, Y_2, Y_3,$ or Y_4 is high, then is low while $Y_5, Y_6, Y_7, Y_8,$ or Y_9 is high.

This device can be used in frequency-division applications as well as decade-counter or decimal-decode display applications.

recommended operating conditions

		TF4017A				TP4017A				UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Pulse width, t_w	Clock high or low	500	170	830	250	ns				
	Clear	500	170	830	250	ns				
Setup time, t_{su}	Enable	500	200	700	300	ns				
	Clear inactive state	750	225	1000	275	ns				



logic: see description

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and below	Page 63, Group 3, except as on following page

TYPES TF4017A, TP4017A DECADE COUNTERS/DIVIDERS

electrical characteristics

PARAMETER		TEST CONDITIONS†		TF4017A				TP4017A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
I _{OH}	High-level output-current	Y outputs	V _{IH} = V _{DD} , V _O = V _{OH} min V _{IL} = 0,	T _A = MIN	-120	-120	-85	-85	μA			
				T _A = 25°C	-100	-100	-70	-70				
				T _A = MAX	-70	-70	-55	-55				
	Carry output	T _A = MIN		-450	-450	-300	-300	μA				
		T _A = 25°C		-350	-350	-240	-240					
		T _A = MAX		-250	-250	-200	-200					
I _{OL}	Low-level output current	Y outputs	V _{IH} = V _{DD} , V _O = V _{OL} max V _{IL} = 0,	T _A = MIN	60	120	30		85	μA		
				T _A = 25°C	50	100	25		70			
				T _A = MAX	35	70	20		55			
	Carry output	T _A = MIN		185	450	95	300	μA				
		T _A = 25°C		150	350	80	250					
		T _A = MAX		105	250	65	200					

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER‡	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4017A				TP4017A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}			C _L = 50 pF§, R _L = 200 kΩ, See Note 1	1		3		0.6		2		MHz
t _{PLH}	Clock or clear	Any Y output		2000		600		2500		750		ns
t _{PHL}				2000		600		2500		750		
t _{PLH}	Clock or clear	Carry output		1300		400		1600		500		ns
t _{PHL}				1300		400		1600		500		
t _{TLH}		Any Y output		1800		700		2400		900		ns
t _{THL}				1800		700		2400		900		
t _{TLLH}		Carry output		600		300		700		400		ns
t _{THL}				600		300		700		400		

‡f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

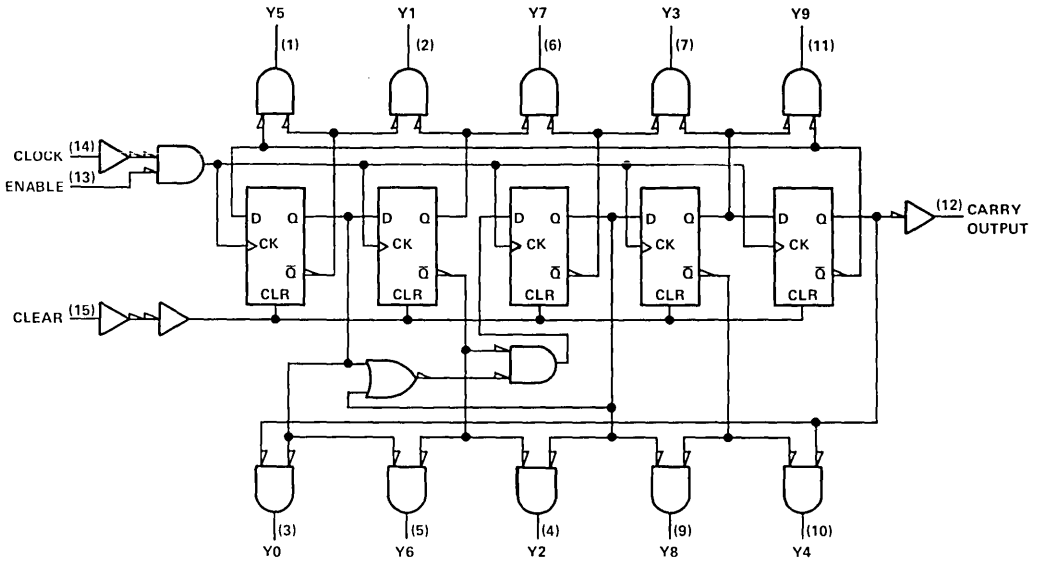
t_{THL} ≡ Transition time, high-to-low-level output

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4017A.

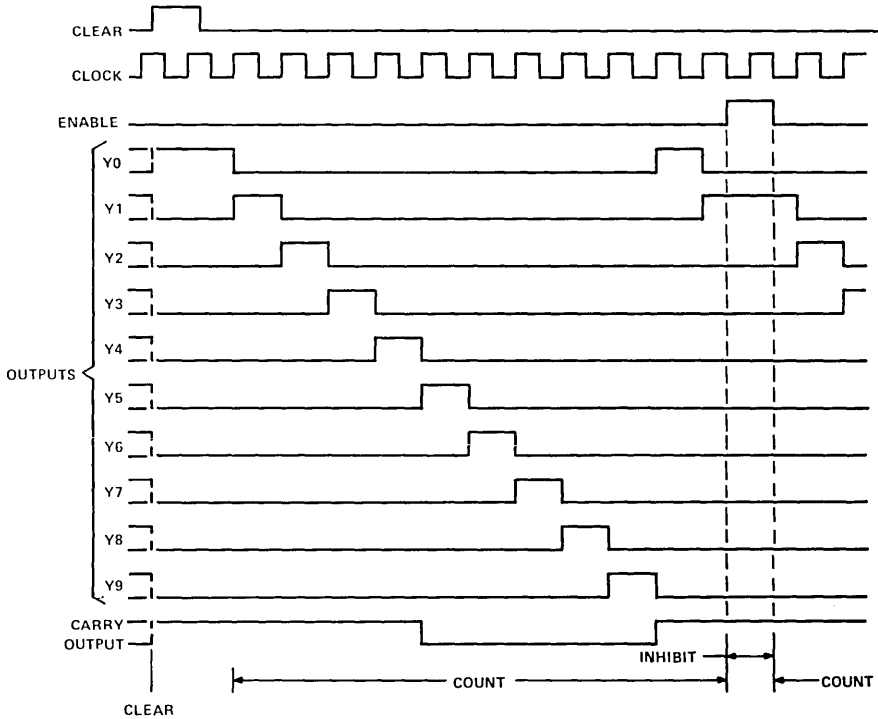
NOTE 1: See load circuit and voltage waveforms on page 170.

TYPES TF4017A, TP4017A DECADE COUNTERS/DIVIDERS

functional block diagram



typical clear, count, and inhibit sequences



CMOS LOGIC CIRCUITS

TYPES TF4018A, TP4018A PRESETTABLE DIVIDE-BY-N COUNTERS

SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4018A
- Maximum Clock Frequency . . . 5 MHz
Typical at $V_{DD} = 10\text{ V}$

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and below	Page 63, group 3

description

The '4018A consist of five Johnson counters, buffered \bar{Q} outputs from each stage, and preset control gating. Clear, preset enable, clock, feedback, and five parallel load inputs are provided.

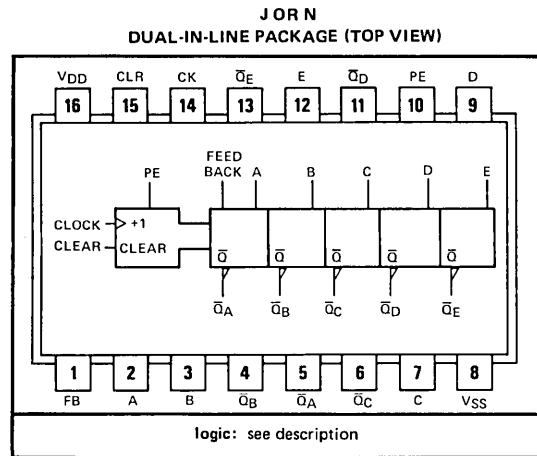
A high clear signal asynchronously clears the counter so that all \bar{Q} outputs are high. A high preset enable signal asynchronously loads the counter and the \bar{Q} outputs will take on the complements of the parallel inputs. The counter is advanced one count on the low-to-high transition of the clock input.

Various counter configurations may be implemented as follows:

Divide by	Connect These Outputs to Feedback Input	Via	Results from Each \bar{Q} Output (See Timing Diagram)
10	\bar{Q}_E	direct	5 counts high, 5 counts low
9	\bar{Q}_D, \bar{Q}_E	AND gate	5 counts high, 4 counts low
8	\bar{Q}_D	direct	4 counts high, 4 counts low
7	\bar{Q}_C, \bar{Q}_D	AND gate	4 counts high, 3 counts low
6	\bar{Q}_C	direct	3 counts high, 3 counts low
5	\bar{Q}_B, \bar{Q}_C	AND gate	3 counts high, 2 counts low
4	\bar{Q}_B	direct	2 counts high, 2 counts low
3	\bar{Q}_A, \bar{Q}_B	AND gate	2 counts high, 1 count low
2	\bar{Q}_A	direct	1 count high, 1 count low

recommended operating conditions

		TF4018A				TP4018A				UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Pulse width, t_w	Clock high or low	500		170		830		250		ns
	Clear or preset enable	500		170		830		250		ns
Setup time, t_{su}	Feedback	500		200		700		300		
	Clear or preset enable inactive state	750		225		1000		275		ns



TYPES TF4018A, TP4018A PRESETTABLE DIVIDE-BY-N COUNTERS

switching characteristics at 25°C free-air temperature

PARAMETER†	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4018A				TP4018A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}			C _L = 50 pF‡, R _L = 200 kΩ, See Note 1	1		3		0.6		2		MHz
t _{PLH} or t _{PHL}	Clock, clear, preset enable	$\bar{Q}_A, \bar{Q}_B, \bar{Q}_C, \bar{Q}_D$		1375		475		1800		610		ns
t _{PLH} or t _{PHL}		\bar{Q}_E		1175		325		1500		410		ns
t _{TLH} or t _{THL}		Any		350		150		400		225		ns

†f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

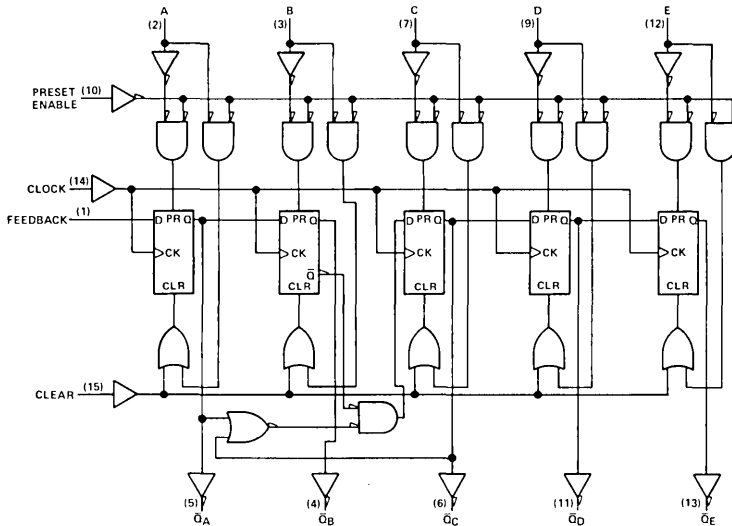
t_{TLH} ≡ Transition time, low-to-high-level output

t_{THL} ≡ Transition time, high-to-low-level output

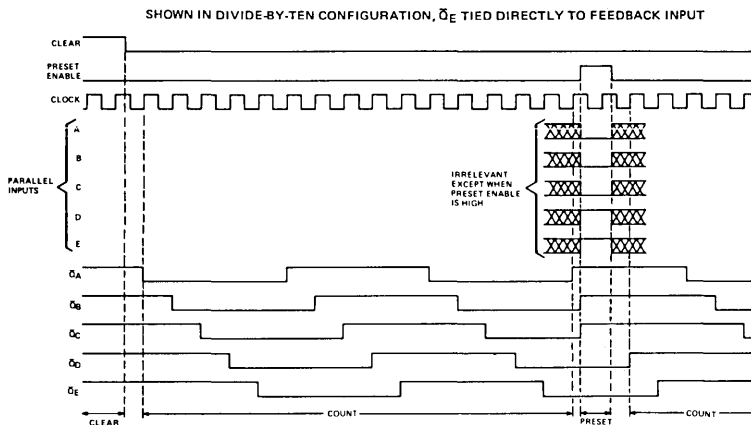
‡With a 15-pF load, these devices switch with times similar to those of the RCA CD4018A

NOTE 1: See load circuit and voltage waveforms on page 170.

functional block diagram



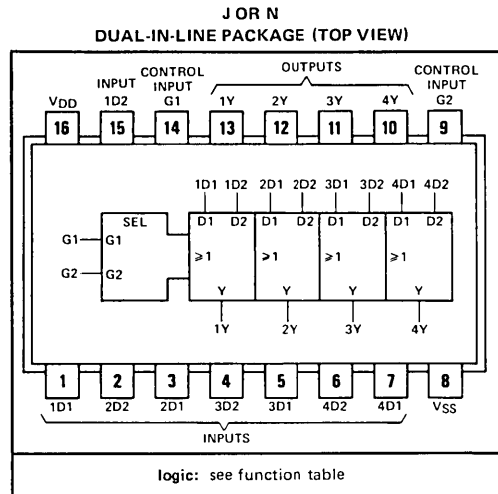
typical clear, count, and preset sequence



- Designed to be Interchangeable with RCA CD4019A

description

These devices consist of four AND-OR select gate configurations, each with two two-input AND gates driving a single two-input OR gate. Selection is determined by control inputs G1 and G2.



specifications

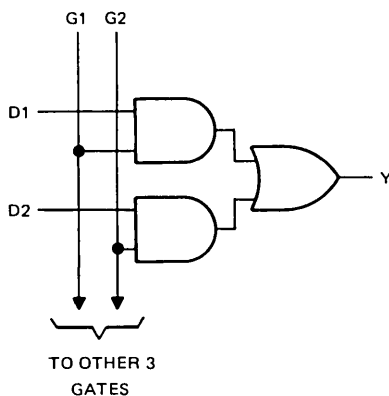
MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 2, except as on following page

**FUNCTION TABLE
(EACH GATE)**

INPUTS				OUTPUT Y
CONTROL		DATA		
G1	G2	D1	D2	
L	L	X	X	L
H	L	H	X	H
H	L	L	X	L
L	H	X	H	H
L	H	X	L	L
H	H	H	X	H
H	H	X	H	H
H	H	L	L	L

H = high level, L = low level, X = irrelevant

functional block diagram (each gate)



TYPES TF4019A, TP4019A QUAD AND-OR SELECT GATES

electrical characteristics

$V_{DD} = 5\text{ V}$ and 10 V

PARAMETER	TEST CONDITIONS†		TF4019A		TP4019A		UNIT
			$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
			MIN	MAX	MIN	MAX	
I_{OH} High-level output current	$V_{IH} = V_{DD}$, $V_{IL} = 0$, $V_O = V_{OH\text{ min}}$	$T_A = \text{MIN}$	-0.95	-0.95	-0.6	-0.6	mA
		$T_A = 25^\circ\text{C}$	-0.7	-0.7	-0.5	-0.5	
		$T_A = \text{MAX}$	-0.5	-0.5	-0.4	-0.4	
I_{OL} Low-level output current	$V_{IH} = V_{DD}$, $V_{IL} = 0$, $V_O = V_{OL\text{ max}}$	$T_A = \text{MIN}$	0.6	0.9	0.37	0.8	mA
		$T_A = 25^\circ\text{C}$	0.45	0.75	0.3	0.65	
		$T_A = \text{MAX}$	0.3	0.55	0.23	0.5	
I_{DD} or $-I_{SS}$ Quiescent supply current	$V_I = V_{DD}$ or 0, No load	$T_A = \text{MIN}$ or 25°C	5	10	50	100	μA
		$T_A = \text{MAX}$	300	600	700	1400	

$V_{DD} = 15\text{ V}$

PARAMETER	TEST CONDITIONS†		TF4019A		TP4019A		UNIT
			MIN	MAX	MIN	MAX	
I_{DD} or $-I_{SS}$ Quiescent supply current	$V_I = V_{DD}$ or 0, No load	$T_A = \text{MIN}$ or 25°C		30		300	μA
		$T_A = \text{MAX}$		1800		4200	

† $T_A = \text{MIN}$ or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4019A		TP4019A		UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	
t_{PLH} Propagation delay time, low-to-high-level output	$C_L = 50\text{ pF}$ §, $R_L = 200\text{ k}\Omega$, See Note 1	375	170	500	220	ns
t_{PHL} Propagation delay time, high-to-low-level output		375	170	500	220	ns
t_{TLH} Transition time, low-to-high-level output		350	130	475	165	ns
t_{THL} Transition time, high-to-low-level output		350	130	475	165	ns

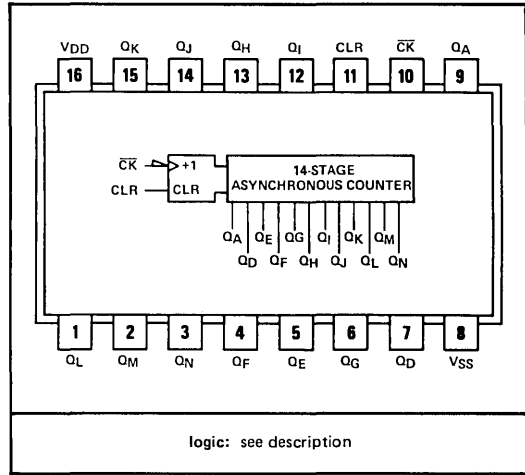
§ With a 15-pF load, these devices switch with times similar to those of the RCA CD4019A.
NOTE 1: See load circuit and voltage waveforms on page 170.

- Designed to be Interchangeable with RCA CD4020A
- Maximum Clock Frequency . . . 7 MHz Typical at 10 V

description

The '4020A is an asynchronous 14-stage binary counter designed with an input pulse-shaping circuit. The outputs of all stages except Q_B and Q_C are externally available. A high clear signal asynchronously clears the counter and resets all outputs low. The count is advanced on the high-to-low transition of the clock pulse. Applications include time-delay circuits, counter controls, and frequency-dividing circuits.

J O R N
DUAL-IN-LINE PACKAGE (TOP VIEW)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and below	Page 63, group 3

recommended operating conditions

		TF4020A		TP4020A		UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	
Pulse width, t_w	Clock high or low	335	125	500	165	ns
	Clear	2500	475	3000	550	ns

switching characteristics at 25°C free-air temperature

PARAMETER‡	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4020A		TP4020A		UNIT
				$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
				MIN	MAX	MIN	MAX	
f_{max}			$C_L = 50\text{ pF} §$, $R_L = 200\text{ k}\Omega$, See Note 1	1.5	4	1	3	MHz
t_{PLH} or t_{PHL}	Clock	Q_A		775	300	850	350	ns
t_{PLH} or t_{PHL}	Clock	Q_N		5600	2000	8400	3000	ns
t_{PHL}	Clear	Any		3200	850	3700	1000	ns
t_{TLH} or t_{THL}		Any		350	150	400	225	ns

‡ f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

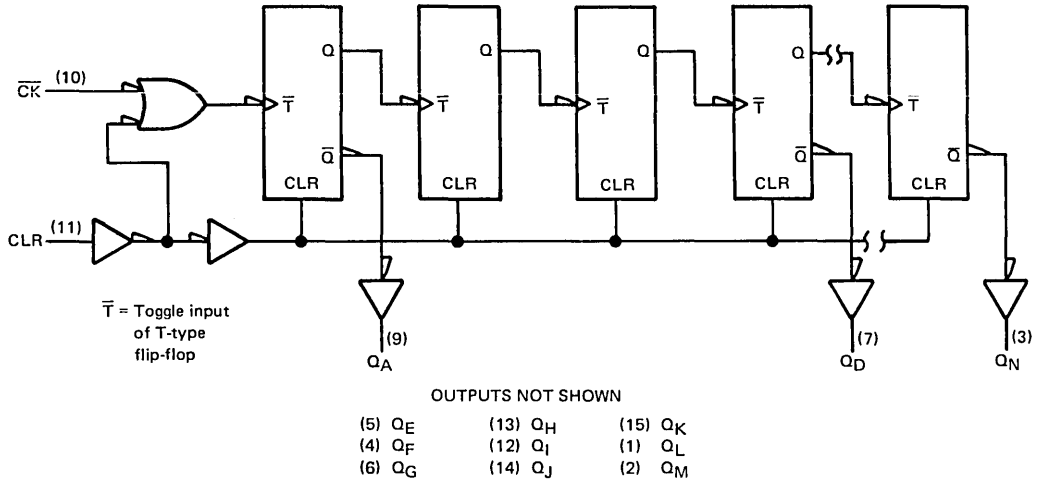
t_{THL} ≡ Transition time, high-to-low-level output

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4020A.

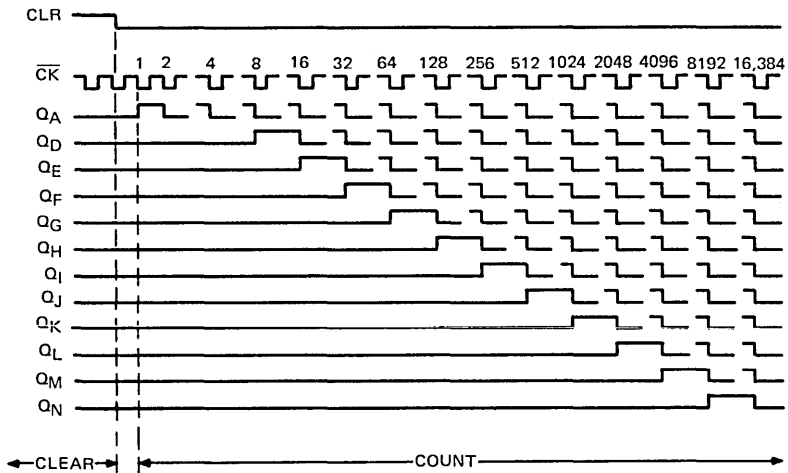
NOTE 1: See load circuit and voltage waveforms on page 170.

TYPES TF4020A, TP4020A 14-BIT BINARY COUNTERS

functional block diagram



typical clear and count sequence



CMOS LOGIC CIRCUITS

TYPES TF4021A, TP4021A 8-BIT STATIC SHIFT REGISTERS

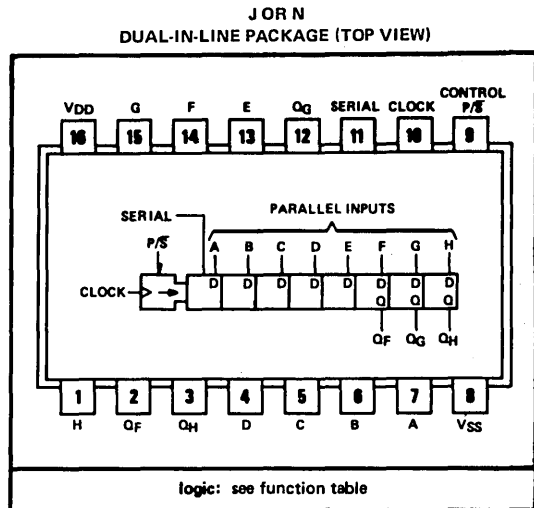
SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4021A
 - Asynchronous Parallel or Synchronous Serial Input, Serial Output
 - Parallel Outputs from Sixth, Seventh, and Eighth Bits
 - Maximum Clock Frequency . . . 5 MHz
Typical at 10 V
- description

These 8-bit registers have a single serial input and parallel-in access to each stage. D-type master-slave flip-flops are used for each stage with parallel access to the outputs of bits F, G, and H.

When the parallel-load/serial-shift input, P/\bar{S} , is high, data is broadcast loaded into the register from the parallel inputs independently of the clock. When the P/\bar{S} input is low, data is synchronously entered at the serial input and each bit shifts one bit position in the direction Q_A toward Q_H . Serial operations occur on the low-to-high transition of the clock input.

The TF4014A and TP4014A are similar to these registers, except for having synchronous parallel inputs.



specifications

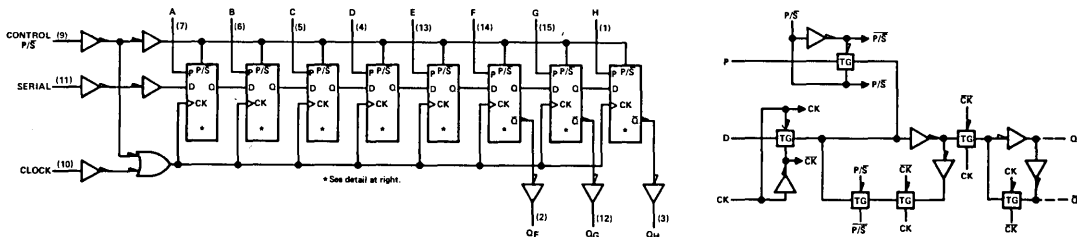
MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and on following page	Page 63, group 3, except as on following page

FUNCTION TABLE

INPUTS				INTERNAL OUTPUTS (2 OF 5)		OUTPUTS		
CONTROL P/\bar{S}	CLOCK	PARALLEL A-H	SERIAL	Q_A	Q_B	Q_F	Q_G	Q_H
H	X	a-h	X	a	b	f	g	h
L	\uparrow	X	H	H	Q_{An}	Q_{En}	Q_{Fn}	Q_{Gn}
L	\uparrow	X	L	L	Q_{An}	Q_{En}	Q_{Fn}	Q_{Gn}
L	L	X	X	Q_{A0}	Q_{B0}	Q_{F0}	Q_{G0}	Q_{H0}

See explanation of function tables, pages 16 and 17.

functional block diagram



DETAIL OF EACH STAGE

TYPES TF4021A, TP4021A

8-BIT STATIC SHIFT REGISTERS

recommended operating conditions

		TF4021A				TP4021A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Pulse width, t _w	Clock high or low	500		175		830		200		ns
	P/S high	500		175		830		200		ns
Setup time, t _{su}		350		80		500		100		ns

electrical characteristics

PARAMETER		TEST CONDITIONS†		TF4021A				TP4021A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
I _{OH} High-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OH} min	T _A = MIN		-0.25		-0.25		-0.12		-0.12	mA	
			T _A = 25°C	-0.2		-0.2		-0.1		-0.1		
			T _A = MAX	-0.14		-0.14		-0.08		-0.08		
I _{OL} Low-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL} max	T _A = MIN		0.15		0.31		0.072		0.12	mA	
			T _A = 25°C	0.12		0.25		0.06		0.1		
			T _A = MAX	0.085		0.175		0.05		0.08		

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER		TEST CONDITIONS	TF4021A				TP4021A				UNIT
			V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max} Maximum clock frequency			1		3		0.6		2.5	MHz	
t _{PLH} Propagation delay time, low-to-high-level output		C _L = 50 pF §, R _L = 200 kΩ, See Note 1		975		300		1300		400	ns
t _{PHL} Propagation delay time, high-to-low-level output				975		300		1300		400	ns
t _{TLH} Transition time, low-to-high-level output				550		225		700		300	ns
t _{THL} Transition time, high-to-low-level output				550		225		700		300	ns

§ With a 15-pF load, these devices switch with times similar to those of the RCA CD4014A.

NOTE 1: See load circuit and voltage waveforms on page 170.

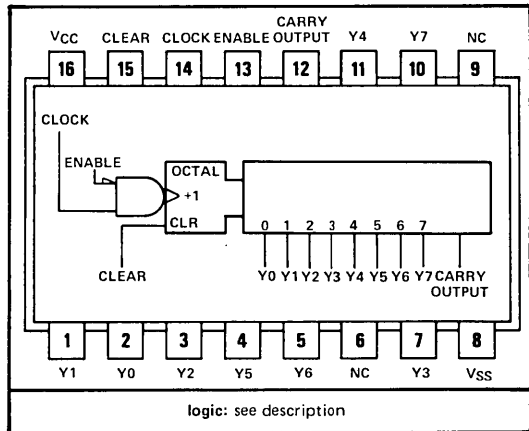
- Designed to be Interchangeable with RCA CD4022A
- Medium-Speed Operation . . . 5 MHz
Typical Maximum Clock Frequency at $V_{DD} = 10\text{ V}$
- Fully Static Operation
- Carry Output for Cascading

description

The '4022A is a four-stage divide-by-8 Johnson counter with built-in code converter. High-speed operation and spike-free outputs are obtained by use of the Johnson octal counter configuration.

The eight decoded outputs are normally low and go high only at their respective octal time period. A high clear signal asynchronously clears the octal counter and sets the carry output and Y0 high. With enable low, the count is advanced on a low-to-high transition at the clock input. Alternatively, if the clock input is high, the count is advanced on a high-to-low transition at enable. The carry output is high while Y0, Y1, Y2, or Y3 is high, then is low while Y4, Y5, Y6, or Y7 is high.

J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



NC—No internal connection

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and below	Page 63, group 3, except as on following page

recommended operating conditions

		TF4022A		TP4022A		UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	
Pulse width, t_w	Clock high or low	500	170	830	250	ns
	Clear	500	170	830	250	ns
Setup time, t_{su}	Enable	350	150	700	300	ns
	Clear inactive state	500	200	750	275	ns

TYPES TF4022A, TP4022A

OCTAL COUNTERS/DIVIDERS

electrical characteristics

PARAMETER		TEST CONDITIONS†		TF4022A				TP4022A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
I _{OH}	High-level output-current	Y outputs	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OH} min	T _A = MIN	-120	-120	-85	-85	μA			
				T _A = 25°C	-100	-100	-70	-70				
	Carry output	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OH} min		T _A = MAX	-70	-70	-55	-55	μA			
				T _A = MIN	-450	-450	-300	-300				
T _A = 25°C	-350		-350	-240	-240	μA						
T _A = MAX	-250		-250	-200	-200							
I _{OL}	Low-level output current	Y outputs	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL} max	T _A = MIN	60	120	30	85	μA			
				T _A = 25°C	50	100	25	70				
	Carry output	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL} max		T _A = MAX	35	70	20	55	μA			
				T _A = MIN	185	450	95	300				
T _A = 25°C	150		350	80	250	μA						
T _A = MAX	105		250	65	200							

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER‡	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4022A				TP4022A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}				1		3		0.6		2	MHz	
t _{PLH}	Clock or clear	Any A output	C _L = 50 pF §, R _L = 200 kΩ, See Note 1	2000		600		2500		750	ns	
t _{PHL}				2000		600		2500		750		
t _{PLH}	Clock or clear	Carry output		1300		400		1600		500	ns	
t _{PHL}				1300		400		1600		500		
t _{TLH}		Any Y		1800		700		2400		900	ns	
t _{THL}				1800		700		2400		900		
t _{TLH}		Carry output		600		300		700		400	ns	
t _{THL}				600		300		700		400		

‡f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

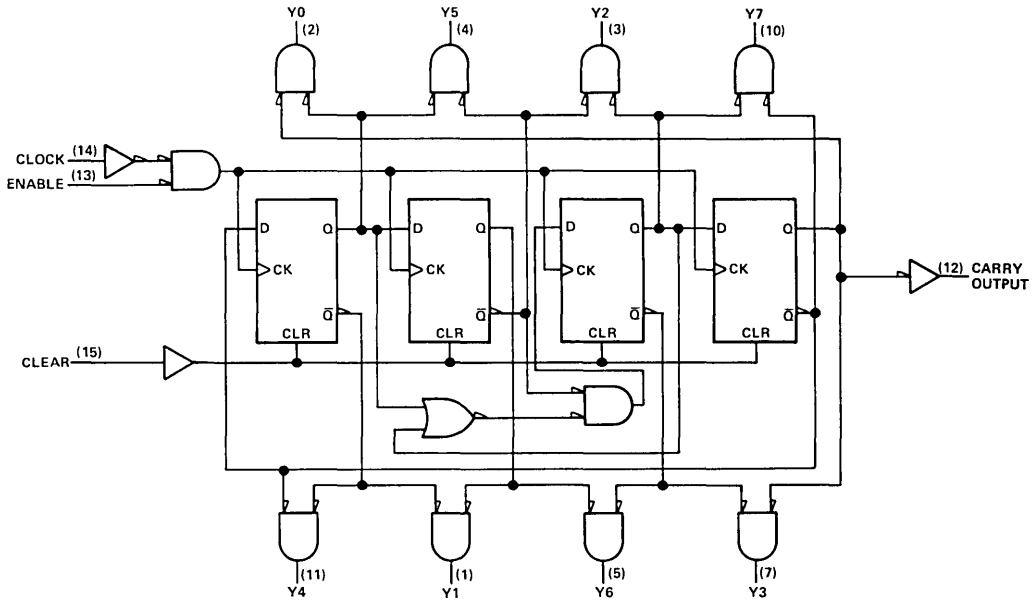
t_{THL} ≡ Transition time, high-to-low-level output

§ With a 15-pF load, these devices switch with times similar to those of the RCA CD4022A.

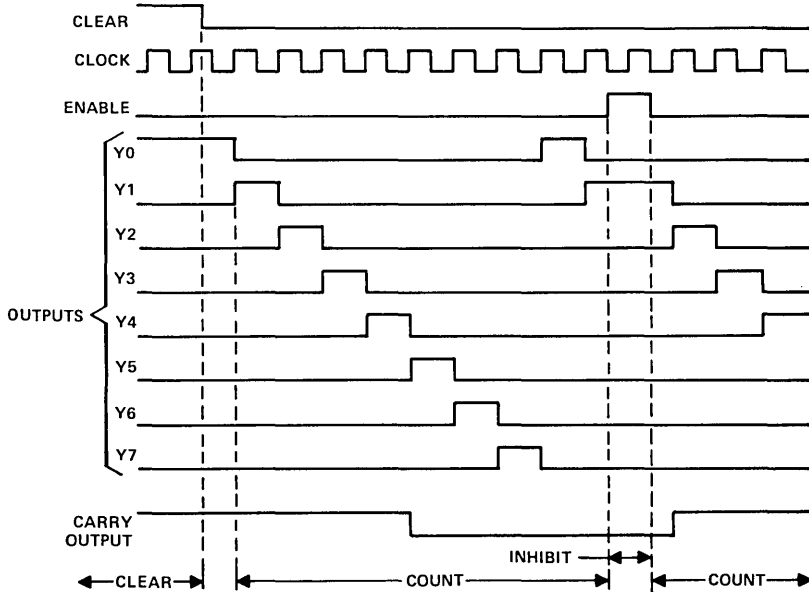
NOTE 1: See load circuit and voltage waveforms on page 170.

TYPES TF4022A, TP4022A OCTAL COUNTERS/DIVIDERS

functional block diagram

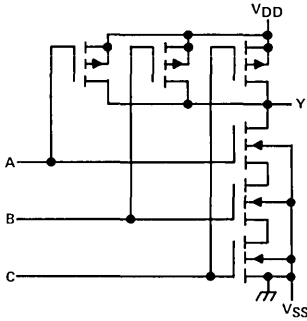


typical clear, count, and inhibit sequences



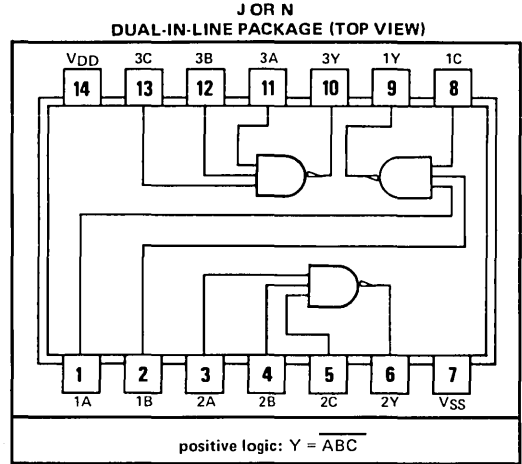
- Designed to be Interchangeable with RCA CD4023A

schematic (each gate)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, Group 1, except as below



electrical characteristics

PARAMETER	TEST CONDITIONS [†]	TF4023A		TP4023A		UNIT	
		V _{DD} = 5 V		V _{DD} = 10 V			
		MIN	MAX	MIN	MAX		
I _{OH} High-level output current	V _{IH} = V _{DD} , V _O = V _{OH} min, V _{IL} = 0,	T _A = MIN	-0.65	-0.75	-0.35	-0.35	mA
		T _A = 25°C	-0.5	-0.6	-0.3	-0.3	
		T _A = MAX	-0.35	-0.4	-0.25	-0.25	
I _{OL} Low-level output current	V _{IH} = V _{DD} , V _O = V _{OL} max, V _{IL} = 0,	T _A = MIN	0.5	1.1	0.35	0.6	mA
		T _A = 25°C	0.4	0.9	0.3	0.5	
		T _A = MAX	0.3	0.65	0.25	0.4	

[†]T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4023A		TP4023A		UNIT			
		V _{DD} = 5 V		V _{DD} = 10 V					
		MIN	MAX	MIN	MAX				
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF §, R _L = 200 kΩ, See Note 1	150		80		200		110	ns
t _{PHL} Propagation delay time, high-to-low-level output		150		80		200		110	
t _{TLH} Transition time, low-to-high-level output		350		175		470		250	
t _{THL} Transition time, high-to-low-level output		450		200		600		275	

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4023A.

NOTE 1: See load circuit and voltage waveforms on Page 170.

CMOS LOGIC CIRCUITS

TYPES TF4024A, TP4024A ASYNCHRONOUS 7-BIT BINARY COUNTERS

SEPTEMBER 1975

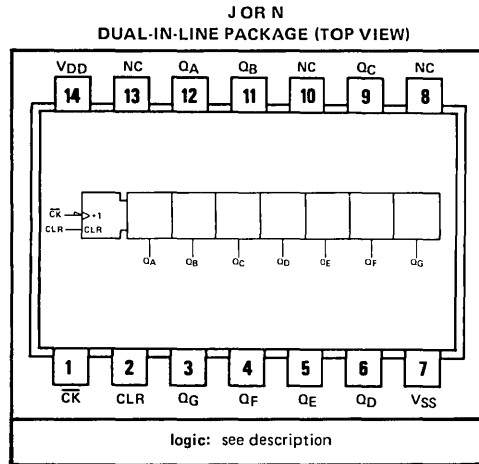
- Designed to be Interchangeable with RCA CD4024A
- Maximum Clock Frequency . . . 7 MHz
Typical at 10 V

description

The '4024A is an asynchronous 7-stage binary counter designed with an input pulse-shaping circuit. The outputs of all stages are available externally. A high clear signal asynchronously clears the counter and resets all outputs low. The count is advanced on the high-to-low transition of the clock pulse. Applications include time-delay circuits, counter controls, and frequency-dividing circuits.

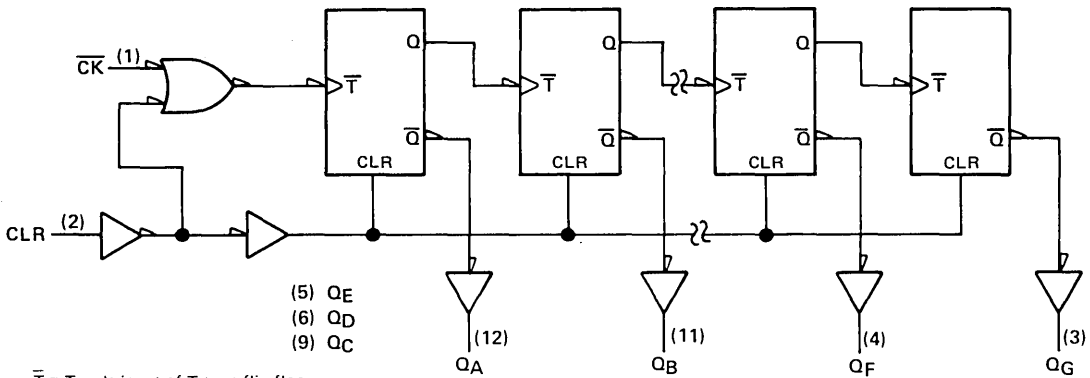
specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and on following page	Page 63, Group 3



NC—No internal connection

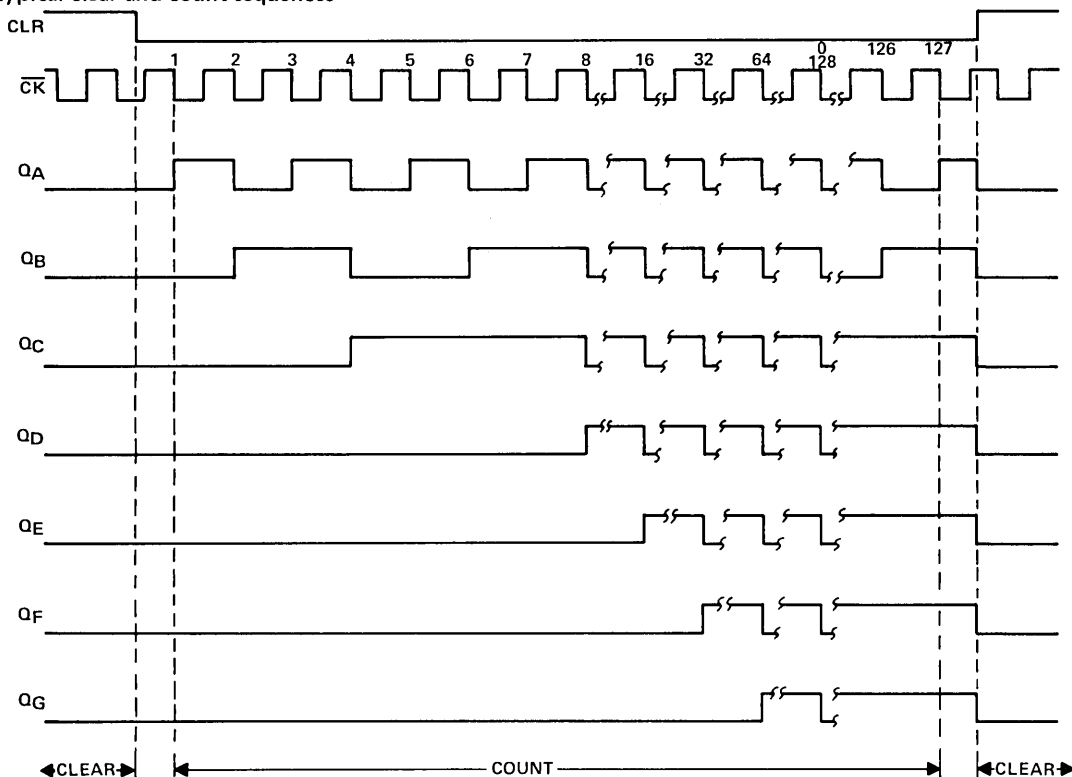
functional block diagram



TYPES TF4024A, TP4024A

ASYNCHRONOUS 7-BIT BINARY COUNTERS

typical clear and count sequences



recommended operating conditions

		TF4024A		TP4024A		UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	
Pulse width, t _w	Clock high or low	330	125	500	165	ns
	Clear	500	300	600	350	ns

switching characteristics at 25°C free-air temperature

PARAMETER†	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4024A		TP4024A		UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	
f _{max}			C _L = 50 pF‡, R _L = 200 kΩ, See Note 1	1.5	4	1	3	MHz
t _{PLH} or t _{PHL}	Clock	Q _A		600	225	700	300	ns
t _{PLH} or t _{PHL}	Clock	Q _G		2000	700	3000	900	ns
t _{PHL}	Clear	Any		900	425	1000	525	ns
t _{TLH} or t _{THL}		Any		350	150	400	225	ns

†f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

t_{THL} ≡ Transition time, high-to-low-level output

‡With a 15-pF load, these devices switch with times similar to those of the RCA CD4024A.

NOTE 1: See load circuit and voltage waveforms on page 170.

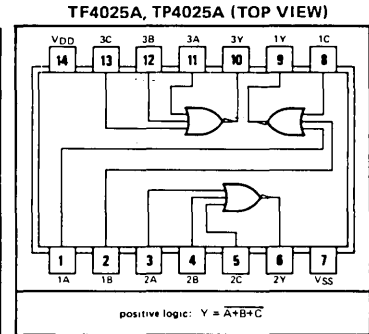
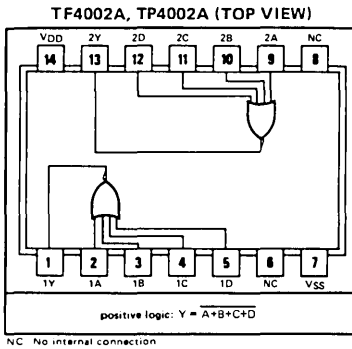
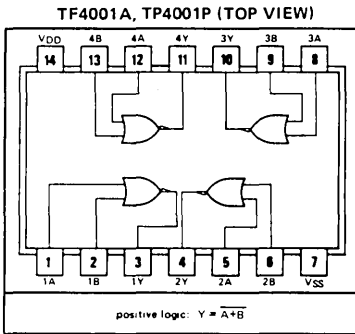
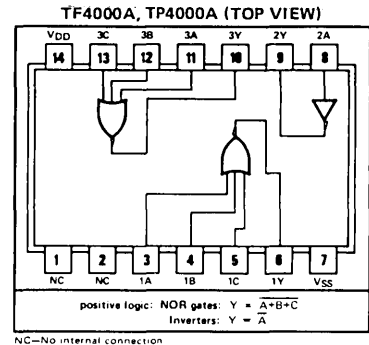
PRINTED IN U.S.A.

CMOS LOGIC CIRCUITS

TYPES TF4025A, TP4025A AND OTHER NOR GATES

SEPTEMBER 1975

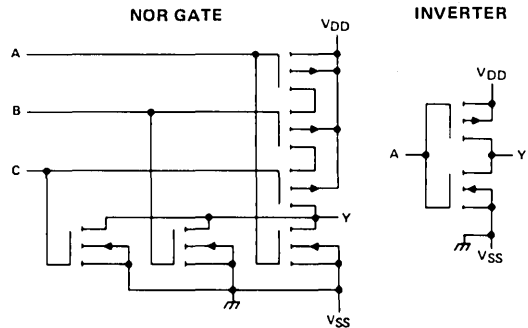
- Designed to be Interchangeable with RCA CD4000A, CD4001A, CD4002A, and CD4025A
- All Products Available in J or N Dual-in-Line Packages
 - '4000 . . . Dual 3-Input NOR Gates Plus Inverters
 - '4001 . . . Quadruple 2-Input NOR Gates
 - '4002 . . . Dual 4-Input NOR Gates
 - '4025 . . . Triple 3-Input NOR Gates



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, Group 1

typical schematics



switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4000A, TF4001A TF4002A, TF4025A		TP4000A, TP4001A TP4002A, TP4025A		UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	
t_{PLH} Propagation delay time, low-to-high-level output	$C_L = 50\text{ pF}$ §, $R_L = 200\text{ k}\Omega$, See Note 1	150	100	200	130	ns
t_{PHL} Propagation delay time, high-to-low-level output		150	100	200	130	ns
t_{TLH} Transition time, low-to-high-level output		350	175	450	300	ns
t_{THL} Transition time, high-to-low-level output		350	175	450	300	ns

§ With a 15-pF load, these devices switch with times similar to those of the RCA CD4000A, CD4001A, CD4002A, and CD4025A, respectively.
NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4027A, TP4027A DUAL J-K FLIP-FLOPS

SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4027A
- Toggle Rate . . . 8 MHz Typical at $V_{DD} = 10\text{ V}$

description

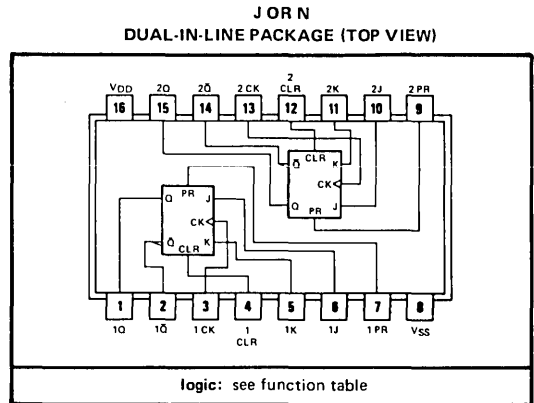
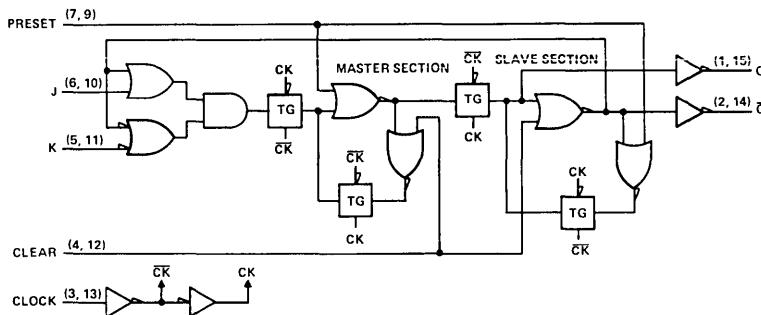
These circuits are dual J-K-type transition-operated master-slave flip-flops with buffered outputs, independent direct overriding preset and clear inputs, and J, K, and clock inputs. While the clock is low, the data at the J and K inputs is entered into the master section, which is isolated from the slave section. On the rising transition of the clock, the J and K inputs are disabled and data previously set up in the master section is transferred to the slave section. Circuit logic for various input configurations is shown in the function table.

Presetting and clearing are independent of the clock and are accomplished by a high-level voltage at the respective input. The \bar{Q} output is complementary to the Q output except for the nonstable situation that exists when both preset and clear inputs are simultaneously high.

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and on following page	Page 63, Group 2, except as on following page

functional block diagram



FUNCTION TABLE
(EACH FLIP-FLOP)

INPUTS					OUTPUTS	
PRESET	CLEAR	CK	J	K	Q	\bar{Q}
H	L	X	X	X	H	L
L	H	X	X	X	L	H
H	H	X	X	X	H*	H*
L	L	↑	L	L	Q_0	\bar{Q}_0
L	L	↑	H	L	H	L
L	L	↑	L	H	L	H
L	L	↑	H	H	TOGGLE	
L	L	L	X	X	Q_0	\bar{Q}_0

See explanation of function tables on pages 16 and 17.

* This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (low) level.

TYPES TF4027A, TP4027A DUAL J-K FLIP-FLOPS

recommended operating conditions

		TF4027A				TP4027A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Pulse width, t _w	Clock high or low	330		110		500		165		ns
	Preset or clear	200		80		300		120		
Setup time, t _{su}		150		50		200		75		ns

electrical characteristics

PARAMETER	TEST CONDITIONS†	TF4027A				TP4027A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
I _{OH} High-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OH} min	T _A = MIN		-0.65	-0.8	T _A = MIN		-0.35	-0.4	mA
		T _A = 25°C		-0.5	-0.65	T _A = 25°C		-0.3	-0.35	
		T _A = MAX		-0.35	-0.45	T _A = MAX		-0.25	-0.3	
I _{OL} Low-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL} max	T _A = MIN		0.5	1.25	T _A = MIN		0.35	0.75	mA
		T _A = 25°C		0.4	1	T _A = 25°C		0.3	0.6	
		T _A = MAX		0.3	0.75	T _A = MAX		0.25	0.5	

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER‡	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4027A				TP4027A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}			C _L = 50 pF §, R _L = 200 kΩ, See Note 1	1.5		4.5		1		3		MHz
t _{PLH} or t _{PHL}	Clock	Q or \bar{Q}		420		185		550		250		ns
t _{PLH} or t _{PHL}	Preset or Clear	Q or \bar{Q}		320		185		450		250		ns
t _{TLH} or t _{THL}		Any		235		130		300		175		ns

‡f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

t_{THL} ≡ Transition time, high-to-low-level output

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4027A.

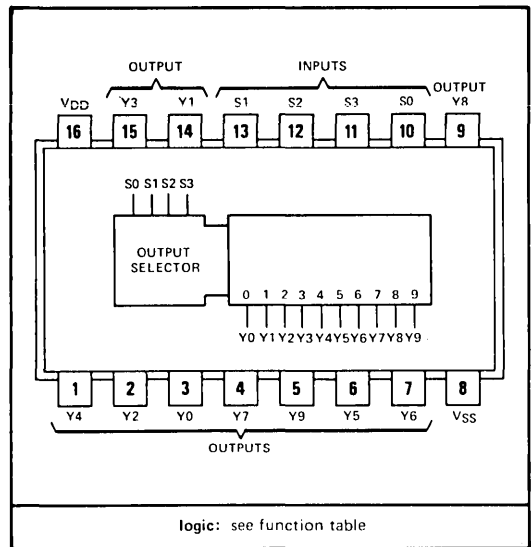
NOTE 1: See load circuit and voltage waveforms on page 170.

- Designed to be Interchangeable with RCA CD4028A

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 3

J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



description

These circuits are BCD-to-decimal or binary-to-octal decoders with ten buffered outputs. An 8-4-2-1 BCD code applied to the four inputs provides a decimal (one of ten) decoded output. With the S3 input held at a low level, a 3-bit binary input provides a decoded octal (one of eight) code output. The selected output is high, all others are low. These devices have applications including code conversion, address decoding, memory selection control, and demultiplexing or readout decoding.

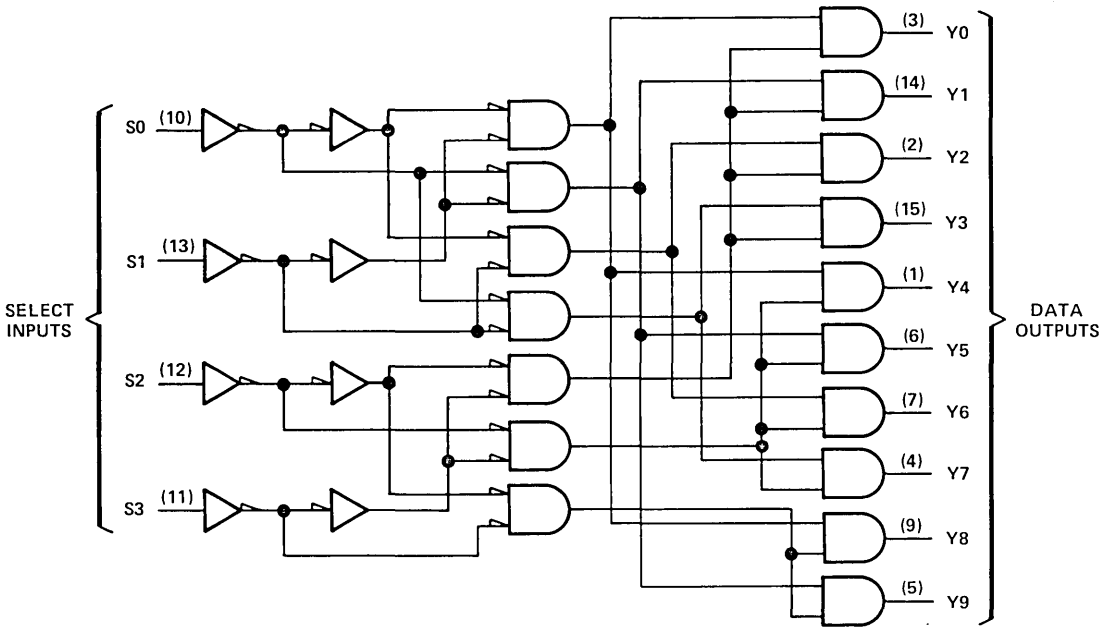
FUNCTION TABLE

NO.	INPUTS				OUTPUTS										
	S3	S2	S1	S0	Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7	Y8	Y9	
0	L	L	L	L	H	L	L	L	L	L	L	L	L	L	L
1	L	L	L	H	L	H	L	L	L	L	L	L	L	L	L
2	L	L	H	L	L	L	H	L	L	L	L	L	L	L	L
3	L	L	H	H	L	L	L	H	L	L	L	L	L	L	L
4	L	H	L	L	L	L	L	L	H	L	L	L	L	L	L
5	L	H	L	H	L	L	L	L	L	H	L	L	L	L	L
6	L	H	H	L	L	L	L	L	L	L	H	L	L	L	L
7	L	H	H	H	L	L	L	L	L	L	L	H	L	L	L
8	H	L	L	L	L	L	L	L	L	L	L	L	H	L	L
9	H	L	L	H	L	L	L	L	L	L	L	L	L	H	H
INVALID	H	L	H	L	L	L	L	L	L	L	L	L	L	L	L
	H	L	H	H	L	L	L	L	L	L	L	L	L	L	L
	H	H	L	L	L	L	L	L	L	L	L	L	L	L	L
	H	H	L	H	L	L	L	L	L	L	L	L	L	L	L
	H	H	H	H	L	L	L	L	L	L	L	L	L	L	L

H high level, L low level

TYPES TF4028A, TP4028A BCD-TO-DECIMAL DECODERS

functional block diagram



switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4028A				TP4028A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF [§] , R _L = 200 kΩ, See Note 1	630		250		900		400		ns
t _{PHL} Propagation delay time, high-to-low-level output		630		250		900		400		ns
t _{TLH} Transition time, low-to-high-level output		300		150		400		220		ns
t _{THL} Transition time, high-to-low-level output		300		150		400		220		ns

[§]With a 15-pF load, these devices switch with times similar to those of the RCA CD4028A.

NOTE 1: See load circuit and voltage waveforms on page 170.

- Designed to be Interchangeable with RCA CD4029A
- Medium Speed Operation . . . 5 MHz
Typical at $V_{DD} = 10\text{ V}$
- Binary or Decade Up/Down Counting
- BCD Outputs in Decade Mode

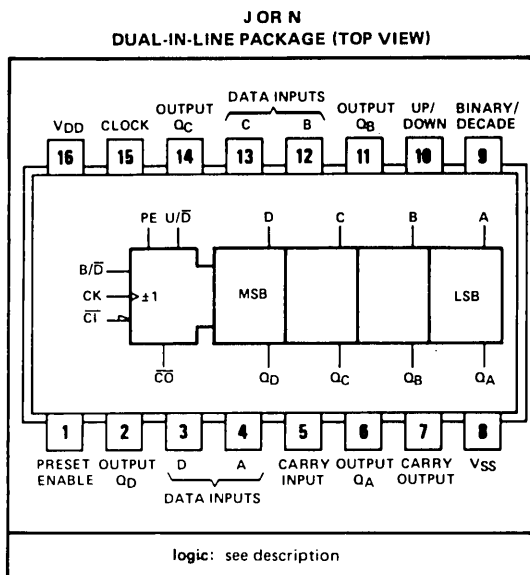
description

The '4029A counter consists of a four-stage binary or BCD-decade up/down counter with provision for look-ahead carry in both counting modes. The inputs consist of a single clock, carry input (clock enable), binary/decade, up/down, preset enable, and four individual parallel data inputs. Four separate buffered data outputs and a carry output are provided.

A high at the preset-enable input allows information at the parallel inputs to preset the counter to any count independently of the clock. A low at each parallel input, when the preset-enable input is high, resets the counter to its zero count. The counter is advanced one count at the low-to-high transition of the clock when the carry input and preset-enable input are low. Advancement is inhibited when the carry input or preset-enable input is high. The carry output is normally high and goes low when the counter reaches its maximum count in the up mode or its minimum count in the down mode, provided the carry input is low. The carry input terminal must be connected to V_{SS} when not in use.

Binary counting is accomplished when the binary/decade input is high; the counter counts in the decade mode when the binary/decade input is low. The counter counts up when the up/down input is high, and down when the up/down input is low.

Multiple packages can be connected in either a parallel-clocking or a ripple-clocking arrangement as shown in Figure 1. Parallel clocking provides synchronous control and hence faster response from all counting outputs. Ripple clocking permits longer clock input rise and fall times.



**SUMMARY OF CONTROL INPUT FUNCTIONS
(COMPLETE COUNTER)**

CONTROL INPUT	LOGIC LEVEL	FUNCTION
Binary/Decade (B/D)	H L	Binary count Decade count
Up/Down (U/D)	H L	Count up Count down
Preset enable (PE)	H L	Parallel load Enable counting
Carry input (CI)	H L	Inhibit counting Enable counting

specification

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and on following page	Page 63, group 3, except as on following page

TYPES TF4029A, TP4029A

PRESETTABLE UP/DOWN BINARY/DECADE COUNTERS

recommended operating conditions

		TF4029A		TP4029A		UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	
Pulse width, t _w	Clock high or low	340	170	500	250	ns
	Preset enable	330	160	660	320	
Setup time, t _{su}	Binary/Decade	650	230	1300	460	ns
	Up/Down	650	230	1300	460	
	Carry input	650	230	1300	460	
	Preset enable inactive state	650	230	1300	460	

electrical characteristics

PARAMETER		TEST CONDITIONS†		TF4029A		TP4029A		UNIT		
				V _{DD} = 5 V		V _{DD} = 10 V				
				MIN	MAX	MIN	MAX			
I _{OH}	High-level output-current	Q outputs	V _{IH} = V _{DD} , V _O = V _{OH} min	V _{IL} = 0,	T _A = MIN	-300	-300	-140	-140	μA
					T _A = 25°C	-200	-200	-100	-100	
					T _A = MAX	-140	-140	-80	-80	
	Carry output	V _{IH} = V _{DD} , V _O = V _{OH} min	V _{IL} = 0,	T _A = MIN	-150	-150	-70	-70	μA	
				T _A = 25°C	-100	-100	-50	-50		
				T _A = MAX	-70	-70	-40	-40		
I _{OL}	Low-level output current	Q outputs	V _{IH} = V _{DD} , V _O = V _{OL} max	V _{IL} = 0,	T _A = MIN	500	740	240	360	μA
					T _A = 25°C	400	600	200	300	
					T _A = MAX	280	420	160	240	
	Carry output	V _{IH} = V _{DD} , V _O = V _{OL} max	V _{IL} = 0,	T _A = MIN	100	400	50	190	μA	
				T _A = 25°C	80	320	40	160		
				T _A = MAX	60	220	30	130		

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER‡	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4029A		TP4029A		UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	
f _{max}				1.5	3	1	2	MHz
t _{PLH} or t _{PHL}	Clock	Any Q output	C _L = 50 pF §, R _L = 200 kΩ, See load circuit and voltage waveforms on page 170.	900	350	1800	700	ns
t _{PLH} or t _{PHL}	Clock	Carry output		1300	550	2600	1100	ns
t _{PLH} or t _{PHL}	Preset enable	Any Q output		900	350	1800	700	ns
t _{PLH} or t _{PHL}	Preset enable	Carry output		1300	550	2600	1100	ns
t _{PLH} or t _{PHL}	Carry input	Carry output		800	350	1600	700	ns
t _{TLH} or t _{THL}		Any Q output		450	225	900	450	ns
t _{TLH} or t _{THL}		Carry output		850	450	1700	900	ns

‡f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

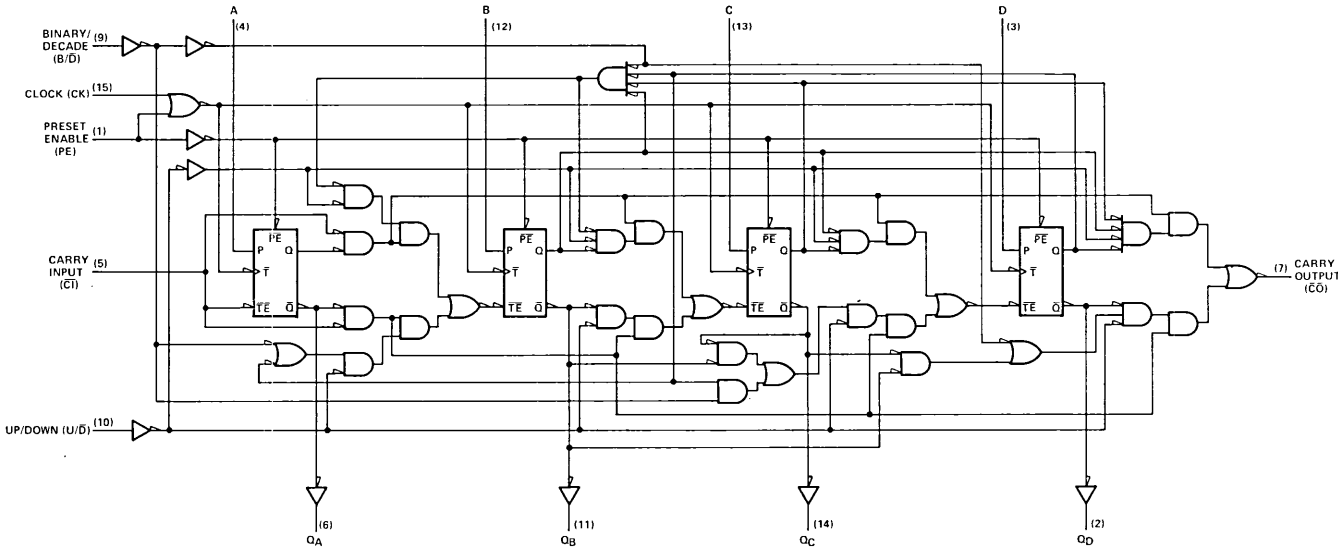
t_{TLH} ≡ Transition time, low-to-high-level output

t_{THL} ≡ Transition time, high-to-low-level output

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4029A.

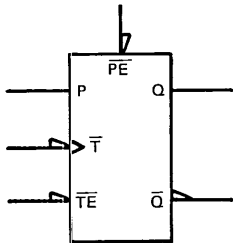
TYPES TF4029A, TP4029A PRESETTABLE UP/DOWN BINARY/DECADE COUNTERS

functional block diagram



EACH FLIP-FLOP

SYMBOL



\overline{TE} = toggle-enable input
P = parallel data input
 \overline{T} = toggle input

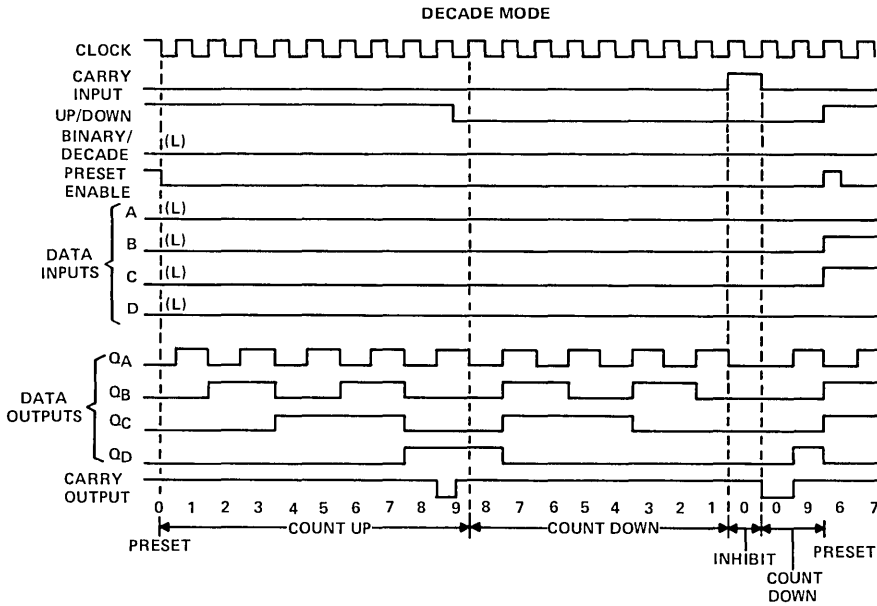
FUNCTION TABLE (NOT INCLUDING GATING EXTERNAL TO THE FLIP-FLOP)

INPUTS				OUTPUTS	
\overline{PE}	\overline{TE}	\overline{T}	P	Q	\overline{Q}
L	X	L	H	H	L
L	X	L	L	L	H
H	H	↓	X	Q_n	\overline{Q}_n
H	L	↓	X	\overline{Q}_n	Q_n
X	X	H	X	Q_0	\overline{Q}_0

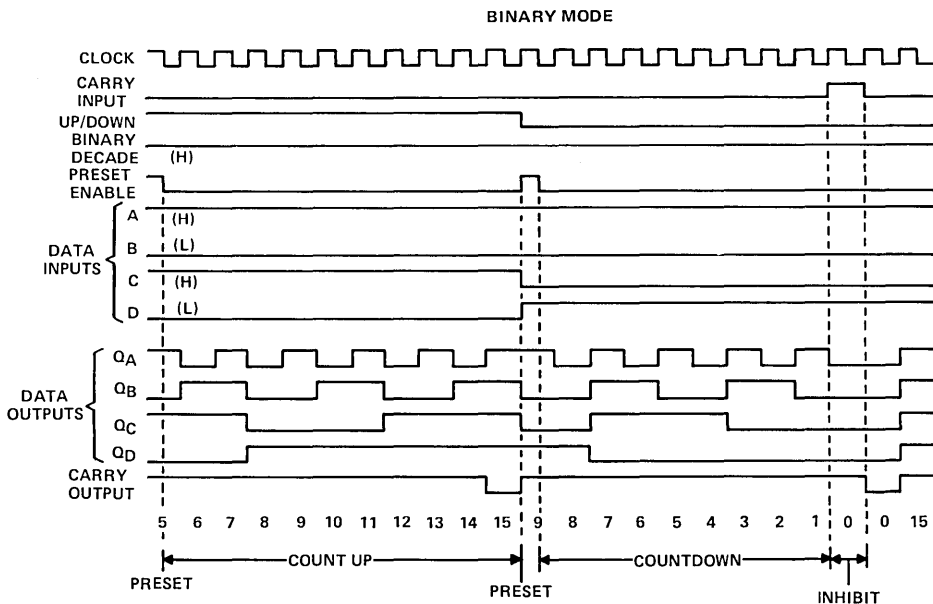
H = high level (steady state)
L = low level (steady state)
X = irrelevant (any input, including transitions)
↓ = transition from high to low level
 Q_n = the level of Q before the most-recent
↓ transition of \overline{T} .
 Q_0 = the level of Q before the indicated
steady-state conditions were established

TYPES TF4029A, TP4029A PRESETTABLE UP/DOWN BINARY/DECADE COUNTERS

typical count up, count down, inhibit, and preset sequences

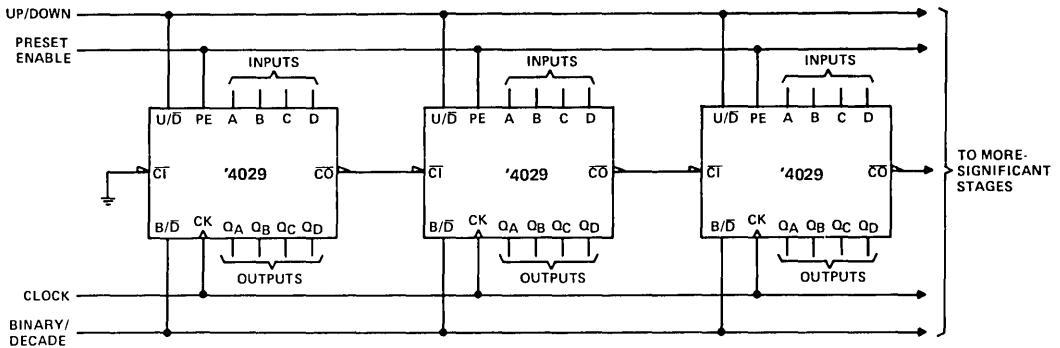


typical count up, preset, count down, and inhibit sequences

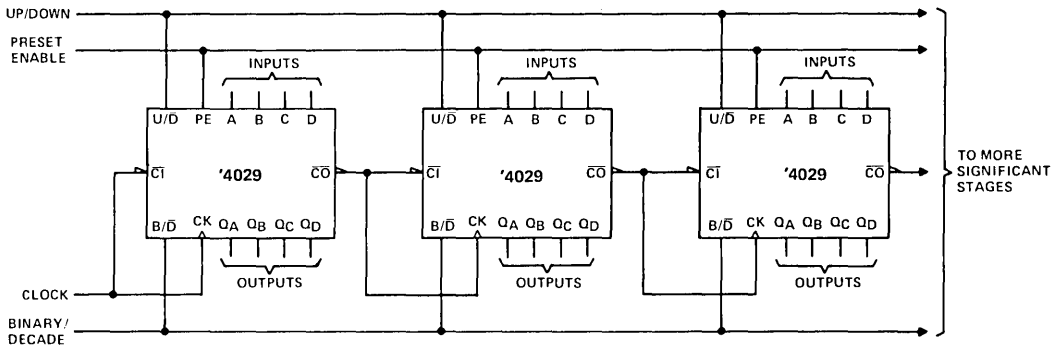


TYPES TF4029A, TP4029A PRESETTABLE UP/DOWN BINARY/DECADE COUNTERS

TYPICAL APPLICATION DATA PARALLEL CLOCKING



RIPPLE CLOCKING



NOTE A: The up/down control can be changed at any count. The only restriction is that in the ripple-clocked application, the clock input (including \overline{CI}) of the first counting stage must be high when the up/down control is changed.

FIGURE 1—CASCADED COUNTER PACKAGES

The '4029 clock and up/down inputs are used directly in most applications. In applications where clock-up and clock-down inputs are provided, conversion to the '4029 clock and up/down inputs can easily be realized by use of the circuit shown below. The '4029 changes count on the low-to-high transitions of the clock-up or clock-down inputs. For the gate configuration shown below, when counting up the clock-down input must be maintained high and conversely, when counting down the clock-up input must be maintained high.

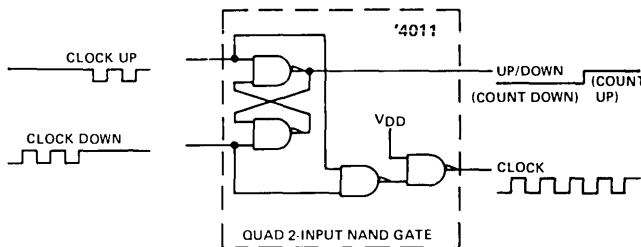


FIGURE 2—CONVERSION OF CLOCK-UP AND CLOCK-DOWN INPUT SIGNALS TO CLOCK AND UP/DOWN INPUT SIGNALS

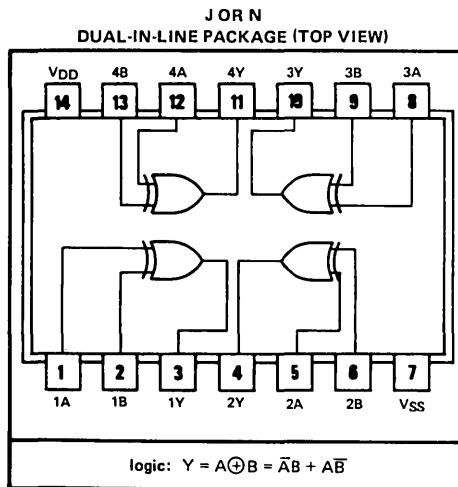
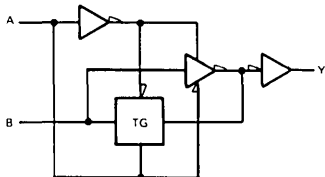
- Designed to be Interchangeable with RCA CD4030A and Motorola MC14507
- Even- and Odd-Parity Generators and Checkers
- Logical Comparators
- Adders and Subtractors
- True/Complement Gating

FUNCTION TABLE

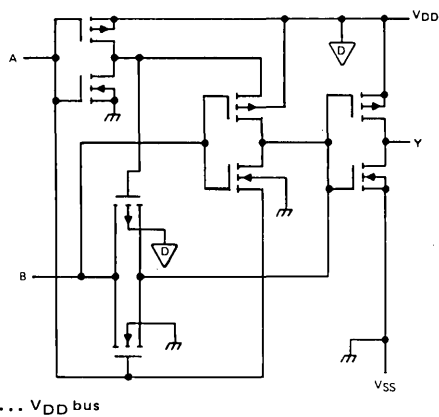
INPUTS		OUTPUT
A	B	Y
L	L	L
H	L	H
L	H	H
H	H	L

H = high level, L = low level

functional block diagram (each gate)



schematic (each gate)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 2, and on following page

TYPES TF4030A, TP4030A

QUAD EXCLUSIVE-OR GATES

electrical characteristics

$V_{DD} = 5\text{ V}$ and 10 V

PARAMETER	TEST CONDITIONS†		TF4030A		TP4030A		UNIT
			$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
			MIN	MAX	MIN	MAX	
I_{OH} High-level output current	$V_{IH} = V_{DD}$, $V_{IL} = 0$, $V_O = V_{OH\text{ min}}$	$T_A = \text{MIN}$	-0.95	-0.95	-0.45	-0.45	mA
		$T_A = 25^\circ\text{C}$	-0.65	-0.65	-0.32	-0.32	
		$T_A = \text{MAX}$	-0.45	-0.45	-0.25	-0.25	
I_{OL} Low-level output current	$V_{IH} = V_{DD}$, $V_{IL} = 0$, $V_O = V_{OL\text{ max}}$	$T_A = \text{MIN}$	0.75	1.5	0.35	0.7	mA
		$T_A = 25^\circ\text{C}$	0.6	1.2	0.3	0.6	
		$T_A = \text{MAX}$	0.45	0.9	0.25	0.5	
I_{DD} or $-I_{SS}$ Quiescent supply current	$V_I = V_{DD}$ or 0 , No load	$T_A = \text{MIN}$ or 25°C	0.5	1	5	10	μA
		$T_A = \text{MAX}$	30	60	70	140	

$V_{DD} = 15\text{ V}$

PARAMETER	TEST CONDITIONS†		TF4030A		TP4030A		UNIT
			MIN	MAX	MIN	MAX	
I_{DD} or $-I_{SS}$ Quiescent supply current	$V_I = V_{DD}$ or 0 , No load	$T_A = \text{MIN}$ or 25°C	3		30		μA
		$T_A = \text{MAX}$	180		420		

† $T_A = \text{MIN}$ or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4030A		TP4030A		UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	
t_{PLH} Propagation delay time, low-to-high-level output	$C_L = 50\text{ pF}$ §, $R_L = 200\text{ k}\Omega$, See Note 1	350		175		ns
t_{PHL} Propagation delay time, high-to-low-level output		350		175		
t_{TLH} Transition time, low-to-high-level output		300		150		ns
t_{THL} Transition time, high-to-low-level output		300		150		

§ With a 15-pF load, these devices switch with times similar to those of the RCA CD4030A and Motorola MC14507.

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

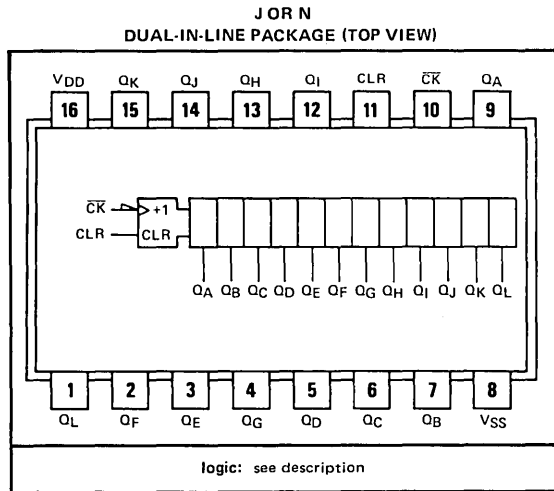
TYPES TF4040A, TP4040A ASYNCHRONOUS 12-BIT BINARY COUNTERS

SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4040A
- Maximum Clock Frequency . . . 7 MHz Typical at 10 V

description

The '4040 is an asynchronous 12-stage binary counter designed with an input pulse-shaping circuit. The outputs of all stages are available externally. A high clear signal asynchronously clears the counter and resets all outputs low. The count is advanced on the high-to-low transition of the clock pulse. Applications include time delay circuits, counter controls, and frequency-dividing circuits.



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and below	Page 63, group 3

recommended operating conditions

		TF4040A		TP4040A		UNIT	
		V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 5 V	V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX
Pulse width, t _w	Clock high or low	335	110	500	125	ns	
	Clear	1000	500	1250	600	ns	

switching characteristics at 25°C free-air temperature

PARAMETER‡	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4040A		TP4040A		UNIT	
				V _{DD} = 5 V	V _{DD} = 10 V	V _{DD} = 5 V	V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX
f _{max}			C _L = 50 pF§, R _L = 200 kΩ, See Note 1	1.5	4	1	3	MHz	
t _{PLH} or t _{PHL}	Clock	Q _A		775	300	850	350	ns	
t _{PLH} or t _{PHL}	Clock	Q _L		5000	1800	7500	2700	ns	
t _{PHL}	Clear	Any		1200	475	1800	725	ns	
t _{TLH} or t _{THL}		Any		350	150	400	225	ns	

‡f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

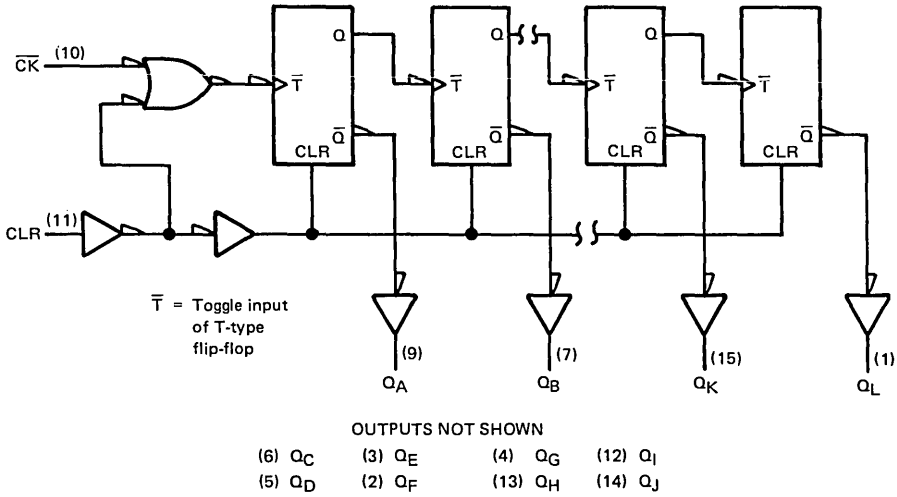
t_{THL} ≡ Transition time, high-to-low-level output

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4040A.

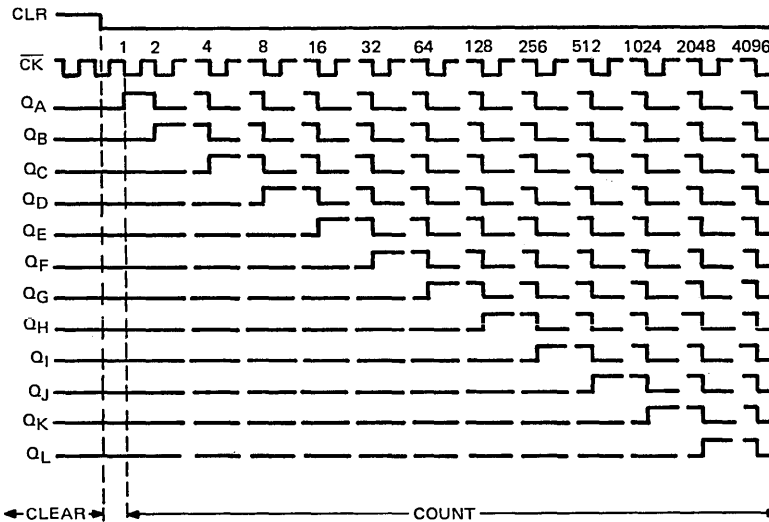
NOTE 1: See load circuit and voltage waveforms on page 170.

TYPES TF4040A, TP4040A ASYNCHRONOUS 12-BIT BINARY COUNTERS

functional block diagram



typical clear and count sequence



CMOS LOGIC CIRCUITS

TYPES TF4042A, TP4042A QUAD D-TYPE LATCHES

SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4042A
- Control and Polarity Inputs
- Complementary Outputs

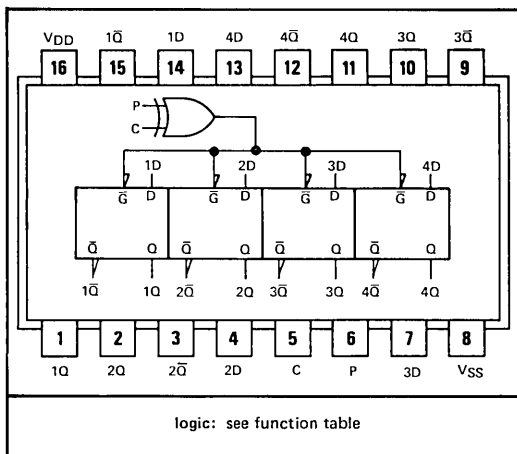
description

The '4042A is a quadruple D-type latch with common control and polarity inputs, C and P. Complementary buffered outputs are available from each latch.

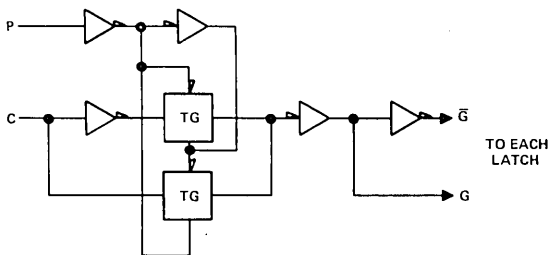
When P is high, C determines the state of all the latches. If C is high, the latches pass data from their D inputs to their Q outputs and the data complement to their \bar{Q} outputs. If C is low, the data is latched.

When P is low, C still determines the state of all the latches, but now data is passed when C is low and is latched when C is high.

J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



functional block diagram



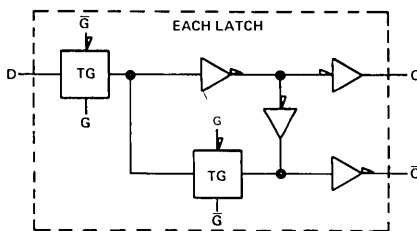
FUNCTION TABLE

P	C	FUNCTION
H	H	Pass data
H	L	Latch data
L	H	Latch data
L	L	Pass data

H = high level, L = low level

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and below	Page 63, group 3, except as on following page



recommended operating conditions

	TF4042A		TP4042A		UNIT
	V _{DD} = 5 V		V _{DD} = 10 V		
	MIN	MAX	MIN	MAX	
Width of control pulse (high or low), $t_w(\text{control})$	250	75	350	175	ns
Data setup time before latching, $t_{su}(\text{data})$	100	50	125	60	ns

TYPES TF4042A, TP4042A

QUAD D-TYPE LATCHES

electrical characteristics

$V_{DD} = 5\text{ V}$ and 10 V

PARAMETER	TEST CONDITIONS†		TF4042A		TP4042A		UNIT
			$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
			MIN	MAX	MIN	MAX	
I_{DD} or Quiescent supply current $-I_{SS}$	$V_I = V_{DD}$ or 0, No load	$T_A = \text{MIN}$, or 25°C	1	2	10	20	μA
		$T_A = \text{MAX}$	60	120	140	280	

$V_{DD} = 15\text{ V}$

PARAMETER	TEST CONDITIONS†		TF4042A		TP4042A		UNIT
			MIN	MAX	MIN	MAX	
I_{DD} or Quiescent supply current $-I_{SS}$	$V_I = V_{DD}$ or 0, No load	$T_A = \text{MIN}$ or 25°C	6		60		μA
		$T_A = \text{MAX}$	360		840		

† $T_A = \text{MIN}$ or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4042A		TP4042A		UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	
t_{PLH} Propagation delay time, low-to-high-level output	$C_L = 50\text{ pF}$ §, $R_L = 200\text{ k}\Omega$, See Note 1	475	200	600	300	ns
t_{PHL} Propagation delay time, high-to-low-level output		475	200	600	300	ns
t_{TLH} Transition time, low-to-high-level output		350	150	400	220	ns
t_{THL} Transition time, high-to-low-level output		350	150	400	220	ns

§ With a 15-pF load, these devices switch with times similar to those of the RCA CD4042A.

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4043A, TF4044A, TP4043A, TP4044A QUAD S-R AND \bar{S} - \bar{R} LATCHES WITH 3-STATE OUTPUTS

SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4043A and CD4044A
- 3-State Outputs with Common Enable

description

The '4043A and '4044A are quadruple S-R and \bar{S} - \bar{R} latches, respectively, with three-state outputs. Each latch has separate active-high ('4043A) or active-low ('4044A) set and reset inputs. The three-state outputs are controlled by a common output control. When high, this control permits each output to assume the state of the cross-coupled NOR-gate or NAND-gate latch. When the output control is low, all the outputs are in a high-impedance state.

**FUNCTION TABLES
(EACH LATCH)
TF4043A, TP4043B**

OUTPUT CONTROL	INPUTS		OUTPUT Q
	S	R	
L	X	X	Hi-Z
H	L	L	No change
H	H	L	H
H	L	H	L
H	H	H	H*

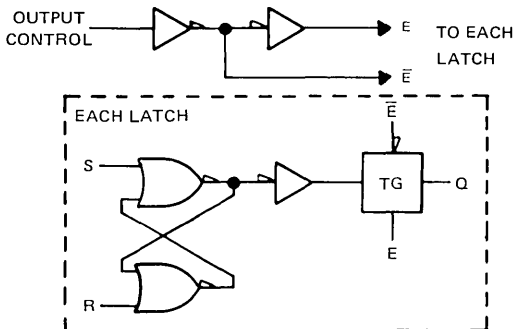
TF4044A, TP4044A

OUTPUT CONTROL	INPUTS		OUTPUT Q
	\bar{S}	\bar{R}	
L	X	X	Hi-Z
H	H	H	No change
H	L	H	H
H	H	L	L
H	L	L	L*

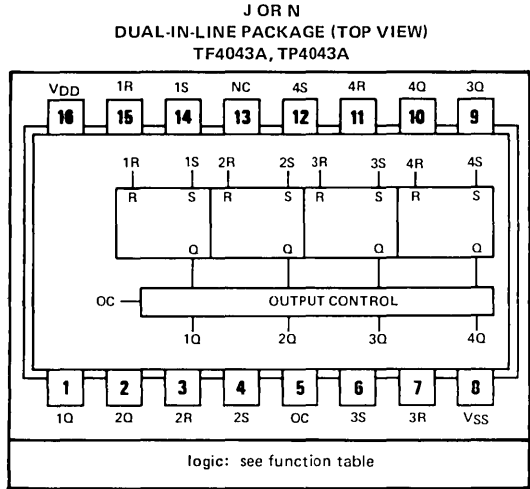
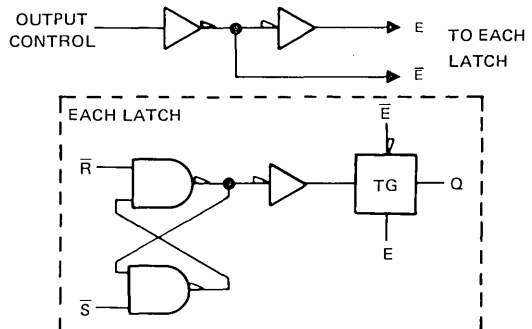
*This output level is pseudo stable; that is, it may not persist when the S and R inputs return to their inactive (low) level or the \bar{S} and \bar{R} inputs return to their inactive (high) level. See explanation of function tables, pages 16 and 17.

functional block diagrams

TF4043A, TP4043A

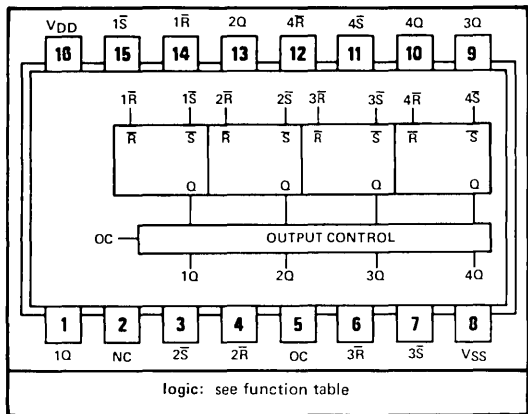


TF4044A, TP4044A



NC—No internal connection

TF4044A, TP4044A



NC—No internal connection

TYPES TF4043A, TF4044A, TP4043A, TP4044A

QUAD S-R AND $\bar{S}\bar{R}$ LATCHES WITH 3-STATE OUTPUTS

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and below	Page 63, group 3, except as below

recommended operating conditions

	TF4043A, TF4044A		TP4043A, TP4044A		UNIT
	V _{DD} = 5 V		V _{DD} = 10 V		
	MIN	MAX	MIN	MAX	
Pulse width, set or reset, t _w	200	100	225	110	ns

electrical characteristics

V_{DD} = 5 V and 10 V

PARAMETER	TEST CONDITIONS†	TF4043A, TF4044A		TP4043A, TP4044A		UNIT		
		V _{DD} = 5 V		V _{DD} = 10 V				
		MIN	MAX	MIN	MAX			
I _{OZH} Off-state output current, high-level voltage applied	OC at V _{SS} , V _O = V _{DD}	T _A = MIN or 25°C		0.05	0.1	0.5	1	μA
		T _A = MAX		3	6	7	14	
I _{OZL} Off-state output current, low-level voltage applied	OC at V _{SS} , V _O = 0 V	T _A = MIN or 25°C		-0.05	-0.1	-0.5	-1	μA
		T _A = MAX		-3	-6	-7	-14	
I _{DD} or -I _{SS} Quiescent supply current	V _I = V _{DD} or 0, No load	T _A = MIN, or 25°C		1	2	10	20	μA
		T _A = MAX		60	120	140	280	

V_{DD} = 15 V

PARAMETER	TEST CONDITIONS	TF4043A, TF4044A		TP4043A, TP4044A		UNIT
		MIN	MAX	MIN	MAX	
I _{DD} or -I _{SS} Quiescent supply current	V _I = V _{DD} or 0, No load	T _A = MIN or 25°C		6		μA
		T _A = MAX		360		
				840		

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4043A, TF4044A		TP4043A, TP4044A		UNIT		
		V _{DD} = 5 V		V _{DD} = 10 V				
		MIN	MAX	MIN	MAX			
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF§, R _L = 200 kΩ, See Note 1	525		250		600	310	ns
t _{PHL} Propagation delay time, high-to-low-level output		525		250		600	310	ns
t _{T LH} Transition time, low-to-high-level output		350		150		400	220	ns
t _{T HL} Transition time, high-to-low-level output		350		150		400	220	ns

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4043A and CD4044A.

NOTE 1: See load circuit and voltage waveforms on page 170.

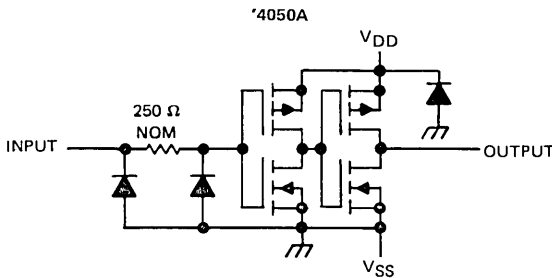
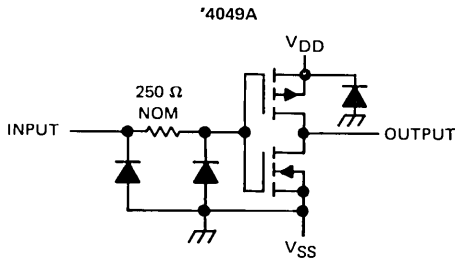
CMOS LOGIC CIRCUITS

TYPES TF4049A, TF4050A, TP4049A, TP4050A HEX INVERTING AND NONINVERTING BUFFERS

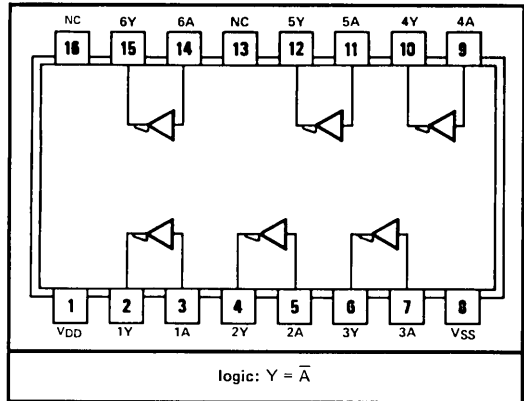
SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4049A and RCA CD4050A
- High Current Sinking Capability . . . 8 mA Minimum at $V_{OL} = 0.5\text{ V}$, $V_{DD} = 10\text{ V}$, $T_A = 25^\circ\text{C}$

schematic (each buffer)

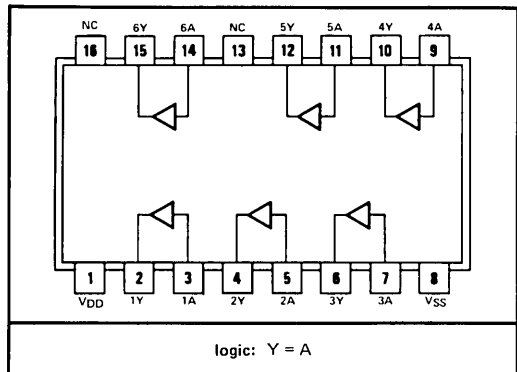


J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)
TF4049A, TP4049A



NC—No internal connection

TF4050A, TP4050A



NC—No internal connection

description

The '4049A and '4050A hex CMOS inverting and noninverting buffers may be used as current sinks or source drivers, hex CMOS drivers, or high-to-low-logic-level (e.g., CMOS to DTL or TTL) converters. Logic-level conversion is accomplished using only one supply voltage (V_{DD}). The high-level input signal (V_{IH}) can exceed the V_{DD} supply voltage when this device is used for logic-level conversions. Table 1 shows the range of voltage levels that can be utilized in these applications. Conversions to logic levels greater than six volts are permitted provided that V_{DD} is less than or equal to V_{IH} .

Since these devices require only one power supply, V_{DD} , they should be used in place of the '4009A and '4010A in all current driver or logic-level conversion applications. They are interchangeable with '4009A and '4010A, respectively, and can be substituted in existing as well as new designs. Pin 16 of the '4049A and '4050A is not internally connected; therefore, any external connection to this pin does not affect circuit operation.

TABLE 1

FUNCTION	INPUT HIGH-LEVEL VOLTAGE RANGE	OUTPUT HIGH-LEVEL VOLTAGE RANGE	POWER SUPPLY VOLTAGE RANGE (V_{DD})
Level Shifter	3 to 15 V	3 to 6 V	3 to 6 V
Buffer	3 to 15 V	3 to 15 V	3 to 15 V

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 2, except as on following page

TYPES TF4049A, TF4050A, TP4049A, TP4050A

HEX INVERTING AND NONINVERTING BUFFERS

electrical characteristics

'4049 only

PARAMETER	TEST CONDITIONS†	TF4049A				TP4049A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
V _{IL} Low-level input voltage	T _A = MIN or 25°C T _A = MAX	1		2		1		2		V
		0.9		1.9		0.9		1.9		

'4049A and '4050A at V_{DD} = 5 V and 10 V

PARAMETER	TEST CONDITIONS†	TF4050A				TP4050A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
I _{OH} High-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OH min} T _A = MIN T _A = 25°C T _A = MAX	-1.85	-1.85	-1.85	-1.85	-1.5	-1.5	-1.5	-1.5	mA
I _{OL} Low-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL} T _A = MIN T _A = 25°C T _A = MAX	3.75	10	3.75	10	3.6	9.6	3.6	9.6	
I _{DD} or -I _{SS} Quiescent supply current	V _I = V _{DD} or 0, No load T _A = MIN or 25°C T _A = MAX	0.3	0.5	0.3	0.5	3	5	3	5	
		20	30	20	30	42	70	42	70	

'4049A and '4050A at V_{DD} = 15 V

PARAMETER	TEST CONDITIONS†	TF4049A, TF4050A		TP4049A, TP4050A		UNIT
		MIN	MAX	MIN	MAX	
I _{DD} or -I _{SS} Quiescent supply current	V _I = V _{DD} or 0, No load T _A = MIN or 25°C T _A = MAX	1.5		15		μA
		90		210		

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

'4049A switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4049A				TP4049A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF §, R _L = 200 kΩ, See Note 1	120		95		160		125		ns
t _{PHL} Propagation delay time, high-to-low-level output		100		55		125		75		
t _{TLH} Transition time, low-to-high-level output		170		85		225		120		
t _{THL} Transition time, high-to-low-level output		70		55		90		75		

'4050A switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4050A				TP4050A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF §, R _L = 200 kΩ, See Note 1	180		125		250		160		ns
t _{PHL} Propagation delay time, high-to-low-level output		155		80		200		110		
t _{TLH} Transition time, low-to-high-level output		170		85		225		120		
t _{THL} Transition time, high-to-low-level output		70		55		90		75		

§With a 15-pF load, these devices switch with times similar to those of the RCA CD4049A and RCA CD4050A respectively.

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4051A, TF4052A, TF4053A, TP4051A, TP4052A, TP4053A ANALOG MULTIPLEXERS/DEMULTIPLEXERS

SEPTEMBER 1975

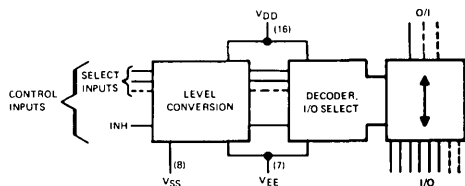
- Designed to be Interchangeable with RCA CD4051A, CD4052A, and CD4053A
- Difference in r_{ON} Between Switches in One Package Typically 5Ω at $V_{DD}-V_{EE} = 15 V$
- High Degree of Linearity . . . $< 0.1\%$ Distortion Typical at 1 kHz, $V_{DD}-V_{EE} = 15 V$
- Switches Can Transmit Signals in Either Direction at Frequencies of up to 40 MHz Typically at $V_{DD}-V_{EE} = 10 V$
- Extremely Low Off-State Switch Current Resulting in Very High Effective Off-State Resistance . . . 10 pA Typical at $V_{DD}-V_{SS} = 10 V$
- Low Crosstalk Between Switches . . . 40 dB Typical at 1 MHz, $R_L = 1 \text{ k}\Omega$

description

These devices are analog multiplexers/demultiplexers incorporating built-in level shifting. Any combination of supply voltages is permissible provided that V_{SS} and V_{EE} are each within the range of -3 to -15 volts with respect to V_{DD} . The level shifting is between V_{SS} and V_{EE} . The control input range is V_{SS} to V_{DD} and the analog signal range is V_{EE} to V_{DD} . The common situation of positive digital signals controlling the multiplexing of both positive and negative analog signals can be accommodated. The table indicates some of the possible combinations of supply, input, and output voltages.

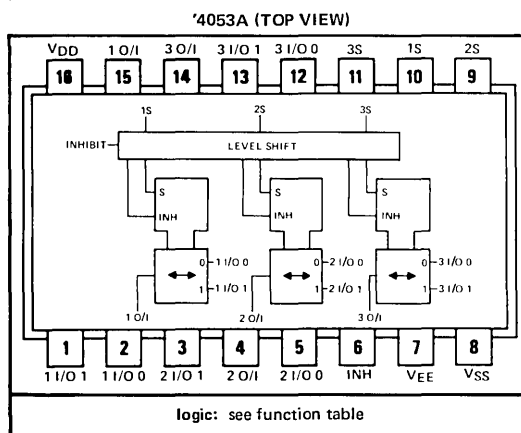
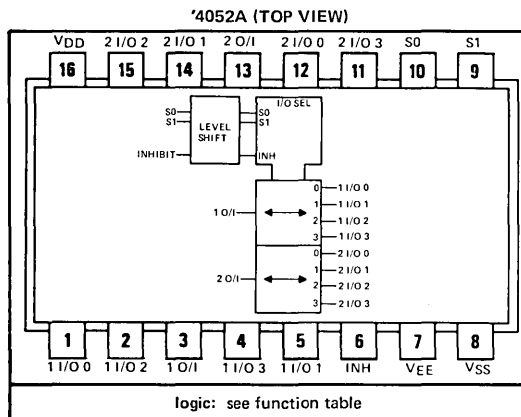
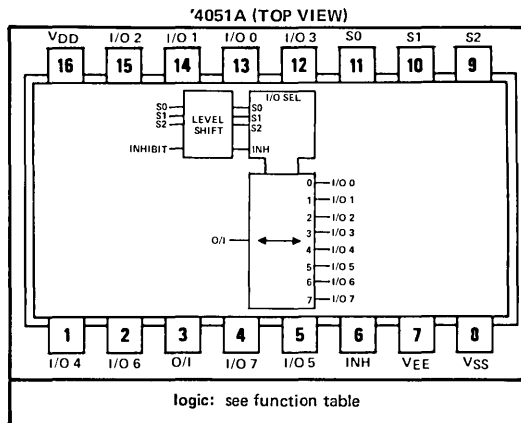
TYPICAL SUPPLY AND SIGNAL VOLTAGES

V_{DD}	15 V	10 V	7.5 V	7.5 V
V_{SS}	0 V	0 V	0 V	-7.5 V
V_{EE}	0 V	-5 V	-7.5 V	-7.5 V
Control Inputs	0 to 15 V	0 to 10 V	0 to 7.5 V	-7.5 to 7.5 V
Analog Signals	0 to 15 V	-5 to 10 V	-7.5 to 7.5 V	-7.5 to 7.5 V



INTERNAL POWER SUPPLY CONNECTIONS

J OR N DUAL-IN-LINE PACKAGES



TYPES TF4051A, TF4052A, TF4053A, TP4051A, TP4052A, TP4053A ANALOG MULTIPLEXERS/DEMULTIPLEXERS

description (continued)

These digitally controlled bilateral analog switches have low on-state impedance and very low off-state current. When the inhibit input terminal is high, all channels are off.

The '4051A is a single eight-channel multiplexer having three binary control inputs (S0, S1, and S2) and an inhibit input. The three binary signals select one of eight channels to be turned on.

The '4052A is a dual four-channel multiplexer having two binary control inputs (S0 and S1) and an inhibit input. The two binary signals select one of four channels in each of the two sections and the selected channels are respectively paired between the independent sections.

The '4053A is a triple two-channel multiplexer having three separate control inputs (1S, 2S, and 3S) and a common inhibit input. Each input independently selects one of two channels in one of the three sections so that any of eight combinations may be selected.

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62 and below	Page 62	Page 63, group 3, except as below. I_{OH} and I_{OL} do not apply.

absolute maximum ratings over operating free-air temperature range

Supply voltage V_{EE} (with respect to V_{DD}) -15 V

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted), $V_{EE} = V_{SS} = 0$ V

PARAMETER	TEST CONDITIONS	$V_{DD} = 5$ V		$V_{DD} = 10$ V		UNIT
		MIN	MAX	MIN	MAX	
V_{OH} High-level output voltage	Control inputs at V_{IH} min or V_{IL} max, Channel off, I/O at 0 V, $I_O = 10 \mu A$	4.5		9		V
V_{OL} Low-level output voltage	Control inputs at V_{IH} min or V_{IL} max, Channel on, I/O at 0 V, $I_O = 10 \mu A$		0.5		1	V
Input-to-output off-state current	Control inputs at 0 V or V_{DD} , Channel off, I/O at 5 V, O/I at 0 V to V_{DD} , $T_A = 25^\circ C$				± 125	nA

'4051A

FUNCTION TABLE

INH	INPUTS			CHANNEL TURNED ON
	S2	S1	S0	
H	X	X	X	None
L	L	L	L	0
L	L	L	H	1
L	L	H	L	2
L	L	H	H	3
L	H	L	L	4
L	H	L	H	5
L	H	H	L	6
L	H	H	H	7

'4052A

FUNCTION TABLE
(EACH BILATERAL SWITCH)

INH	INPUTS		CHANNEL TURNED ON
	S1	S0	
H	X	X	None
L	L	L	0
L	L	H	1
L	H	L	2
L	H	H	3

'4053A

FUNCTION TABLE
(EACH BILATERAL SWITCH)

INH	INPUTS		CHANNEL TURNED ON
	S		
H	X		None
L	L		0
L	H		1

H = high level, L = low level, X = irrelevant

TYPES TF4051A, TF4052A, TF4053A, TP4051A, TP4052A, TP4053A

ANALOG MULTIPLEXERS/DEMULTIPLEXERS

on-state resistance at 25°C free-air temperature, $R_L = 10\text{ k}\Omega$ to 0 V

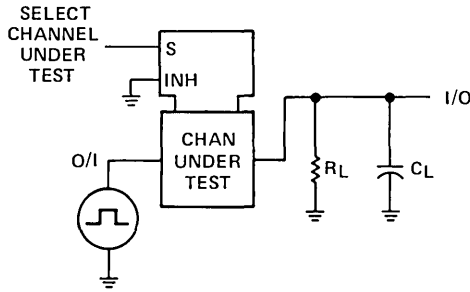
TEST CONDITIONS			TYP	MAX	UNIT
$V_{DD} = 7.5\text{ V}$	$V_{EE} = -7.5\text{ V}$,	$V_{SS} = 0\text{ V}$	80		Ω
$V_{DD} = 15\text{ V}$,	$V_{EE} = 0\text{ V}$,	$V_{SS} = 0\text{ V}$			
$V_{DD} = 5\text{ V}$,	$V_{EE} = -5\text{ V}$,	$V_{SS} = 0\text{ V}$	120		Ω
$V_{DD} = 10\text{ V}$,	$V_{EE} = 0\text{ V}$,	$V_{SS} = 0\text{ V}$			
$V_{DD} = 5\text{ V}$,	$V_{EE} = 0\text{ V}$,	$V_{SS} = 0\text{ V}$	270		Ω

switching characteristics at 25°C free-air temperature, $V_{EE} = V_{SS} = 0\text{ V}$

PARAMETER [†]	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		UNIT
				TYP	MAX	TYP	MAX	
t_{PLH}	O/I	I/O	$R_L = 10\text{ k}\Omega$, $C_L = 50\text{ pF}$, See Figure 1, $V_{EE} = V_{SS} = 0\text{ V}$	25		10		ns
t_{PHL}	O/I	I/O		25		10		
t_{PLH}	S	I/O	$C_L = 50\text{ pF}$, See Figure 2, $R_L = 10\text{ k}\Omega$ to 0 V	400		200		ns
t_{PHL}	S	I/O		$R_L = 10\text{ k}\Omega$ to V_{DD}	400		200	
t_{PLH}	INH	I/O	$R_L = 10\text{ k}\Omega$, $C_L = 50\text{ pF}$, See Figure 2		600		300	
t_{PHL}	INH	I/O		600		300		

[†] t_{PLH} ≡ Propagation delay time, low-to-high-level output.
 t_{PHL} ≡ Propagation delay time, high-to-low-level output.

PARAMETER MEASUREMENT



TEST CIRCUIT

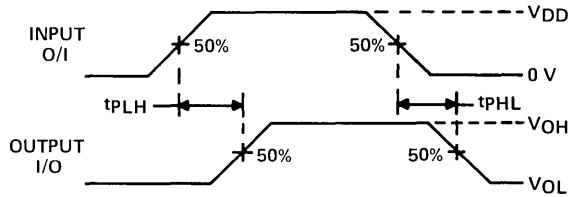
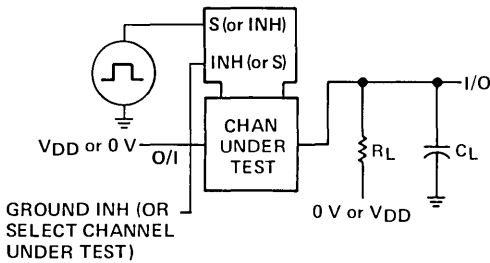


FIGURE 1

VOLTAGE WAVEFORMS



TEST CIRCUIT

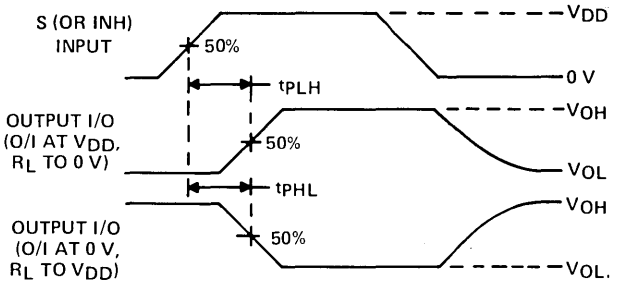


FIGURE 2

VOLTAGE WAVEFORMS

NOTES: A. Input pulses are supplied by generators having the following characteristics: $Z_{out} = 50\ \Omega$, $PRR = 10\text{ kHz}$, $t_r < 20\text{ ns}$, $t_f \leq 20\text{ ns}$.
 B. C_L includes probe and jig capacitance.
 C. The waveforms are monitored on an oscilloscope with the following characteristics: $t_r \leq 20\text{ ns}$, $R_{in} \geq 1\text{ M}\Omega$.

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CMOS LOGIC CIRCUITS

TYPES TF4301A, TP4301A QUAD 2-INPUT NOR BUFFERS

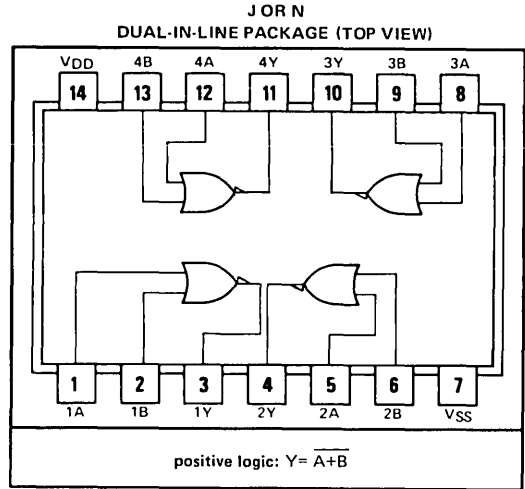
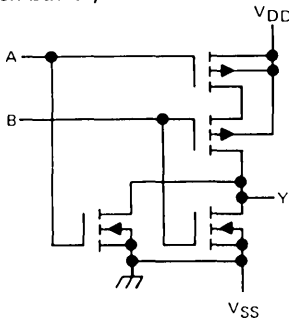
SEPTEMBER 1975

- Buffer Circuit Designed to be Plug-In Replacement for RCA CD4001A
- Improved Static and Dynamic Drive Characteristics

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 1, and below

schematic (each buffer)



electrical characteristics

PARAMETER	TEST CONDITIONS†	TF4301A		TP4301A		UNIT		
		V _{DD} = 5 V		V _{DD} = 10 V				
		MIN	MAX	MIN	MAX			
I _{OL} Low-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL} max	T _A = MIN		2	4	1.6	3.2	mA
		T _A = 25°C		1.6	3.2	1.3	2.6	
		T _A = MAX		1.1	2.2	0.9	1.8	

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4301A		TP4301A		UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	120	80	160	110	ns
t _{PHL} Propagation delay time, high-to-low-level output		100	70	130	100	ns
t _{TLH} Transition time, low-to-high-level output		300	150	400	200	ns
t _{THL} Transition time, high-to-low-level output		220	110	300	150	ns

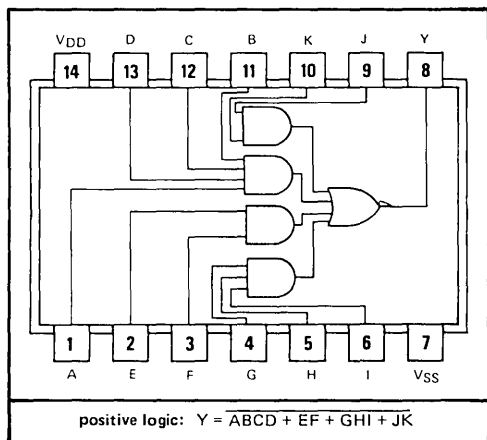
NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

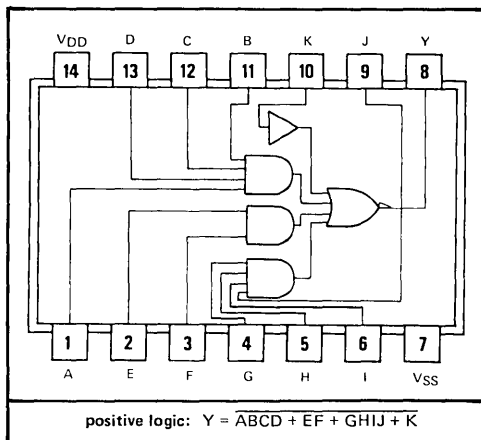
TYPES TF4302A, TF4303A, TP4302A, TP4303A AND-OR-INVERT GATES

SEPTEMBER 1975

J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)
TF4302A, TP4302A



J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)
TF4303A, TP4303A



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 1

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4302A, TF4303A		TP4302A, TP4303A		UNIT				
		V _{DD} = 5 V		V _{DD} = 10 V						
		MIN	MAX	MIN	MAX		MIN	MAX		
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	500		200		675		275		ns
t _{PHL} Propagation delay time, high-to-low-level output		500		200		675		275		ns
t _{TLH} Transition time, low-to-high-level output		350		150		400		225		ns
t _{THL} Transition time, high-to-low-level output		350		150		400		225		ns

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4304A, TP4304A HEX SCHMITT TRIGGER

SEPTEMBER 1975

- No External Components Required for Schmitt Trigger Action
- No Limit on Input Rise and Fall Times
- Typical Hysteresis . . . 0.6 V at $V_{DD} = 5\text{ V}$, 2 V at $V_{DD} = 10\text{ V}$

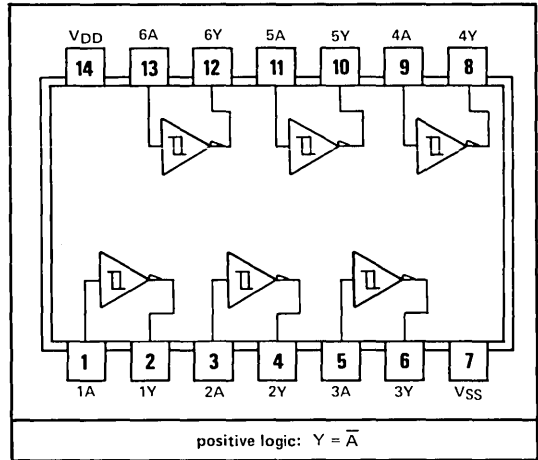
description

These circuits are hex inverting Schmitt triggers for use where low power dissipation and/or high noise immunity is desired. Applications include the speedup of a slow waveform edge in interface receivers, level detectors, etc.

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 2 except as below

J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



electrical characteristics (see note 1)

PARAMETER	TEST CONDITIONS	TF4304A				TP4304A				UNIT	
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$			
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
V_{T+} Positive-going threshold voltage	$T_A = 25^\circ\text{C}$	2.3	3.5	4.5	7	2.3	3.5	4.5	7	V	
V_{T-} Negative-going threshold voltage	$T_A = 25^\circ\text{C}$	1.5	2.7	3	5.5	1.5	2.7	3	5.5	V	
I_{DD} or $-I_{SS}$ Quiescent supply current	$V_I = 0$ or V_{DD} , No load	$T_A = \text{MIN or } 25^\circ\text{C}$		0.5		1		5		10	
		$T_A = \text{MAX}$		30		60		70		140	

$T_A = \text{MIN or MAX}$ refers to the respective values of free-air temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

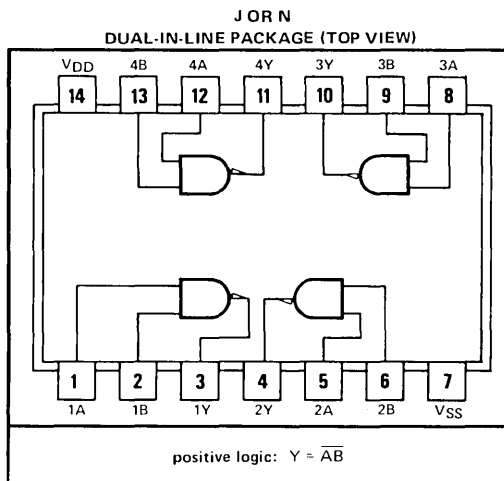
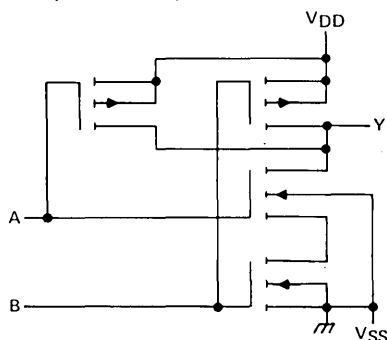
PARAMETER	TEST CONDITIONS	TF4304A				TP4304A				UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH} Propagation delay time, low-to-high-level output	$C_L = 50\text{ pF}$, $R_L = 200\text{ k}\Omega$, See Note 2	630		250		900		400		ns
t_{PHL} Propagation delay time, high-to-low-level output		630		250		900		400		
t_{TLH} Transition time, low-to-high-level output		350		150		400		225		
t_{THL} Transition time, high-to-low-level output		350		150		400		225		

NOTES: 1. When testing V_{OH} at $T_A = 25^\circ\text{C}$, V_{T+} min and V_{T-} min replace V_{IL} max. When testing V_{OL} at $T_A = 25^\circ\text{C}$, V_{T+} max and V_{T-} max replace V_{IH} min. Minimum and maximum levels of V_{T+} are set by applying an input voltage below V_{IL} max and then increasing it to the specified level. Minimum and maximum levels of V_{T-} are set by applying an input voltage above V_{IH} min and then decreasing it to the specified level.

2. See load circuit and voltage waveforms on page 170.

- Buffer Circuit Designed to be Plug-In Replacement for RCA CD4011A
- Improved Static and Dynamic Drive Characteristics

schematic (each buffer)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 1, except as below

electrical characteristics

PARAMETER	TEST CONDITIONS†	TF4311A		TP4311A		UNIT	
		V _{DD} = 5 V		V _{DD} = 10 V			
		MIN	MAX	MIN	MAX		
I _{OH} High-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OH} min	T _A = MIN	-0.65	-0.75	-0.35	-0.35	mA
		T _A = 25°C	-0.5	-0.6	-0.3	-0.3	
		T _A = MAX	-0.35	-0.4	-0.25	-0.25	
I _{OL} Low-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL} max	T _A = MIN	1	2	0.8	1.6	mA
		T _A = 25°C	0.75	1.6	0.65	1.3	
		T _A = MAX	0.55	1.1	0.45	0.9	

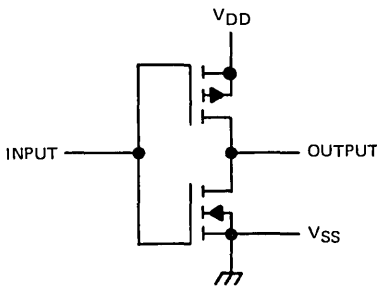
† T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

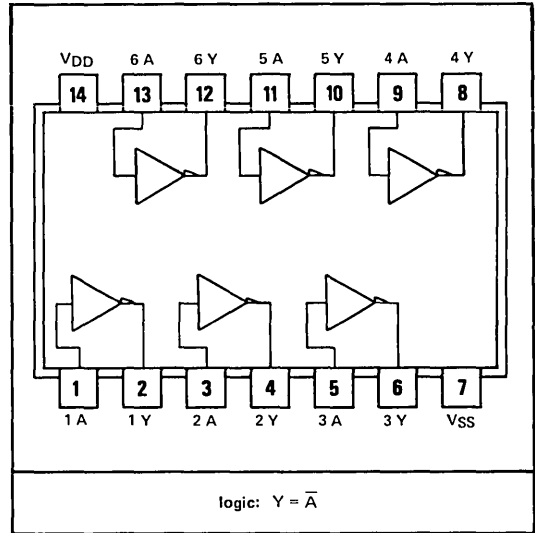
PARAMETER	TEST CONDITIONS	TF4311A		TP4311A		UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	100	70	130	100	ns
t _{PHL} Propagation delay time, high-to-low-level output		120	80	160	110	ns
t _{TLH} Transition time, low-to-high-level output		220	110	300	150	ns
t _{THL} Transition time, high-to-low-level output		300	150	400	200	ns

NOTE 1: See load circuit and voltage waveforms on page 170.

schematic (each buffer)



J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 1

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4315A		TP4315A		UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	135	75	180	100	ns
t _{PHL} Propagation delay time, high-to-low-level output		135	75	180	100	ns
t _{TLH} Transition time, low-to-high-level output		350	150	400	220	ns
t _{THL} Transition time, high-to-low-level output		350	150	400	220	ns

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4316A, TP4316A QUAD BILATERAL SWITCHES

SEPTEMBER 1975

- Designed to be Interchangeable with RCA CD4016A
- Difference in r_{on} between Switches in One Package Typically 10Ω when $V_I = V_{SS}$ or V_{DD}
- High Degree of Linearity . . . $< 0.5\%$ Distortion Typical at 1 kHz
- Switches Can Transmit Signals in Either Direction at Frequencies of up to 50 MHz Typically
- Extremely Low Off-State Switch Current Resulting in Very High Effective Off-State Resistance . . . 10 pA Typical at $V_{DD} - V_{SS} = 10 V$
- Maximum Control Input Frequency . . . 10 MHz Typical at $V_{DD} = 10 V, C_L = 15 pF, R_L = 1 k\Omega$
- High On/Off Output Voltage Ratio . . . 65 dB Typical
- Extremely High Control-Input Impedance (Control Circuit Isolated from Switch Circuit) . . . $10^{12} \Omega$ Typical
- Low Crosstalk Between Switches . . . 50 dB Typical at 0.9 MHz, $R_L = 1 k\Omega$
- Control Input Current . . . $< 10 pA$ Typical

description

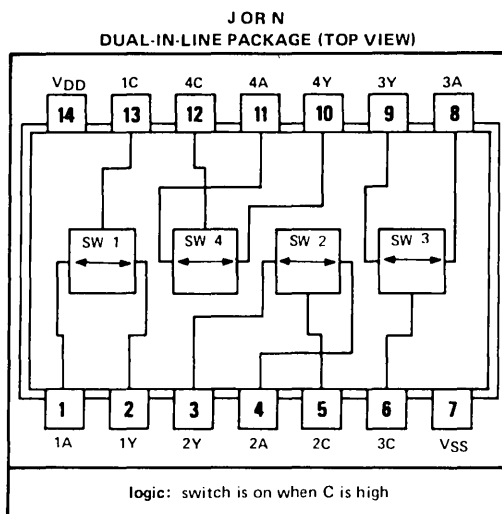
The '4316A is a quadruple bilateral switch constructed with P-channel and N-channel enhancement-type devices in a monolithic structure, and finds primary use where low power dissipation and/or high noise immunity is desired.

Applications include digital switching and multiplexing; analog-to-digital and digital-to-analog conversion; digital control of frequency, impedance, phase and analog-signal gain; signal gating; and use as a squelch control, chopper, modulator, demodulator, or commutating switch.

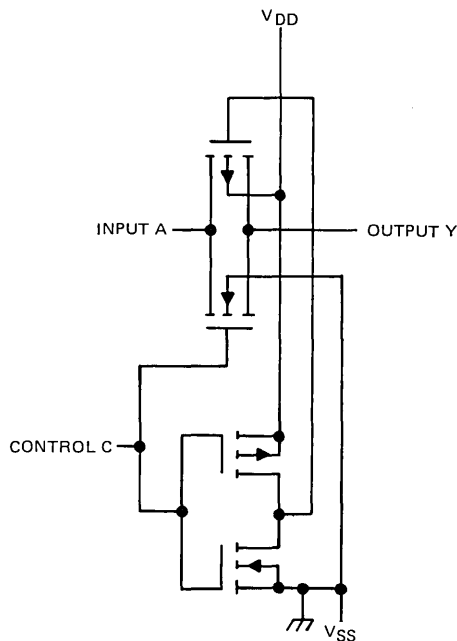
The P⁻ well is permanently connected to V_{SS}. This results in a higher average on-state resistance than the '4016A has but lower transient current into input A.

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	See the following page. Page 63 does not apply.



schematic (each switch)



TYPES TF4316A, TP4316A

QUAD BILATERAL SWITCHES

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

$V_{DD} = 5\text{ V}$ and 10 V

PARAMETER	TEST CONDITIONS†	$V_{DD} = 5$		TF4316A		TP4316A		UNIT
				$V_{DD} = 10\text{ V}$				
		MIN	MAX	MIN	MAX	MIN	MAX	
V_{IH} High-level control input voltage		3		4		4		V
V_{IL} Low-level control input voltage			0.9		0.9		0.9	V
V_{OH} High-level output voltage	A at 0 V, C at V_{IL} max, $I_O = 10\ \mu\text{A}$	4.5		9		9		V
V_{OL} Low-level output voltage	A at 0 V, C at V_{IH} min, $I_O = 10\ \mu\text{A}$		0.5		1		1	V
Input-to-output off-state current	A at 0 V to V_{DD} , C at 0 V, Y at 5 V, $T_A = 25^\circ\text{C}$				±125		±125	nA
Total Quiescent Current‡	A at 0 V to V_{DD} , C at 0 V, $T_A = \text{MIN or } 25^\circ\text{C}$				1		1	μA
	Y at 0 V to V_{DD} , $T_A = \text{MAX}$				60		16	μA
	A = Y = 0 V to V_{DD} , $T_A = \text{MIN or } 25^\circ\text{C}$				1		1	μA
	C at V_{DD} , $T_A = \text{MAX}$				60		16	μA

$V_{DD} = 15\text{ V}$

PARAMETER	TEST CONDITIONS†	TF4016A		TP4016A		UNIT
		MIN	MAX	MIN	MAX	
I_I Input current	$V_I = 0$ or V_{DD}		±1		±1	μA
I_{DD} or Quiescent supply current $-I_{SS}$	$V_I = V_{DD}$ or 0, No load, $T_A = \text{MIN or } 25^\circ\text{C}$		3		3	μA
			180		48	

† $T_A = \text{MIN or MAX}$ refers to the respective values of free-air temperature specified under recommended operating conditions.

‡ This is the total of supply current, control input current, and input-to-output off-state current.

on-state resistance at specified free-air temperature, C at V_{DD} , $R_L = 10\text{ k}\Omega$ to 0 V

TEST CONDITIONS†			TF4316A		TP4316A		UNIT
			MIN	MAX	MIN	MAX	
$V_{DD} = 5\text{ V}, V_{SS} = -5\text{ V}$	A at 5 V or -5 V	$T_A = \text{MIN}$	600		610		Ω
		$T_A = 25^\circ\text{C}$	660		660		
		$T_A = \text{MAX}$	960		840		
	A at 0.25 V or -0.25 V	$T_A = \text{MIN}$	1870		1900		Ω
		$T_A = 25^\circ\text{C}$	2000		2000		
		$T_A = \text{MAX}$	2600		2380		
$V_{DD} = 7.5\text{ V}, V_{SS} = -7.5\text{ V}$	A at 7.5 V or -7.5 V	$T_A = \text{MIN}$	360		370		Ω
		$T_A = 25^\circ\text{C}$	400		400		
		$T_A = \text{MAX}$	600		520		
	A at 0.25 V or -0.25 V	$T_A = \text{MIN}$	775		790		Ω
		$T_A = 25^\circ\text{C}$	850		850		
		$T_A = \text{MAX}$	1230		1080		
$V_{DD} = 10\text{ V}, V_{SS} = 0\text{ V}$	A at 10 V or 0.25 V	$T_A = \text{MIN}$	600		610		Ω
		$T_A = 25^\circ\text{C}$	660		660		
		$T_A = \text{MAX}$	960		840		
	A at 5.6 V	$T_A = \text{MIN}$	1870		1900		Ω
		$T_A = 25^\circ\text{C}$	2000		2000		
		$T_A = \text{MAX}$	2600		2380		
$V_{DD} = 15\text{ V}, V_{SS} = 0\text{ V}$	A at 15 V or 0.25 V	$T_A = \text{MIN}$	360		370		Ω
		$T_A = 25^\circ\text{C}$	400		400		
		$T_A = \text{MAX}$	600		520		
	A at 9.3 V	$T_A = \text{MIN}$	775		790		Ω
		$T_A = 25^\circ\text{C}$	850		850		
		$T_A = \text{MAX}$	1230		1080		

† $T_A = \text{MIN or MAX}$ refers to the respective values of free-air temperature specified under recommended operating conditions.

TYPES TF4316A, TP4316A QUAD BILATERAL SWITCHES

switching characteristics at 25°C free-air temperature

PARAMETER†	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{DD} = 5 V		V _{DD} = 10 V		UNIT
				TYP	MAX	TYP	MAX	
t _{PLH}	A	Y	R _L = 10 kΩ, C _L = 50 pF, C at V _{DD} , See Figure 1	30	15	ns		
t _{PHL}	A	Y		30	15			
t _{PLH}	C	Y	C _L = 50 pF, See Figure 2	80	30	ns		
t _{PHL}	C	Y		R _L = 10 kΩ to 0 V	80		30	
				R _L = 10 kΩ to V _{DD}				

†t_{PLH} ≡ Propagation delay time, low-to-high-level output
 †t_{PHL} ≡ Propagation delay time, high-to-low-level output

PARAMETER MEASUREMENT INFORMATION

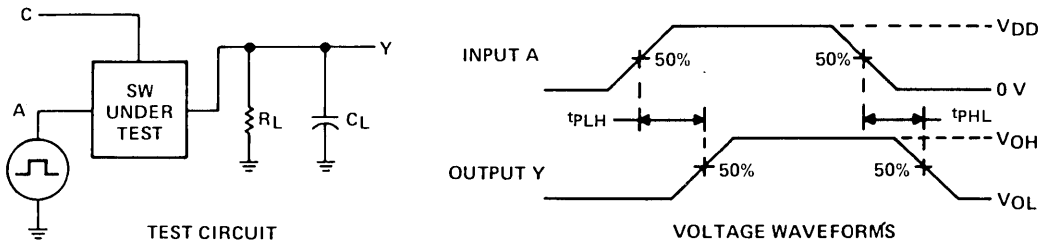


FIGURE 1—PROPAGATION DELAY TIME, SWITCH INPUT A TO OUTPUT Y

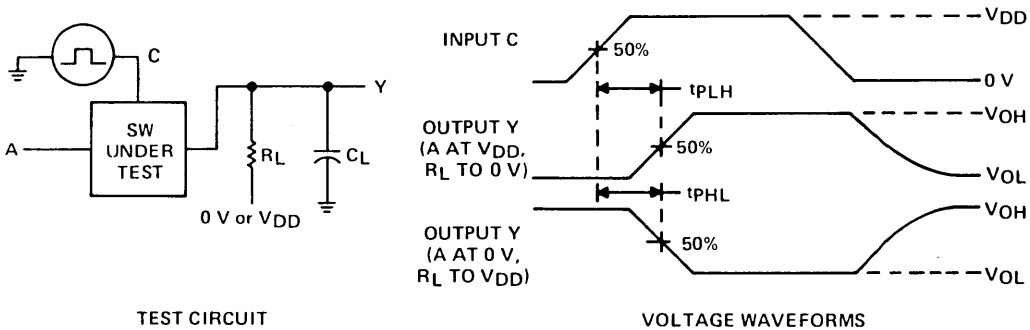


FIGURE 2—PROPAGATION DELAY TIMES, CONTROL INPUT C TO OUTPUT Y

NOTES: A. Input pulses are supplied by generators having the following characteristics: Z_{out} = 50 Ω, PRR = 10 kHz, t_r ≤ 20 ns, t_f ≤ 20 ns.
 B. C_L includes probe and jig capacitance.
 C. The waveforms are monitored on an oscilloscope with the following characteristics: t_r < 10 ns, R_{in} > 1 MΩ.

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CMOS LOGIC CIRCUITS

TYPES TF4320A, TP4320A 16-CHANNEL DATA SELECTORS WITH 3-STATE OUTPUTS

SEPTEMBER 1975

• 3-State Output

description

These circuits are single 16-channel data selectors having four digital select inputs, S0, S1, S2, and S3, and an output control. When the output control is low, the output will be in the high-impedance (off) state. Applications of this device include signal multiplexing, data routing, and number sequence generation.

FUNCTION TABLE

OUTPUT CONTROL	INPUTS				OUTPUT Y
	S3	S2	S1	S0	
L	X	X	X	X	Z
H	L	L	L	L	D0
H	L	L	L	H	D1
H	L	L	H	L	D2
H	L	L	H	H	D3
H	L	H	L	L	D4
H	L	H	L	H	D5
H	L	H	H	L	D6
H	L	H	H	H	D7
H	H	L	L	L	D8
H	H	L	L	H	D9
H	H	L	H	L	D10
H	H	L	H	H	D11
H	H	H	L	L	D12
H	H	H	L	H	D13
H	H	H	H	L	D14
H	H	H	H	H	D15

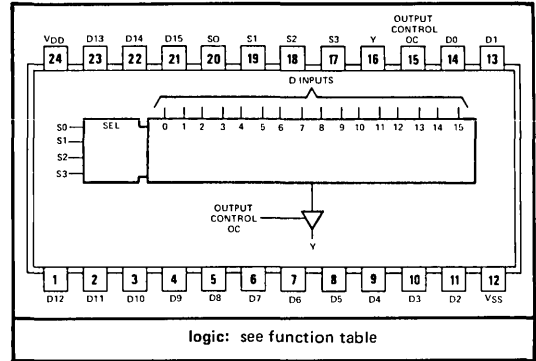
H = high level, L = low level, X = irrelevant, Z = high-impedance (off)
D0 . . . D15 = the logic level of the indicated D input.

electrical characteristics

PARAMETER	TEST CONDITIONS†	TF4320A		TP4320A		UNIT	
		V _{DD} = 5 V		V _{DD} = 10 V			
		MIN	MAX	MIN	MAX		
I _{OH} High-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OHI} min	T _A = MIN	-0.5	-0.5	-0.25	-0.25	mA
		T _A = 25°C	-0.4	-0.4	-0.2	-0.2	
		T _A = MAX	-0.3	-0.3	-0.17	-0.17	
I _{OL} Low-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL} max	T _A = MIN	0.3	0.6	0.2	0.35	mA
		T _A = 25°C	0.25	0.5	0.15	0.3	
		T _A = MAX	0.2	0.4	0.12	0.25	
I _{OZH} Off-state output current, high-level voltage applied	OC at V _{SS} , V _O = V _{DD}	T _A = MIN or 25°C	0.05	0.1	0.5	1	μA
		T _A = MAX	3	6	7	14	
I _{OZL} Off-state output current, low-level voltage applied	OC at V _{SS} , V _O = 0 V	T _A = MIN or 25°C	-0.05	-0.1	-0.5	-1	μA
		T _A = MAX	-3	-6	-7	-14	

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 3, and below

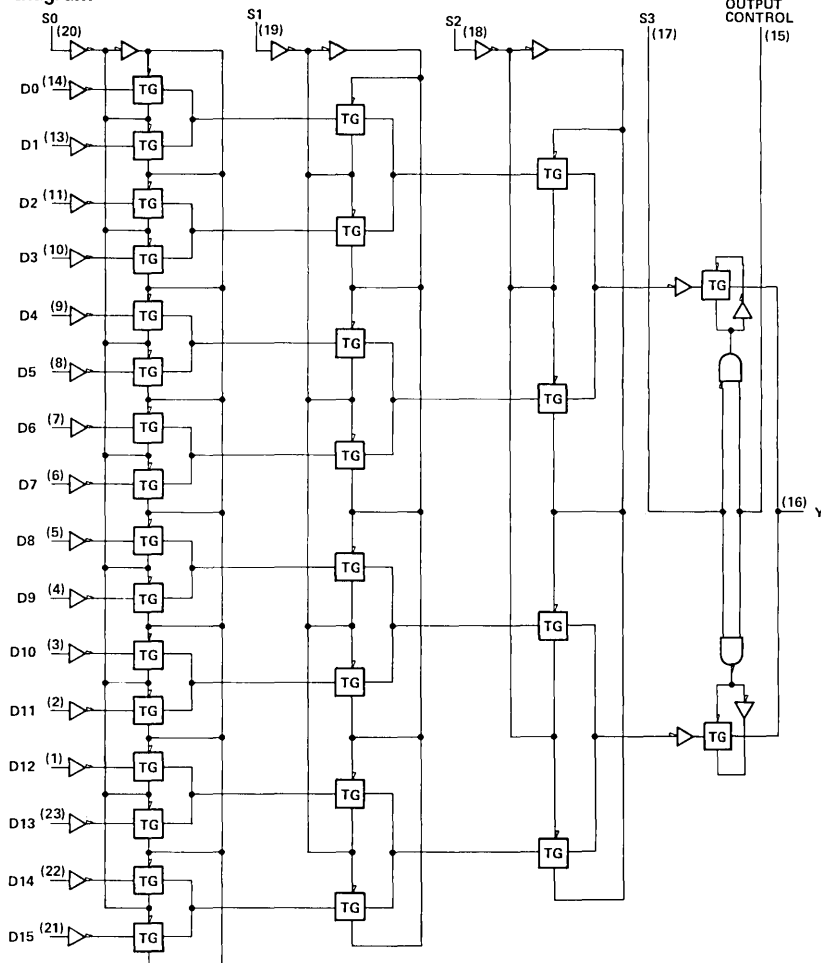
TYPES TF4320A, TP4320A 16-CHANNEL DATA SELECTORS WITH 3-STATE OUTPUTS

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4320A				TP4320A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	750		325		1000		375		ns
t _{PHL} Propagation delay time, high-to-low-level output		750		325		1000		375		ns
t _{TLH} Transition time, low-to-high-level output		500		250		600		300		ns
t _{THL} Transition time, high-to-low-level output		500		250		600		300		ns
tpZH Output enable time to high level	C _L = 50 pF, R _L = 10 kΩ, See Note 1	430		150		500		200		ns
tpZL Output enable time to low level		250		130		300		170		
tPHZ Output disable time from high level		260		170		320		240		
tPLZ Output disable time from low level		160		140		220		200		

NOTE 1: See load circuit and voltage waveforms on page 170.

functional block diagram



• 3-State Output description

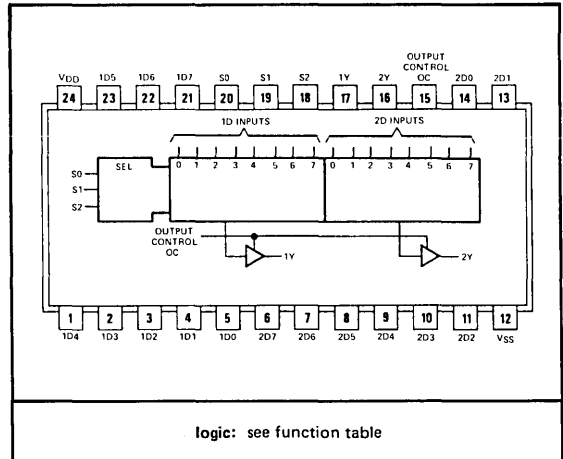
These circuits are dual 8-channel data selectors having three digital select inputs, S0, S1, and S2, and an output control. When the output control is low, both outputs will be in the high-impedance (off) state. Applications of this device include signal multiplexing, data routing, and number sequence generation.

FUNCTION TABLE
(EACH SELECTOR)

OUTPUT CONTROL	INPUTS			OUTPUT Y
	S2	S1	S0	
L	X	X	X	Z
H	L	L	L	D0
H	L	L	H	D1
H	L	H	L	D2
H	L	H	H	D3
H	H	L	L	D4
H	H	L	H	D5
H	H	H	L	D6
H	H	H	H	D7

H = high level, L = low level, X = irrelevant, Z = high-impedance (off).
D0 . . . D7 = the logic level of the indicated D input.

J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



logic: see function table

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 3, and below

electrical characteristics

PARAMETER	TEST CONDITIONS†	TF4321A		TP4321A		UNIT	
		VDD = 5 V		VDD = 10 V			
		MIN	MAX	MIN	MAX		
IOH High-level output current	VIH = VDD, VIL = 0, VO = VOH min	TA = MIN	-0.5	-0.5	-0.25	-0.25	mA
		TA = 25°C	-0.4	-0.4	-0.2	-0.2	
		TA = MAX	-0.3	-0.3	-0.17	-0.17	
IOL Low-level output current	VIH = VDD, VIL = 0, VO = VOL max	TA = MIN	0.3	0.6	0.2	0.35	mA
		TA = 25°C	0.25	0.5	0.15	0.3	
		TA = MAX	0.2	0.4	0.12	0.25	
IOZH Off-state output current, high-level voltage applied	OC at VSS, VO = VDD	TA = MIN or 25°C	0.05	0.1	0.5	1	µA
		TA = MAX	3	6	7	14	
IOZL Off-state output current, low-level voltage applied	OC at VSS, VO = 0 V	TA = MIN or 25°C	-0.05	-0.1	-0.5	-1	µA
		TA = MAX	-3	-6	-7	-14	

†TA = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

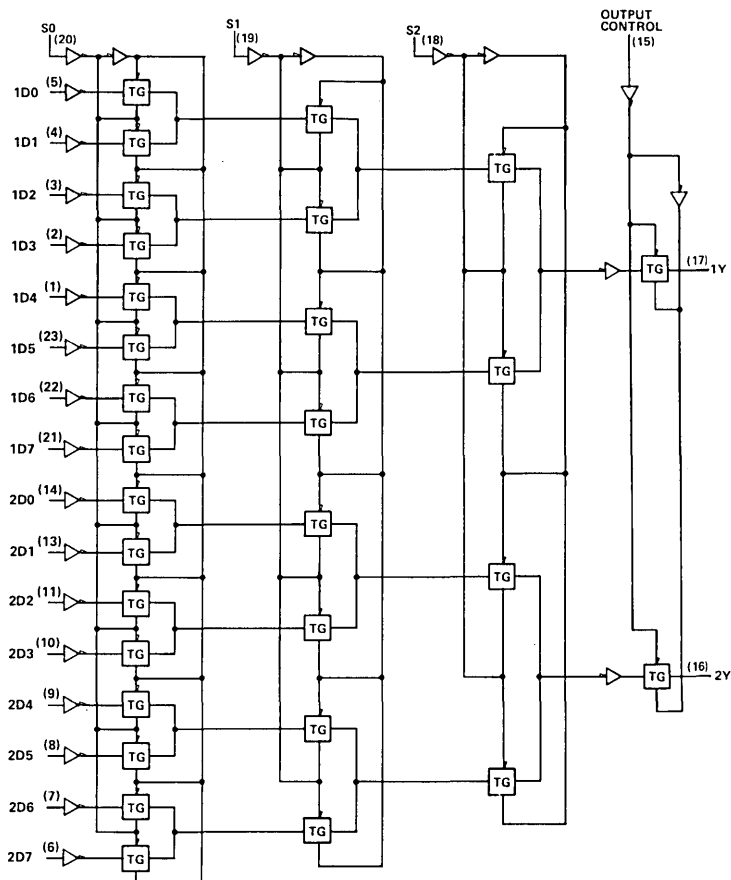
TYPES TF4321A, TP4321A DUAL 8-CHANNEL DATA SELECTORS WITH 3-STATE OUTPUTS

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4321A				TP4321A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	750		325		1000		375		ns
t _{PHL} Propagation delay time, high-to-low-level output		750		325		1000		375		ns
t _{TLH} Transition time, low-to-high-level output		500		250		600		300		ns
t _{THL} Transition time, high-to-low-level output		500		250		600		300		ns
t _{pZH} Output enable time to high level	C _L = 50 pF, R _L = 10 kΩ, See Note 1	430		150		500		200		ns
t _{pZL} Output enable time to low level		250		130		300		170		ns
t _{pHZ} Output disable time from high level		260		170		320		240		ns
t _{pLZ} Output disable time from low level		160		140		220		200		ns

NOTE 1: See load circuit and voltage waveforms on page 170.

functional block diagram



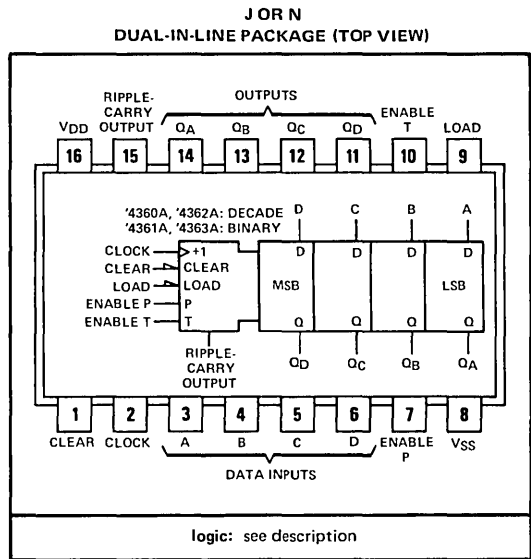
- '4360A DECADE COUNTER WITH ASYNCHRONOUS CLEAR
- '4361A BINARY COUNTER WITH ASYNCHRONOUS CLEAR
- '4362A DECADE COUNTER WITH SYNCHRONOUS CLEAR
- '4363A BINARY COUNTER WITH SYNCHRONOUS CLEAR

- Designed to be Interchangeable with National Semiconductor MM54C160, MM74C160, MM54C161, MM74C161, MM54C162, MM74C162, MM54C163, and MM74C163
- Counting Rate . . . 8 MHz
Typical at $V_{DD} = 10\text{ V}$

description

These synchronous presettable up counters feature an internal carry look-ahead for cascading packages without additional gating in high-speed counting systems.

A low level at the load input disables the counter and causes the outputs to agree with the setup data after the next low-to-high transition of the clock. The clear function of the '4360A and '4361A is asynchronous and a low level at the clear input sets all four of the flip-flop outputs low regardless of the levels of the clock, load, or enable inputs. The clear function of the '4362A and '4363A is synchronous and a low level at the clear input sets all four outputs low after the next low-to-high transition of the clock regardless of the levels of the load or enable inputs. Both count-enable inputs (P and T) must be high to count, and T is fed forward to enable the ripple-carry output. The ripple-carry output thus enabled will produce a high-level output pulse with a duration approximately equal to the high-level portion of the Q_A output. This high-level overflow ripple-carry pulse can be used to enable successive cascaded stages. Transitions at the enable P or T inputs are allowed regardless of the level of the clock input.

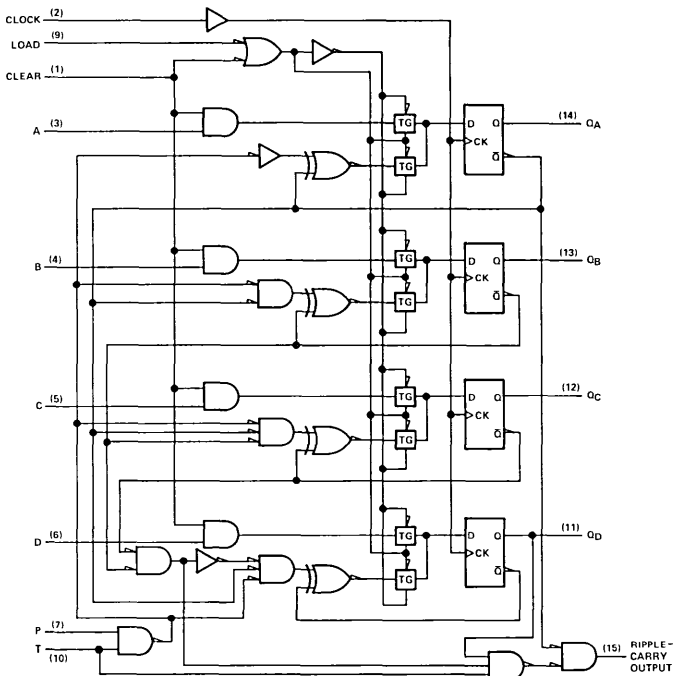


**TYPES TF4360A THRU TF4363A, TP4360A THRU TP4363A
SYNCHRONOUS 4-BIT DECADE AND BINARY COUNTERS**

functional block diagrams

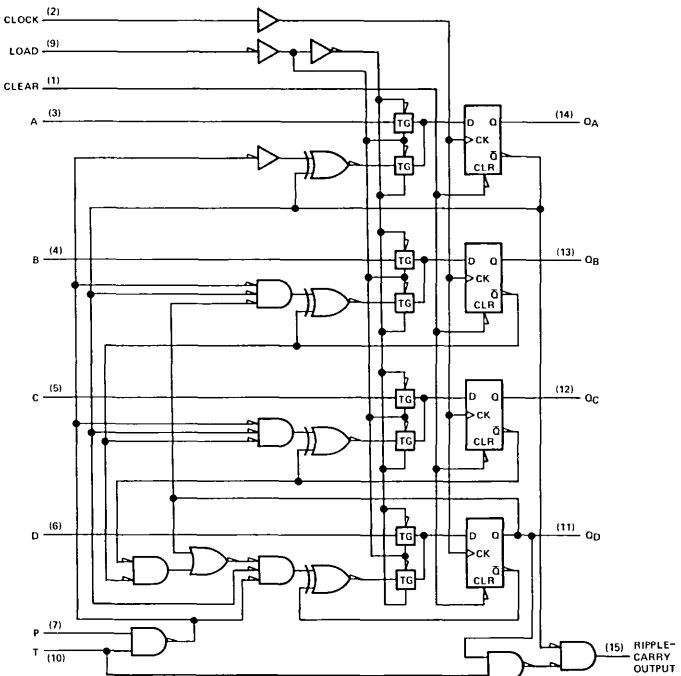
'4363A BINARY COUNTER WITH SYNCHRONOUS CLEAR

'4361A binary counters are similar; however, the clear is direct (asynchronous) as shown for the '4360A decade counters at left.



'4360A DECADE COUNTER WITH ASYNCHRONOUS CLEAR

'4362A decade counters are similar; however, the clear is synchronous as shown for the '4363A binary counters at right.



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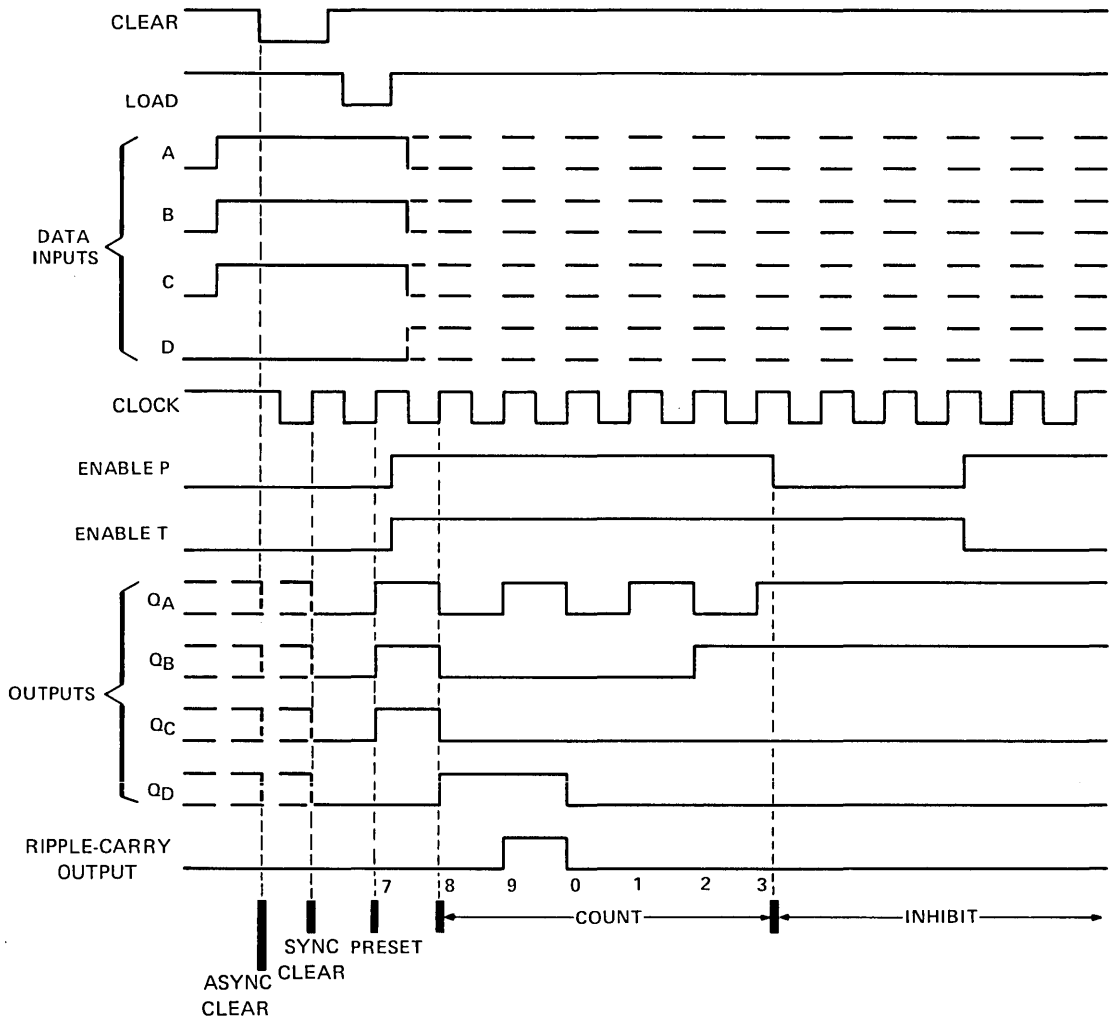
TYPES TF4360A THRU TF4363A, TP4360A THRU TP4363A SYNCHRONOUS 4-BIT DECADE AND BINARY COUNTERS

'4360A AND '4362A DECADE COUNTERS

typical clear, preset, count, and inhibit sequences

Illustrated below is the following sequence:

1. Clear output to zero ('4360A is asynchronous, '4362A is synchronous)
2. Preset to BCD seven
3. Count to eight, nine, zero, one, two, and three
4. Inhibit



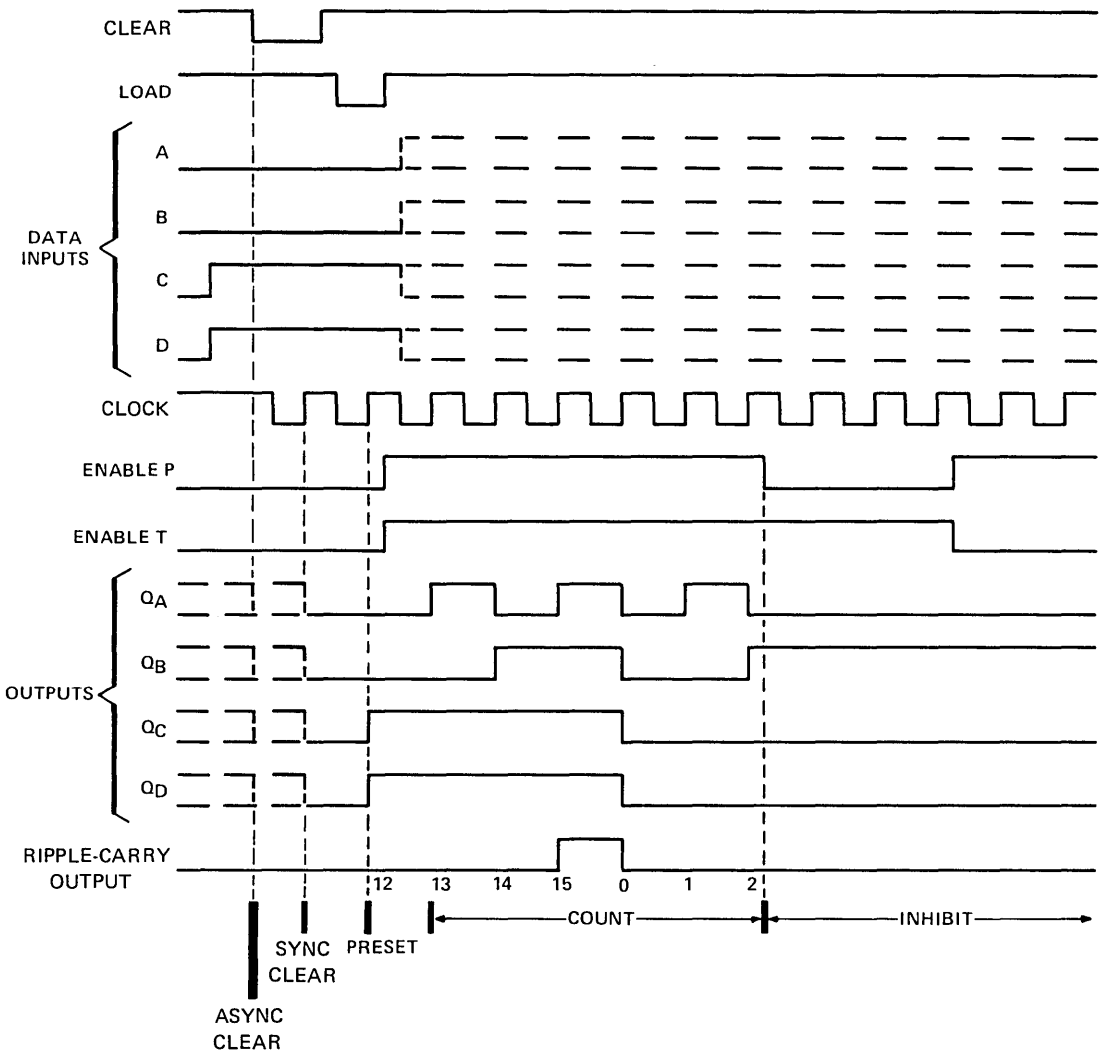
TYPES TF4360A THRU TF4363A, TP4360A THRU TP4363A SYNCHRONOUS 4-BIT DECADE AND BINARY COUNTERS

'4361A AND '4363A BINARY COUNTERS

typical clear, preset, count, and inhibit sequences

Illustrated below is the following sequence:

1. Clear outputs to zero ('4361A is asynchronous, '4363A is synchronous)
2. Preset to binary twelve
3. Count to thirteen, fourteen fifteen, zero, one, and two
4. Inhibit



TF4360A THRU TF4363A, TP4360A THRU TP4363A SYNCHRONOUS 4-BIT DECADE AND BINARY COUNTERS

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and below	Page 63, group 3

recommended operating conditions

		TF4360A, TF4361A TF4362A, TF4363A		TP4360A, TP4361A TP4362A, TP4363A		UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	
Width of clock pulse, t _w (clock)	Clock high or low	200	90	300	150	ns
	Data or load	200	80	300	110	
Setup time, t _{su}	Enable P or T	375	150	500	200	ns
	Clear [◇]	250	100	350	135	

◇ This applies only for '4362A and '4363A, which have synchronous clear inputs.

switching characteristics at 25°C free-air temperature

PARAMETER ‡	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4360A, TF4361A TF4362A, TF4363A		TP4360A, TP4361A TP4362A, TP4363A		UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	
f _{max}				1	3	0.6	2.5	MHz
t _{PLH}	Clock	Any Q	C _L = 50 pF, R _L = 200 kΩ, See Note 1	550	200	750	275	ns
t _{PHL}				550	200	750	275	
t _{PLH}	Clock	Ripple-carry output		650	250	850	350	ns
t _{PHL}				650	250	850	350	
t _{PLH}	Enable T	Ripple-carry output		350	175	490	240	ns
t _{PHL}				350	175	490	240	
t _{PHL} [□]	Clear	Any Q		400	250	550	350	ns
t _{TLH}		Any		300	150	400	220	ns
t _{THL}				300	150	400	220	

‡ f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

t_{THL} ≡ Transition time, high-to-low-level output

□ This applies only for '4360A and '4361A, which have asynchronous clear inputs.

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4370A, TP4370A QUAD D-TYPE EDGE-TRIGGERED FLIP-FLOPS

SEPTEMBER 1975

- Maximum Clock Frequency . . . 10 MHz
Typical at 10 V

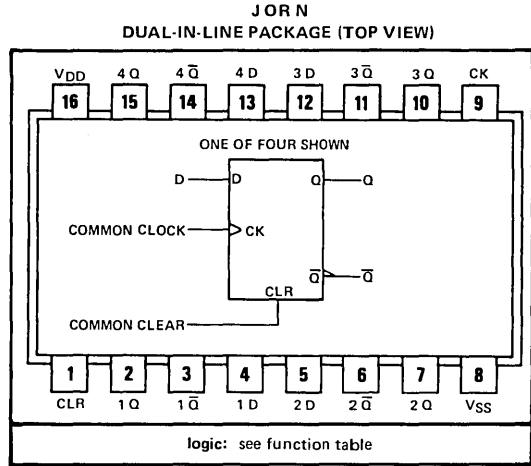
description

These circuits are quad D-type transition-operated master-slave flip-flops with buffered outputs, common direct overriding clear input, and D and clock inputs. While the clock is low, the data at the D input is entered into the master section, which is isolated from the slave section. On the rising transition of the clock, the D input is disabled and data previously set up in the master section is transferred to the slave section and appears in true form at the Q output and in complementary form at the \bar{Q} output.

Clearing is independent of the clock and is accomplished by a high-level voltage at the clear input.

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 63 and on following page	Page 63, group 3

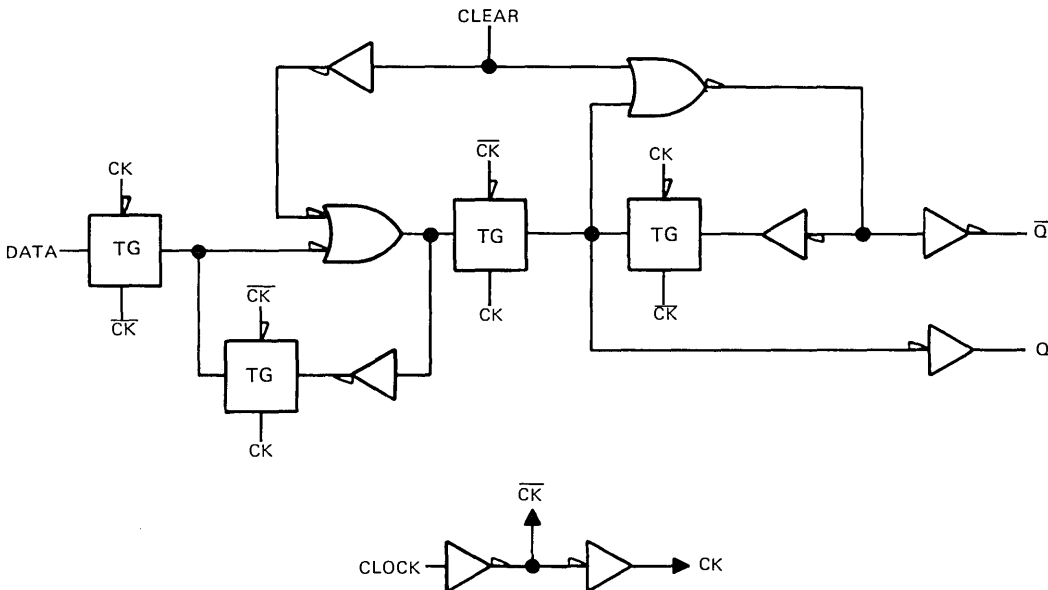


FUNCTION TABLE
(EACH FLIP-FLOP)

Clear	INPUTS		OUTPUTS	
	CK	D	Q	\bar{Q}
H	X	X	L	H
L	↑	L	L	H
L	↑	H	H	L
L	L	X	Q_0	\bar{Q}_0

See explanation of function tables on pages 16 and 17.

functional block diagram (each flip-flop)



TYPES TF4370A, TP4370A

QUAD D-TYPE EDGE-TRIGGERED FLIP-FLOPS

recommended operating conditions

		TF4370A				TP4370A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Pulse width, t _w	Clock high or low	200		80		500		100		ns
	Clear	250		100		500		125		ns
Setup time, t _{su}		60		20		120		30		ns

switching characteristics at 25°C free-air temperature

PARAMETER†	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4370A				TP4370A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}			C _L = 50 pF, R _L = 200 kΩ, See Note 1	2.5		7		1		5		MHz
t _{PLH} or t _{PHL}	Clock	Any Q or \bar{Q}		475		185		500		235		ns
t _{PLH} or t _{PHL}	Clear	Any Q or \bar{Q}		475		185		550		235		ns
t _{TLH} or t _{THL}		Any		350		150		400		220		ns

†f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

t_{THL} ≡ Transition time, high-to-low-level output

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4376A, TF4377A, TP4376A, TP4377A QUAD S-R AND \bar{S} - \bar{R} LATCHES

SEPTEMBER 1975

- Same as TF4043A, TF4044A, TP4043A, and TP4044A, Respectively, except with Normal 2-State Totem-Pole Outputs

description

The '4376 and '4377A are quadruple S-R and \bar{S} - \bar{R} latches, respectively, with normal two-state totem-pole outputs. Each latch has separate active-high ('4376A) or active-low ('4377A) set and reset inputs.

FUNCTION TABLES
(EACH LATCH)
TF4376A, TP4376A

INPUTS		OUTPUT
S	R	Q
L	L	No change
H	L	H
L	H	L
H	H	H*

TF4377A, TP4377A

INPUTS		OUTPUT
\bar{S}	\bar{R}	Q
H	H	No change
L	H	H
H	L	L
L	L	L*

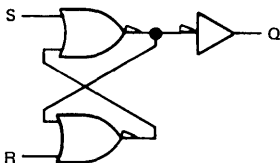
*This output level is psuedo stable; that is, it may not persist when the S and R inputs return to their inactive (low) level or the \bar{S} and \bar{R} inputs return to their inactive (high) level. See explanation of function tables, pages 16 and 17.

specifications

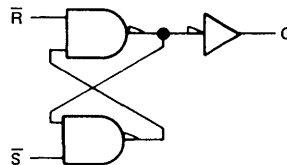
MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and below	Page 63, group 3, except as on following page

functional block diagrams (each latch)

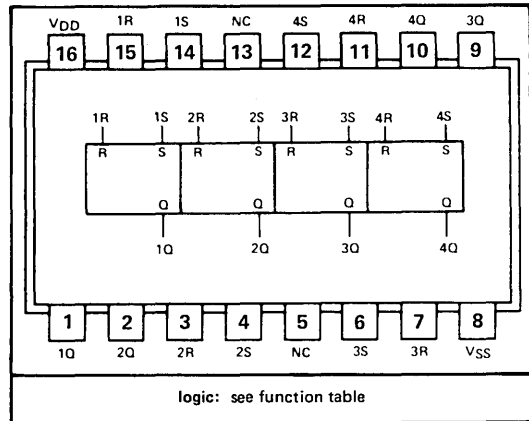
TF4376A, TP4376A



TF4377A, TP4377A

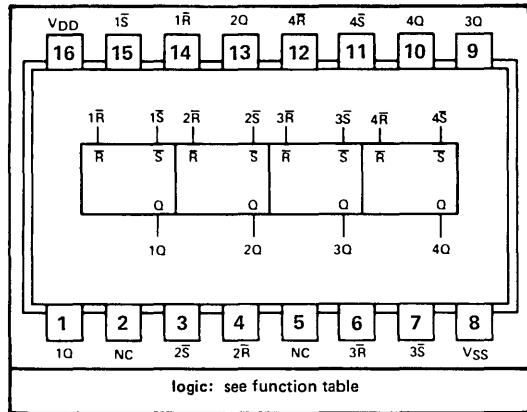


J O R N
DUAL-IN-LINE PACKAGE (TOP VIEW)
TF4376A, TP4376A



NC—No internal connection

TF4377A, TP4377A



NC—No internal connection

TYPES TF4376A, TF4377A, TP4376A, TP4377A

QUAD S-R AND \bar{S} - \bar{R} LATCHES

recommended operating conditions

	TF4376A, TF4377A				TP4376A, TP4377A				UNIT
	V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Pulse width, set or reset, t _w	200		100		225		110		ns

electrical characteristics

V_{DD} = 5 V and 10 V

PARAMETER	TEST CONDITIONS†		TF4376A, TF4377A				TP4376A, TP4377A				UNIT
			V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
I _{DD} or Quiescent supply current -I _{SS}	V _I = V _{DD} or 0, No load	T _A = MIN or 25°C	1		2		10		20		μA
		T _A = MAX	60		120		140		280		

V_{DD} = 15 V

PARAMETER	TEST CONDITIONS†		TF4376A, TF4377A		TP4376A, TP4377A		UNIT
			MIN	MAX	MIN	MAX	
			I _{DD} or Quiescent supply current -I _{SS}	V _I = V _{DD} or 0, No load	T _A = MIN or 25°C	6	
T _A = MAX	360				840		

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4376A, TF4377A				TP4376A, TP4377A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF, R _L = 200 kΩ, See Note 1	500		235		575		300		ns
t _{PHL} Propagation delay time, high-to-low-level output		500		235		575		300		ns
t _{TLH} Transition time, low-to-high-level output		325		135		375		200		ns
t _{THL} Transition time, high-to-low-level output		325		135		375		200		ns

NOTE 1: See load circuit and voltage waveforms on page 170.

**FUTURE CMOS PRODUCT
TO BE ANNOUNCED**

**TYPES TF4380A, TP4380A
256-BIT RANDOM-ACCESS MEMORIES
WITH 3-STATE OUTPUTS**

SEPTEMBER 1975

- Static Memory
- Fully Decoded, Organized as 256 Words of 1 Bit Each
- Multiple Chip Enables
- 3-State Output
- High-Speed Operation

description

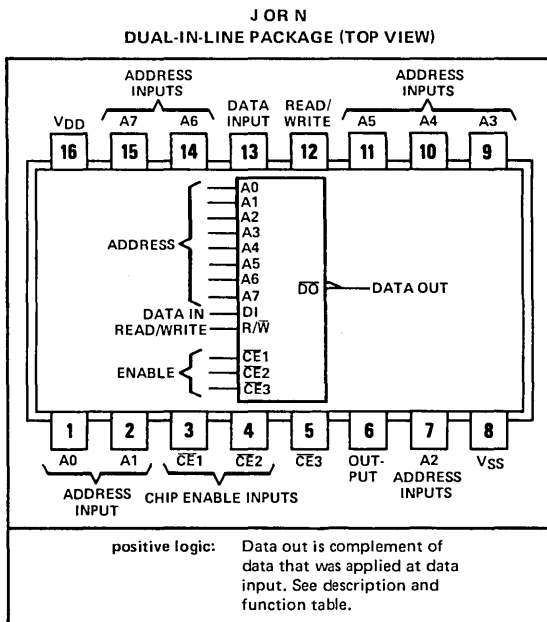
This 256-bit active-element memory is a monolithic CMOS array organized as 256 words of one bit each. It is fully decoded and has three gated chip-enable inputs to simplify decoding required to achieve the desired system organization. At least one chip enable input must be high whenever the address is changed to avoid erroneous alteration of stored data. The '4380A features a three-state output to facilitate word expansion.

write cycle

Information to be stored in the memory is written into the selected address location when all chip-enable inputs and the read/write input are low. While the read/write input is low, the output is in the high-impedance state. When a number of outputs are bus-connected, this high-impedance output state will neither load nor drive the bus line, but it will allow the bus line to be driven by another active output or a passive pull-up if desired.

read cycle

The complement of information applied at the data input during the write cycle is available at the output when the read/write input is high and the three chip-enable inputs are low. When any one of the chip-enable inputs is high, the output will be in the high-impedance state.



FUNCTION TABLE

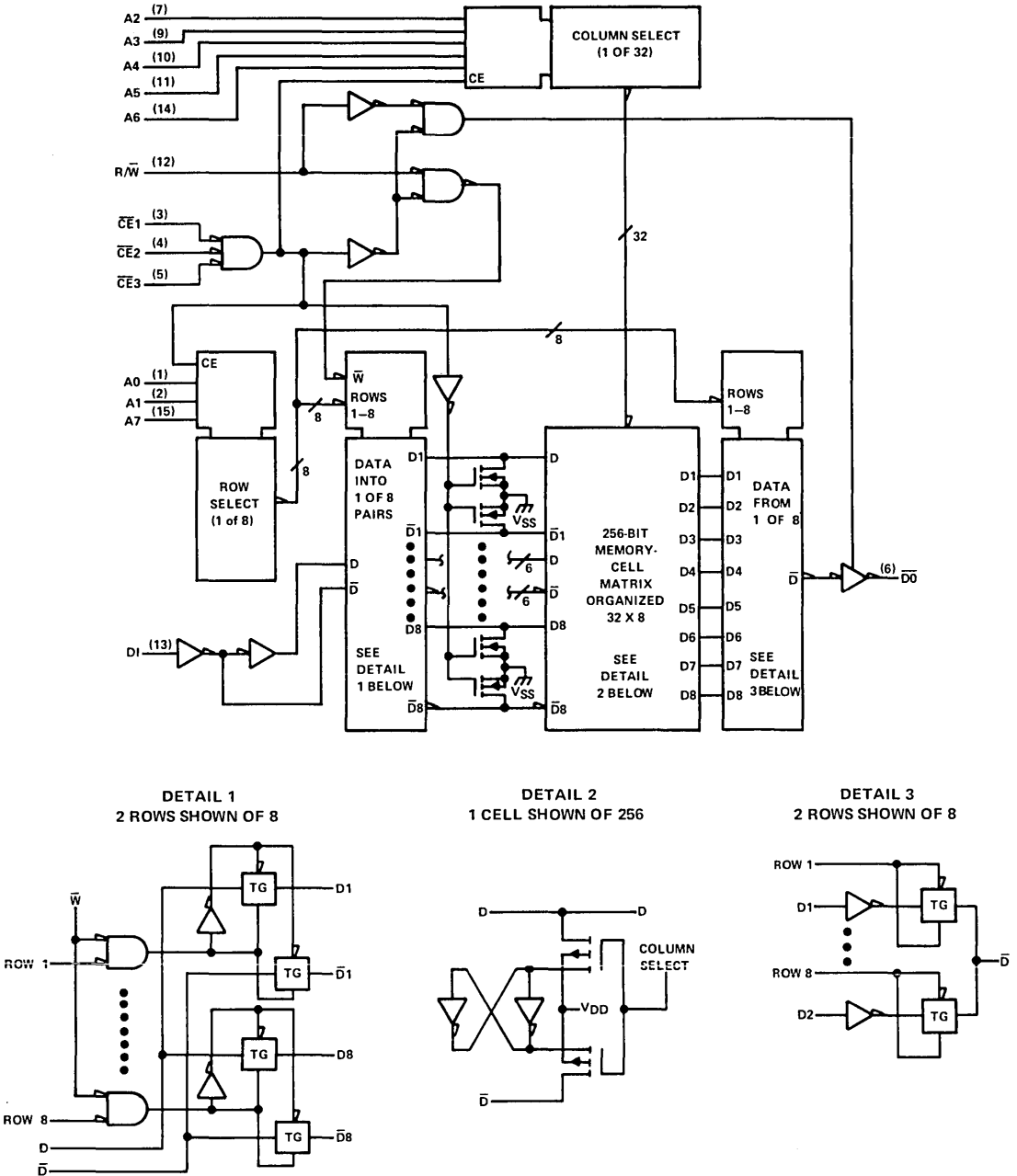
FUNCTION	INPUTS		OUTPUT
	CHIP ENABLE	READ/WRITE	
Write	LLL	L	High Impedance
Read	LLL	H	Complement of Data Entered
Inhibit	HXX	X	High Impedance

H = high level, L = low level, X = irrelevant,
LLL = all CE inputs low,
HXX = one or more CE inputs high.

TYPES TF4380A, TP4380A

256-BIT RANDOM-ACCESS MEMORIES WITH 3-STATE OUTPUTS

functional block diagram



TYPES TF4380A, TP4380A

256-BIT RANDOM-ACCESS MEMORIES WITH 3-STATE OUTPUTS

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and below	Page 63, group 3 except as below

recommended operating conditions (see figures 1, 2, and 3)

		TF4380A				TP4380A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Write pulse width, t _{w(wr)}		*	*	*	*	*	*	*	*	ns
Setup time	Address before CE low, t _{su(ad)}	*	*	*	*	*	*	*	*	ns
	Data before end of write, t _{su(da)}	*	*	*	*	*	*	*	*	
	Read before CE low, t _{su(rd)}	*	*	*	*	*	*	*	*	
Hold time	Address after CE high, t _{h(ad)}	*	*	*	*	*	*	*	*	ns
	Data after end of write, t _{h(da)}	*	*	*	*	*	*	*	*	
	Read after CE high, t _{h(rd)}	*	*	*	*	*	*	*	*	

electrical characteristics

PARAMETER		TEST CONDITIONS†		TF4380A				TP4380A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
I _{OH}	High-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OH min}	T _A = MIN	*	*	*	*	*	*	*	mA	
			T _A = 25°C	*	*	*	*	*	*	*		
			T _A = MAX	*	*	*	*	*	*	*		
I _{OL}	Low-level output current	V _{IH} = V _{DD} , V _{IL} = 0, V _O = V _{OL}	T _A = MIN	*	*	*	*	*	*	*	mA	
			T _A = 25°C	*	*	*	*	*	*	*		
			T _A = MAX	*	*	*	*	*	*	*		

†T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER		TEST CONDITIONS		TF4380A				TP4380A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{a(CE)}	Access times from chip enable	C _L = 50 pF, R _L = 200 kΩ,		*	*	*	*	*	*	*	ns	
tp _{XZ}	Output disable time	See Figures 1 and 3 and Note 1		*	*	*	*	*	*	*	ns	

*These specifications for this product have not been determined. It is planned to specify values where asterisks appear above.

NOTE 1: See load circuit on page 170.

TYPES TF4380A, TP4380A

256-BIT RANDOM-ACCESS MEMORIES WITH 3-STATE OUTPUTS

PARAMETER MEASUREMENT INFORMATION

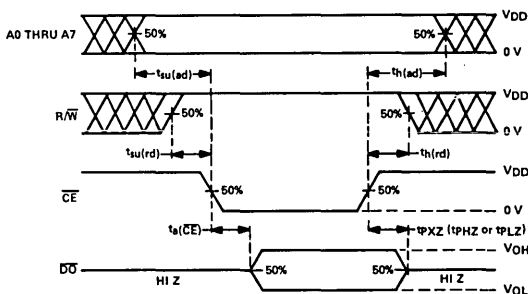


FIGURE 1—READ CYCLE VOLTAGE WAVEFORMS

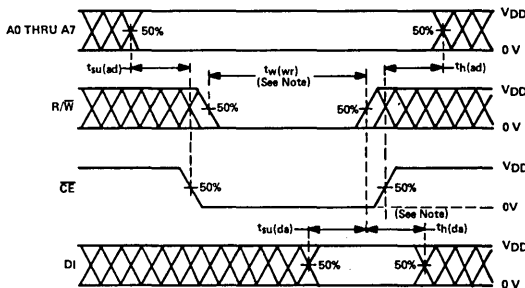


FIGURE 2—WRITE CYCLE VOLTAGE WAVEFORMS

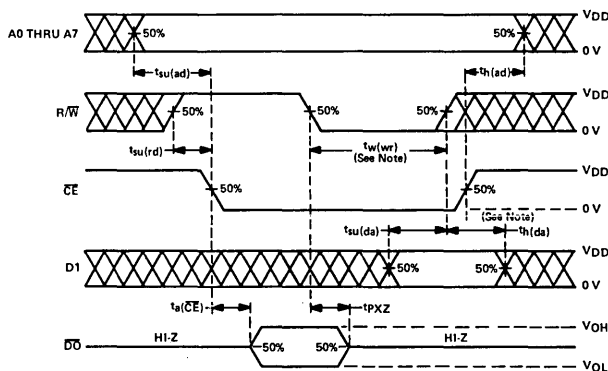


FIGURE 3—READ-WRITE (READ, MODIFY WRITE) CYCLE VOLTAGE WAVEFORMS

NOTE: The effective width of the write pulse is the interval in which R/\bar{W} and $\bar{C}\bar{E}$ are simultaneously low. The data setup and hold times are with respect to the low-to-high transition of either R/\bar{W} or $\bar{C}\bar{E}$, whichever occurs first.

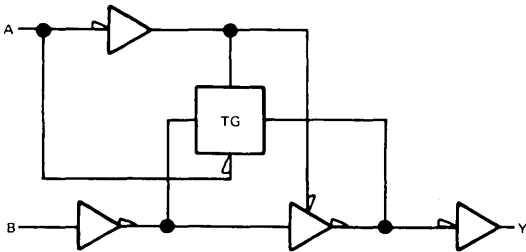
CMOS LOGIC CIRCUITS

TYPES TF4507A, TP4507A QUAD EXCLUSIVE-OR GATES

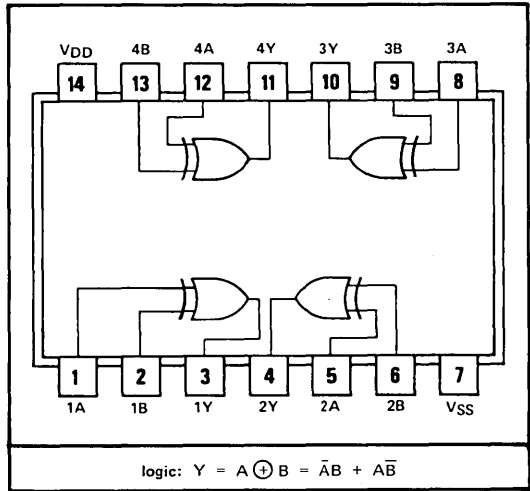
SEPTEMBER 1975

- Designed to be Interchangeable with Motorola MC14507 and RCA CD4030A

functional block diagram (each gate)



J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



FUNCTION TABLE

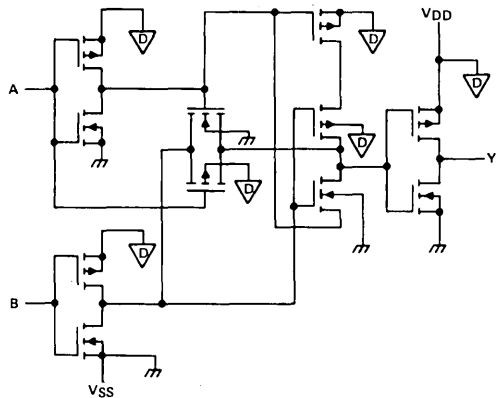
INPUTS		OUTPUT
A	B	Y
L	L	L
H	L	H
L	H	H
H	H	L

H = high level, L = low level

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 2, and on following page

schematic (each gate)



△ . . . V_{DD} bus

TYPES TF4507A, TP4507A

QUAD EXCLUSIVE-OR GATES

electrical characteristics

$V_{DD} = 5\text{ V}$ and 10 V

PARAMETER	TEST CONDITIONS†		TF4507A		TP4507A		UNIT
			$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
			MIN	MAX	MIN	MAX	
I_{OH} High-level output current	$V_{IH} = V_{DD}$, $V_{IL} = 0$, $V_O = V_{OH\text{ min}}$	$T_A = \text{MIN}$	-0.95	-0.95	-0.45	-0.45	mA
		$T_A = 25^\circ\text{C}$	-0.65	-0.65	-0.32	-0.32	
		$T_A = \text{MAX}$	-0.45	-0.45	-0.25	-0.25	
I_{OL} Low-level output current	$V_{IH} = V_{DD}$, $V_{IL} = 0$, $V_O = V_{OL\text{ max}}$	$T_A = \text{MIN}$	0.75	1.5	0.35	0.7	mA
		$T_A = 25^\circ\text{C}$	0.6	1.2	0.3	0.6	
		$T_A = \text{MAX}$	0.45	0.9	0.25	0.5	
I_{DD} or $-I_{SS}$ Quiescent supply current	$V_I = V_{DD}$ or 0, No load	$T_A = \text{MIN or } 25^\circ\text{C}$	0.5	1	5	10	μA
		$T_A = \text{MAX}$	30	60	70	140	

$V_{DD} = 15\text{ V}$

PARAMETER	TEST CONDITIONS†		TF4507A		TP4507A		UNIT
			MIN	MAX	MIN	MAX	
I_{DD} or $-I_{SS}$ Quiescent supply current	No load	$V_I = V_{DD}$ or 0, $T_A = \text{MIN or } 25^\circ\text{C}$	3		30		μA
		$T_A = \text{MAX}$	180		420		

† $T_A = \text{MIN or MAX}$ refers to the respective values of temperature specified under recommended operating conditions.

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4507A		TP4507A		UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	
t_{PLH} Propagation delay time, low-to-high-level output	$C_L = 50\text{ pF}$ §, $R_L = 200\text{ k}\Omega$, See Note 1	350	175	475	250	ns
t_{PHL} Propagation delay time, high-to-low-level output		350	175	475	250	ns
t_{TLH} Transition time, low-to-high-level output		300	150	450	225	ns
t_{THL} Transition time, high-to-low-level output		300	150	450	225	ns

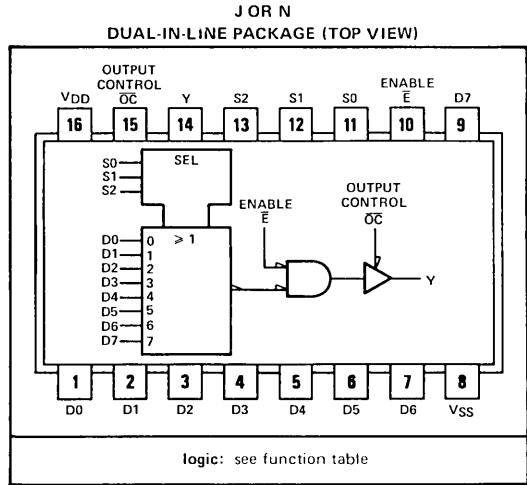
§With a 15-pF load, these devices switch with times similar to those of the Motorola MC14507 and RCA CD4030A.

NOTE 1: See load circuit and voltage waveforms on page 170.

- Designed to be Interchangeable with Motorola MC14512

description

These circuits are single 8-channel data selectors having three digital select inputs, S0, S1, and S2, an enable input, \bar{E} , and an output control. When the output control, \bar{OC} , is high, the output will be in the high-impedance (off) state. Applications of this device include signal multiplexing, data routing, and number sequence generation.



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 3, and below

FUNCTION TABLE

OUTPUT CONTROL	INPUTS			OUTPUT Y
	ENABLE E	SELECT		
		S2	S1 S0	
H	X	X	X X	Z
L	H	X	X X	L
L	L	L	L L	D0
L	L	L	L H	D1
L	L	L	H L	D2
L	L	L	H H	D3
L	L	H	L L	D4
L	L	H	L H	D5
L	L	H	H L	D6
L	L	H	H H	D7

H = high level, L = low level, X = irrelevant, Z = high-impedance (off)
D0 . . . D7 = the logic level of the indicated D input.

electrical characteristics

PARAMETER	TEST CONDITIONS [†]	TF4512A		TP4512A		UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	
I _{OZH} Off-state output current, high-level voltage applied	\bar{OC} at V _{DD} , V _O = V _{DD}	T _A = MIN or 25°C		0.05		μA
		T _A = MAX		3		
I _{OZL} Off-state output current, low-level voltage applied	\bar{OC} at V _{DD} , V _O = 0 V	T _A = MIN or 25°C		-0.05		μA
		T _A = MAX		-3		

[†]T_A = MIN or MAX refers to the respective values of temperature specified under recommended operating conditions.

TYPES TF4512A, TP4512A

8-CHANNEL DATA SELECTORS WITH 3-STATE OUTPUTS

switching characteristics at 25°C free-air temperature

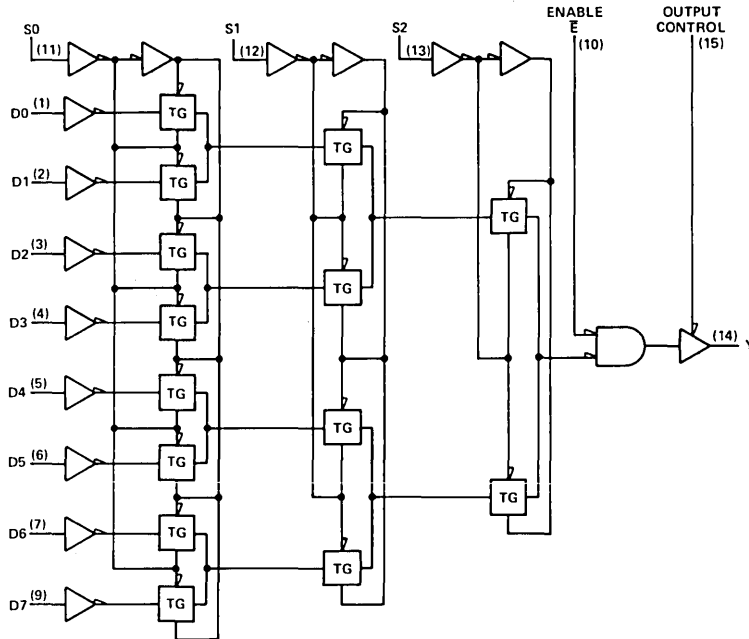
PARAMETER	TEST CONDITIONS	TF4512A		TP4512A		UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	
t _{PLH} Propagation delay time, low-to-high-level output	C _L = 50 pF [§] , R _L = 200 kΩ, See Note 1	750	325	1000	375	ns
t _{PHL} Propagation delay time, high-to-low-level output		750	325	1000	375	ns
t _{T_{LH}} Transition time, low-to-high-level output		500	250	600	300	ns
t _{T_{HL}} Transition time, high-to-low-level output		500	250	600	300	ns
t _{pZH} Output enable time to high level	C _L = 50 pF [¶] , R _L = 10 kΩ, See Note 1	430	150	500	200	ns
t _{pZL} Output enable time to low level		250	130	300	170	ns
t _{pHZ} Output disable time from high level		260	170	320	240	ns
t _{pLZ} Output disable time from low level		160	140	220	200	ns

[§] With a 15-pF load, these devices switch with times similar to those of the Motorola MC14512.

[¶] With a 15-pF, 1-kΩ load, these devices switch with times similar to those of the Motorola MC14512.

NOTE 1: See load circuit and voltage waveforms on page 170.

functional block diagram

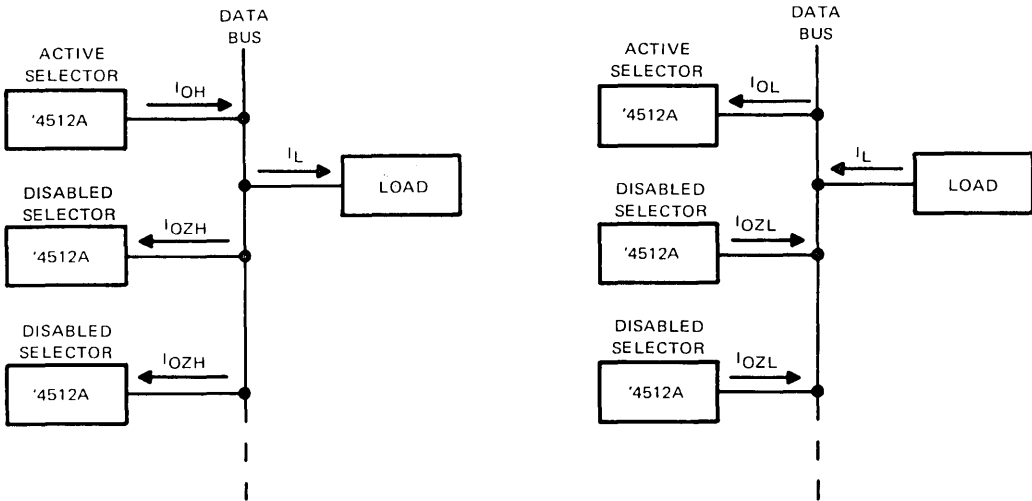


TYPES TF4512A, TP4512A 8-CHANNEL DATA SELECTORS WITH 3-STATE OUTPUTS

TYPICAL APPLICATION DATA

The output terminals of several '4512A 8-bit data selectors can be connected to a single data bus as shown. One output is placed in the active state (output control low) and the remaining outputs are disabled (output controls high). The number of outputs, N , that may be connected to a bus line is determined from the output drive current I_{OH} or I_{OL} , the off-state output current, I_{OZH} or I_{OZL} , and load current required to drive the bus line (including fan-out to other device inputs), I_L . N can be calculated for the high-level and low-level logic states, respectively, by:

$$N = \frac{I_{OH} - I_L}{I_{OZH}} + 1 \text{ and } N = \frac{I_{OL} - I_L}{I_{OZL}} + 1.$$



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CMOS LOGIC CIRCUITS

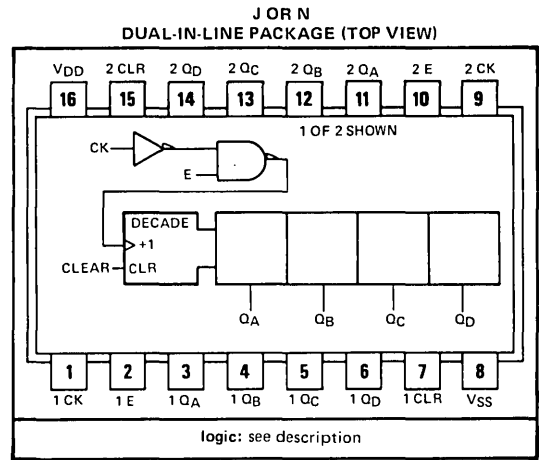
TYPES TF4518A, TP4518A DUAL DECADE COUNTERS

SEPTEMBER 1975

- Designed to be Interchangeable with Motorola MC14518
- Medium-Speed Operation . . . 6 MHz
Typical Maximum Clock Frequency at $V_{DD} = 10\text{ V}$

description

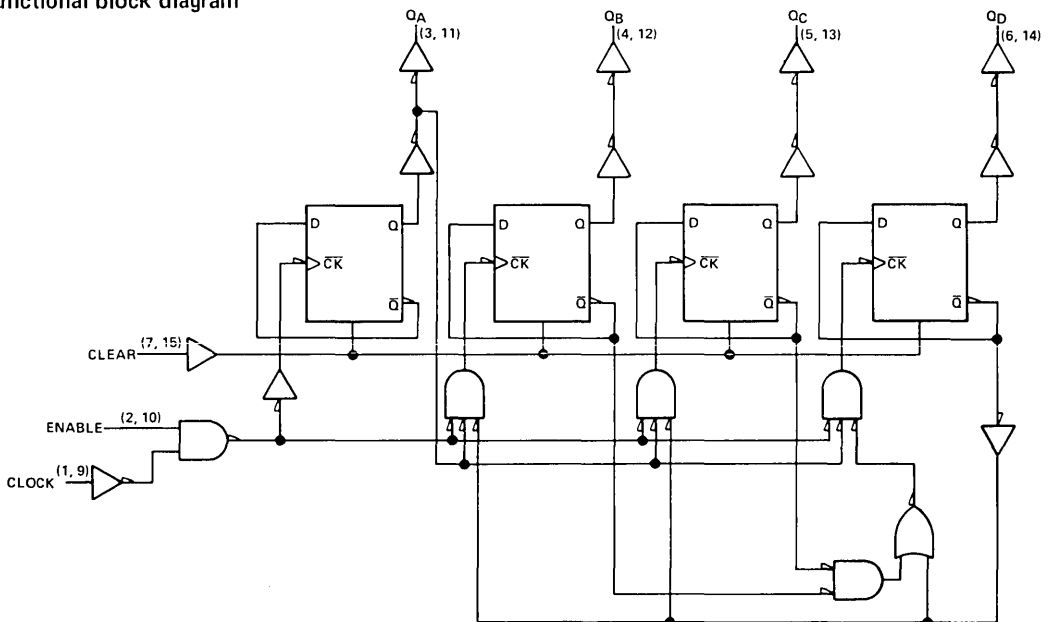
The '4518A dual decade counter consists of two identical, independent synchronous 4-stage counters. The counter stages are D-type flip-flops with interchangeable clock and enable lines. With enable high, the count is advanced on a low-to-high transition at the clock input. Alternatively, if the clock input is low, the count is advanced on a high-to-low transition at enable. If clock is high or enable is low, changes at the other input (enable or clock) have no effect. A high clear signal asynchronously clears the counters and resets all outputs low.



specifications

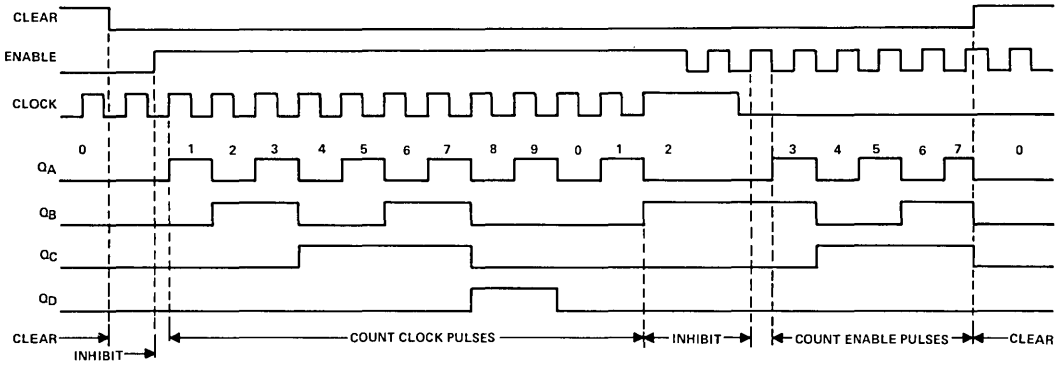
MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and on following page	Page 63, group 3

functional block diagram



TYPES TF4518A, TP4518A DUAL DECADE COUNTERS

typical clear, count, and inhibit sequences



recommended operating conditions

		TF4518A				TP4518A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Pulse width, t _w	Clock high or low	200		100		300		120		ns
	Clear	325		100		500		125		ns
Enable setup time, t _{SU}		440		220		660		260		ns

switching characteristics at 25°C free-air temperature

PARAMETER ‡	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4518A				TP4518A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}				1.5		3		1		2.5	MHz	
t _{PLH} or t _{PHL}	Clock or enable	Any Q	C _L = 50 pF §, R _L = 200 kΩ, See Note 1	825		300		1200		410	ns	
t _{PHL}	Clear	All		825		300		1200		410	ns	
t _{TLH} or t _{THL}		All		350		150		400		220	ns	

‡f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

t_{THL} ≡ Transition time, high-to-low-level output

§With a 15-pF load, these devices switch with times similar to those of the Motorola MC14518.

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4519A, TP4519A 4-BIT AND-OR SELECT GATES

SEPTEMBER 1975

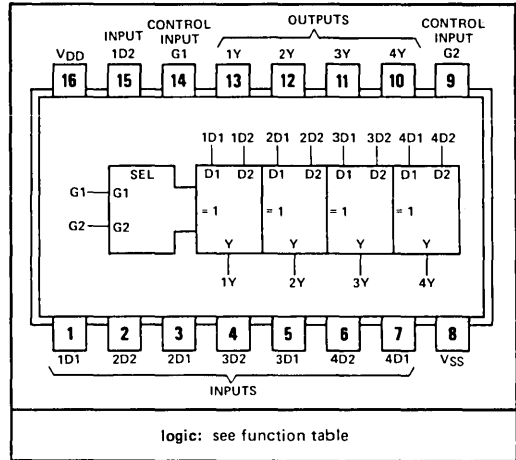
- Designed to be Interchangeable with Motorola MC14519

FUNCTION TABLE

INPUTS		DATA		OUTPUT Y
CONTROL G1	G2	D1	D2	
L	L	X	X	L
H	L	H	X	H
H	L	L	X	L
L	H	X	H	H
L	H	X	L	L
H	H	L	L	H
H	H	H	L	L
H	H	L	H	L
H	H	H	H	H

H = high level, L = low level, X = irrelevant

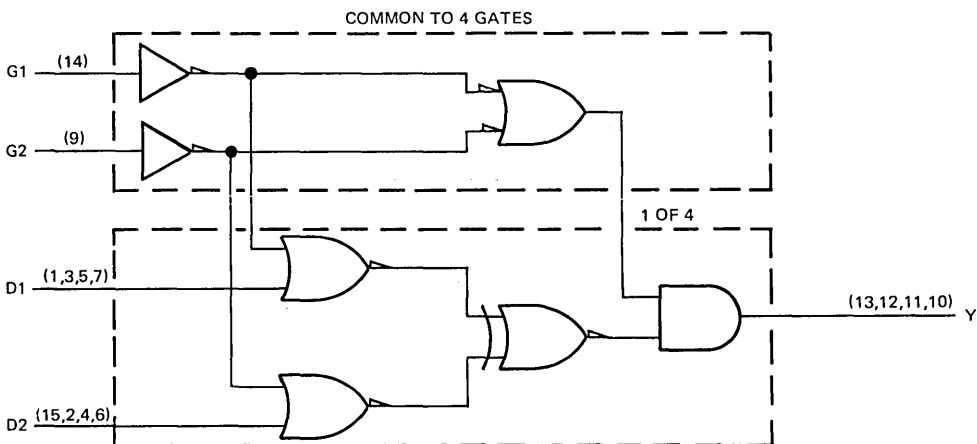
J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 2

functional block diagram



TYPES TF4519A, TP4519A 4-BIT AND-OR SELECT GATES

electrical characteristics

$V_{DD} = 5\text{ V and }10\text{ V}$

PARAMETER	TEST CONDITIONS		TF4519A		TP4519A		UNIT
			$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
			MIN	MAX	MIN	MAX	
I_{DD} or Quiescent supply current $-I_{SS}$	$V_I = V_{DD}$ or 0, No load	$T_A = \text{MIN or } 25^\circ\text{C}$	0.5	1	5	10	μA
		$T_A = \text{MAX}$	30	60	150	300	

$V_{DD} = 15\text{ V}$

PARAMETER	TEST CONDITIONS†		TF4519A		TP4519A		UNIT
			MIN	MAX	MIN	MAX	
I_{DD} or Quiescent supply current $-I_{SS}$	$V_I = V_{DD}$ or 0, No load	$T_A = \text{MIN or } 25^\circ\text{C}$	3		30		μA
		$T_A = \text{MAX}$	180		900		

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4519A		TP4519A		UNIT		
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$				
		MIN	MAX	MIN	MAX		MIN	MAX
t_{PLH} Propagation delay time, low-to-high-level output	$C_L = 50\text{ pF}^\S,$ $R_L = 200\text{ k}\Omega,$ See Note 1	450		225		600	300	ns
t_{PHL} Propagation delay time, high-to-low-level output		450		225		600	300	
t_{TLH} Transition time, low-to-high-level output		350		150		400	220	
t_{THL} Transition time, high-to-low-level output		350		150		400	220	

§ With a 15-pF load, these devices switch with times similar to those of the Motorola MC14519.

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

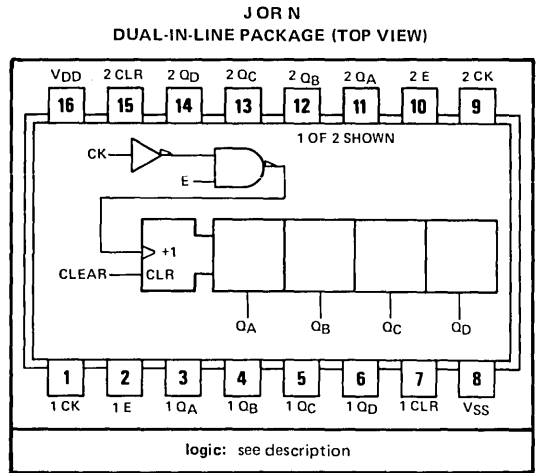
TYPES TF4520A, TP4520A DUAL BINARY COUNTERS

SEPTEMBER 1975

- Designed to be Interchangeable with Motorola MC14520
- Medium-Speed Operation . . . 6 MHz
Typical Maximum Clock Frequency at $V_{DD} = 10\text{ V}$

description

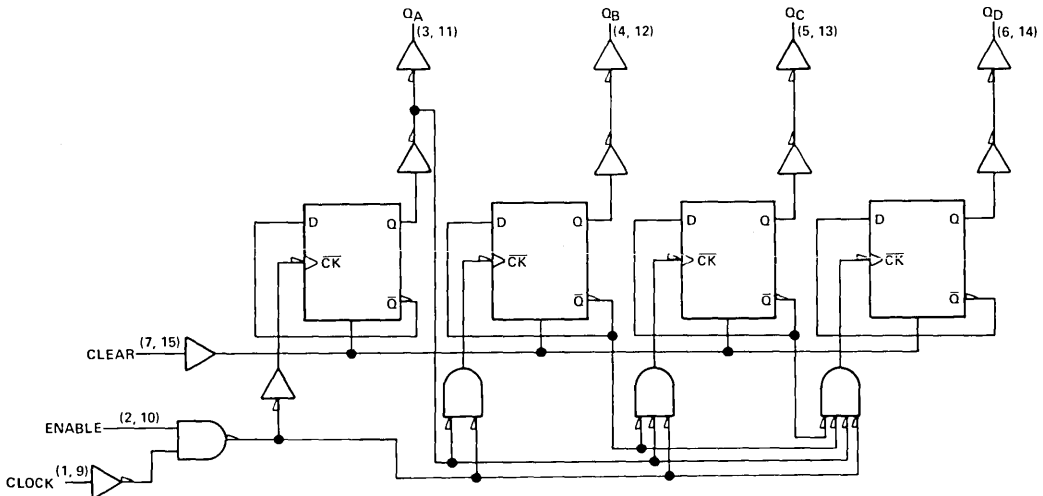
The '4520A dual binary counter consists of two identical, independent, synchronous 4-stage counters. The counter stages are D-type flip-flops with interchangeable clock and enable lines. With enable high, the count is advanced on a low-to-high transition at the clock input. Alternatively, if the clock input is low, the count is advanced on a high-to-low transition at enable. If clock is high or enable is low, changes at the other input (enable or clock) have no effect. A high clear signal asynchronously clears the counters and resets all outputs low. A high clear signal asynchronously clears the counters and resets all outputs low.



specifications

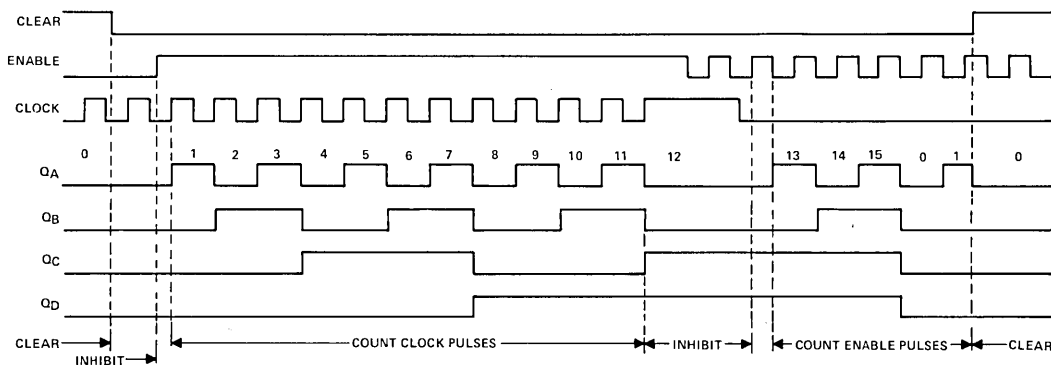
MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and on following page	Page 63, group 3

functional block diagram



TYPES TF4520A, TP4520A DUAL BINARY COUNTERS

typical clear, count, and inhibit sequences



recommended operating conditions

		TF4520A				TP4520A				UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Pulse width, t _w	Clock high or low	200		100		300		120		ns
	Clear	325		100		500		125		ns
Enable setup time, t _{su}		440		220		660		260		ns

switching characteristics at 25°C free-air temperature

PARAMETER‡	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4520A				TP4520A				UNIT
				V _{DD} = 5 V		V _{DD} = 10 V		V _{DD} = 5 V		V _{DD} = 10 V		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}			C _L = 50 pF§, R _L = 200 kΩ, See Note 1	1.5		3		1		2.5		MHz
t _{PLH} or t _{PHL}	Clock or enable	Any Q		825		300		1200		410		ns
t _{PHL}	Clear	All		825		300		1200		410		ns
t _{TLH} or t _{THL}		All		350		150		400		220		ns

‡f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

t_{THL} ≡ Transition time, high-to-low-level output

§With a 15-pF load, these devices switch with times similar to those of the Motorola MC14520.

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4522A, TF4526A, TP4522A, TP4526A DECADE AND BINARY DIVIDE-BY-N COUNTERS

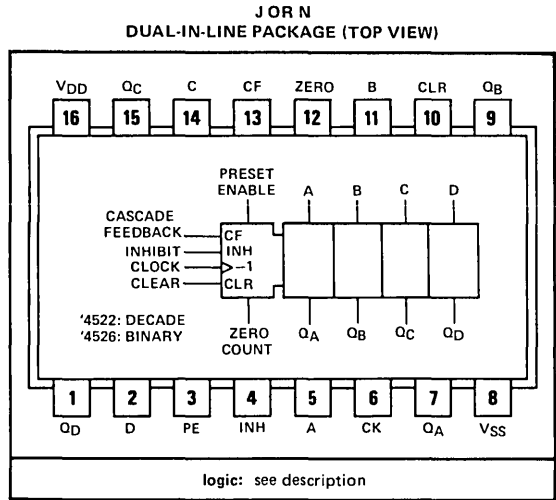
SEPTEMBER 1975

- Designed to be Interchangeable with Motorola MC14522, MC14526
- Maximum Clock Frequency . . . 5 MHz Typical at 10 V

description

The '4522A and '4526A are presettable decade and binary down counters with a decoded zero-state output for divide-by-N applications. While the counter is at minimum count (all outputs low), the zero-count output will be high if the cascade feedback input is high, otherwise, it remains low. The counters may be preset by taking preset enable (PE) high after setting up the desired data at the parallel inputs A, B, C, and D. Parallel loading is asynchronous and the clock input has no effect while PE is high. The count is decreased by 1 on the low-to-high transition of the clock but the clock signal is only effective if the inhibit input is low. Transitions of the inhibit input from high to low should be made while the clock is low in order to avoid causing one extra down count triggered by the inhibit transition. A high clear signal asynchronously clears the counter and resets all outputs low.

Applications include frequency synthesizers, phase-locked loops, and other frequency-division applications.



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62 and below	Page 63, group 3

recommended operating conditions

		TF4522A, TF4526A		TP4522A, TP4526A		UNIT
		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
		MIN	MAX	MIN	MAX	
Pulse width, t_w	Clock high or low	250	100	300	150	ns
	Preset enable	250	100	300	150	ns
	Clear	300	250	350	300	ns
Data hold time after preset enable		125	50	150	75	ns

switching characteristics at 25°C free-air temperature

PARAMETER†	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TF4522A, TF4526A		TP4522A, TP4526A		UNIT
				$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
				MIN	MAX	MIN	MAX	
f_{max}			$C_L = 50\text{ pF}^{\S}$, $R_L = 200\text{ k}\Omega$, See Note 1	1.5	3	1	2.5	MHz
t_{PLH} or t_{PHL}	A, B, C, D	Q		1000	425	1300	550	ns
t_{PLH} or t_{PHL}	Clock	Zero-count		450	350	600	450	ns
t_{TLH} or t_{THL}		Any		500	250	600	300	ns

† f_{max} ≡ Maximum clock frequency

t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

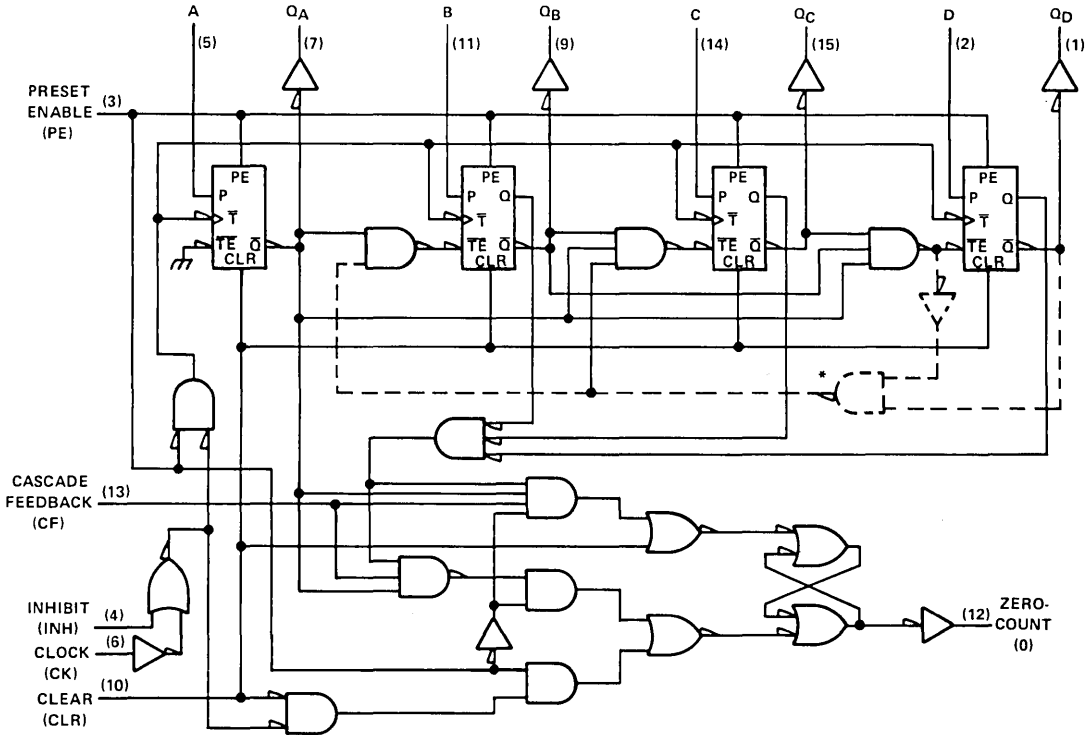
t_{THL} ≡ Transition time, high-to-low-level output

§ With a 15-pF load, these devices switch with times similar to those of the Motorola MC14522 and MC14526.

NOTE 1: See load circuit and voltage waveforms on page 170.

TYPES TF4522A, TF4526A, TP4522A, TP4526A DECADE AND BINARY DIVIDE-BY-N COUNTERS

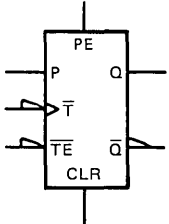
functional block diagram



* THE DOTTED LINES AND GATES ARE OMITTED ON THE '4526A

EACH FLIP-FLOP

SYMBOL



\overline{TE} = toggle enable input
P = parallel date input
 \overline{T} = toggle input

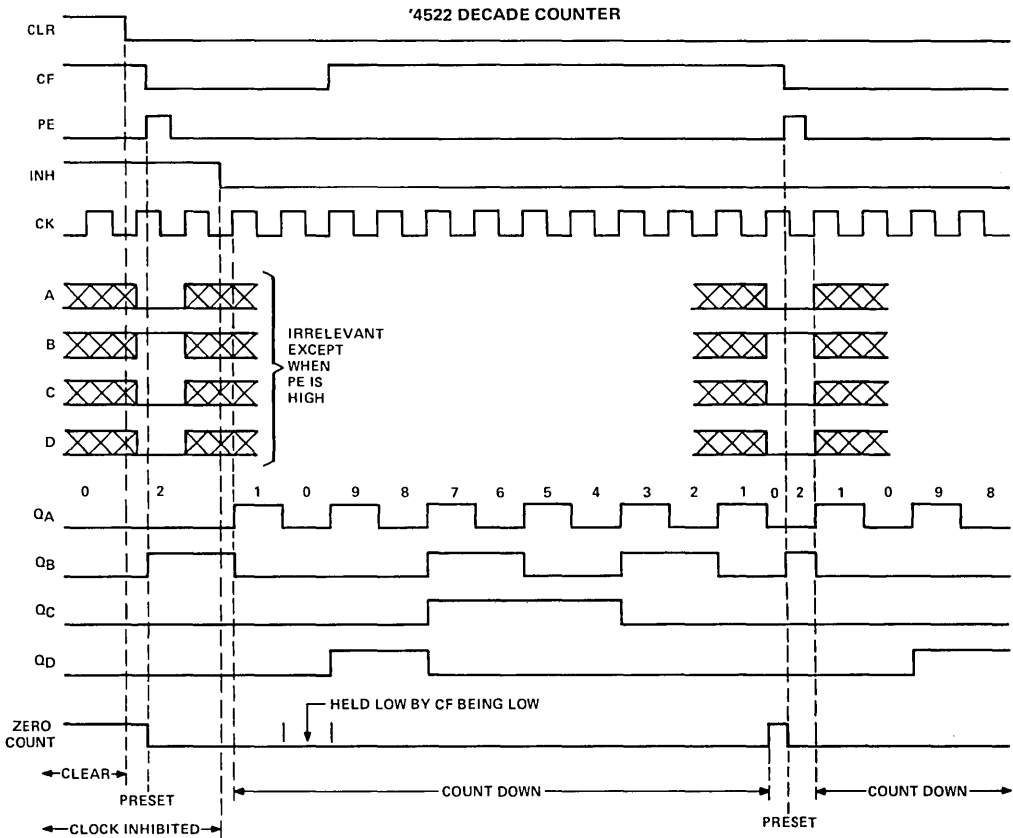
FUNCTION TABLE
(NOT INCLUDING EXTERNAL GATING
TO THE FLIP-FLOPS)

INPUTS					OUTPUTS	
CLR	PE	\overline{TE}	\overline{T}	P	Q	\overline{Q}
H	X	X	X	X	L	H
L	H	X	L	H	H	L
L	H	X	L	L	L	H
L	L	H	\downarrow	X	Q_n	\overline{Q}_n
L	L	L	\downarrow	X	\overline{Q}_n	Q_n
L	X	X	H	X	Q_0	\overline{Q}_0

H = high level (steady state)
L = low level (steady state)
X = irrelevant (any input, including transitions)
 \downarrow = transition from high to low level
 Q_n = the level of Q before the most-recent
 \downarrow transition of \overline{T} .
 Q_0 = the level of Q before the indicated
steady-state conditions were established

TYPES TF4522A, TF4526A, TP4522A, TP4526A DECADE AND BINARY DIVIDE-BY-N COUNTERS

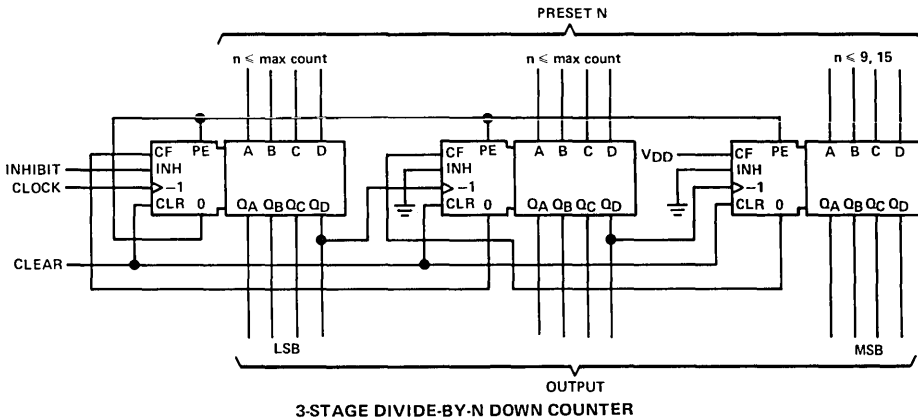
typical clear, asynchronously load, and count down sequence



CF has effect only during the zero count. It is shown changing as if driven by the zero output of a more significant bit in a divide-by-12 cascade.

A sequence for the '4526A binary counter would be similar except that 15 (HHHH) instead of 9 (HLLH) would follow 0 (LLLL), with counting down proceeding from there.

TYPICAL APPLICATION DATA



CMOS LOGIC CIRCUITS

TYPES TF4531A, TP4531A 12-BIT PARITY TREES

SEPTEMBER 1975

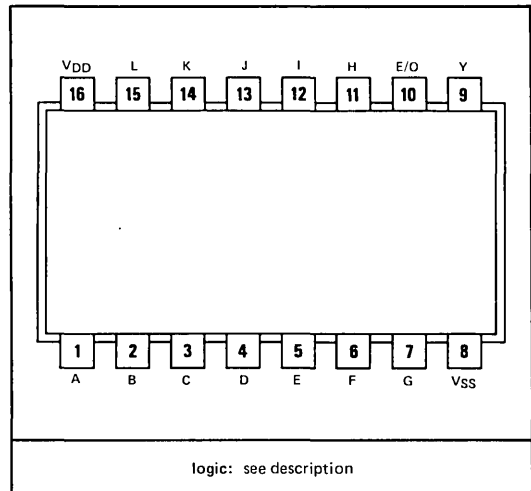
- Designed to be Interchangeable with Motorola MC14531

description

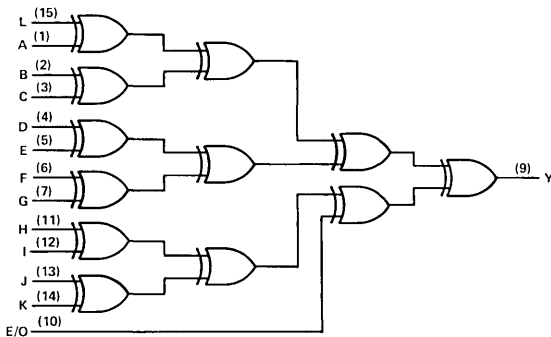
These circuits consist of 12 data-bit inputs (A thru L), an even or odd parity selection input (E/O) and an output. The parity selection input can be considered as an additional bit. With an even number of inputs (including E/O) high, the output is low; with an odd number high, the output is high. Words of greater than 12 bits can be accommodated by cascading other '4351A devices by using the E/O input.

Applications include checking or including a redundant (parity) bit of a word for error detection/correction systems, controlling remote digital sensors or switches (digital event detection/correction), or use as a multiple input adder without carries.

J OR N
DUAL-IN-LINE PACKAGE (TOP VIEW)



functional block diagram



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 3

switching characteristics at 25°C free-air temperature

PARAMETER†	TEST CONDITIONS	TF4531A		TP4531A		UNIT
		V _{DD} = 5 V		V _{DD} = 10 V		
		MIN	MAX	MIN	MAX	
t _{PLH} or t _{PHL}	from A-L	1050		425		ns
	from E/O	675		275		
t _{TLH} or t _{THL}	See Note 1	350		150		ns

†t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

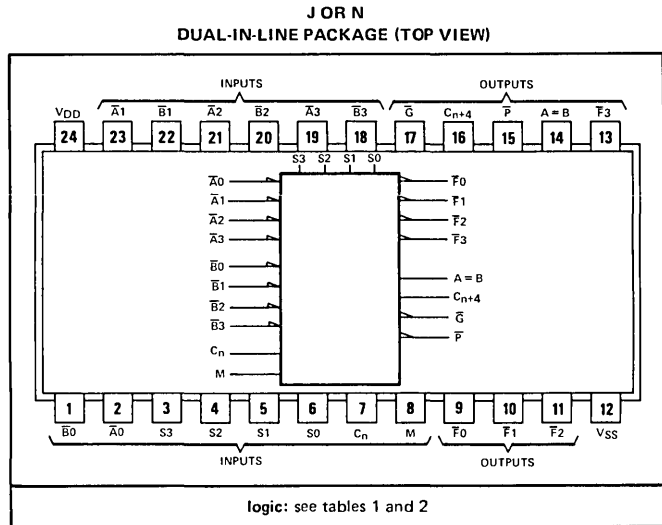
t_{TLH} ≡ Transition time, low-to-high-level output

t_{THL} ≡ Transition time, high-to-low-level output

§With a 15-pF load, these devices switch with times similar to those of the Motorola MC14531.

NOTE 1: See load circuit and voltage waveforms on page 170.

- Designed to be Interchangeable with Motorola MC14581
- All Outputs Buffered
- Full Look-Ahead for High-Speed Operations on Long Words
- Arithmetic Operating Modes:
 - Addition
 - Subtraction
 - Shift Operand A One Position
 - Magnitude Comparison
 - Plus Twelve Other Arithmetic Operations
- Logic Function Modes:
 - Exclusive-OR
 - Comparator
 - AND, NAND, OR, NOR
 - Plus Ten Other Logic Operations



description

The TF4581A and TP4581A are arithmetic logic units (ALU)/function generators that have a complexity of 89 equivalent gates on a monolithic chip. These circuits perform 16 binary arithmetic operations on two 4-bit words as shown in Tables 1 and 2. These operations are selected by the four function-select lines (S0, S1, S2, S3) and include addition, subtraction, decrement, and straight transfer. When performing arithmetic manipulations, the internal carries must be enabled by applying a low-level voltage to the mode control input (M). A full carry look-ahead scheme is made available in these devices for fast, simultaneous carry generation by means of two cascade-outputs (pins 15 and 17) for the four bits in the package. When used in conjunction with the TF4582A or TP4582A full carry look-ahead circuits, high-speed arithmetic operations can be performed. The method of cascading '4582 circuits and these ALU's to provide multi-level full carry look ahead is illustrated under typical applications data for the '4582A.

If high speed is not of importance, a ripple-carry input (C_n) and a ripple-carry output (C_{n+4}) are available. However, the ripple-carry delay has also been minimized so that arithmetic manipulations for small word lengths can be performed without external circuitry.

The '4581A will accommodate active-low or active-high data if the pin designations are interpreted as follows:

PIN NUMBER	2	1	23	22	21	20	19	18	9	10	11	13	7	16	15	17
Active-low data (Table 1)	\bar{A}_0	\bar{B}_0	\bar{A}_1	\bar{B}_1	\bar{A}_2	\bar{B}_2	\bar{A}_3	\bar{B}_3	F ₀	F ₁	F ₂	F ₃	C _n	C _{n+4}	P	G
Active-high data (Table 2)	A ₀	B ₀	A ₁	B ₁	A ₂	B ₂	A ₃	B ₃	F ₀	F ₁	F ₂	F ₃	C _n	C _{n+4}	P	G

Subtraction is accomplished by 1's complement addition where the 1's complement of the subtrahend is generated internally. The resultant output is A-B-1, which requires an end-around or forced carry to provide A-B.

TYPES TF4581A, TP4581A ARITHMETIC LOGIC UNITS/FUNCTION GENERATORS

description (continued)

The '4581A can also be utilized as a comparator. The $A = B$ output is internally decoded from the function outputs ($\overline{F0}$, $\overline{F1}$, $\overline{F2}$, $\overline{F3}$) so that when two words of equal magnitude are applied at the \overline{A} and \overline{B} inputs, it will assume a high level to indicate equality ($A = B$). The ALU should be in the subtract mode with $C_n = H$ when performing this comparison. The carry output (C_{n+4}) can also be used to supply relative magnitude information. Again, the ALU should be placed in the subtract mode by placing the function select inputs $S3, S2, S1, S0$ at L, H, H, L, respectively.

INPUT C_n	OUTPUT C_{n+4}	ACTIVE-LOW DATA (FIGURE 1)	ACTIVE-HIGH DATA (FIGURE 2)
H	H	$A \geq B$	$A \leq B$
H	L	$A < B$	$A > B$
L	H	$A > B$	$A < B$
L	L	$A \leq B$	$A \geq B$

These circuits have been designed to not only incorporate all of the designer's requirements for arithmetic operations, but also to provide 16 possible functions of two Boolean variables without the use of external circuitry. These logic functions are selected by use of the four function-select inputs ($S0, S1, S2, S3$) with the mode-control input (M) at a high level to disable the internal carry. The 16 logic functions are detailed in Tables 1 and 2 and include exclusive-OR, NAND, AND, NOR, and OR functions.

signal designations

The '4581A and '4582A can be used with the signal designations of either Figure 1 or Figure 2. The polarity indicators (\supset) and the bars over the terminal letter symbols (e.g., \overline{C}) each indicate that the associated input or output is active with respect to the selected function of the device when that input or output is low. That is, a low at \overline{C} means "do carry" while a high means "do not carry".

The logic functions and arithmetic operations obtained with signal designations of Figure 1 are given in Table 1; those obtained with signal designations of Figure 2 are given in Table 2. Because the terminals have been renamed between Figures 1 and 2, the equations in both tables are actually in positive logic. For negative logic, the equations in Table 1 may be used with the terminal nomenclature of Figure 2 or the equations of Table 2 may be used with the terminal nomenclature of Figure 1.

TYPES TF4581A, TP4581A ARITHMETIC LOGIC UNITS/FUNCTION GENERATORS

signal designations (continued)

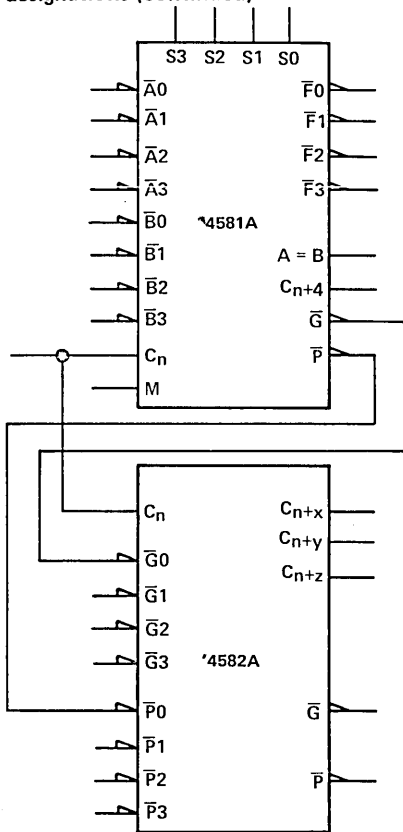


FIGURE 1

(Use with Table 1 for positive logic, with Table 2 for negative logic)

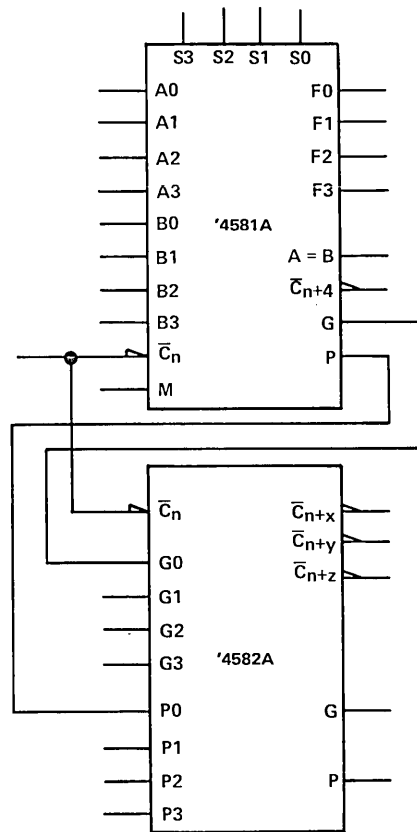


FIGURE 2

(Use with Table 2 for positive logic, with Table 1 for negative logic)

TABLE 1

SELECTION	ACTIVE-LOW DATA						
	M = H		M = L; ARITHMETIC OPERATIONS				
	LOGIC FUNCTIONS		C _n = L (no carry)		C _n = H (with carry)		
S3	S2	S1	S0				
L	L	L	L	$F = \bar{A}$	F = A MINUS 1	F = A	
L	L	L	H	$F = \bar{A}\bar{B}$	F = AB MINUS 1	F = AB	
L	L	H	L	$F = \bar{A} + B$	F = $\bar{A}\bar{B}$ MINUS 1	F = $\bar{A}\bar{B}$	
L	L	H	H	F = 1	F = MINUS 1 (2's COMPL)	F = ZERO	
L	H	L	L	$F = \bar{A} + \bar{B}$	F = A PLUS (A + \bar{B})	F = A PLUS (A + \bar{B}) PLUS 1	
L	H	L	H	$F = \bar{B}$	F = AB PLUS (A + \bar{B})	F = AB PLUS (A + \bar{B}) PLUS 1	
L	H	H	L	$F = A \oplus B$	F = A MINUS B MINUS 1	F = A MINUS B	
L	H	H	H	$F = A + \bar{B}$	F = A + \bar{B}	F = (A + \bar{B}) PLUS 1	
H	L	L	L	$F = \bar{A}B$	F = A PLUS (A + B)	F = A PLUS (A + B) PLUS 1	
H	L	L	H	$F = A \oplus B$	F = A PLUS B	F = A PLUS B PLUS 1	
H	L	H	L	F = B	F = $\bar{A}\bar{B}$ PLUS (A + B)	F = $\bar{A}\bar{B}$ PLUS (A + B) PLUS 1	
H	L	H	H	F = A + B	F = (A + B)	F = (A + B) PLUS 1	
H	H	L	L	F = 0	F = A PLUS A*	F = A PLUS A PLUS 1	
H	H	L	H	$F = A\bar{B}$	F = AB PLUS A	F = AB PLUS A PLUS 1	
H	H	H	L	F = AB	F = $\bar{A}\bar{B}$ PLUS A	F = $\bar{A}\bar{B}$ PLUS A PLUS 1	
H	H	H	H	F = A	F = A	F = A PLUS 1	

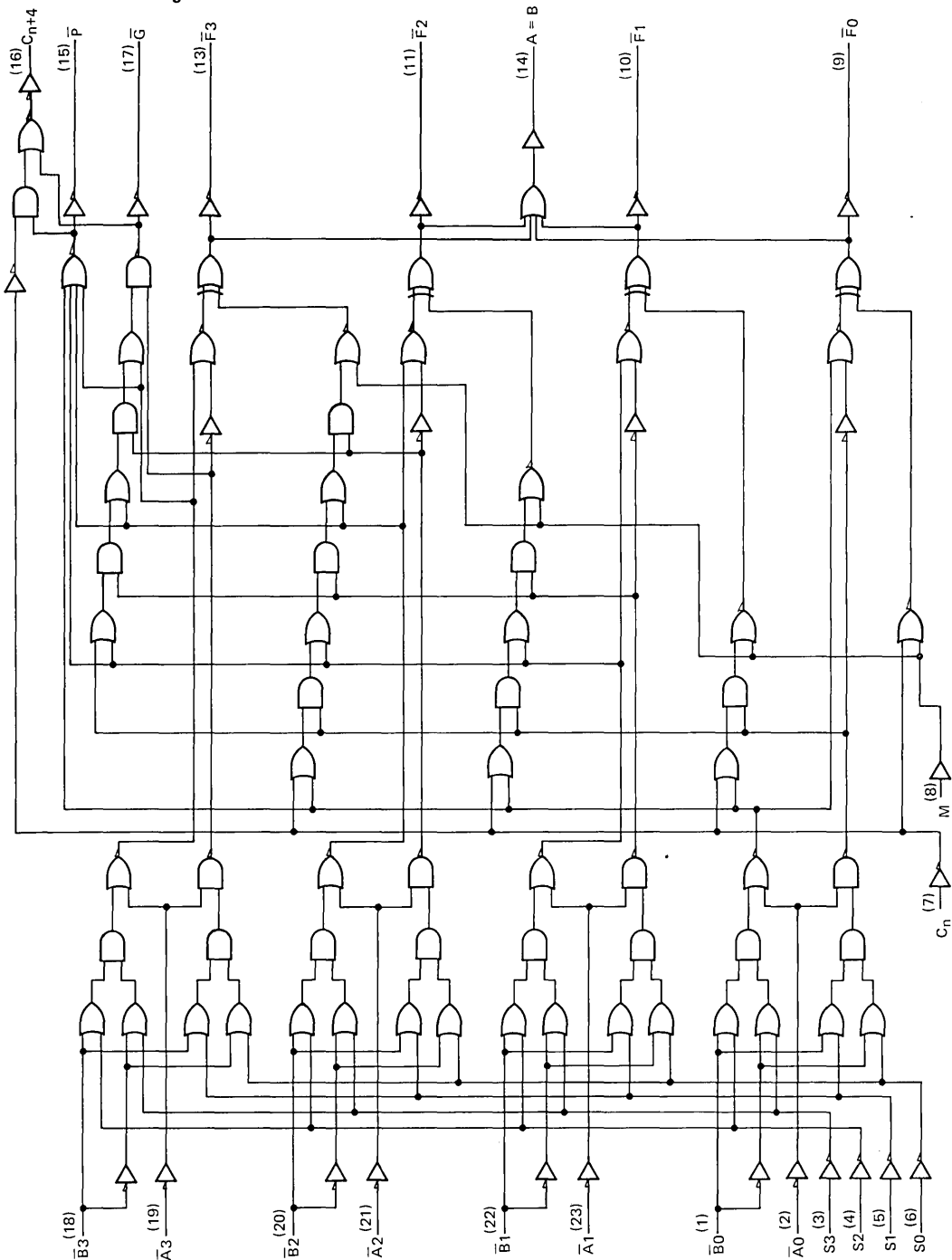
TABLE 2

SELECTION	ACTIVE-HIGH DATA						
	M = H		M = L; ARITHMETIC OPERATIONS				
	LOGIC FUNCTIONS		C _n = H (no carry)		C _n = L (with carry)		
S3	S2	S1	S0				
L	L	L	L	$F = \bar{A}$	F = A	F = A PLUS 1	
L	L	L	H	$F = \bar{A} + \bar{B}$	F = A + B	F = (A + B) PLUS 1	
L	L	H	L	$F = \bar{A}B$	F = A + \bar{B}	F = (A + \bar{B}) PLUS 1	
L	L	H	H	F = 0	F = MINUS 1 (2's COMPL)	F = ZERO	
L	H	L	L	$F = \bar{A}\bar{B}$	F = A PLUS $\bar{A}\bar{B}$	F = A PLUS $\bar{A}\bar{B}$ PLUS 1	
L	H	L	H	$F = \bar{B}$	F = (A + B) PLUS $\bar{A}\bar{B}$	F = (A + B) PLUS $\bar{A}\bar{B}$ PLUS 1	
L	H	H	L	$F = A \oplus B$	F = A MINUS B MINUS 1	F = A MINUS B	
L	H	H	H	$F = \bar{A}B$	F = $\bar{A}\bar{B}$ MINUS 1	F = $\bar{A}\bar{B}$	
H	L	L	L	$F = \bar{A} + B$	F = A PLUS AB	F = A PLUS AB PLUS 1	
H	L	L	H	$F = A \oplus B$	F = A PLUS B	F = A PLUS B PLUS 1	
H	L	H	L	F = B	F = (A + \bar{B}) PLUS AB	F = (A + \bar{B}) PLUS AB PLUS 1	
H	L	H	H	F = AB	F = AB MINUS 1	F = AB	
H	H	L	L	F = 1	F = A PLUS A*	F = A PLUS A PLUS 1	
H	H	L	H	$F = A + \bar{B}$	F = (A + \bar{B}) PLUS A	F = (A + \bar{B}) PLUS A PLUS 1	
H	H	H	L	F = A + B	F = (A + \bar{B}) PLUS A	F = (A + \bar{B}) PLUS A PLUS 1	
H	H	H	H	F = A	F = A MINUS 1	F = A	

* Each bit is shifted to the next more significant position.

TYPES TF4581A, TP4581A ARITHMETIC LOGIC UNITS/FUNCTION GENERATORS

functional block diagram



TYPES TF4581A, TP4581A

ARITHMETIC LOGIC UNITS/FUNCTION GENERATORS

specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 3

switching characteristics at $T_A = 25^\circ\text{C}$, $C_L = 50\text{ pF}$ §, $R_L = 200\text{ k}\Omega$ (See Note 1)

PARAMETER‡	FROM	TO	MODE¶	TF4581A				TP4581A				UNIT
				$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		$V_{DD} = 5\text{ V}$		$V_{DD} = 10\text{ V}$		
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH} or t_{PHL}	Sum In ($\bar{A}0$)	Sum Out (Any \bar{F})	Add	1200		425		2200		810	ns	
t_{PLH} or t_{PHL}	Sum In ($\bar{A}0$)	\bar{F}	Add	825		300		1500		560	ns	
t_{PLH} or t_{PHL}	Sum In ($\bar{B}0$)	\bar{G}	Add	825		300		1500		560	ns	
t_{PLH} or t_{PHL}	Sum In ($\bar{B}0$)	C_{n+4}	Add	1200		425		1900		710	ns	
t_{PLH} or t_{PHL}	C_n	Sum Out (Any \bar{F})	Add	625		235		1200		460	ns	
t_{PLH} or t_{PHL}	C_n	C_{n+4}	Add	550		210		950		380	ns	
t_{PLH} or t_{PHL}	Sum In ($\bar{A}0$)	$A = B$	Sub	1700		575		3200		1100	ns	
t_{PLH} or t_{PHL}	Sum In (All \bar{B})	Sum Out (Any \bar{F})	Exclusive OR	1200		425		1900		710	ns	
t_{TLH} or t_{THL}		Any	Any	350		150		400		220	ns	

TEST SETUP TABLE

FROM	TO	MODE¶	CONNECTION OF OTHER INPUTS	
			To V_{SS}	To V_{DD}
Sum In ($\bar{A}0$)	Sum Out (Any \bar{F})	Add	Remaining \bar{A} , C_n	All \bar{B}
Sum In ($\bar{A}0$)	\bar{F}	Add	Remaining \bar{A} , C_n	All \bar{B}
Sum In ($\bar{B}0$)	\bar{G}	Add	All \bar{A} , C_n	Remaining \bar{B}
Sum In ($\bar{B}0$)	C_{n+4}	Add	All \bar{A} , C_n	Remaining \bar{B}
C_n	Sum Out (Any \bar{F})	Add	All \bar{A}	All \bar{B}
C_n	C_{n+4}	Add	All \bar{A}	All \bar{B}
Sum In ($\bar{A}0$)	$A = B$	Sub	All \bar{B} , Remaining A	C_n
Sum In (All \bar{B})	Sum Out (Any \bar{F})	Exclusive OR	All \bar{A}	M

‡ t_{PLH} ≡ Propagation delay time, low-to-high-level output

t_{PHL} ≡ Propagation delay time, high-to-low-level output

t_{TLH} ≡ Transition time, low-to-high-level output

t_{THL} ≡ Transition time, high-to-low-level output

§ With a 15-pF load, these devices switch with times similar to those of Motorola MC14581.

¶ For Add mode: $M = 0\text{ V}$, $S3 = V_{DD}$, $S2 = 0\text{ V}$, $S1 = 0\text{ V}$, $S0 = V_{DD}$

For Subtract mode: $M = 0\text{ V}$, $S3 = 0\text{ V}$, $S2 = V_{DD}$, $S1 = V_{DD}$, $S0 = 0\text{ V}$

Exclusive-OR mode: $M = V_{DD}$, $S3 = V_{DD}$, $S2 = 0\text{ V}$, $S1 = 0\text{ V}$, $S0 = V_{DD}$

NOTE 1: See load circuit and voltage waveforms on page 170.

CMOS LOGIC CIRCUITS

TYPES TF4582A, TP4582A LOOK-AHEAD CARRY GENERATORS

SEPTEMBER 1975

- Designed to be Interchangeable with Motorola MC14582
- Expandable to Any Number of Bits
- Buffered Inputs and Outputs

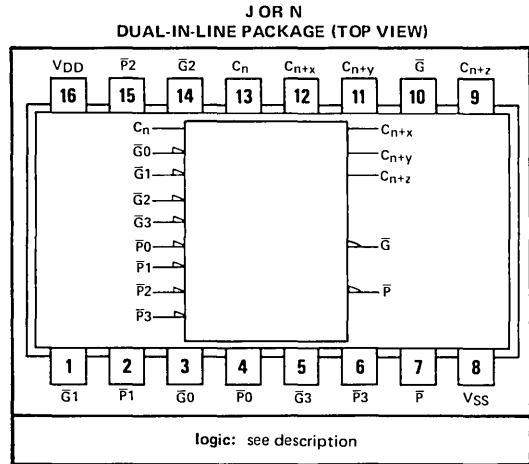
description

The TF4582A and TP4582A are high-speed, look-ahead carry generators capable of anticipating a carry across four binary adders or group of adders. They are cascadable to perform full look-ahead across n-bit adders. Carry, generate-carry, and propagate-carry functions are provided as shown in the function tables.

When used in conjunction with the '4581A arithmetic logic unit (ALU), these generators provide high-speed carry look-ahead capability for any word length. Each '4582A generates the look-ahead (anticipated carry) across a group of four ALU's and, in addition, other carry look-ahead circuits may be employed to anticipate carry across sections of four look-ahead packages up to n-bits. The method of cascading '4582A circuits to perform multi-level look-ahead is illustrated under typical application data.

Carry input and outputs of the '4581A ALU are in their true form and the carry propagate (\bar{P}) and carry generate (\bar{G}) are in negated form; therefore, the carry functions (inputs, outputs, generate, and propagate) of the look-ahead generators are implemented in the compatible forms for direct connection to the ALU. Reinterpretations of carry functions explained on the '4581A data sheet are also applicable to and compatible with the look-ahead generator. Positive logic equations for the '4582A are:

$$\begin{aligned}
 C_{n+x} &= G_0 + P_0 C_n \\
 C_{n+y} &= G_1 + G_0 P_1 + P_1 P_0 C_n \\
 C_{n+z} &= G_2 + G_1 P_2 + G_0 P_2 P_1 + P_2 P_1 P_0 C_n \\
 \bar{G} &= \overline{G_3 + G_2 P_3 + G_1 P_3 P_2 + G_0 P_3 P_2 P_1} \\
 \bar{P} &= P_3 P_2 P_1 P_0
 \end{aligned}$$



specifications

MAXIMUM RATINGS	RECOMMENDED OPERATING CONDITIONS	ELECTRICAL CHARACTERISTICS
Page 62	Page 62	Page 63, group 3, except as on page 169

TYPES TF4582A, TP4582A LOOK-AHEAD CARRY GENERATORS

FUNCTION TABLE
FOR C_{n+x} OUTPUT

INPUTS			OUTPUT
\bar{G}_0	P_0	C_n	C_{n+x}
L	X	X	H
X	L	H	H
All other combinations			L

FUNCTION TABLE FOR C_{n+z} OUTPUT

INPUTS							OUTPUT
\bar{G}_2	\bar{G}_1	\bar{G}_0	\bar{P}_2	\bar{P}_1	\bar{P}_0	C_n	C_{n+z}
L	X	X	X	X	X	X	H
X	L	X	L	X	X	X	H
X	X	L	L	L	X	X	H
X	X	X	L	L	L	H	H
All other combinations							L

FUNCTION TABLE
FOR C_{n+y} OUTPUT

INPUTS					OUTPUT
\bar{G}_1	\bar{G}_0	\bar{P}_1	\bar{P}_0	C_n	C_{n+y}
L	X	X	X	X	H
X	L	L	X	X	H
X	X	L	L	H	H
All other combinations					L

FUNCTION TABLE FOR \bar{G} OUTPUT

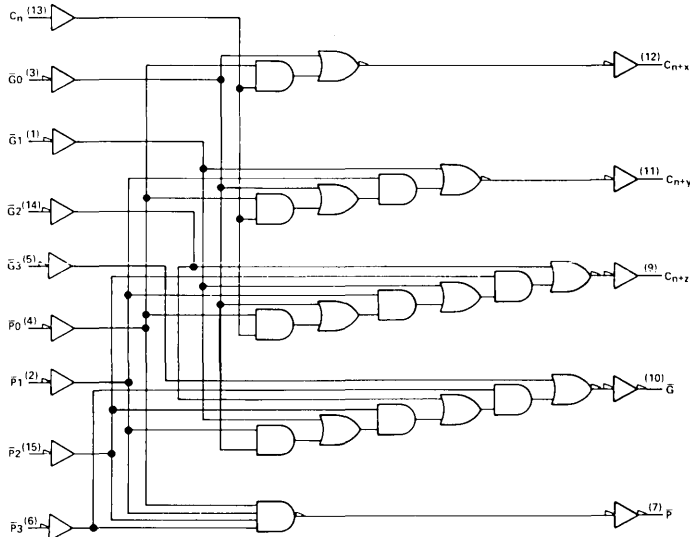
INPUTS							OUTPUT
\bar{G}_3	\bar{G}_2	\bar{G}_1	\bar{G}_0	\bar{P}_3	\bar{P}_2	\bar{P}_1	\bar{G}
L	X	X	X	X	X	X	L
X	L	X	X	L	X	X	L
X	X	L	X	L	L	X	L
X	X	X	L	L	L	L	L
All other combinations							H

H = high level, L = low level, X = irrelevant
Any inputs not shown in a given table are irrelevant with respect to that output.

FUNCTION TABLE
FOR \bar{P} OUTPUT

INPUTS				OUTPUT
\bar{P}_3	\bar{P}_2	\bar{P}_1	\bar{P}_0	\bar{P}
L	L	L	L	L
All other combinations				H

functional block diagram



TYPES TF4582A, TP4582A LOOK-AHEAD CARRY GENERATORS

electrical characteristics

$V_{DD} = 5$ and 10 V

PARAMETER	TEST CONDITIONS†	TF4582A				TP4582A				UNIT	
		$V_{DD} = 5$ V		$V_{DD} = 10$ V		$V_{DD} = 5$ V		$V_{DD} = 10$ V			
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
I_{DD} or Quiescent supply current – I_{SS}	$V_I = V_{DD}$ or 0, No load	$T_A = \text{MIN}$ or 25°C		0.5		1		5		10	
		$T_A = \text{MAX}$		30		60		150		300	

$V_{DD} = 15$ V

PARAMETER	TEST CONDITIONS†	TF4582A		TP4582A		UNIT	
		MIN	MAX	MIN	MAX		
		I_{DD} or Quiescent supply current – I_{SS}	$V_I = V_{DD}$ or 0, No load	$T_A = \text{MIN}$ or 25°C			3
$T_A = \text{MAX}$				180		900	

† $T_A = \text{MIN}$ or MAX refers to the respective values of temperature specified under recommended operating conditions.

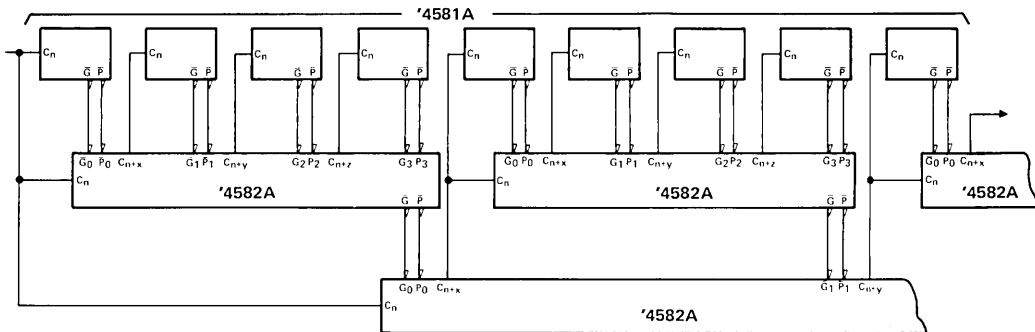
switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	TF4582A				TP4582A				UNIT
		$V_{DD} = 5$ V		$V_{DD} = 10$ V		$V_{DD} = 5$ V		$V_{DD} = 10$ V		
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH} Propagation delay time, low-to-high-level output	$C_L = 50$ pF §, $R_L = 200$ k Ω , See Note 1	550		225		950		410		ns
t_{PHL} Propagation delay time, high-to-low-level output		550		225		950		410		ns
t_{TLH} Transition time, low-to-high-level output		350		150		400		220		ns
t_{THL} Transition time, high-to-low-level output		350		150		400		220		ns

§With a 15-pF load, these devices switch with times similar to those of the Motorola MC14582.

NOTE 1: See load circuit and voltage waveforms on page 170.

TYPICAL APPLICATION DATA



\bar{A} and \bar{B} inputs and \bar{F} outputs of '4581A are not shown.

64-BIT ALU, FULL-CARRY LOOK-AHEAD IN THREE LEVELS

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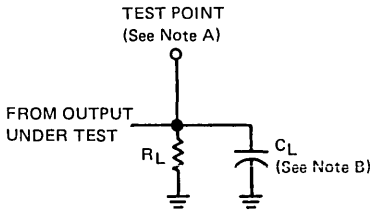
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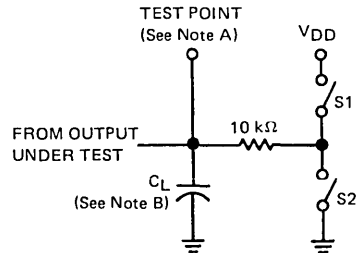
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CMOS LOGIC CIRCUITS

PARAMETER MEASUREMENT INFORMATION

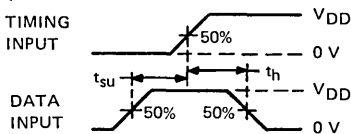


LOAD CIRCUIT FOR PROPAGATION DELAY AND TRANSITION TIMES

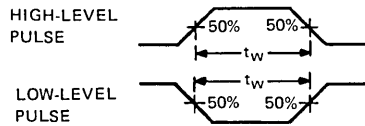


LOAD CIRCUIT FOR ENABLE AND DISABLE TIMES OF THREE-STATE OUTPUTS

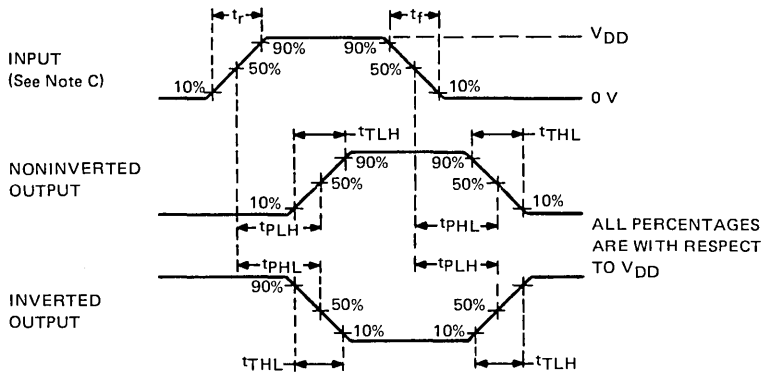
NOTES: A. The waveforms are monitored on an oscilloscope with the following characteristics: $t_r \leq 10\text{ ns}$, $R_{in} \geq 1\text{ M}\Omega$.
B. C_L includes probe and jig capacitance.



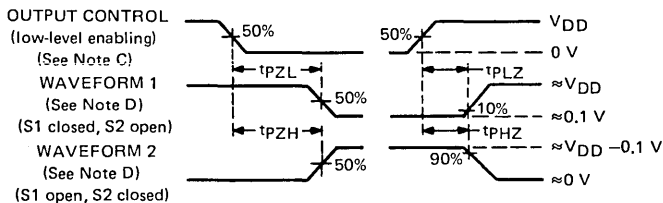
VOLTAGE WAVEFORMS SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS PULSE WIDTHS



VOLTAGE WAVEFORMS PROPAGATION DELAY AND TRANSITION TIMES



VOLTAGE WAVEFORMS ENABLE AND DISABLE TIMES

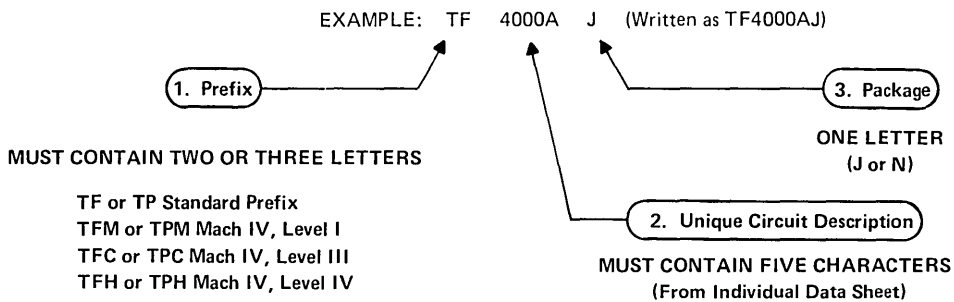
NOTES: C. Input pulse is supplied by a generator having the following characteristics: $Z_{out} = 50\ \Omega$, $PRR = 10\text{ kHz}$, $t_r \leq 20\text{ ns}$, $t_f \leq 20\text{ ns}$.
D. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
E. In the examples above, the phase relationships between inputs and outputs have been chosen arbitrarily.

CMOS ORDERING INSTRUCTIONS AND MECHANICAL DATA

CMOS ORDERING INSTRUCTIONS AND MECHANICAL DATA

general

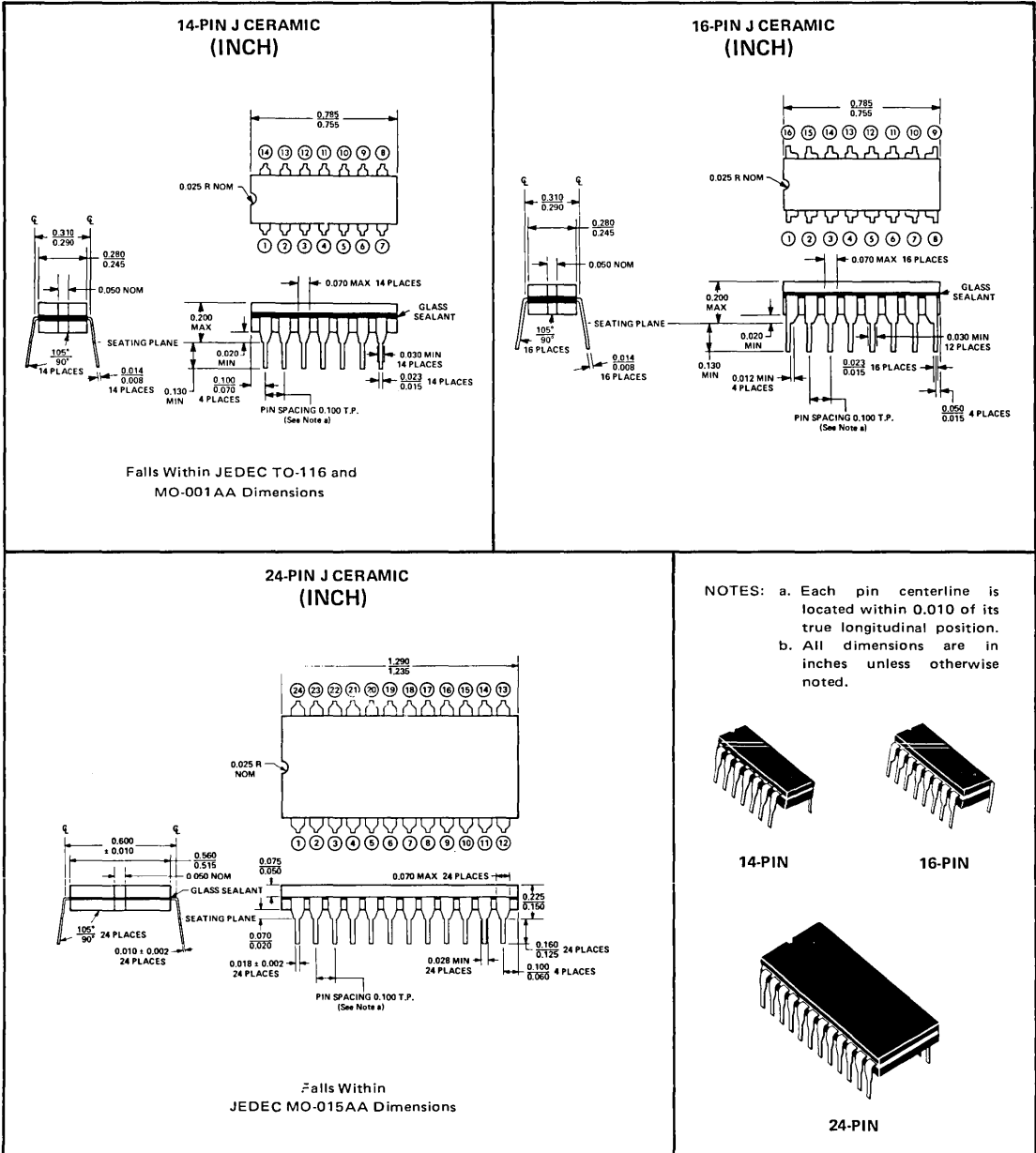
All CMOS circuits in this book are available in the ceramic dual-in-line package (outline J). Circuits with type number prefix TP are also available in the plastic dual-in-line package (outline N). Factory orders for these circuits should include a three-part type number as explained in the following example.



CMOS ORDERING INSTRUCTIONS AND MECHANICAL DATA

J ceramic dual-in-line packages (inch dimensions, see page 174 for metric dimensions)

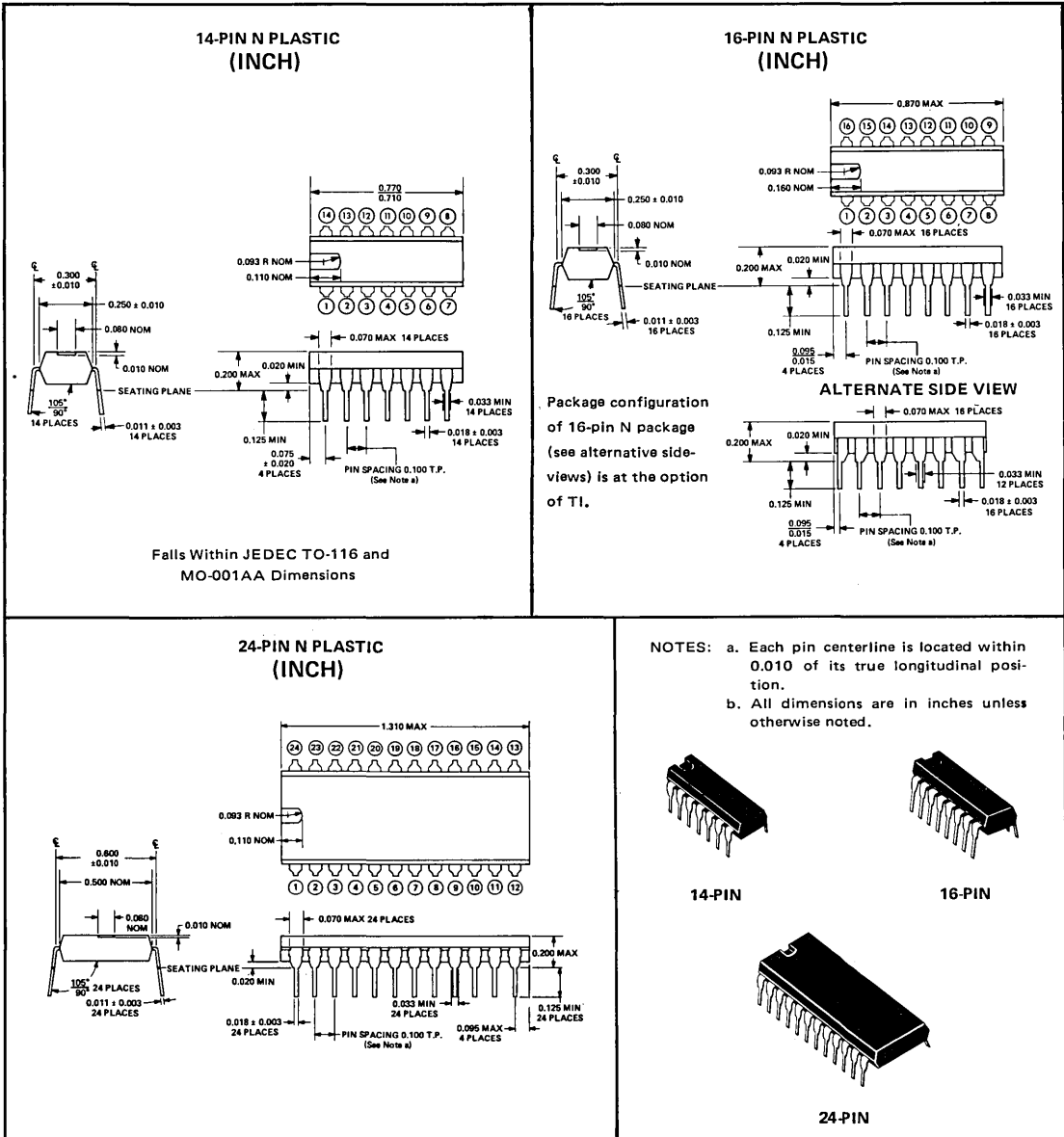
These hermetically sealed dual-in-line packages consist of a ceramic base, ceramic cap, and a 14-, 16-, or 24-lead frame. The packages are intended for insertion in mounting-hole rows on 0.300-inch or 0.600-inch centers. Once the leads are compressed and inserted, sufficient tension is provided to secure the package in the board during soldering. Tin-plated ("bright-dipped") leads require no additional cleaning or processing when used in soldered assembly.



CMOS ORDERING INSTRUCTIONS AND MECHANICAL DATA

N plastic dual-in-line packages (inch dimensions, see page 175 for metric dimensions)

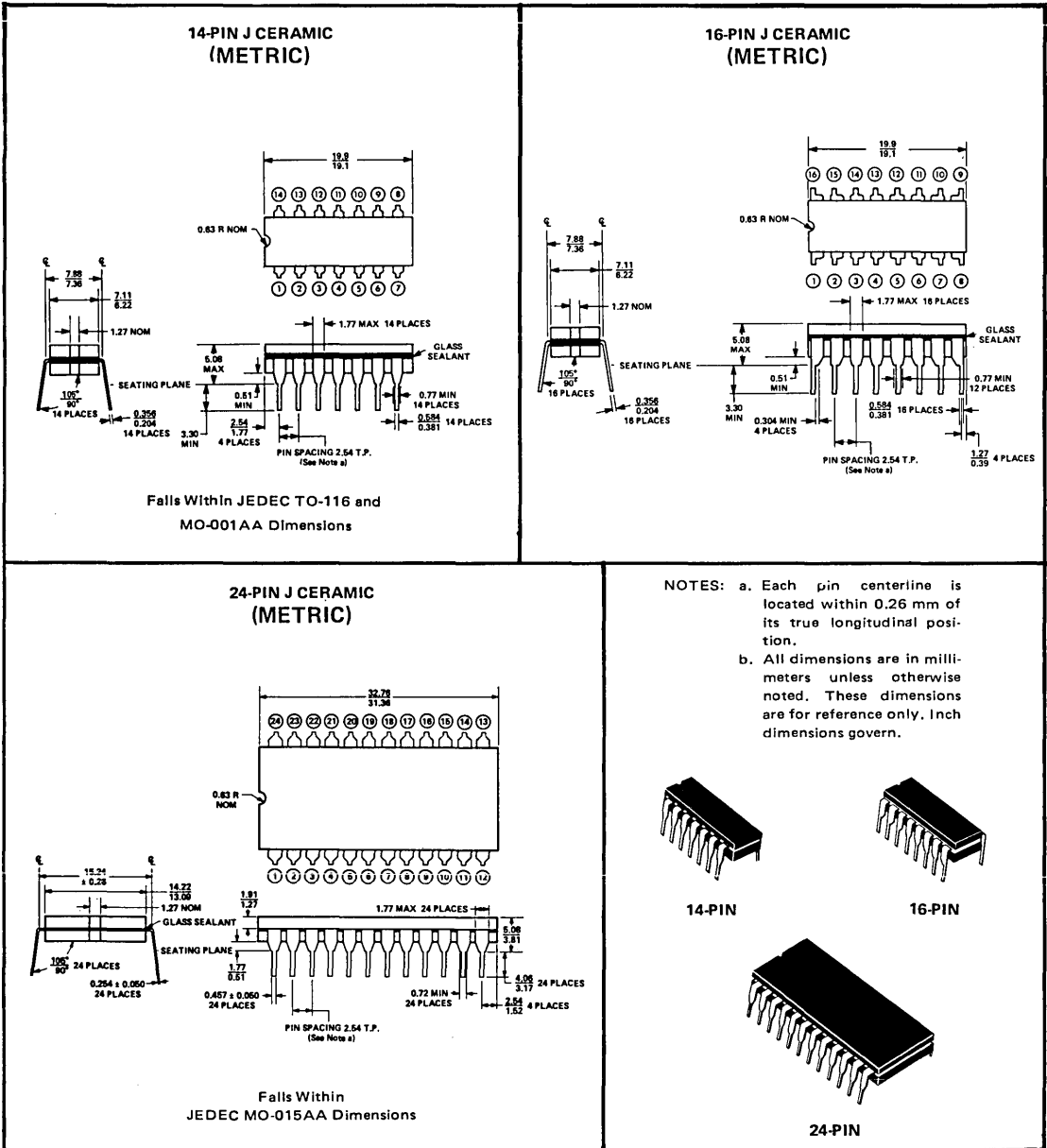
These dual-in-line packages consist of a circuit mounted on a 14-, 16-, or 24-lead frame and encapsulated within an electrically nonconductive plastic compound. The compound will withstand soldering temperature with no deformation and circuit performance characteristics remain stable when operated in high-humidity conditions. The packages are intended for insertion in mounting-hole rows on 0.300-inch or 0.600-inch centers. Once the leads are compressed and inserted, sufficient tension is provided to secure the package in the board during soldering. Leads require no additional cleaning or processing when used in soldered assembly.



CMOS ORDERING INSTRUCTIONS AND MECHANICAL DATA

J ceramic dual-in-line packages (metric dimensions, see page 172 for inch dimensions)

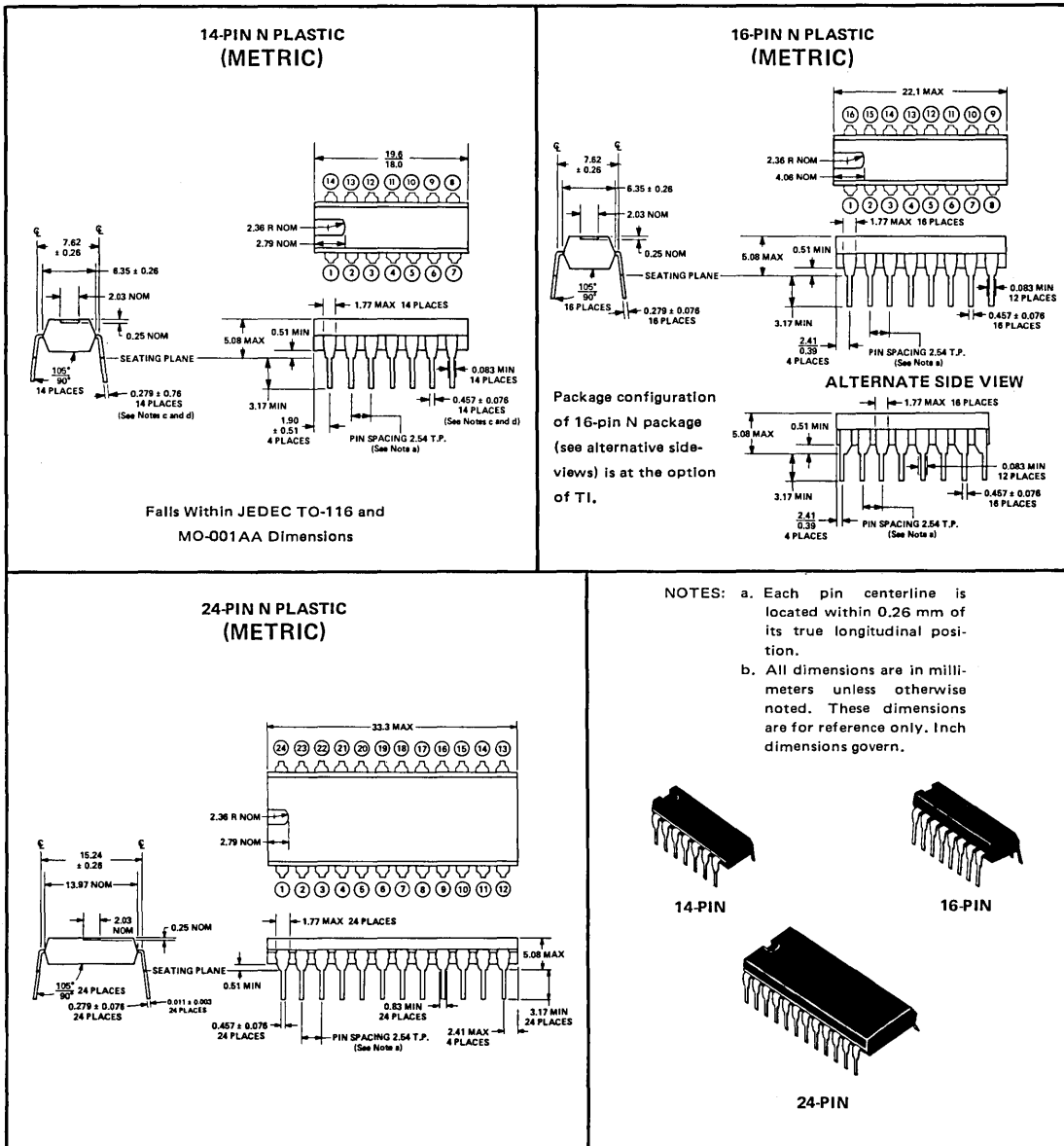
These hermetically sealed dual-in-line packages consist of a ceramic base, ceramic cap, and a 14-, 16-, or 24-lead frame. The packages are intended for insertion in mounting-hole rows on 7.62-mm or 15.24-mm centers. Once the leads are compressed and inserted, sufficient tension is provided to secure the package in the board during soldering. Tin-plated ("bright-dipped") leads require no additional cleaning or processing when used in soldered assembly.



CMOS ORDERING INSTRUCTIONS AND MECHANICAL DATA

N plastic dual-in-line packages (metric dimensions, see page 173 for inch dimensions)

These dual-in-line packages consist of a circuit mounted on a 14-, 16-, or 24-lead frame and encapsulated within an electrically nonconductive plastic compound. The compound will withstand soldering temperature with no deformation and circuit performance characteristics remain stable when operated in high-humidity conditions. The packages are intended for insertion in mounting-hole rows on 7.62-mm or 15.24-mm centers. Once the leads are compressed and inserted, sufficient tension is provided to secure the package in the board during soldering. Leads require no additional cleaning or processing when used in soldered assembly.



TI worldwide sales offices

ALABAMA

304 Wynn Drive
Huntsville, Alabama 35806
205-837-7530

ARIZONA

4820 N. Black Canyon Hwy.
Suite 202
Phoenix, Arizona 85017
602-248-8028

CALIFORNIA

831 S. Douglass St.
El Segundo, California 90245
213-973-2571

3186J Airway
Costa Mesa, California 92626
714-540-7311

Balboa Towers Bldg., Suite 805
5252 Balboa Avenue
San Diego, California 92117
714-279-2622

776 Palomar Avenue
Sunnyvale, California 94086
408-732-1840

COLORADO

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Denver, Colorado 80231
303-751-1780

CONNECTICUT

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203-281-0074

FLORIDA

601 W. Oakland Park Blvd.
Fort Lauderdale, Florida 33311
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1505 Cedar Way
Holiday, Florida 33589
813-934-4115

2221 Lee Road, Suite 108
Winter Park, Florida 32789
305-644-3535

ILLINOIS

1701 Lake Avenue, Suite 300
Glenview, Illinois 60025
312-729-5710

INDIANA

3705 Rupp Drive
Arch Bldg.
Fort Wayne, Indiana 46805
219-484-0606

2346 S. Lynhurst Dr., Suite 101
Indianapolis, Indiana 46241
317-248-8555

MASSACHUSETTS

504 Totten Pond Road
Walham, Mass. 02154
617-890-7400

MICHIGAN

Central Park Plaza
26211 Central Park Blvd., Suite 215
Southfield, Michigan 48076
313-353-0830

MINNESOTA

A.I.C. Bldg., Suite 202
7615 Metro Blvd.
Edina, Minn. 55435
612-835-2900

NEW JERSEY

1245 Westfield Ave.
Clark, New Jersey 07066
201-574-9800

NEW MEXICO

1101 Cardenas Drive, N.E.,
Room 215
Albuquerque, New Mexico 87110
505-265-8491

NEW YORK

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OHIO

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Dayton, Ohio 45432
513-253-3121

OREGON

10700 S.W. Beaverton Hwy., Suite 111
Beaverton, Oregon 97005
503-643-1182

PENNSYLVANIA

275 Commerce Drive
Fort Washington, Pa. 19034
215-643-6450

TEXAS

Headquarters - Gen. Offices
Dallas, Texas 75222
214-238-2011

MS366 - P.O. Box 5012
Dallas, Texas 75222
214-238-6805

3939 Ann Arbor
Houston, Texas 77042
713-785-6906

VIRGINIA

8512 Trabue Road
Richmond, Virginia 23235
804-320-3830

WASHINGTON

700 112th N.E., Suite 101
Bellevue, Washington 98004
206-455-3480

WASHINGTON, D.C.

1500 Wilson Blvd., Suite 1100
Arlington, Virginia 22209
703-525-0336

ARGENTINA

Texas Instruments Argentina S.A.I.C.F.

C.C. Box 2296 - Correo Central
Buenos Aires, Argentina
748-1141

ASIA

Texas Instruments Asia Limited

5F Aoyama Tower Bldg.
24-15 Minami Aoyama Chome
Minato-ku, Tokyo 107, Japan
402-6171

11A-15 Chatham Road
First Floor, Kowloon
Hong Kong
3-670061

Texas Instruments Singapore (PTE) Ltd.
27 Kallang Place
Singapore 1, Rep. of Singapore
253-1122

Texas Instruments Taiwan Limited
P.O. Box 3999
Taipei, Chung Ho, Taiwan
921 623

Texas Instruments Malaysia SDN. BHD.
Number 1 Lorong Enggang 33
Kuala Lumpur 15-07, Malaysia
647 911

AUSTRALIA

Texas Instruments Australia Ltd.

Suite 205, 118 Great North Road
Five Dock N.S.W. 2046 Australia
831-2555

Box 63, Post Office
171-175 Philip Highway
Elizabeth 5112 South Australia
255-2066

BRAZIL

Texas Instrumentos Electronicos
do Brasil Ltda.

Rua Joao Annes, 153-Lapa
Caixa Postal 30.103, CEP 01.000
Sao Paulo, SP, Brasil
260-2956

CANADA

Texas Instruments Incorporated

935 Montee De Liesse
St. Laurent H4T 1R2
Quebec, Canada
514-341-3232

5F Caesar Avenue
Ottawa 12
Ontario, Canada
613-825-3716

280 Centre Str. East
Richmond Hill (Toronto)
Ontario, Canada
716-856-4453

DENMARK

Texas Instruments Denmark

46D, Marielundvej
2730 Herlev, Denmark
(01) 91 74 00

FINLAND

Texas Instruments Finland OY

Fredrikinkatu 75, A7
Helsinki 10, Finland
44 71 71

FRANCE

Texas Instruments France

Boite Postale 5
06 Villeneuve-Loubet, France
31 03 64

La Boursiere, Bloc A
R.N. 186, 92350 Le Plessis Robinson
630.23.43

30-31 Quai Rambaud
69 Lyon, France
42 78 50

GERMANY

Texas Instruments Deutschland GmbH

Haggerty Str. 1
8050 Freising, Germany
08161/80-1

Frankfurter Ring 243
8000 Munich 40, Germany
089/325011-15

Lazarettstrasse, 19
4300 Essen, Germany
02141/20916

Krugerstrasse 24
1000 Berlin 49, Germany
0311/74 44 041

Akazlenstrasse 22-26
6230 Frankfurt-Griesheim
Germany
0611/39 90 61

Steimböcker Hof 8A
3000 Hannover, Germany
0511/55 60 41

Krefelderstrasse 11-15
7000 Stuttgart 60, Germany
0711/54 70 01

ITALY

Texas Instruments Italia SpA

Via Della Giustizia 9
20125 Milan, Italy
02-688 31 41

Via L. Mancinella 65
00199 Roma, Italy
06-83 77 45

Via Montebello 27
10124 Torino, Italy
011-83 22 76

MEXICO

Texas Instruments de Mexico S.A.

Poniente 116 #489
Col. Industrial Vallejo
Mexico City, D.F., Mexico
567-92-00

NETHERLANDS

Texas Instruments Holland N.V.

Entrepot Gebouw-Kamer 225
P.O. Box 7603
Schiphol-Centrum
020-17 36 36

NORWAY

Texas Instruments Norway A/S
Sentrumskontorene
Brugaten 1
Oslo 1, Norway
33 18 80

SWEDEN

Texas Instruments Sweden AB

S-104 40 Stockholm 14
Skeppargatan 26
67 98 35

UNITED KINGDOM

Texas Instruments Limited

Manton Lane
Bedford, England
0234-67466



